

Electron tubes

Part 4 June 1972

Receiving tubes

972

Receiving tubes

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ELECTRON TUBES

Part 4

June 1972

General section



DATA HANDBOOK SYSTEM

To provide you with a comprehensive source of information on electronic components, subassemblies and materials, our Data Handbook System is made up of three series of handbooks, each comprising several parts.

The three series, identified by the colours noted, are:

ELECTRON TUBES (9 parts)

BLUE

SEMICONDUCTORS AND INTEGRATED CIRCUITS (6 parts)

RED

COMPONENTS AND MATERIALS (7 parts)

GREEN

The several parts contain all pertinent data available at the time of publication, and each is revised and reissued annually; the contents of each series are summarized on the following pages.

We have made every effort to ensure that each series is as accurate, comprehensive and up-to-date as possible, and we hope you will find it to be a valuable source of reference. Where ratings or specifications quoted differ from those published in the preceding edition they will be pointed out by arrows. You will understand that we can not guarantee that all products listed in any one edition of the handbook will remain available, or that their specifications will not be changed, before the next edition is published. If you need confirmation that the published data about any of our products are the latest available, may we ask that you contact our representative. He is at your service and will be glad to answer your inquiries.

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Miscellaneous devices

Part 4 Receiving tubes June 1972

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July 1971

Part 7 Gas-filled tubes

Voltage stabilizing and reference tubes
Counter, selector, and indicator tubes
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Thyratrons
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Part 8 T.V.Picture tubes August 1971

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Part 3 High frequency; Switching

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Part 4 Special types

General
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Dual transistors
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Part 5 Linear Integrated Circuits

General

Part 6 Digital integrated circuits

General
DTL (FC family)
DTL/HNIL (FZ family)
TTL (FJ family)

September 1971

Thyristors, diacs, triacs Rectifier stacks Accessories Heatsinks

October 1971

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November 1971

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COMPONENTS AND MATERIALS (GREEN SERIES)

This series consists of the following parts, issued on the dates indicated.

Part 1 Circuit Blocks, Input/Output Devices, October 1971 Electro-mechanical Components *), Peripheral Devices

Circuit blocks 40-Series Counter modules 50-Series Norbits 60-Series, 61-Series Circuit blocks 90-Series Input/output devices
Electro-mechanical components *)
Peripheral devices

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Fixed resistors
Variable resistors
Non-linear resistors
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Paper capacitors and film capacitors Electrolytic capacitors Variable capacitors

December 1971

February 1972

Part 3 Radio, Audio, Television

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Coil assemblies
Piezoelectric ceramic resonators
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Audio and mains transformers
Television tuners, aerial input assemblies
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Components for colour television
Deflection assemblies for camera tubes

Part 4 Magnetic Materials, Piezoelectric Ceramics, Ni Cd cells May 1972

Ferrites for radio, audio and television Small coils and assembling parts Ferroxcube potcores and square cores Ferroxcube transformer cores Piezoelectric ceramics Permanent magnet materials Cylindrical nickel cadmium cells

Part 5 Memory Products, Magnetic Heads, Quartz Crystals, June 1971 Microwave Devices, Variable Transformers

Ferrite memory cores Matrix planes, matrix stacks Complete memories Magnetic heads Quartz crystal units, crystal filters Isolators, circulators Variable mains transformers

Part 6 Electric Motors and Accessories, Timing and Control Devices

August 1971

Stepper motors Small synchronous motors Asynchronous motors Small d.c. motors Tachogenerators and servomotors Indicators for built-in test equipment

Part 7 Circuit Blocks

Circuit blocks 100kHz Series Circuit blocks 1-Series Circuit blocks 10-Series September 1971

Circuit blocks for ferrite core memory drive

^{*)} From October 1971 published in Part 1 instead of Part 5.

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LIST OF SYMBOLS

Symbols denoting electrodes and electrode/element connections Heater or filament Heater or filament tap f_{c} Cathode k Input cathode lead ki Output cathode lead ko Grid g Electrostatic deflection plate or rod D Fluorescent screen 0 Anode Anode of a detection diode d Tube pin which must not be connected externally i.c. Tube pin which may be connected externally n.c. External conductive coating m Internal shield

Remarks

Equivalent electrodes of a multiple unit tube are distinguished by means of accents; e.g. the anodes of a double-anode rectifying tube are indicated by a and a'.

Similar electrodes of the same electrode system are distinguished by means of an additional numeral; the electrode nearest to the cathode has the lowest number.

The electrodes of multiple-unit tubes, in which the units are different, are distinguished by means of the following indices:

diode	D
triode	Т
tetrode	Q
pentode	P
hexode or heptode	Н

Symbols denoting voltages (average values unless otherwise stated)

Symbol for voltage, followed by an index denoting the relevant electrode/element	V
Heater or filament voltage	$V_{\mathbf{f}}$
Peak value of a voltage	V_p
Peak to peak value of a voltage	V _{pp}
Supply voltage of tube electrodes	Vb.
Anode voltage of a detection diode	v_d
RMS value of a voltage	v_{RMS}
Heater starting voltage	V_{fo}
Grid voltage	V_g
A.C. input voltage	$V_{\mathbf{i}}$
Voltage between cathode and heater	V_{kf}
D.C. voltage supplied by a rectifying tube	V_{0}
A.C. output voltage	V_{o}
Voltage for gain control	v_R
Transformer voltage (secondary)	v_{tr}
Anode voltage under cold condition or cut-off condition (I_k approx.0)	v_{a_0}
Screen grid voltage under cold condition or cut-off condition (I_k approx.0)	$v_{g_{2o}}$

Remarks

In the case of indirectly heated tubes the electrode voltages are specified with respect to the cathode.

In the case of directly heated tubes the electrode voltages are specified with respect to the negative terminal of the filament, unless otherwise stated.

Symbols denoting currents

Remarks

The positive electrical current is directed opposite to the direction of the electron current.

Ι

The symbols quoted represent average values unless otherwise stated.

Symbol	for	current	followed	by	an	index	
--------	-----	---------	----------	----	----	-------	--

denoting the relevant electrode

Heater or filament current If

Anode current I_a

Current of a detection diode Id

RMS value of a current I_{RMS}

Grid current I_{ϱ}

Cathode current I_k

Current to fluorescent screen I o

D.C. current supplied by a rectifying tube I_{O}

Peak value of a current I_p

Symbols denoting powers

Grid dissipation

Symbol for power followed by an index denoting the relevant electrode W

Anode dissipation W_a Wg

Input power W_{i}

 w_{i_a} Anode supply D.C. power

Dissipation of a fluorescent screen

We Output power Wo

Symbols denoting capacitances

See IEC Publication 100

Symbols denoting resistance and impedance

Protecting resistance in the anode lead of

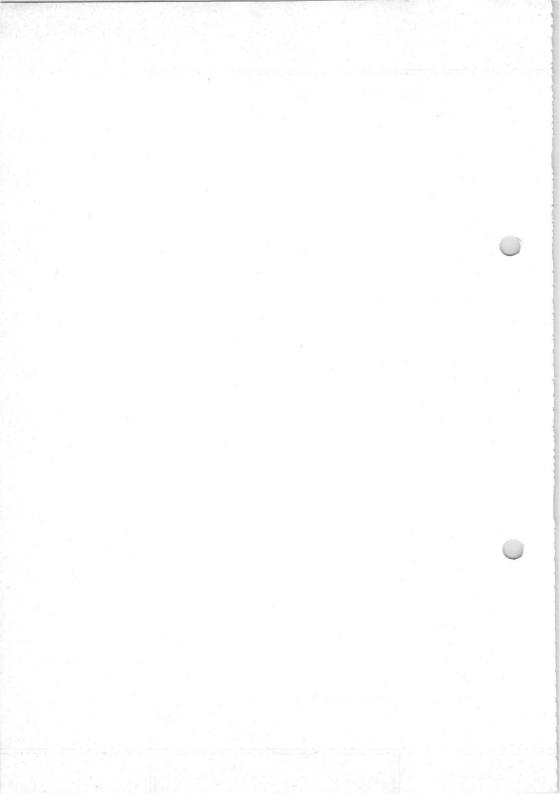
a rectifying tube

When for one of the following symbols Z is used instead of an R the word "resistance" should read "impedance" $\,$

External resistance in an anode lead	Ra
External A.C. resistance or load resistance in an anode lead	R _a ∼
Load resistance of a push-pull amplifier	
(anode to anode)	Raa~
Equivalent noise resistance	Req
External resistor in a grid lead or	
grid circuit resistance	Rg
Input resistance	rg
Internal resistance	R_{i}
Resistor in a cathode lead	R_k
External resistance between cathode and heater	Rkf

 R_{t}

Symbols denoting various quantities	
Brightness	В
Bandwidth	В
Distortion factor	d
n-th harmonic distortion	d _n
Noise factor	F
Frequency	f
Pulse repetition rate	f_{imp}
Power gain	G
Voltage gain	$V_0/V_{i,g}$
Height above sea level	h
Magnetic field strength	Н
Cross modulation factor	K
Hum modulation factor	m_b
Transformer ratio	n
Transconductance	S
Conversion conductance	S_{c}
Effective transconductance of an oscillator	Seff
Temperature	t
Ambient temperature	t _{amb}
Time	T
Averaging time of current or voltages	T_{av}
Cathode heating time	T_h
Pulse duration	T_{imp}
Shadow section on a fluorescent screen	α
Light sector on a fluorescent screen	β
Duty factor	δ
Phase angle	φ
Efficiency	η
Wavelength	λ
Amplification factor	μ
Amplification factor of grid No. 2 with	
respect to grid No.1	$\mu_{g_2g_1}$



GENERAL OPERATIONAL RECOMMENDATIONS RECEIVING TUBES

CONTENTS

- 1. General
- 2. Spread in tube characteristics
- 3. Spread and variation in operating conditions
- 4. Limiting values
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- 9. Heater-to-cathode circuit
- 10. Suppressor grid circuit
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GENERAL OPERATIONAL RECOMMENDATIONS RECEIVING TUBES

1. GENERAL

Where deviations from these directives are permissible or necessary, statements to that effect will be made on the relevant data sheets. If applications are considered not referred to in the data sheet of the relevant tube type extra care should be taken with circuit design to avoid that the tube is overloaded due to unfavourable operating conditions.

Users are warned for applying a tube in circuits where use is made of tube characteristics not controlled by the manufacturer. When at a later date batches of tubes are delivered which show different values for these characteristics this may result in unsatisfactory performance of the equipment.

2. SPREAD IN TUBE CHARACTERISTICS

Equipment design should be based on the characteristics as stated in the data sheets.

Tube data not stated as maximum or minimum values apply to a nominal tube. When measurements are carried out on a small number of tubes, and in particular on new tube types it should be taken into account that average values and the spread figures may differ from those obtained for larger quantities.

No guarantee is given for values of characteristics in settings substantially differing from those specified in the data sheets.

3. SPREAD AND VARIATION IN OPERATING CONDITIONS

The operating conditions of the tube in the equipment are expressed as a number of parameter values each of which is subject to spread and/or variation.

- 3.1 Spread. Spread in a parameter value will result in individual values deviating permanently from the average value; spread is due to e.g. component value deviations. The average value is the average of such a number of individual values taken at random that an increase of the number will have a negligible influence on the average value.
- $3.2 \, \underline{\text{Variation.}}$ Variation of a parameter value is the change of value occurring as a function of time, e.g. due to supply voltage fluctuations.

The average value is calculated over a period such that a prolongation of that period will have a negligible influence on the average value.

4. LIMITING VALUES

- 4.1 Limiting values are in accordance with the applicable rating system as defined by I.E.C. publication 134.
 - Reference may be made to one of the following 3 rating systems.
- 4.1.1 Absolute maximum rating system. Absolute maximum ratings are limiting values of operating and environmental conditions applicable to any electronic device of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking no responsibility for equipment variations, environmental variations, and the effects of changes in operating conditions due to variations in the characteristics of the device under consideration and of all other electronic devices in the equipment.

The equipment manufacturer should design so that, initially and throughout life, no absolute maximum value for the intended service is exceeded with any device under the worst probable operating conditions with respect to supply voltage variation, equipment components spread and variation, equipment control adjustment, load variations, signal variation, environmental conditions, and spread or variations in characteristics of the device under consideration and of all other electronic devices in the equipment.

4.1.2 Design-maximum rating system. Design-maximum ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device* of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking responsibility for the effects of changes in operating conditions due to variations in the characteristics of the electronic device under consideration.

The equipment manufacturer should design so that, initially and throughout life, no design-maximum value for the intended service is exceeded with a bogey device under the worst probable operating conditions with respect to supply-voltage variation, equipment component variation, variation in characteristics of all other devices in the equipment, equipment control adjustment, load variation, signal variation and environmental conditions.

- 4.1.3 Design-centre rating system. Design-centre ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device* of a specified type as defined by its published data, and should not be exceeded under average conditions.
- Note*. A bogey tube is a tube whose characteristics have the published nominal values for the type. A bogey tube for any particular application can be obtained by considering only those characteristics which are directly related to the application.

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These values are chosen by the device manufacturer to provide acceptable serviceability of the device in average applications, taking responsibility for normal changes in operating conditions due to rated supply-voltage variation, equipment component spread and variation, equipment control adjustment, load variation, signal variation, environmental conditions, and variations or spread in the characteristics of all electronic devices.

The equipment manufacturer should design so that, initially, no design-centre value for the intended service is exceeded with a bogey electronic device * in equipment operating at the stated normal supply-voltage.

- 4.2 If the tube data specify limiting values according to more than one rating system the circuit has to be designed so that none of these limiting values is exceeded under the relevant conditions.
- 4.3 In addition to the limiting values given in the individual data sheets the directives in the following paragraphs should be observed.

5. ELECTRODE VOLTAGES

- 5.1 All electrode voltages are given with respect to cathode.
- 5.2 Two limiting values of electrode voltage are given
 - a) V_{a_0} , $V_{g_{20}}$ etc. These values are continuously permitted with cold cathode. They are also permitted as peak voltage during operation when a D.C. voltage in combination with a superimposed A.C. voltage is present at the electrode provided that the peak value coincides with approx. zero electrode current.
 - b) V_a , V_{g_2} etc. These values are D.C. components of the ele

These values are D.C. components of the electrode voltages and are continuously permitted.

In circuits with automatic gain control the D.C. component may exceed the published limiting value with 20% provided that the increase of voltage results solely from the a.g.c. action and that maximum voltage coincides with approximately zero electrode current.

Proper functioning of the tubes at supply voltages lower than 50 volts cannot be guaranteed if these values are not quoted under the operating characteristics. Unless otherwise stated all values refer to positive voltages.

Floating electrodes. All tube electrodes should have a D.C. connection to the cathode (no floating electrodes).

6. ELECTRODE CURRENT

The limiting values I_a , I_{g_2} , I_k etc. are the D.C. components of the electrode currents averaged over any 50 ms period.

If no specific pulse ratings apply, a peak value of three times I_a , I_{g_2} , I_k etc. is permitted for maximum 25 ms.

See note on previous page.

Spread and variation in electrode currents should be restricted so that with nominal tubes the specified design centre limiting values are not exceeded by more than 10% under the worst probable conditions.

7. ELECTRODE DISSIPATION

The limiting values W_a , W_{g_2} etc. are the average values, obtained by averaging over any 1 s period.

7.1 If not otherwise indicated the quoted operating conditions for audio output tubes are permitted only with speech and music signals.

When for power output tubes a limiting value $W_{g_{2p}}$ is stated this value applies only in the case of speech and music drive and it should not be exceeded when measured with a sinusoidal signal and at maximum output.

With class B operation and speech and music excitation the quoted limiting value of anode dissipation is allowed to be exceeded by max. 10% if measured with a sinusoidal signal at 2/3 of maximum drive.

When the operating conditions differ from those stated a non-decoupled series resistor of 0.5 to 1 $k\Omega$ may be required to avoid exceeding the limiting values of screen grid dissipation.

When load values vary during operation care should be taken that the limiting values of W_a or W_{g_2} are not exceeded.

Spread and variation in the electrode dissipation of audio output tubes should be restricted so that with bogey tubes the specified design centre limiting values are not exceeded by more than 20% under the worst probable conditions.

7.2 For all other types the quoted design centre limits for the electrode dissipations should not be exceeded by more than 15% with bogey tubes under the worst probable conditions unless otherwise stated in the relevant data sheets.

8. HEATER CIRCUIT

Any deviation from the nominal heater voltage (in case of parallel connection) or from the nominal heater current (in case of series connection) has a detrimental effect on tube performance and life, and should therefore be kept at a minimum. Such deviations may be caused by:

- a) Mains voltage fluctuations.
- b) Spread in the characteristics of components such as transformers, resistors, capacitors etc.

Designers of heater circuits are strongly recommended to bear this in mind when dealing with equipment to be used in areas where the actual mains voltage is likely to differ from the nominal value.

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8.1 Parallel connection

The maximum deviation of the heater voltage should not exceed $\pm\,15\%$ (design max. value).

This condition will be fulfilled when the mains voltage fluctuates by $\pm~10\%$ and a ordinary transformer (see below) is used.

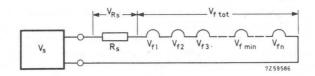
8.2 Series connection

The maximum deviation of the heater current should not exceed \pm 8% (design max. value).

When a small number of tubes with large differences in the heater voltage is used in series connection combined with a series resistor or a series capacitor, the maximum permitted deviation of the heater current may be exceeded.

To avoid this, certain restrictions must be imposed on the composition of the heater chain; the maximum part of the supply voltage that can be eliminated, and the tolerances of the voltage dropper in series with the heaters.

A number of circuits for If = 300 mA will be described in detail below.



V_S = source voltage (mains voltage or mains voltage stepped down via a transformer)

VRs = voltage drop over series resistor

 $V_{ftot.} = V_{f1} + V_{f2} + V_{f3} + V_{fmin.} + \dots V_{fmin.} + \dots$

 $V_{fmin.}$ = lowest individual heater voltage of all tubes in the chain

R_S = series resistor

Voltage source

The following spreads have been taken into account for the source voltage:

- Mains voltage spread $\pm 10\%$ either or not combined with the voltage spread caused by a transformer with a permanent deviation from the nominal value of $\pm 1\%$ and with a spread of $\pm 2\%$ (ordinary, well made transformer).

The following circuits are allowed:

- 8.2.1 Supply directly from a voltage source (V_S = V_{ftot.})
 - No restrictions.
- 8.2.2 Supply from a voltage source via a 5% series resistor ($V_S = V_{RS} + V_{ftot.}$)
 - a. One single tube: permitted if $\frac{VRs}{V_{ftot}} \le 2$
 - b. Heater chain consisting of 2 or more tubes:

the maximum permitted ratio $\frac{VRs}{Vftot}$ can be read from diagram number 1 as follows:

Determine $\frac{V_{f\,min.}}{V_{f\,tot.}}$ of the heater chain. Draw a vertical line through the corresponding point in the diagram. Draw a horizontal line through the point of intersection of this vertical line with the line which indicates the total number of tubes in the chain. The point of intersection of this horizontal line with the vertical axis gives the maximum permitted ratio between the series resistor and the sum of the heater voltages of all tubes in the chain.

- 8.2.3 Supply from a voltage source via a series diode $(\frac{V_s}{\sqrt{2}} = V_{ftot.})$
 - No restrictions.
- 8.2.4 Supply from a voltage source via a series diode and a series resistor

$$(\frac{V_S}{\sqrt{2}} = V_{ftot.} + V_{Rs})$$

In the above formula V_{ftot} , and V_{Rs} are RMS values and the maximum permitted ratio $\frac{V_{Rs}}{V_{ftot}}$ can be read from diagram number 1 (see 8.2.2).

For calculation of R_S divide the required V_{RS} (RMS) by the nominal heater current: $R_S = \frac{V_{RS}}{Q_S}$

Remark to 8.2.3 and 8.2.4:

When series diodes are applied, the D.C. component of the resulting heater voltage should preferably be negative with respect to the cathodes of the tubes.

8.2.5 Supply from a voltage source via a series capacitor

a. One single 300 mA tube; permitted if

 $\frac{V f tot.}{V_S}$ \geq 0.50 when 5% paper capacitors are applied.

- b. $\frac{V_{ftot.}}{V_{s}}$ \geq 0.70 when 10% metalized polycarbonate capacitors are applied.
- c. Heater chain consisting of 2 tubes or more; permitted if $\frac{V_{ftot.}}{V_{S}}$

 $\frac{V_{ftot.}}{V_{S}}~\geq~0.6~$ when 5% paper capacitors are applied.

 $\frac{V_{ftot.}}{V_{S}} \geq$ 0.8 when 10% metallized polycarbonate capacitors are applied.

8.3 Stand-by (instant-on circuits)

In order to maintain reliability during life, it is recommended to reduce the heater voltage of the tubes during stand-by operation to 75% of the nominal value.

Note

If other designs for the heater supply circuit are wanted than the configurations described above it is strongly recommended to contact the tube manufacturer.

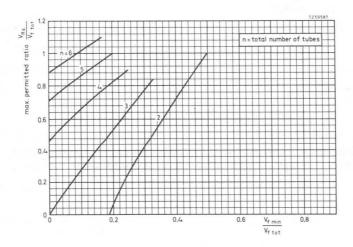


Diagram No. 1

9. HEATER-TO-CATHODE CIRCUIT

The published limiting values of $V_{\rm kf}$ apply to the positive and negative D.C. component of the voltage between the cathode and any of the heater terminals.

The limiting peak value is twice the rated D.C. value with a maximum of 315 V.

In stating these values figures only the risk of breakdown has been considered. No conclusions with respect to hum should be drawn from them.

To minimize the influence of variation and spread in the leakage current between heater and cathode the resistance of the external heater to cathode circuit should not exceed 20 k Ω .

However, when the D.C. value of V_{kf} never drops below three times the RMS value of the heater voltage a resistor of maximum 220 $k\Omega$ may be connected between heater and cathode provided that the hum voltage which may develop across the cathode resistor is acceptable for the application considered.

An interruption of the D.C. connection between cathode and earth or heater and earth may introduce heater-cathode breakdown and should be avoided.

10. SUPPRESSOR GRID CIRCUIT

The suppressor grid should normally be connected to the cathode; any series resistance in the suppressor grid lead should not exceed a value of $50~\rm k\Omega$. The suppressor grid should not be used as a control grid unless specific recommendations are made in the data sheets. Where the suppressor grid is so used, care should be taken not to exceed the maximum screen-grid dissipation. When a tube is connected as a triode, the suppressor grid should be connected directly to the cathode, except where other recommendations are given in the data sheets. If the circuit is such that the suppressor grid is liable to be driven positive, it is recommended to consult the tube manufacturer.

11. CONTROL GRID CIRCUIT

In the interest of low hum and noise the resistance in the control grid circuit should be as low as possible.

The limiting value of the grid resistance given in the data sheets is so chosen that during the tube life the negative grid current which may occur will not result in unacceptable tube operation.

If only the limiting value of the resistance for fixed bias operation is given and stabilizing elements are used in the circuit, this limiting value may be multiplied by the D.C. feedback factor obtained by these stabilizing elements; the maximum limiting value should not exceed $20~\mathrm{M}\Omega$.

12. CAPACITANCES

All data have been measured according to I.E.C. Publication 100

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13. PROTECTIVE RESISTORS FOR MAINS RECTIFYING TUBES

To restrict the peak value of cathode current in a mains rectifying tube the ohmic resistance (R_t) in series with the anode should not be less than that specified in the data sheet.

When the anode supply voltage is obtained from a transformer the value of the resistance to be added in each anode lead should be calculated from the following formula:

 $R_t = R_s + n^2 R_p + R_1$.

In case of half-wave rectification

 R_t = the required protective resistance

 R_s = the ohmic resistance of the secondary coil

n = the transformer ratio

 R_{p} = the ohmic resistance of the primary coil

 R_1^r = resistance that must be added

In case of full-wave rectification

 R_t = the required protective resistance per anode

Rs = ohmic resistance of half the secondary coil

n = transformer ratio between primary and half the secondary coil

 $R_{\rm p}$ = ohmic resistance of the primary coil

 R_1 = resistance to be added in each anode lead.

When an auto transformer is applied it should be taken into account that the transformer winding is partly short-circuited by the mains.

When a filter input capacitor is applied the power dissipation in R_t is supplemented by the contribution of the ripple current up to three times the value produced by the D.C. component of current.

14. <u>LIFE</u>

Optimum life performance is ensured if the tube is operated according to the published "Operating conditions". Spread and variation of operating conditions should be limited as much as possible.

15. HUM

15.1 When the heater supply is obtained from the mains voltage the cathode current may be modulated by the A.C. mains frequency.

This modulation, resulting in hum, may be caused by capacitive or leakage currents between the heater and the tube electrodes, by the magnetic field of the heater or by external fields.

15.2 The following measures can be taken to reduce hum.

Cathode hum

Keep the A.C. voltage between cathode and heater as small as possible; with series operation insert the most critical tube at the earthed side of the heater chain and with parallel operation connect the electrical centre of the heater to earth.

Do not include the impedance between cathode and heater in an R.F. circuit. If this cannot be avoided and the cathode must be connected to a tapping of a tuned circuit, choose the highest practicable tuning capacitance in order to reduce the influence of possible variations in circuit capacitance. This applies especially to oscillator circuits where variations in the capacitance between cathode and heater may lead to modulation hum.

Decouple the cathode resistance as far as possible.

Where negative feedback is applied, take the non-decoupled part as small as possible.

Control grid hum

Keep the A.C. voltage between cathode and heater as small as possible. Do not use idle socket contacts in the proximity of the control grid contact as anchoring points for joints connected to 50 Hz as this may cause hum due to leakage or capacitance in the tube socket.

Keep the impedance at the mains frequency in the control grid lead as small as possible.

15.3 For tubes mainly intended for use in broadcast receivers the value of $\rm Z_{g1}$ at mains frequency is so chosen that the hum voltage will be -60 dB (design centre value) with respect to the input voltage for 50 mW output power.

The hum voltage in this case is measured behind a filter, the characteristic, of which agrees with the C.C.I.R. aural sensitivity curve (see graph on next page).

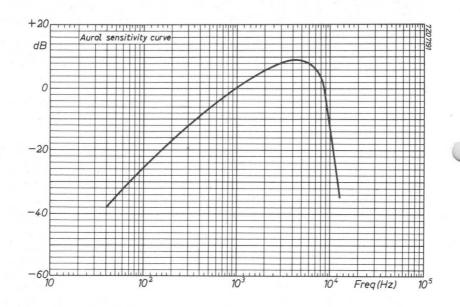
For tubes mainly intended for use in audio equipment the value of Z_{g_1} is so chosen that the level of hum voltage, measured with a filter linear up to 500 Hz, is – 60 dB with respect to the input voltage for maximum output power. To obtain these values the centre of parallel-connected heaters should be earthed whereas with series-connected heaters the value of V_{kf} , permitted in connection with hum, should not be exceeded; when a cathode resistor is used, it should be decoupled by a capacitor of at least $100~\mu\mathrm{F}$.

It should be realized that, although the tubes may meet the requirement of a -60 dB hum level, the total hum level of the circuitry stage under consideration may be higher owing to imperfect circuitry (magnetic hum induced by transformers and smoothing chokes; unsatisfactory smoothing of the rectified voltage, etc.).

For several R.F. and I.F. types a curve has been published which shows, as a function of the transconductance, the hum voltage (V_i) on the control-grid which causes a modulation hum of 1%.

The published limiting value of $V_{\rm kf}$ is the maximum permissible value up to which there will be no danger of breakdown between cathode and heater, and it does not give information about the resulting hum level.

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16. MICROPHONY

Whenever a tube is subjected to vibration, caused by e.g. a loudspeaker, motor, switch etc., some disturbance in the output of the tube occurs. The effect of this disturbance will depend on the individual application. The published data of various tube types make reference to the microphonic sensitivity and this should be noted when a tube is chosen for a specific application.

Where the effects of microphony are found to be objectionable, special steps may have to be taken to reduce the vibration reaching the tube. The chassis itself may show wide variations in amplitude of vibration over its area, due to resonances; therefore favourable location of the tube, or local strengthening of the chassis, may appreciably reduce microphony.

The maximum peak acceleration to which the tube may be subjected under the most unfavourable conditions is 1.5 g at frequencies $<600\,\mathrm{Hz}$ and 0.2 g at frequencies $>600\,\mathrm{Hz}$. However, tubes should not be subjected to the maximum acceleration at a given frequency for a long period of time. In case the actual acceleration is higher than these values, difficulties with regard to microphony may be expected.

Warning: It should be noted that excessive mechanical vibration may result in the destruction of the internal tube structure.

17. ENVIRONMENTAL CONDITIONS

- 1. Atmospheric pressure. Ratings apply to operation at normal atmospheric pressure at altitudes below 3000 m.
 - It is advised to consult the tube manufacturer if tubes have to be operated at lower pressures.
- Thermal considerations. The bulb and the base temperature are defined as the highest temperature at any place on the bulb or the base. The base temperature should not exceed 165 °C.

Used in practical circuits and under design centre conditions the bulb temperature of a tube should not exceed by more than 30 $^{\rm oC}$ that temperature which would be attained if the tube were operated at its maximum ratings in free air at a room temperature of 20 $^{\rm oC}$.

If, for instance, the bulb temperature of a certain type of tube operating in free air at maximum ratings is shown to be 200 °C, it is permissible to use this tube in equipment where the bulb attains a temperature of 230 °C (thus at an excess of 30 °C). In practice this means that the "ambient" temperature in the equipment may rise above room temperature by about twice 30 °C and thus may attain a value of 80 °C.

When a tube runs particularly hot this increase of 30 $^{\circ}$ C is not permissible; the design maximum should then be 250 $^{\circ}$ C unless otherwise stated in the relevant data sheets.

When the maximum permitted base or bulb temperature is exceeded, the tube reliability during life may deteriorate. Cooling should therefore always be adequate; it may be obtained by convection, radiation or conduction. To make it most efficient a free circulation of air should be assured around the tube and the temperature of neighbouring bodies should below. These neighbouring bodies should preferably approach a perfect black body.

The design of screening or retaining devices should also be such that the reflection of heat back to the bulb must be minimized. In some cases it may be necessary to reduce the electrode dissipation.

Heat dissipating shields have the property to reduce the hot-spot temperature at the tube envelope. However, this is generally accompanied by a rise in base temperature whereas also the normal sublimation pattern inside the tube may be drastically disturbed. For this reason extreme care should be exercised when applying these devices.

3. High Voltage insulation. To avoid insulation breakdown due to ionization or tracking at high electrode voltages adequate ventilation is required. High voltage terminals should not have sharp or pointed edges.

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18. MOUNTING AND WIRING

- 1. Mounting position. Unless otherwise specified, a tube may be mounted in any position.
- 2. Pins and sockets. Many tube types employ semi-rigid pins.

To ensure that these pins are straight before insertion into the tube socket use may be made of a pin straightening tool. It is recommended both in wired and in printed circuits to use sockets in which the contact springs are reasonably flexible. Too stiff wiring may hold the contacts out of position in such a way that the tube base is damaged upon insertion. To avoid this the use of a wiring jig is recommended. The dimensions of the wiring jig shall b in conformity with the nominal base dimensions specified in this Handbook.

No connections should be made to a pin marked i.c.

The sockets used shall comply with the following:

The insertion and withdrawal forces of sockets shall be checked before any previous gauging or sizing. The sockets shall be capable of accepting and having withdrawn from them the insertion and withdrawal force gauge* within the force limits specified below. These tests shall be made with a test jig.

Socket compatible with small button miniature 7 pin base (IEC 67-I-10a)

max. insertion force 72 N (7.2 kgf)

min. withdrawal force 12 N (1.2 kgf)

Socket compatible with small button noval 9 pin base (IEC 67-I-12a)

max. insertion force 91 N (9.1 kgf)

min. withdrawal force 13.5 N (1.35 kgf)

Socket compatible with small button decal 10 pin base (IEC 67-I-41a)

max. insertion force 91 N (9.1 kgf)

min. withdrawal force 13.5 N (1.35 kgf)

Socket compatible with magnoval base (IEC 67-I-36a)

max. insertion force 91 N (9.1 kgf)

min, withdrawal force 13.5 N (1.35 kgf)

3. Retaining devices. When measures are required to prevent a tube from being

shaken out of the socket a retaining device may be used. Care should then be taken to avoid the maximum permitted bulb temperature being exceeded.

^{*} Described in I.E.C. Publication 149.

DIMENSIONS OF BASES

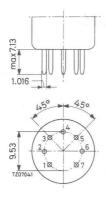
In the outline drawings of bases given below, some main dimensions (in mm) only have been given.

For further details is referred to IEC publication 67.

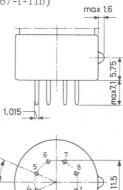
The page number on which the outline drawing can be found in this publication is therefore given for each base type.

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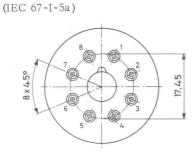
MINIATURE 7-PIN BASE (IEC 67-I-10a)

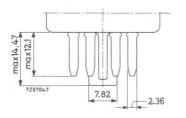


RIMLOCK BASE (IEC 67-I-11b)

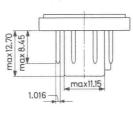


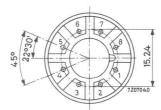
OCTAL BASE



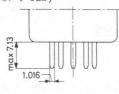


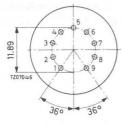
NEO EIGHTAR BASE (IEC 67-I-31a)



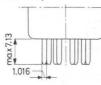


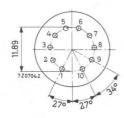




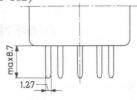


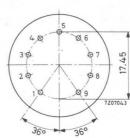
DECAL BASE (IEC 67-I-41a)



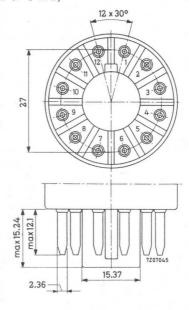


MAGNOVAL BASE (IEC 67-I-36a)



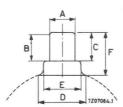


DUODECAL BASE (IEC 67-I-17a)



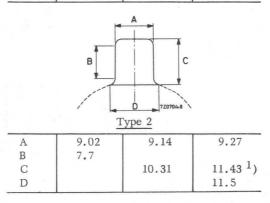
DIMENSIONS OF CAPS

The dimensions for the drawings of top caps have been given in mm. The dimensions A, B and C, which are those necessary to ensure compatibility between cap and corresponding connector are in accordance with IEC publication 67, page 67-III-1 a.



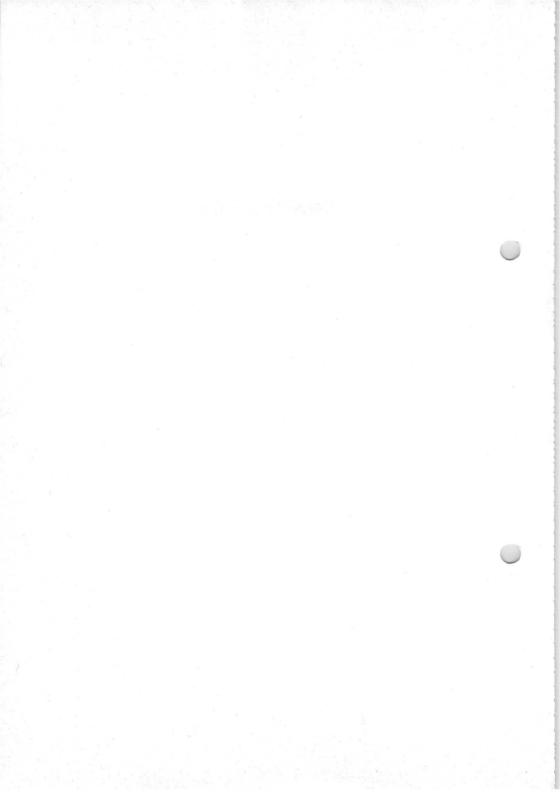
Type 1

ref.	min.	nom.	max.
A	6.23	6.35	6.47
В	5.1		
C		7.14	8.89 1)
D	1	,	11.5
E		9.15	
F		10.31	11.43 ¹)



Without solder. On finished article an increase of 0,5 mm is allowed on this dimension for solder.

Receiving Tubes



SINGLE ANODE E.H.T. RECTIFYING TUBE

Single anode high vacuum rectifying tube intended for use in portable T.V. receivers.

HEATING: Indirect; parallel supply

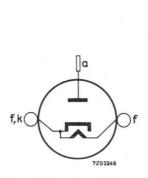
Heater voltage

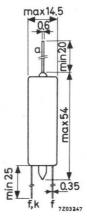
Heater current

$$\frac{V_f}{I_f}$$
 1.4 V If 550 mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm





The tube has flexible leads, which must not be bent nearer than 10 mm to the tube bottom.

The leads should not be soldered nearer than 1.5 mm to the seal.

CAPACITANCE

Anode to all

 C_a

0.8 pF

TYPICAL CHARACTERISTICS

Anode voltage

 v_a

100 V

Anode current

 I_a

13 mA

LIMITING VALUES (Design centre rating system, unless otherwise specified)

Anode voltage, negative peak	$-v_{a_{D}}$	max. 15	kV
Anode voltage, negative peak (abs. max.)	-V _{ap}	max. 18	kV
Anode current, average	Ia	max. 350	μ A
Anode current, peak	I_{a_p}	max. 40	mA î
Filter input capacitance	C _{filt}	max. 2000	pF
Heater voltage ($I_a < 200~\mu\text{A}$) (abs. max.)	v_f	max. 1.6	V
Heater voltage ($I_a > 200~\mu\text{A}$) (abs. max.)	$V_{\mathbf{f}}$	min. 1.3	V

 $^{^{1})}$ Max. duration is 10 % of a line-scanning cycle, but max. 10 $\mu \rm{sec}$.

SINGLE ANODE E.H.T. RECTIFYING TUBES

High-vacuum single-anode rectifying tubes for high tension in television receivers (E.H.T. supply from the line time base).

The DY86 and DY87 are equivalent except for the DY87 having a chemically treated envelope which avoids flash-over under conditions of high humidity and low atmospheric pressure (45 cm $\rm Hg$).

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage $\dfrac{V_{f}}{I_{f}}$ 1.4 V Heater current I_{f} 550 mA

When the heater is to be operated on R.F. or flyback pulses, the heater voltage can be adjusted to 1.4 V e.g. by measurement with a thermocouple.

Tolerances of V_f

a. As E.H.T. rectifier in television receivers

The heater voltage should be adjusted to its nominal value at a D.C. output current of $200\,\mu\mathrm{A}$. At an increase of the D.C. output current to 400 to $600\,\mu\mathrm{A}$ which can incidentically occur during operation the decrease of the heater voltage may amount to max. 15 %. These requirements hold for nominal mains voltage and full horizontal scanning of the picture tube. If the picture width control is such that also the heater voltage of the E.H.T. diode is influenced, the influence of this control must be kept within the 15 % limit indicated above.

b. For all other applications the limits for the heater voltage are as given in the application directions in front of this section.

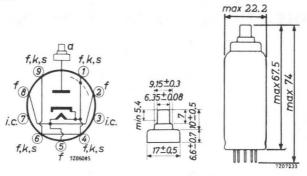
DIMENSIONS AND CONNECTIONS

Dimensions in mm

 C_a

1.55 pF

Base: NOVAL



REMARKS

Anode to all

- a. Pins 1, 4, 6 and 9 can be used for fixing an anti-corona ring.
- b. Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.
- c. If the tube operates at high values of $V_{a\;invp}$ and/or under conditions of high relative humidity or low pressure the metal top-cap should get an insulating cover to avoid corona phenomena.

CAPACITANCES (without external shield)

OPERATING CHARACTERISTICS		
Output current	Io	0.15 mA
Output voltage	V	18 kV

LIMITING VALUES (Design centre rating system unless otherwise stated)

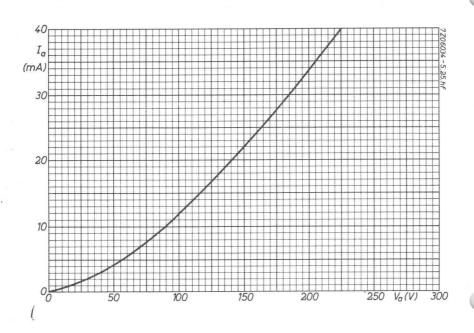
	Output voltage	Vo	max.	18	kV
	Peak inverse voltage	V _{ainvp}	max.	22	kV 1)
	Peak inverse voltage				
	(Absolute max.)	v_{ainv_p}	max.	27	kV 1)
	Peak inverse voltage without current	$V_{a inv_D}(I_O = 0)$	max.	24	kV 1)
	Output current	Io	max.	0.5	mA^2)
	Peak output current	I_{a_p}	max.	40	mA^3)
)	Filter input capacitance	C _{filt}	max.	2000	pF

¹⁾ Maximum pulse duration 22 % of a line scanning cycle with a maximum of 18 $\mu{\rm sec.}$

The negative peak anode voltage due to ringing in the line-output transformer must be taken into account. The ratio between this negative peak value and the positive D.C. voltage can be about 1:4.5.

²⁾ During short periods as in television service $I_{\rm O}$ = max. 0.8 mA.

³⁾ Maximum pulse duration 10 % of a line scanning cycle with a maximum of 10 $\mu{\rm sec.}$



E.H.T. RECTIFYING TUBE

High-vacuum single-anode rectifying tube for high tension in television receivers (E.H.T. supply from the line time base)

The DY802 has a chemically treated envelope which avoids flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

v_{f}	1.4	V
$I_{\mathbf{f}}$	600	mA

Tolerances of Vf

a. As E.H.T. rectifier in television receivers

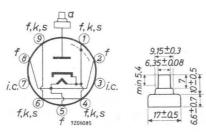
The heater voltage should be adjusted to its nominal value at a D.C. output current of 200 μ A. At an increase of the D.C. output current to 400-800 μ A which can incidentically occur during operation the decrease of the heater voltage may amount to max. 15%. These requirements hold for nominal mains voltage and full horizontal scanning of the picture tube. If the picture width control is such that also the heater voltage of the E.H.T. diode is influenced, the influence of this control must be kept within the 15% limit indicated above

b. For all other applications the limits for the heater voltage are as given in the application directions.

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





REMARKS

- a. Pins 1, 4, 6 and 9 can be used for fixing an anti-corona ring.
- b. Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.
- c. If the tube operates a high values of V_{ainvp} and/or under conditions of high relative humidity or low pressure the metal top-cap should get an insulating cover to avoid corona phenomena.

CAPACITANCE

Anode to all	C_a	1.0	рг
OPERATING CHARACTERISTICS			

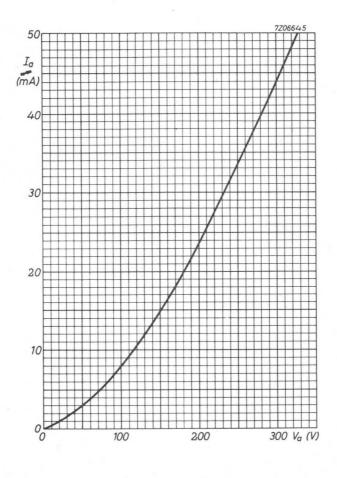
Output current	I_{o}	200	μ A
Output voltage	V_{o}	20	kV

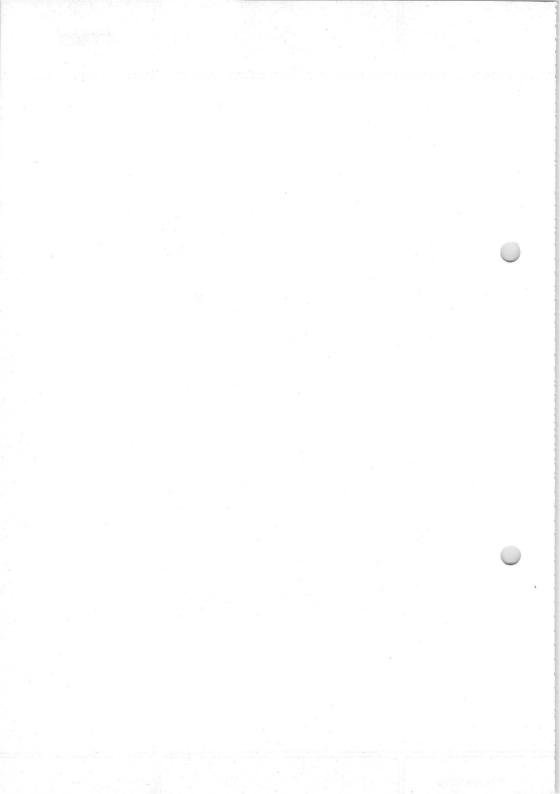
LIMITING VALUES (Design centre rating system unless otherwise stated)

Output voltage	v_{o}	max.	20	kV
Peak inverse voltage	v_{ainv_p}	max.	25	kV 1)
Peak inverse voltage (Abs. max.)	$V_{a_{inv_{D}}}$	max.	30	kV 1)
Output current, average	Io	max.	500	μA 2)
peak	I_{op}	max.	50	mA
Filter input capacitance	C_{filt}	max.	3000	pF

 $^{^1)}$ Max. duration 22% of a line scanning cycle and maximum 18 μs . The negative peak anode voltage due to ringing in the line-output transformer must be taken into account.

²) During short periods as in TV operation I_0 = max. 800 μA .





DOUBLE DIODE

Double diode with separate cathodes.

QUICK REFERENCE DATA			7
A.C. supply voltage	V _{tr}	150	V _{RMS}
D.C. current per system	I_{O}	9	mA

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

Heater current

$v_{\rm f}$	6.3	V
$I_{\mathbf{f}}$	300	mA

Dimensions in mm

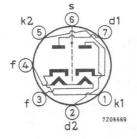
Without

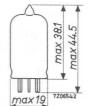
external

DIMENSIONS AND CONNECTIONS

Base: Miniature

CAPACITANCES





With

external

		shield	shield	
Diode No.1 to all	C_{d_1}	3.0	2.5	pF
Diode No.2 to all	C_{d_2}	3.0	2.5	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.0.026	max.0.068	pF
Cathode No.1 to all	$C_{\mathbf{k_1}}$	3.4	3.4	pF
Cathode No. 2 to all	Ck	3.4	3.4	pF

LIMITING VALUES Design centre rating system. (Each system)

Diode voltage, negative peak		v_{d_p}	max.	420	V
Diode current		Id	max.	9	mA
Diode current, peak		I_{d_p}	max.	54	mA
Cathode to heater voltage pea	ak (k neg)	V _{kfp} (k neg)	max.	150	V
Cathode to heater voltage, pe	eak (k pos)	V _{kfp} (k pos)	max.	33 0	V
D	C. component		max.	200	V
A	C. component		max.	165	v_{RMS}
As half wave rectifier					
A.C. supply voltage		V _{tr}	max.	150	v_{RMS}
D.C. current		I_{Ω}	max.	9	mA

Input capacitor of smoothing filter $$C_{\mbox{\scriptsize filt}}$$ Protecting resistance $$R_{\mbox{\scriptsize t}}$$

Cathode to heater voltage, peak (k pos) $V_{\mathrm{kf}_{\mathrm{D}}}$ (k pos)

D.C. component

A.C. component

100 [E941 18-17-58]

80

40

20

5 10 15 ½ (V)

max.

min. 300

max. 330

max. 200

max. 165 V_{RMS}

 μF

TRIPLE DIODE-TRIODE

Triple diode-triode intended for F.M. and A.M. signal detection and A.F. signal amplification.

QUICK REFE	ERENCE DATA		
Triode section			
Anode current	Ia	0.8	mA
Transconductance	S	1.45	mA/V
Amplification factor	μ	70	-

HEATING: Indirect by A.C. or D.C.; parallel supply

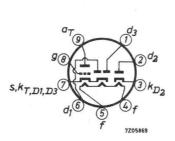
Heater voltage

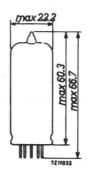
Heater current

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





EABC80

CAPACITANCES					
Triode section					
Grid to all except anode	Cg(a)		1.9	pF	
Anode to all except grid	$C_{a(g)}$		1.4	pF	
Anode to grid	Cag		2.0	pF	
Grid to heater	C_{gf}	max.	0.04	pF	
Diode sections					
Diode No.1 to all	C_{d_1}		0.8	pF	
Diode No.2 to all	C_{d_2}		4.8	pF	
Diode No.3 to all	C_{d_3}		4.8	pF	
Cathode (D ₂) to all	C_{kD_2}		4.9	pF	
Diode No.1 to heater	C_{d_1f}	max.	0.25	pF	
Diode No.3 to heater	C_{d_3f}	max.	0.2	pF	
Cathode (D ₂) to heater	$C_{kD_{2}f}$		2.5	pF	
Between triode and diode sections					
Anode to diode No.1	C_{ad_1}	max.	0.12	pF	
Anode to diode No.3	Cad3	max.	0.1	pF	
Anode to cathode (D ₂)	C_{akD_2}	max.	0.01	pF	
Grid to diode No.1	C_{gd_1}	max.	0.07	pF	
Grid to diode No.3	C_{gd_3}	max.	0.02	pF	
Grid to cathode (D ₂)	C_{gkD_2}	max.	0.005	pF	
TYPICAL CHARACTERISTICS Triode section					
Anode voltage	v_a	100	250	V	
Grid voltage	Vg	-1	-3	V	
Anode current	Ia	0.8	1.0	mA	
Transconductance	S	1.45	1.4	mA/V	
Amplification factor	μ	70	70	-	

 R_i

Internal resistance

48 50 k Ω

OPERATING CHARACTERISTICS

Triode section as RC coupled A.F. amplifier

Grid resistor R_g = 10 $M\Omega$

Supply voltage	v_b	250	250	250	200	200	200	V
Anode resistor	Ra	220	100	47	220	100	47	$k\Omega$
Grid resistor next stage	Rg'	0.68	0.33	0.15	0.68	0.33	0.15	$M\Omega$
Anode current	I_a	0.76	1.40	2.20	0.56	1.00	1.60	mA
Voltage gain	v_o/v_i	54	47	36	53	44	34	-
Distortion:								
at output voltage $V_0 = 3 V_{RMS}$	d_{tot}	0.2	0.25	0.3	0.3	0.4	0.5	%
at output voltage $V_0 = 5 V_{RMS}$	d_{tot}	0.25	0.5	0.6	0.4	0.6	0.9	%
at output voltage $V_0 = 8 V_{RMS}$	\mathbf{d}_{tot}	0.6	0.8	1.0	0.9	1.0	1.5	%
Supply voltage	V _b	170	170	170	100	100	100	V
Anode resistor	R_a	220	100	47	220	100	47	$k\Omega$
Grid resistor next stage	Rg'	0.68	0.33	0.15	0.68	0.33	0.15	$\mathrm{M}\Omega$
Anode current	Ia	0.46	0.82	1.25	0.21	0.35	0.52	mA
Voltage gain	V_{o}/V_{j}	51	42	32	44	35	26	-
Distortion:								
at output voltage $V_0 = 3 V_{RMS}$	d_{tot}	0.4	0.5	0.6	1.0	1.3	2.0	%
at output voltage $V_0 = 5 V_{RMS}$	d_{tot}	0.5	0.8	1.1	1.7	2.3	4.3	%
at output voltage $V_0 = 8 V_{RMS}$	dtot	1.1	1.3	2.0	_		-	%

TYPICAL CHARACTERISTICS Diode sections

Internal resistance diode No.1 Diode voltage V _{d1} = +10 V	R_{iD_1}		5	kΩ
Internal resistance diode No.2 Diode voltage V _{d2} = +5 V	R_{iD_2}		200	Ω
Internal resistance diode No.3 Diode voltage $V_{d_3} = +5 \text{ V}$	R_{iD_3}		200	Ω
Ratio between R_{iD_2} and R_{iD_3}	R_{iD_2}/R_{iD_3}	min. (

MICROPHONY Triode section

No special precautions against microphony are required in circuits where the input voltage is min. 10~mV for 50~mW output of the output tube at frequencies higher than 800~Hz. At lower frequencies the sensitivity may be increased according to figure 1.

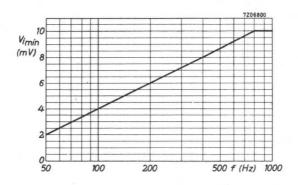
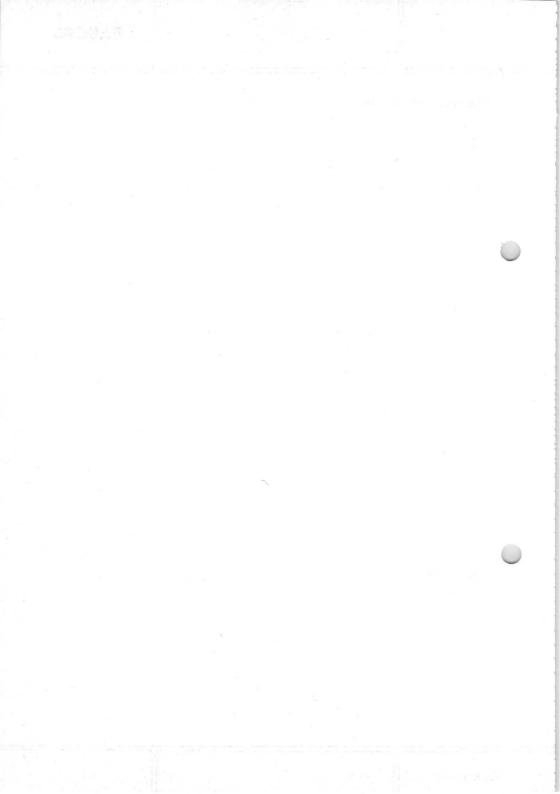


fig.1

LIMITING VALUES (Design centre rating system)

Triode	section

Triode section			
Anode voltage	V_{a_0}	max. 550	V
	V_a	max. 300	V
Anode dissipation	Wa	max. 1	W
Cathode current	I_k	max. 5	mA
Grid resistor	R_g	max. 3	$M\Omega$
Grid resistor (grid current bias)	Rg	max. 22	ΜΩ
Cathode to heater voltage	v_{kf}	max. 150	V
Diode sections			
Diode No.1 voltage, peak negative	$-v_{d_{1p}}$	max. 350	v
Diode No.2 voltage, peak negative	-V _{d2p}	max. 350	V
Diode No.3 voltage, peak negative	-V _{d3p}	max. 350	V
Diode No.1 current:	эр		
D.C. component	I_{d_1}	max. 1	mA
peak	$I_{d_{1p}}$	max. 6	m A
Diode No.2 current:	тр		
D.C. component	I_{d_2}	max. 10	mA
peak	$I_{d_{2p}}$	max. 75	mA
Diode No.3 current:	26		
D.C. component	I_{d_3}	max. 10	mA
peak	$I_{d_{3p}}$	max. 75	mA
Cathode (D ₂) to heater voltage	V _{kD2} /f	max. 150	V
	_		



DOUBLE DIODE

Double diode with separate cathodes.

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

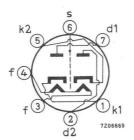
Heater current

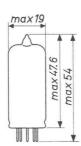
$V_{\mathbf{f}}$	6.3	V
$I_{\mathbf{f}}$	300	mA

DIMENSIONS AND CONNECTIONS

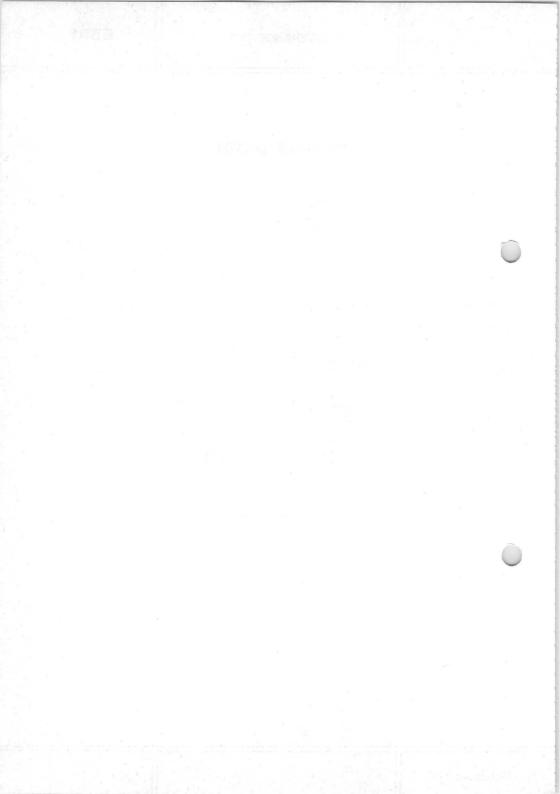
Dimensions in mm

Base: Miniature





For further data please refer to type EAA91



DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

QUICK REFEREN	CE DATA		
Triode section			
Anode current	I_a	1.0	mA
Transconductance	S	1.2	mA/V
Amplification factor	μ	70	-

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

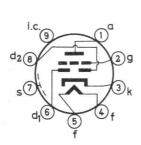
Heater current

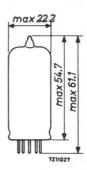
 $\frac{V_{\mathrm{f}}}{I_{\mathrm{f}}}$ 6.3 V $\frac{V_{\mathrm{f}}}{230}$ mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





EBC81

CAPACITANCES				
Triode section				
Grid to all except anode	Cg(a)	2.3	pF	
Anode to all except grid	$C_{a(g)}$	2.3	pF	
Anode to grid	Cag	1.2	pF	
Grid to heater	C_{gf}	max. 0.05	pF	
Diode sections				
Diode No.1 to all	C_{d_1}	0.9	pF	
Diode No.2 to all	C_{d_2}	0.9	pF	
Diode No.1 to diode No.2	$C_{d_1d_2}$	max. 0.2	pF	
Diode No.1 to heater	C_{d_1f}	max. 0.25	pF	
Diode No.2 to heater	C_{d_2f}	max. 0.05	pF	
Between diode and triode sections				
Diode No.1 to grid	C_{d_1g}	max.0.007	pF	
Diode No.2 to grid	C_{d_2g}	max.0.007	pF	
Diode No.1 to anode	C _{d1a}	max.0.005	pF	
Diode No.2 to anode	C_{d_2a}	max.0.010	pF	
TYPICAL CHARACTERISTICS				
Triode section				
Anode voltage	v_a	250 V		
Grid voltage	Vg	-3 V		
Anode current	Ia	1.0 m	.A	
Transconductance	S	1.2 m	A/V	
Amplification factor	μ	70 -		

 R_{i}

Req

 $58 k\Omega$

 $\text{max.150} \quad k\Omega$

Internal resistance

Equivalent noise resistance (A.F.)

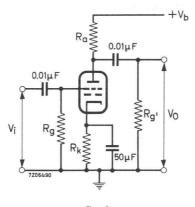
OPERATING CHARACTERISTICS

Triode section as A.F. amplifier, circuit Fig.1

7	- 0						
Supply voltage	v_b	250	250	250	250	V	
Anode resistor	R_a	0.22	0.1	0.22	0.1	$\mathrm{M}\Omega$	
Cathode resistor	$R_{\mathbf{k}}$	1.8	1.2	0	0	$\mathbf{k}\Omega$	
Grid resistor	R_g	1	1	22	22	$M\Omega$	
Grid resistor next stage	Rg.	0.68	0.33	0.68	0.33	$\mathrm{M}\Omega$	
Anode current	I_a	0.70	1.15	0.76	1.40	mA	
Voltage gain	V_{o}/V_{i}	51	43	52	44	-	
Distortion:							
at output voltage $V_0 = 5 V_{RMS}$	d_{tot}	0.55	0.6	0.5	0.7	%	
at output voltage V_0 = 10 V_{RMS}	d_{tot}	0.9	1.1	0.8	0.9	%	

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 10~mV for 50~mW output of the output tube.



LIMITING VALUES (Design centre rating system)

Anode voltage	v_{a_0}	max. 550	V
	V_a	max. 300	V
Anode dissipation	w_a	max. 0.5	W
Cathode current	$I_{\mathbf{k}}$	max. 5	mA
Grid resistor	Rg	max. 3	$M\Omega$
Cathode to heater voltage	v_{kf}	max. 100	V
Diode sections (each diode)			
Diode voltage, negative peak	$-v_{d_p}$	max. 350	V
Diode current, average	I_d	max. 0.8	mA
peak	I_{d_p}	max. 5	mA
Cathode to heater voltage	$V_{\mathbf{kf}}$	max. 100	V

Note

The use of a socket with skirt is advisable to reduce the capacitances between tube elements and external conductors.

DOUBLE DIODE-PENTODE

Double diode-pentode. Pentode intended for use as R.F., I.F., or A.F. amplifier.

QUICK REFERENCE DATA					
Pentode section					
Variable transconductance					
Anode current		Ia	5	mA	
Transconductance		S	2.2	mA/V	
Amplification		$\mu_{g_2g_1}$	18	-	

HEATING: Indirect by A.C. or D.C.; parallel or series supply.

Heater voltage Heater current

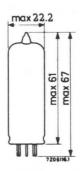
v_f	6.3	V
If	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





EBF80

CAPACITANCES

Diode No.2 to anode

Pentode section			
Anode to all except grid No.1	$C_{a(g_1)}$	4.9	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	4.2	pF
Anode to grid No.1	C_{ag_1}	max. 0.0025	pF
Grid No.1 to heater	c_{g_1f}	max. 0.07	pF
Diode section			
Diode No.1 to all	C_{d_1}	2.2	pF
Diode No.2 to all	C_{d_2}	2.35	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max. 0.35	pF
Diode No.1 to heater	C_{d_1f}	max. 0.02	pF
Diode No.2 to heater	$C_{d_{2f}}$	max. 0.005	pF
Between diode and pentode sections			
Diode No.1 to grid No.1	$C_{d_1g_1}$	max. 0.0008	pF
Diode No.2 to grid No.1	$C_{d_2d_1}$	max. 0.001	pF
Diode No.1 to anode	C_{d_1a}	max. 0.2	pF

 C_{d_2a} max. 0.05 pF

OPERATING CHARACTERISTICS

Supply voltage		v_b		250)	V	
Anode resistor		Ra		()	Ω	
Grid No.3 voltage		v_{g_3}		()	V	
Grid No.2 resistor		Rg ₂		95	5	$k\Omega$	
Cathode resistor		Rk		300)	Ω	
Grid No.1 voltage		Vg		$\overline{-2}$	-41.5	V	
Grid No.2 voltage		v_{g_2}		85	250	V	
Anode current		Ia		5	-	mA	
Grid No.2 current		I_{g_2}		1.75	_	mA	
Transconductance		S		2200	22	μA/V	
Internal resistance		Ri		1.4	min.10	МΩ	
Amplification factor		μ_{g_2}	21	18	-	-	
Equivalent noise resistance		Reg		6.8		kΩ	
1		- ec					
Pentode section as resistance cou	pled A.F.				g.1.		
	upled A.F.				g.1. 250	V	
Pentode section as resistance cou		. amplif	ier, ci	rcuit fi	250	V MΩ	
Pentode section as resistance cou Supply voltage	V _b R _a	amplif	ier, ci 250	250 0.22	250 0.1		
Pentode section as resistance cou Supply voltage Anode resistor	V_b R_a R_{g_2}	250 0.22	ier, ci 250 0.1	250 0.22	250 0.1	МΩ	
Pentode section as resistance cou Supply voltage Anode resistor Grid No.2 resistor	V _b R _a	. amplif 250 0.22 0.82	250 0.1 0.39	250 0.22 1.0	250 0.1 0.47	MΩ MΩ	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor	V_b R_a R_{g_2} R_{g_1}	250 0.22 0.82	250 0.1 0.39	250 0.22 1.0	250 0.1 0.47 10 0	MΩ MΩ MΩ	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor Cathode resistor	V_b R_a R_{g_2} R_{g_1} R_k	250 0.22 0.82 1 1800	250 0.1 0.39 1	250 0.22 1.0 10	250 0.1 0.47 10 0	$M\Omega$ $M\Omega$ $M\Omega$	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor Cathode resistor Grid No.1 resistor	V _b R _a R _{g2} R _{g1} R _k R _{g'} I _a	. amplif 250 0.22 0.82 1 1800 0.68	250 0.1 0.39 1 1000 0.33	rcuit fi 250 0.22 1.0 10 0 0.68 0.75	250 0.1 0.47 10 0 0.33 1.5	MΩ MΩ MΩ Ω MΩ	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor Cathode resistor Grid No.1 resistor Grid No.1 resistor	V _b R _a R _{g2} R _{g1} R _k R _g '	250 0.22 0.82 1 1800 0.68 0.75	250 0.1 0.39 1 1000 0.33	rcuit fi 250 0.22 1.0 10 0 0.68 0.75	250 0.1 0.47 10 0 0.33 1.5	$M\Omega$ $M\Omega$ $M\Omega$ Ω $M\Omega$ $M\Omega$	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor Cathode resistor Grid No.1 resistor next stage Anode current Grid No.2 current	V_b R_a R_{g_2} R_{g_1} R_k $R_{g'}$ I_a I_{g_2}	. amplif 250 0.22 0.82 1 1800 0.68 0.75	250 0.1 0.39 1 1000 0.33 1.5 0.53	250 0.22 1.0 10 0.68 0.75	250 0.1 0.47 10 0 0.33 1.5	$M\Omega$ $M\Omega$ $M\Omega$ Ω $M\Omega$ $M\Omega$	
Pentode section as resistance council Supply voltage Anode resistor Grid No.2 resistor Grid No.1 resistor Cathode resistor Grid No.1 resistor next stage Anode current Grid No.2 current Voltage gain	V_b R_a R_{g_2} R_{g_1} R_k $R_{g'}$ I_a I_{g_2}	. amplif 250 0.22 0.82 1 1800 0.68 0.75	250 0.1 0.39 1 1000 0.33 1.5 0.53	reuit fi 250 0.22 1.0 10 0.68 0.75 0.25	250 0.1 0.47 10 0 0.33 1.5 0.50	$M\Omega$ $M\Omega$ $M\Omega$ Ω $M\Omega$ $M\Omega$	
Pentode section as resistance councillated as section as resistance councillated and section as resistance councillated as section as a resistance councillated and section as resistance and section as resistance councillated as resistance councillated and section as resistance councillated as resistance councillated and section as resistance councillated as resistance c	V_b R_a R_{g_2} R_{g_1} R_k R_g I_a I_{g_2} V_o/V_i	. amplif 250 0.22 0.82 1 1800 0.68 0.75 0.30	250 0.1 0.39 1 1000 0.33 1.5 0.53	reuit fi 250 0.22 1.0 10 0.68 0.75 0.25 160	250 0.1 0.47 10 0 0.33 1.5 0.50 110	MΩ MΩ MΩ Ω MΩ mA	

OPERATING CHARACTERISTICS (continued)

Pentode section, triode connected (g2 connected to anode) as resista	nce coupled
A.F. amplifier.	

-						
Supply voltage	v_b	250	250	250	250	V
Anode resistor	Ra	0.1	0.047	0.1	0.047	$M\Omega$
Grid No.1 resistor	R_{g_1}	1	1	10	10	$M\Omega$
Cathode resistor	R_k	820	560	0	0	Ω
Grid No.1 resistor next stage	Rg'	0.33	0.15	0.33	0.15	$M\Omega$
Anode current	Ia	2.08	4.10	2.16	4.50	mA
Voltage gain	v_o/v_i	14	13	15	15	-
Distortion:						
at output voltage $V_0 = 3 V_{RMS}$	d_{tot}	1.6	1.3	2.0	1.7	%
at output voltage V_0 = 5 V_{RMS}	d_{tot}	2.5	2.0	3.1	2.7	%
at output voltage V_0 = 8 V_{RMS}	d_{tot}	4.3	2.9	4.8	4.1	%

LIMITING VALUES (Design centre rating system)

Pentode section

OR THE PROPERTY OF THE PROPERT				
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	300	V
Anode dissipation	W_a	max.	1.5	W
Grid No.2 voltage	$v_{g_{2_0}}$	max.	550	V
at anode current $I_a = max. 2.5 mA$	v_{g_2}	max.	300	V
at anode current I _a = 5 mA	v_{g_2}	max.	125	V
Grid No.2 dissipation	W_{g_2}	max.	0.3	W
Cathode current	$I_{\mathbf{k}}$	max.	10	mA
Grid resistor, automatic bias	R_{g_1}	max.	3	$M\Omega$
Grid resistor, grid current bias	R_{g_1}	max.	22	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	100	V

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 25 mV for an output of 50 mW of the output tube.

LIMITING VALUES (continued)

Diode section

	Diode No.1 voltage, negat	ive peak	$-v_{d_p}$	max.	350	V
	Diode No.2 voltage, negat	ive peak	$-v_{d_p}$	max.	350	V
	Diode No.1 current		I_{d_1}	max.	0.8	mA
	Diode No.2 current		I_{d_2}	max.	0.8	mA
	Diode No.1 current, peak		$I_{d_{1p}}$	max.	5	mA
1	Diode No.2 current, peak		$I_{d_{2p}}$	max.	5	mA
9	Cathode to heater voltage		v_{kf}	max.	100	V

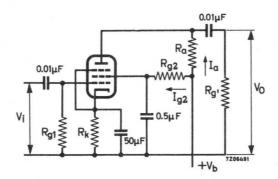
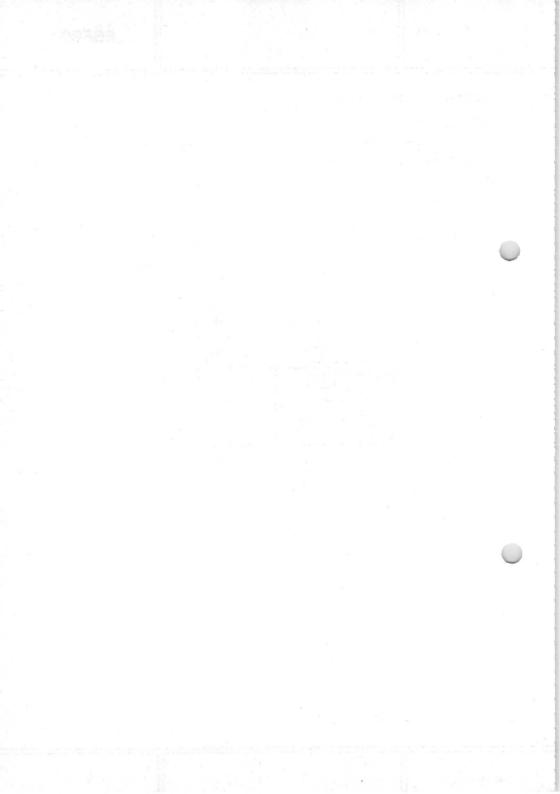


fig.1



DOUBLE DIODE - PENTODE

Double diode-pentode. Pentode intended for use as R.F. or I.F. amplifier.

QUICK REFERENCE DATA									
Pentode section	× .								
Variable transconductance									
Anode current		Ia	9	mA					
Transconductance		S	4.5	mA/V					
Amplification factor		$\mu_{g_2g_1}$	20						

HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage

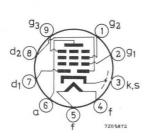
Heater current

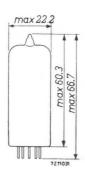
 $\begin{array}{ccc} V_{f} & 6.3 & V \\ \hline I_{f} & 300 & mA \end{array}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





EBF89

CAPACITANCES

Pentode	section

Diode No.2 to anode

and the same of th					
Anode to all except grid No.1	$C_{a}(g_{1})$		5.2	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$		5.0	pF	
Anode to grid No.1	C_{ag_1}	max.	0.0025	pF	
Grid No.1 to heater	c_{g_1f}	max.	0.05	pF	
Diode sections					
Diode No.1 to all	C_{d_1}		2.5	pF	
Diode No.2 to all	C_{d_2}		2.5	pF	
Diode No.1 to diode No.2	$c_{d_1d_2}$	max.	0.25	pF	
Diode No.1 to heater	C_{d_1f}	max.	0.015	pF	
Diode No.2 to heater	C_{d_2f}	max.	0.003	pF	
Between diode and pentode sections					
Diode No.1 to grid No.1	$C_{d_1g_1}$	max.	0.0008	pF	
Diode No.2 to grid No.1	$C_{d_2g_1}$	max.	0.001	pF	
Diode No.1 to anode	C_{d_1a}	max.	0.15	pF	
	_				

 C_{d_2a}

max. 0.025 pF

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	v_a	250	250	200	170	V	
Grid No.2 voltage	v_{g_2}	100	80	100	100	V	
Grid No.3 voltage	v_{g_3}	0	0	0	0	V	
Grid No.1 voltage	v_{g_1}	-2	-1 ¹)	-1. 5	-1 ¹)	V	
Anode current	I_a	9	9	11	12	mA	

1.0

0.9

0.6 0.4 $M\Omega$

OPERATING CHARACTERISTICS

Internal resistance

Pentode section as R.F. or I.F. amplifier

 R_i

Supply voltage	v_b	25	50	2	00	25	0	V
Anode resistor	R_a		0		0		0	Ω
Grid No.3 voltage	v_{g_3}		0		0		0	V
Grid No.2 resistor	R_{g_2}		56		30	6	2	kΩ
Grid No.1 voltage	v_{g_1}	-2.0	-20	-1.5	-20	-1 ¹)	-20	V
Anode current	Ia	9	-	11	-	9	-	mA
Grid No.2 current	I_{g_2}	2.7	-	3.3	-	2.7	-	mA
Transconductance	S	3.8	0.2	4.5	0.12	4.5	0.2	mA/V
Internal resistance	R_i	1.0	-	0.6		0.9	-	$M\Omega$

 $^{^{\}rm 1})$ To avoid grid No.1 current the negative grid No.1 voltage should be min. 1.5 V.

LIMITING VALUES (Design centre rating system)

Pentode section			
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 300	V 1)
Anode dissipation	Wa	max. 2.25	W
Grid No. 2 voltage	$v_{g_{2o}}$	max. 550	V
Grid No. 2 voltage			
at anode current I_a max. 4 mA	v_{g_2}	max. 300	V 1)
at anode current I_a min. 8 mA	v_{g_2}	max. 125	V
Grid No.2 dissipation	W_{g_2}	max. 0.45	W
Cathode current	$I_{\mathbf{k}}$	max. 16.5	mA
Grid No.1 resistor	R_{g_1}	max. 3	$M\Omega$
Grid No.3 resistor	R_{g_3}	max. 10	kΩ
Cathode to heater voltage	v_{kf}	max. 100	V
Diode sections (each diode)			
Diode voltage, negative peak	$-v_{d_p}$	max. 200	V
Diode current, average	Id	max. 0.8	mA
peak	I_{d_p}	, max. 5	mA
Cathode to heater voltage	Vkf	max. 100	V

 $^{^{1}}$) With supply from a storage battery and vibrator the max. voltage is $250\,\mathrm{V}$.

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier, oscillator or mixer for bands ${\rm IV}$ and ${\rm V.}$

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

V_f 6.3 V I_f 200 mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage, (k pos)

Vkf (k pos) max. 100 V

(k neg)

Vkf (k neg)

max. 50 V

For further data and curves of this type please refer to PC86.

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier for bands IV and V.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_f}{I_f}$ 6.3 V $\frac{V_f}{I_f}$ 165 mA

For further data and curves of this type please refer to $\ensuremath{\mathsf{PC88}}$

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and the company was provided by the control of west, and

R.F. TRIODE

Triode intended for use as oscillator, mixer or amplifier in F.M.- and television receivers.

The First Prints	QUICK REFERENCE DATA	24	1-18-1	
Anode current		Ia	10	mA
Transconductance		S	5.5	mA/V
Amplification factor		μ	60	

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

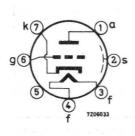
Heater current

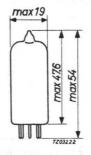
6.3	V mA	
150		

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Miniature





CAPACITANCES

$C_{g(a)}$	2.6	pF
Ca(g)	0.55	pF
C_{ag}	1.6	pF
C_{ak}	0.24	pF
$C_{\mathbf{k}\mathbf{f}}$	2.2	pF
C_{gf}	max. 0.15	pF
Ca/gf	1.8	pF
C _{k/gf}	4.5	pF
	C _a (g) C _{ag} C _{ak} C _{kf} C _{gf} C _{a/gf}	Ca(g) 0.55 Cag 1.6 Cak 0.24 Ckf 2.2 Cgf max. 0.15 Ca/gf 1.8

TYPICAL CHARACTERISTICS AND OPERATING CONDITIONS

Anode voltage	v_a	100	170	200	250	V
Grid voltage	V_g	-1.0	-1.0	-1.0	-2.0	V
Anode current	Ia	3.0	8.5	11.5	10	mA
Transconductance	S	3.75	5.9	6.7	5.5	mA/V
Amplification factor	μ	62	66	70	60	
Internal resistance	R_i	16.5	11	10.5	11	$k\Omega$

LIMITING VALUES (Design centre rating system)

Anode voltage	v_{ao}	max.	550	V
	v_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Cathode current	I_k	max.	15	mA
Grid voltage	-Vg	max.	50	V
Grid resistor (automatic bias)	R_g	max.	1	$M\Omega$
Cathode to heater voltage	Vkf	max.	100	V

For curves please refer to type ECC81

V.H.F. TRIODE

Triode intended for use as R.F. amplifier in V.H.F. television tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_f}{I_f} \qquad \frac{6.3 \text{ V}}{180 \text{ mA}}$

For further data and curves of this type please refer to type PC900

HODIST :

R.F. DOUBLE TRIODE

Double triode intended for use as oscillator, mixer or amplifier in television receivers.

~	REFERENCE DATA (each unit)	E, W	7, A# 54
Anode current	Ia	10	mA
Transconductance	S	5.5	mA/V
Amplification factor	μ	60	-

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

Heater current

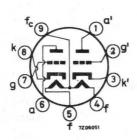
v_{f}	6.3	12.6	V
I_f	300 ¹)	150 ¹)	mA
_			

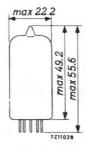
pins 9-(4+5) pins 4-5

DIMENSIONS AND CONNECTIONS

Dimensions in mm

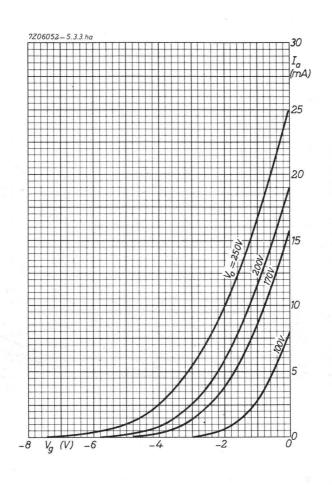
Base: Noval

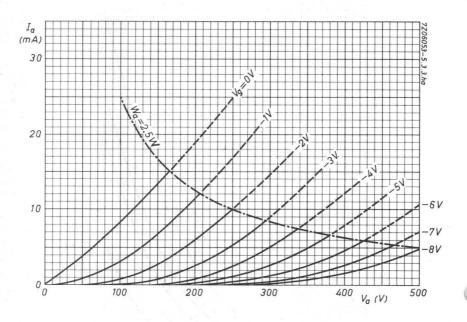




¹⁾ In case of series supply a current limiting device must be inserted in the heater circuit for limiting the current when switching on.

CAPACITANCES							
Grid to all except anode	Grid to all except anode		a) (a')		2.3	pF pF	
Anode to all except grid		Ca(0.45 0.35	pF pF	
Anode to grid		Cag Ca'			1.6 1.6	pF pF	
Anode to cathode		Cak Ca'			0.20	pF pF	
Cathode to heater		C _{kf}			2.5 2.5	pF pF	
Cathode to grid + heater			/g+f //g ' +f		4.7 4.7	pF pF	
Anode to grid + heater			/g+f //g ' +f		1.9	pF pF	
Grid to heater		C _{gf}		max.	0.17	pF pF	
Anode to anode		Caa	a*	max.	0.4	pF	
Grid to grid		C_{gg}	g'	max.	0.005	pF	
Anode to grid other unit		Cag	g '	max.	0.07	pF	
Grid to anode other unit		C_{gs}	a*	max.	0.04	pF	
TYPICAL CHARACTERISTICS AN	D OPE	RATING	CONDI	TIONS	(each t	ınit)	
Anode voltage	V_a	100	170	200	250	V	
Grid voltage	vg	-1.0	-1.0	-1.0	-2.0	V	
Anode current	I_a	3.0	8.5	11.5	10	mA	
Transconductance	S	3.75	5.9	6.7	5.5	mA/V	
Amplification factor	μ	62	66	70	60		
Internal resistance	R_{i}	16.5	11	10.5	11	$k\Omega$	
LIMITING VALUES (Design centr	e ratin	g systen	n) (each	unit)			
Anode voltage			Vao	max.	550	V	
			Va	max.	300	V	
Anode dissipation			Wa	max.	2.5	W	
Cathode current			$I_{\mathbf{k}}$	max.	15	mA	
Grid voltage		_	$-v_g$	max.	50	V	
Grid resistor (automatic bias)			Rg	max.	1	$M\Omega$	
Cathode to heater voltage			V_{kf}	max.	90	V	





A.F. DOUBLE TRIODE

Double triode intended for use as A.F. amplifier.

ing the standing	QUICK REFERENCE DATA (each unit)		Tig.	al Films
Anode current		Ia	10.5	mA
Transconductance		S	2.2	mA/V
Amplification factor		μ	17	-

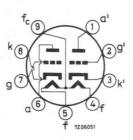
HEATING: Indirect by A.C. or D.C.; series or parallel supply

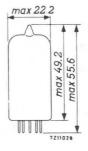
Heater voltage Heater current $V_{\rm f}$ 6.3 12.6 V $I_{\rm f}$ 300 150 mA pins 9-(4+5) pins 4-5

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





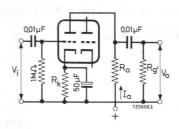
REMARK

With $V_{\rm f}$ applied to pins 4+5 and 9 and the centre tap of the heater transformer connected to earth, the more favourable triode section of the tube with regard to hum is the section connected to pins 6, 7 and 8.

CAPACITANCES					
Grid to all except anode	Cg(a)		1.8	pF	
	Cg'(a')		1.8	pF	
Anode to all except grid	Ca(g)		0.37	pF	
	$C_a'(g')$		0.25	pF	
Anode to grid	C_{ag}		1.5	pF	
	Ca'g'		1.5	pF	
Grid to heater	C_{gf}	max.	0.135	pF	1
	Cg'f	max.	0.135	pF	-
Anode to anode	Caa'	max.	1.1	pF	
Anode to grid other unit	Cag'	max.	0.11	pF	
Grid to anode other unit	Cga'	max.	0.06	pF	
Grid to grid	Cgg'	max.	0.010	pF	
TYPICAL CHARACTERISTICS					
Anode voltage	v_a	100	250	V	
Grid voltage	Vg	0	-8.5	V	
Anode current	Ia	11.8	10.5	mA	
Transconductance	S	3.1	2.2	mA/V	
Amplification factor	μ	19.5	17	- 1	
Internal resistance	Ri	6.25	7.7	$k\Omega$	

OPERATING CHARACTERISTICS

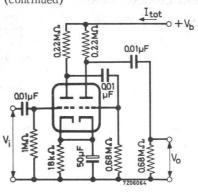
As A.F. amplifier, one unit



	Supply voltage	V_{b}	100	150	200	250	300	350	400	V
h	Anode resistor	Ra	47	47	47	47	47	47	47	$k\Omega$
7	Grid resistor									
	next stage	Rg'	150	150	150	150	150	150	150	$k\Omega$
	Cathode resistor	Rk	1.2	1.2	1.2	1.2	1.2	1.2	1.2	$k\Omega$
	Anode current	I_a	1.20	1.82	2.41	3.02	3.65	4.30	5.00	mA
	Voltage gain	V_{o}/V_{i}	13.5	13.5	13.5	13.5	13.5	13.5	13.5	-
	Output voltage $(I_g = 0.3 \mu A)$	Vo	11	18	26	34	43	51	59	v_{RMS}
	Total distortion	d_{tot}	5.6	6.1	6.3	6.4	6.5	6.6	6.7	%
	Supply voltage	V _b	100	150	200	250	300	350	400	V
	Anode resistor	Ra	100	100	100	100	100	100	100	$k\Omega$
	Grid resistor									
	next stage	Rg'	330	330	330	330	330	330	330	kΩ
	Cathode resistor	Rk	2.2	2.2	2.2	2.2	2.2	2.2	2.2	$k\Omega$
	Anode current	Ia	0.66	0.98	1.30	1.63	1.97	2.30	2.62	mA
	Voltage gain	V_{o}/V_{i}	14	14	14	14	14	14	14	-
	Output voltage									
	$(I_g = 0.3 \mu A)$	Vo	10	17	25	32	41	49	57	v_{RMS}
)	Total distortion	d _{tot}	4.8	5.6	5.8	5.9	6.0	6.1	6.2	%
	Supply voltage	v_b	100	150	200	250	300	350	400	V
	Anode resistor	R_a	220	220	220	220	220	220	220	kΩ
	Grid resistor next stage	Rg'	680	680	680	680	680	680	680	kΩ
	Cathode resistor	$R_{\mathbf{k}}$	3.9	3.9	3.9	3.9	3.9	3.9	3.9	kΩ
	Anode current	Ia	0.33	0.50	0.66	0.82	0.98	1.16	1.31	mA
	Voltage gain	V_o/V_i	14.5	14.5	14.5	14.5	14.5	14.5	14.5	7.2,004
	Output voltage $(I_g = 0.3 \mu A)$	Vo	8	15	22	28	36	43	50	VRMS
	Total distortion	d_{tot}	4.0	4.4	4.7	4.8	4.9	5.0	5.1	%

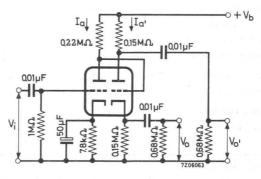
OPERATING CHARACTERISTICS (continued)

Two sections in cascade



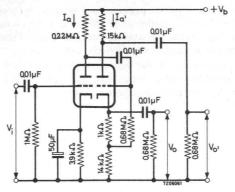
Supply voltage	V_{b}	250	350	V
Total current	I_{tot}	1.66	2.33	mA
Voltage gain	V_{o}/V_{i}	178	178	-
Output voltage ($I_g = 0.3 \mu A$)	V_{o}	15	25	v_{RMS}
Total distortion	d_{tot}	2	2	%

As phase inverter



Supply voltage	V_b	250	350	V
Anode current	Ia	0.70	1.00	mA
Anode current	I _a ,	0.68	0.93	mA
Voltage gain	V_{o}/V_{i}	11	11	· - Program.
Output voltage ($I_g = 0.3 \mu A$)	Vo	15	24	v_{RMS}
Total distortion	d_{tot}	1	1	%

OPERATING CHARACTERISTICS (continued)



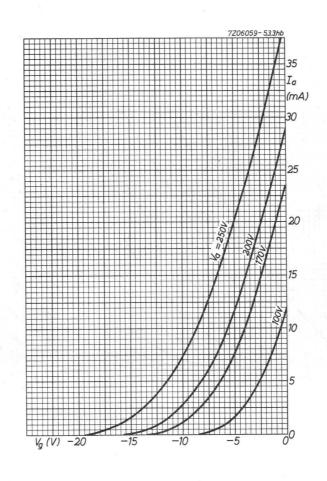
Supply voltage	v_b	250	350	V
Anode current	I_a	0.82	1.16	mA
Anode current	Ia'	4.5	6.3	mA
Voltage gain	v_o/v_i	11	11	-
Output voltage ($I_g = 0.3 \mu A$)	V_{o}	13	20	v_{RMS}
Total distortion	d_{tot}	1.5	1.5	%

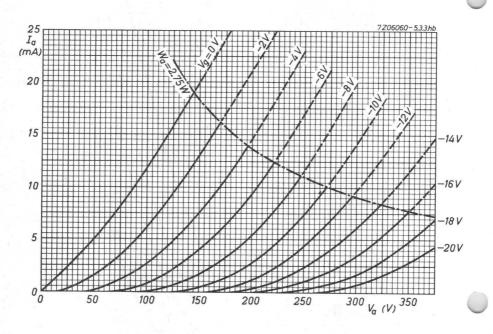
LIMITING VALUES (Design centre rating system) (each unit)

	Anode voltage	v_{a_0}	max.	550	V	
		v_a	max.	300	V	
	Anode dissipation	W_a	max.	2.75	W	
	Cathode current	I_k	max.	20	mA	
)	Grid voltage	$-V_g$	max.	100	$\mathbf{V}_{\mathbf{u}}$	
,	, peak	$-v_{gp}$	max.	250	V	
	Grid resistor (automatic bias)	R_g	max.	1	$M\Omega$	
	Cathode to heater voltage	$V_{\mathbf{kf}}$	max.	180	V	
	Cathode to heater circuit resistance in phase splitting circuits	Rkf	max.	150	kΩ	

REMARK

This tube can be used without precautions against microphony in equipment in which $V_i \geq 10$ mV for an output of 50 mW of the output tube (or $V_i \geq 100$ mV for 5 W output) provided that the average acceleration of the tube is not greater than indicated in the section "Microphonic effect" of the "Application Directions". When the centre tap of the heater transformer has been earthed, $R_g \leq 0.3~M\Omega$ and R_k is sufficiently decoupled, the disturbance level for hum and noise will then be better than 60 dB below 100 mV.





A.F. DOUBLE TRIODE

Double triode intended for use as A.F. amplifier.

	QUICK REFERENCE DATA (each unit)		17.33	
Anode current		Ia	1.2	mA
Transconductance		S	1.6	mA/V
Amplification factor		μ	100	, - chai

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	v_f	6.3	
Heater current	I_f	300	ARLE

pins 9-(4+5) pins 4-5

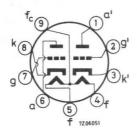
DIMENSIONS AND CONNECTIONS

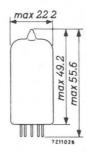
Dimensions in mm

12.6

150 mA

Base: Noval





REMARK

With V_f applied to pins 9 and 4+5 and the centre tap of the heater transformer connected to earth, the triode section connected to pins 6, 7 and 8 is the more favourable section of the tube with respect to hum.

January 1970

CAPAC	CITAN	CES
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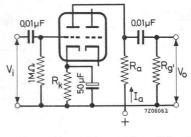
Grid to all except anode	Cg(a)		1.6	pF
	Cg'(a')		1.6	pF
Anode to all except grid	Ca(g)		0.33	pF
	$C_{a'(g')}$		0.23	pF
Anode to grid	C_{ag}		1.6	pF
	Ca'g'		1.6	pF
Grid to heater	C_{gf}	max.	0.15	pF
	Cg'f	max.	0.15	pF
Anode to anode	Caa'	max.	1.2	pF
Anode to grid other unit	Cag'	max.	0.11	pF
Grid to anode other unit	Cga'	max.	0.1	pF
Grid to grid	Corri	max.	0.01	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	250	V
Grid voltage	v_g	-1.0	-2.0	V
Anode current	I_a	0.5	1.2	mA
Transconductance	S	1.25	1.6	mA/V
Amplification factor	μ	100	100	-
Internal resistance	R_i	80	62.5	$k\Omega$

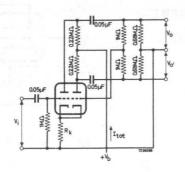
OPERATING CHARACTERISTICS

As A.F. amplifier, one unit

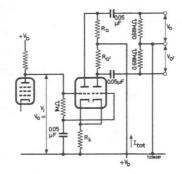


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		0			+	7206062	
Supply voltage	v_b	200	250	300	350	400	V
Anode resistor	Ra	47	47	47	47	47	$k\Omega$
Grid resistor next stage	Rg'	150	150	150	150	150	kΩ
Cathode resistor	R_k	1500	1200	1000	820	680	Ω
Anode current	Ia	0.86	1.18	1.55	1.98	2.45	mA
Voltage gain	V_{o}/V_{i}	34	37.5	40	42.5	44	-
Output voltage ($I_g = 0.3 \mu A$)	V_{o}	18	23	26	33	37	v_{RMS}
Total distortion	d _{tot}	8.5	7.0	5.0	4.4	3.6	%
Supply voltage	V _b	200	250	300	350	400	V
Anode resistor	Ra	100	100	100	100	100	$k\Omega$
Grid resistor next stage	Rg	330	330	330	330	330	kΩ
Cathode resistor	R _k	1800	1500	1200	1000	820	Ω
Anode current	Ia	0.65	0.86	1.11	1.40	1.72	mA
Voltage gain	v_o/v_i	50	54.5	57	61	63	-
Output voltage ($I_g = 0.3 \mu A$)	Vo	20	26	30	36	38	v_{RMS}
Total distortion	d_{tot}	4.8	3.9	2.7	2.2	1.7	%
Supply voltage	V _b	200	250	300	350	400	V
Anode resistor	Ra	220	220	220	220	220	$k\Omega$
Grid resistor next stage	Rg'	680	680	680	680	680	kΩ
Cathode resistor	R_k	3.3	2.7	2.2	1.5	1.2	kΩ
Anode current	Ia	0.36	0.48	0.63	0.85	1.02	mA
Voltage gain	v_o/v_i	56	66.5	72	75.5	76.5	a record
Output voltage ($I_g = 0.3 \mu A$)	Vo	24	28	36	37	38	v_{RMS}
Total distortion	d_{tot}	4.6	3.4	2.6	1.6	1.1	%

As phase inverter



Supply voltage	v_b	250	350	V
Cathode resistor	R_k	1200	820	Ω
Total current	I _{tot}	1.08	1.70	mA
Voltage gain	V_o/V_i	58	62	-
Output voltage ($I_g = 0.3 \mu A$)	V_{o}	35	45	v_{RMS}
Total distortion	d _{tot}	5.5	3.5	%



Supply voltage	v_b	250	350	V
Anode voltage	v_a	65	90	V
Total current	I _{tot}	1	1.2	mA
Cathode resistor	R_k	68	82	kΩ
Anode resistor	Ra	100	150	kΩ
Anode resistor	R _a •	100	150	kΩ
Voltage gain	v_o/v_i	25	27	-
Output voltage ($I_g = 0.3 \mu A$)	V_{o}	20	35	VRMS
Total distortion	d _{tot}	1.8	1.8	%

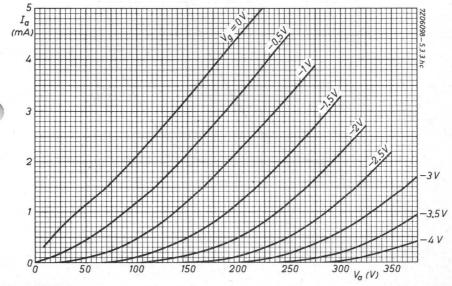
LIMITING VALUE	(Design	centre	rating	system)	
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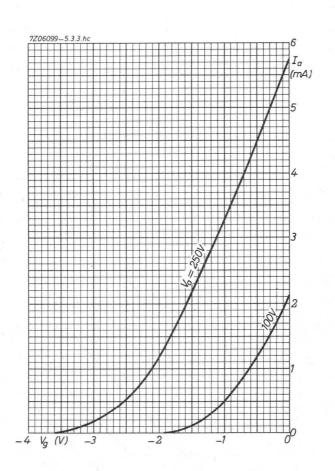
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 300	V
Anode dissipation	w_a	max. 1	W
Cathode current	I_k	max. 8	mA
Grid voltage	-v _g	max. 50	V
Grid resistor (automatic bias)	Rg	max. 2	МΩ
Cathode to heater voltage	v_{kf}	max. 180	V
Cathode to heater circuit resistance in phase splitting circuits	R _{kf}	max. 150	kΩ

REMARK

Microphony and hum

This tube can be used without special precautions against microphony in equipment in which the input voltage $V_i\!\geq\!5$ mV for an output of 50 mW (or 50 mV for an output of 5 W) provided the average acceleration of the tube is not greater than indicated in the section "Microphonic effect" of the "Application directions". In this case the disturbance level for hum and noise will be better than -60 dB when the centre tap of the heater has been earthed, $R_g \leq 0.5~\text{M}\Omega$ and the cathode resistor is sufficiently decoupled.





R.F. DOUBLE TRIODE

Double triode intended for use as $\ensuremath{\text{R.F.}}$ and $\ensuremath{\text{A.F.}}$ amplifier and self oscillating mixer.

	QUICK REFERENCE DATA (each unit)			
Anode current		Ia	10	mA
Transconductance		S	6.1	mA/V
Amplification factor		μ	55	-

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

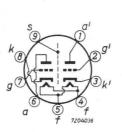
Heater current

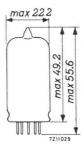
v_{f}	6.3	V
$I_{\mathbf{f}}$	435	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPA	CIT	AN	CES

CAPACITANCES				
Anode to grid	C_{ag}	1.5	pF	
	Ca'g'	1.5	pF	
Anode to cathode	Cak	0.17	pF	
	Ca'k'	0.18	pF	
Anode to cathode + heater + screen	C _{a/kfs}	1.2	pF	
	Ca'/k'fs	1.2	pF	
Grid to cathode + heater + screen	C _{g/kfs}	3.1	pF	
	Cg'/k'fs	3.1	pF	
Anode to cathode + heater + screen	C _{a/kfs}	1.8	pF	
with external screen of 22.5 mm diam.	Ca'/k'fs	1.8	pF	
Anode to anode	C _{aa} ,	max. 0.04	pF	
Grid to grid	Cgg'	max. 0.003	pF	
Anode to grid other unit	Cag'	max. 0.008	pF	
Grid to anode other unit	Cga'	max. 0.008	pF	
Anode to anode with external screen of 22.5 mm diam.	C _{aa} '	max. 0.008	pF	
Anode to cathode other unit	Cak'	max. 0.008	pF	
Grid to cathode other unit	Cgk'	max. 0.003	pF	
Cathode to anode other unit	C _{ka} '	max. 0.008	pF	
Cathode to grid other unit	Ckg'	max. 0.003	pF	
TYPICAL CHARACTERISTICS				
Anode voltage	v_a	250	V	
Grid voltage	Vg	-2.7	v	
Anode current	Ia	10	mA	
Transconductance	S	6.1	mA/V	
Amplification factor	μ	55	-	

REMARK

Microphony

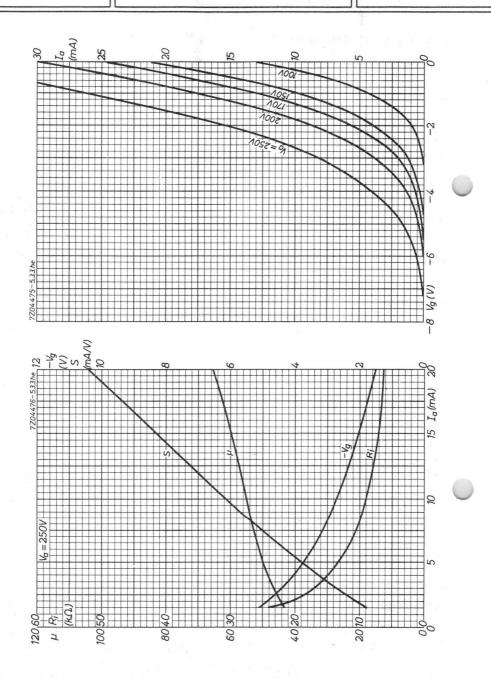
This tube can be used without special precautions against microphony in A.F. applications in which the input voltage $V_i \ge 5 \text{ mV}$ for an output of 50 mW (or 50 mV for an output of 5 W) provided the peak acceleration of the tube is not greater than indicated in the section "Microphony" of the "General Operational Recommendations".

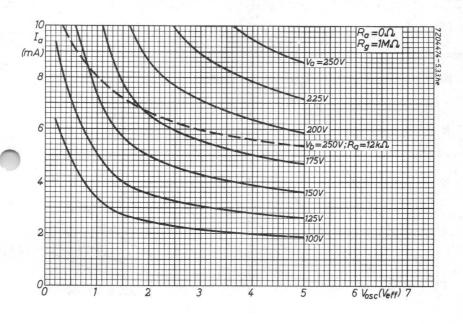
OPERATING CHARACTERISTICS

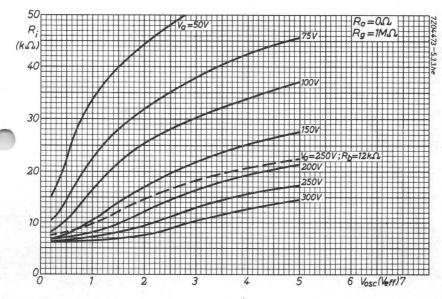
v_b	250	V
Ra	1.8	kΩ
Va	230	V
R_k	200	Ω
V_{g}	-2.2	V
Ia	10.8	mA
S	6.8	mA/V
Ri	8.3	kΩ
r_{g}	4.7	kΩ
	580	Ω
v_b	250	V
Ra	12	kΩ
R_g	1	$M\Omega$
Vosc	3.0	v_{RMS}
Ia	6	mA
S_{c}	3	mA/V
Ri	18	kΩ
r_{g}	15	kΩ
	R _a V _a R _k V _g I _a S R _i r _g R _{eq} V _b R _a R _g V _{osc} I _a S _c R _i	Ra 1.8 Va 230 Rk 200 Vg -2.2 Ia 10.8 S 6.8 Ri 8.3 rg 4.7 Req 580 Vb 250 Ra 12 Rg 1 Vosc 3.0 Ia 6 Sc 3 Ri 18

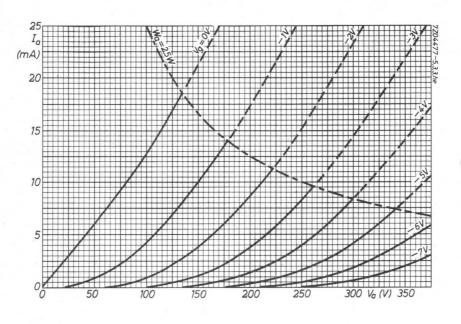
LIMITING VALUES (Design centre rating system) (Each unit unless otherwise stated)

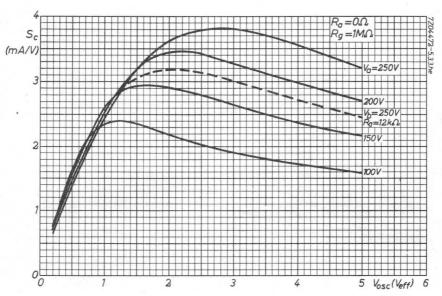
Anode voltage	v_{a_0}	max. 550	V	
	Va	max. 300	V	
Anode dissipation	Wa	max. 2.5	W	
Anode dissipation, total for both units	$W_a+W_{a'}$	max. 4.5	W	
Cathode current	I _k	max. 15	mA	
Grid voltage	-V _g	max. 100	V	
Grid resistor	Rg	max. 1	ΜΩ	
Cathode to heater voltage	v_{kf}	max. 90	V	











R.F. DOUBLE TRIODE

Double triode intended for use as cascode amplifier in tuners for television receivers.

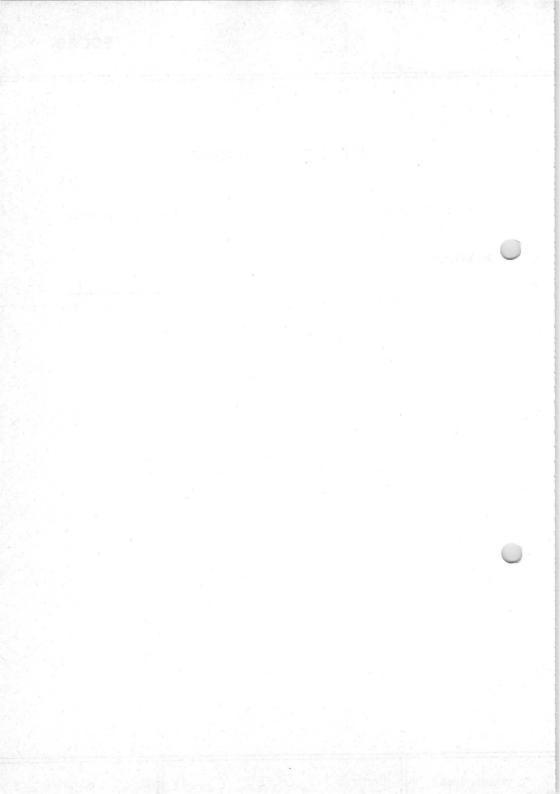
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_{\rm f}}{I_{\rm f}} \qquad \frac{\text{6.3 V}}{\text{365 mA}}$

For further data and curves please refer to $\ensuremath{\mathsf{PCC88}}$



R.F. DOUBLE TRIODE

Double triode with variable transconductance intended for use as V.H.F. cascode amplifier in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage Heater current 6.3 V 365 mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage

max. 50 V

 $V_{k'f}(k pos)$ max. 150 V^{1})

For further data and curves of this type please refer to type PCC189

¹⁾ D.C. component max. 130 V.

TRIODE-PENTODE

Triode-pentode with separate cathodes intended for use as frequency changer in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 V_f 6.3 V

 I_{f} 430 mA

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage

 V_{kf} max. 100 V

Pentode section

Cathode to heater voltage

Vkf max. 100 V

For further data and curves please refer to PCF80

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TRIODE-PENTODE

Triode-pentode intended for use as frequency changer in V.H.F. television tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_f}{I_f} \qquad \frac{6.3 \quad V}{390 \quad mA}$

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage

Vkf max. 100 V

Pentode section

Cathode to heater voltage

V_{kf} max. 100 V

For further data and curves please refer to PCF86

TRIODE-PENTODE

Triode-pentode intended for use in television receivers; triode section as limiter, noise detector, A.G.C. amplifier, sync. separator and pulse-amplifier; pentode section as sound I.F. amplifier and video I.F. amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_{f}}{I_{f}} \quad \frac{6.3}{410} \quad \text{mA}$

For further data and curves please refer to type PCF200

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TRIODE-PENTODE

Triode-pentode intended for use in T.V. receivers; triode section as line-blocking oscillator, part of a multivibrator, sync separator, pulse amplifier or A.G.C. delay diode; pentode section with remote cut-off as video I.F. amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

V_{f}	6.3	V	
I_f	410	mA	

For further data and curves of this type please refer to type PCF201

TRIODE-PENTODE

High transconductance triode and R.F. pentode intended for use as frequency changer in $V.H.F.\ T.V.$ tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

$$\begin{array}{ccc} V_{f} & 6.3 & V \\ \hline I_{f} & 0.41 & A \end{array}$$

For further data and curves of this type please refer to type PCF801

TRIODE-PENTODE

Triode-pentode; triode section intended for use as reactance tube, pentode section intended for use as sine wave oscillator or pulse shaper in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

<u>Vf</u> 6.3 <u>V</u>

Heater current

 $I_{\mathbf{f}}$ 430 mA

LIMITING VALUES

Pentode section

Cathode to heater voltage

Vkf max. 100 V

Triode section

Cathode to heater voltage

Vkf max. 100 V

For further data and curves please refer to type PCF802

TRIODE-HEPTODE

Triode-heptode. Heptode section intended for use as mixer, R.F.-or I.F.amplifier. Triode section intented for use as oscillator in A.M./F.M. receivers.

QUICK REFERENCE DATA							
Triode section							
Anode current	Ia	13.5	mA				
Transconductance	S	3.7	mA/V				
Amplification factor	μ	22	-				
Heptode section							
Anode current	I_a	11	mA				
Transconductance	S	4.5	mA/V				
Amplification factor	$^{\mu}$ g $_2$ g $_1$	25					

HEATING: Indirect by A.C. or D.C.; series or parallel supply

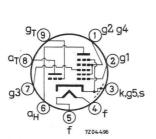
Heater voltage

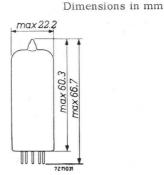
Heater current

$V_{\mathbf{f}}$	6.3	V	
$I_{\mathbf{f}}$	300	mA	

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANO	ES

CAPACITANCES			
Triode section			
Grid to all except anode	Cg(a)	2.6	pF
Anode to all except grid	Ca(g)	2.1	pF
Anode to grid	C_{ag}	1.0	pF
Grid to heater	C_{gf}	max. 0.02	pF
Heptode section			
Grid No.1 to all except anode	$C_{g_1(a)}$	4.8	pF
Anode to all except grid No.1	$C_{a(g_1)}$	7.9	pF
Anode to grid No.1	C_{ag_1}	max.0.006	pF
Grid No.1 to heater	C_{g_1f}	max. 0.17	pF
Grid No.3 to all	C_{g_3}	6	pF
Grid No.1 to grid No.3	$C_{g_1g_3}$	max. 0.3	pF
Grid No.3 to heater	C_{g_3f}	max. 0.06	pF
Between heptode and triode sections			
Anode heptode to anode triode	$C_{a_{\text{H}}a_{\text{T}}}$	0.20	pF
Anode heptode to grid triode	$c_{a_Hg_T}$	max. 0.09	pF
Grid No.1 heptode to anode triode	$C_{g_1H^aT}$	max. 0.06	pF
Grid No.1 heptode to grid triode	$C_{g_1Hg_T}$	max. 0.17	pF
Grid No.1 heptode to grid triode + grid No.3	Cg1H/gTg3	max. 0.45	pF
Anode heptode to grid triode + grid No.3	c_{a_H/g_Tg_3}	max. 0.35	pF

TYPICAL	CHARAC	TERISTICS
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TIPICAL CHARACTERISTICS			
Triode section			
Anode voltage	v_a	100	V
Grid voltage	v_g	0	V
Anode current	Ia	13.5	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	22	- "
Heptode section			
Anode voltage	v_a	160	V
Grid No.3 voltage	v_{g_3}	0	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	100	V
Grid No.1 current	I_{g_1}	0.5	μΑ
Grid No.1 voltage	v_{g_1}	-0.5	V
Anode current	Ia	11	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	7	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	25	-

OPERATING CHARACTERISTICS

Heptode section as mixer 1)					
Supply voltage	$V_{\mathbf{b}}$	2	50	V	
Anode resistor	Ra	8	. 2	$k\Omega$	
Grids No.2 and 4 resistor	R_{g_2+4}		22	kΩ	
Grid triode + grid No.3 resistor	R _{gT+g3}		17	kΩ	
Grid triode + grid No.3 current	IgT+g3	2	00	μ A	
Grid No.1 current	I_{g_1}	0.5		μA^{2})	
Grid No.1 voltage	v_{g_1}	_	-28	V	
Anode voltage	Va	225	240	V	
Grids No.2 and 4 voltage	v_{g_2+4}	78	235	V	
Anode current	Ia	3.3	· · · · · ·	mA	
Grids No.2 and 4 current	I_{g_2+4}	7.8	_	mA	
Conversion conductance	S _c	1100	11	$\mu A/V$	
Internal resistance	R_{i}	0.8	min. 3	$M\Omega$	
Equivalent noise resistance	Req	30	-	$k\Omega$	

 $^{^{1})}$ Triode operating with V $_{b}$ = 250 V, R $_{a}$ = 33 kΩ, V $_{osc}$ = 8 V $_{RMS}.$

²⁾ Grid current bias obtained with Rg $_1$ = 1 $M\Omega$ and with zero volts a.g.c. voltage; resulting grid one voltage: -0.5~V.

OPER ATTAIN	CTY I D I COMPRESSOR	/ 1\
OPERATING	CHARACTERISTICS	(continued)

Heptode section	as	R.F.	or	I.F.	amplifier

Heptode section as R.F. or I.F. amp	lifier		
Supply voltage	v_b	250	V
Anode resistor	R_a	8.2	$k\Omega$
Grid No.3 voltage	v_{g_3}	0	V
Grids No.2 and 4 resistor	$R_{g_{2+4}}$	22	kΩ
Grid No.1 current	I_{g_1}	0.5	μΑ
Grid No.1 voltage	v_{g_1}	35	V 1)
Anode voltage	Va	160 248	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	96 245	V
Anode current	Ia	11 -	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	7 -	mA
Transconductance	S	4500 45	$\mu A/V$
Internal resistance	R_{i}	0.24 min. 10	ΜΩ
Amplification factor	$\mu_{g_2g_1}$	25 -	-
Equivalent noise resistance	Req	4.5	kΩ
Triode section as oscillator			
Supply voltage	v_b	250	V
Anode resistor	Ra	33	kΩ
Grid triode + grid No.3 resistor	R _{gT+g3}	47	kΩ
Grid triode + grid No.3 current	IgT+g3	200	μ A
Anode current	Ia	4.5	mA

Seff

0.65

Effective transconductance

mA/V

 $^{^1)}$ Grid current bias obtained with Rg $_1$ = 1 $\rm M\Omega$ and with zero volts a.g.c. voltage; resulting grid No.1 voltage; -0.5 V.

LIMITING	VALUES	(Design	centre	rating	system)
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Heptode section				
Anode voltage		v_{a_0}	max. 550	V
		v_a	max. 300	V
Anode dissipation		w_a	max. 2.0	W
Grids No.2 and 4 voltage		$v_{g_{2+4_0}}$	max. 550	V
		$v_{g_{2+4}}$	max. 125	V
Grids No.2 and 4 voltage (Ia ma	x. 1 mA)	$v_{g_{2+4}}$	max. 300	V
Grids No.2 and 4 dissipation		$W_{g_{2+4}}$	max. 0.8	W
Cathode current		Ik.	max. 18	mA
Grid No.1 resistor		R_{g_1}	max. 3	$M\Omega$
Grid No.3 resistor		R_{g_3}	max. 20	kΩ
Grid No.3 resistor grid No.3 directly connected to)			
grid triode		R_{g_3}	max. 3	$M\Omega$
Cathode to heater voltage		v_{kf}	max. 100	V
Triode section				
Anode voltage		v_{a_0}	max. 550	V
		v_a	max. 250	V
Anode dissipation		Wa	max. 0.8	W
Cathode current		I_k	max. 6.5	mA
Grid resistor		R_g	max. 3	ΜΩ
Cathode to heater voltage		Vkf	max. 100	V

TRIODE-HEPTODE

Triode-heptode intended for use as mixer in car radio sets and as sync separator in TV receivers.

QUICK REFE	RENCE DA	ATA			
Triode					
Anode voltage	v_a	25	12.6	6.3	V
Anode current	I_a	2	0.75	0.3	mA
Transconductance	S	2.2	1.4	0.8	mA/V
Amplification factor	μ	20	18.3	14.6	-
Heptode as mixer					
Anode voltage	Va	25	12.6	6.3	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$. 25	12.6	6.3	V
Conversion conductance	S_c	450	220	90	$\mu A/V$
Heptode as R.F. or I.F. amplifier					
Anode voltage	v_a	25	12.6	6.3	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	25	12.6	6.3	V
Transconductance	S	1.5	0.75	0.35	mA/V

HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage

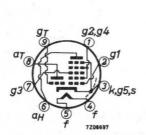
Heater current

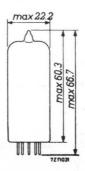
V_{f}	6.3	V
If	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section			
Anode to all except grid	Ca(g)	2.1	pF
Grid to all except anode	$C_{g(a)}$	2.6	pF
Anode to grid	C_{ag}	1.0	pF
Heptode section			
Anode to all	C_a	7.9	pF
Grid No.1 to all	Cg_1	4.8	pF
Anode to grid No.1	C_{ag_1}	max. 0.012	pF
Grid No.3 to all	C_{g_3}	6.0	pF
Grid No.1 to grid No.3	$C_{g_1g_3}$	max. 0.3	pF
Between heptode and triode sections			
Anode heptode to anode triode	C_{aHaT}	0.20	pF
Anode heptode to grid triode	C_{aHgT}	max. 0.09	pF
Grid No.1 heptode to anode triode	C_{g_1HaT}	max. 0.06	pF
Grid No.1 heptode to grid triode	C_{g_1HgT}	max. 0.17	pF
Grid No.1 heptode to grid triode			
and grid No.3	$c_{g_1}H/gTg_3$	max. 0.45	pF
Anode heptode to grid triode and grid No.3	CaH/gTg3	max. 0.35	pF

TYPICAL CHARACTERISTICS

Triode section	
Anode voltage	
Crid voltage	

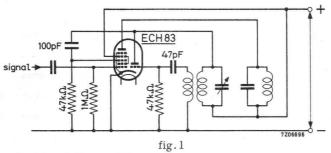
Anode voltage	v_a	25	12.6	6.3	V
Grid voltage	v_g	1)	1)	1)	_
Anode current	Ia	2	0.75	0.3	mA
Transconductance	S	2.2	1.4	0.8	mA/V
Amplification factor	μ	20	18.3	14.6	-

 $[\]overline{\mbox{1}}$) Obtained by grid current biasing: R $_{\mbox{g}}$ = 47 k Ω .

OPERATING CHARACTERISTICS

Heptode as mixer,	circuit	fig.1.
-------------------	---------	--------

Anode voltage	Va	25	12.6	6.3	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	25	12.6	6.3	V
Grid No.1 voltage	v_{g_1}	1)	1)	¹)	
Oscillator voltage	V_{osc}	3.5	1.7	1.1	v_{RMS}
Grid No.3 resistor	R_{g_3}	47	47	47	$k\Omega$
Grid No.3 current	I_{g_3}	40	18	7	μ A
Anode current	Ia	550	170	50	μ A
Grids No.2 and 4 current	$I_{g_{2+4}}$	1000	300	80	μ A
Conversion conductance	s_c	450	220	90	$\mu A/V$
Internal resistance	Ri	0.5	1.5	1.3	$M\Omega$



Heptode	as	R.	F.	or	I.F	. am	plifier

Anode voltage	v_a	25	12.6	6.3	V
Grids No.2, No.3 and No.4 voltage	$v_{g_{2+3+4}}$	25	12.6	6.3	V
Grid No.1 voltage	v_{g_1}	1)	¹)	1)	
Anode current	Ia	1.25	0.4	0.11	mA
Grids No.2, No.3 and 4 current	$I_{g_{2+3+4}}$	0.85	0.25	0.08	mA
Transconductance	S	1.5	0.75	0.35	mA/V
Internal resistance	R_i	0.2	0.85	0.6	ΜΩ
Equivalent noise resistance	Req	5	6.5	8.5	kΩ

 $[\]overline{\mbox{1}}$) Obtained by grid current biasing: R $_{g_1}$ = 1 M Ω .

LIMITING VALUES (Design centre rating system)

, , , ,					
Triode section					
Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	250	v	
Anode dissipation	Wa	max.	0.8	W	
Cathode current	$I_{\mathbf{k}}$	max.	6.5	mA	
Grid resistor	Rg	max.	3	$M\Omega$	
Cathode to heater voltage	v_{kf}	max.	150	v	ž
D.C. component		max.	100	V	-
Heptode section					
Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	50	V	
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	max.	50	V	
Cathode current	I _k	max.	5	mA	
Grid No.1 resistor	R _{g1}	max.	3	$M\Omega$	
Grid No.3 resistor	R_{g_3}	max.	50	$k\Omega$	
Cathode to heater voltage	V_{kf}	max.	150	V	
D.C. component		max.	100	V	

TRIODE-HEPTODE

Triode-heptode intended for use as pulse separator, noise inverter and sync. amplifier.

QUICK RE	FERENCE DATA	
Triode section	The first control of the control of	
Anode voltage	V_a 50 V	
Anode current	I _a 3 mA	
Transconductance	S 3.7 mA/	V
Amplification factor	μ 50 -	
Heptode section		
Anode voltage	V _a 135 V	
Grids No.2 and 4 voltage	$v_{g_{2+4}}$ 14 v	
Anode current	I _a 1.7 mA	
Grids No.2 and 4 current	$I_{g_{2+4}}$ 0.9 mA	
Transconductance	S 2.2 mA/	V

 $\boldsymbol{\mathsf{HEATING}} \colon \mathsf{Indirect}\ \mathsf{by}\ \mathsf{A.C.}$ or $\mathsf{D.C.};\ \mathsf{series}\ \mathsf{or}\ \mathsf{parallel}\ \mathsf{supply}$

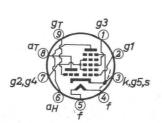
Heater voltage

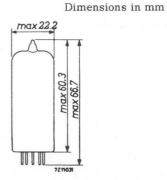
Heater current

$V_{\mathbf{f}}$	6.3	V		
If	300	mA		

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES					
Triode section					
Grid to all except anode	Cg(a)		3.0	pF	
Anode to grid	C_{ag}		1.1	pF	
Heptode section					
Anode to grid No.1	C_{ag_1}	max.	0.009	pF	
Between triode and heptode sections					
Grid triode to grid No.1 heptode	$C_{gTg_{1H}}$	max.	0.10	pF	
Anode triode to grid No.1 heptode	$C_{a_Tg_{1H}}$	max.	0.08	pF	
Anode triode to grid No.3 heptode	$C_{a_{T}g_{3H}}$	max.	0.13	pF	
Grid triode to anode heptode	$C_{g_{\mathrm{T}^a\mathrm{H}}}$	max.	0.09	pF	
Anode triode to anode heptode	$C_{a_{\mathrm{T}}a_{\mathrm{H}}}$	max.	0.25	pF	
TYPICAL CHARACTERISTICS					
Triode section					
Anode voltage	v_a		50	V	
Grid voltage	V_g		0.	V	
Anode current	Ia		3	mA	
Transconductance	S		3.7	mA/V	

μ

Va

 V_g

 I_a

Amplification factor

Anode voltage

Grid voltage

Anode current

50 -

200 V -11 V

max. 0.1 mA

TYPICAL CHARACTERISTICS (continued)				
Heptode section				
Anode voltage	v_a	13	5	V
Grid No.3 voltage	v_{g_3}	()	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	1 14	1	V
Grid No.1 voltage	v_{g_1}		О	V
Anode current	Ia	1.	7	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	0.	9	mA
Transconductance	S	2.	2	mA/V
Grid No.3 voltage	v_{g_3}	-	2	V
Grid No.1 voltage	v_{g_1}	(C	V
Anode current	I_a	20)	μ A
Grid No.1 voltage	v_{g_1}	-1.	9	V
Grid No.3 voltage	v_{g_3}		O	V
Anode current	I_a	20)	μ A
LIMITING VALUES (Design centre rating system	m)			
Heptode section				
Anode voltage	v_{a_0}	max.	550	V
	Va	max. 2	250	V
Anode dissipation	Wa	max.	1:7	W
Grids No.2 + 4 voltage	$v_{g_{2+4_0}}$	max.	550	V
	$v_{g_{2+4}}$	max. 2 min.	250 10	-
Grids No.2 + 4 dissipation	$W_{g_{2+4}}$	max. ().8	W
Grid No.3 voltage, negative peak	-Vg _{3p}	max.	150	V
Grid No.3 resistor	R_{g_3}	max.	3	ΩM

 $-v_{g_{1p}}$

Rg1

 I_k

 $V_{\mathbf{k}\mathbf{f}}$

max. 150 V

max. 12.5 mA

max. 100 V

max.

Grid No.1 voltage, negative peak

Grid No.1 resistor

Cathode to heater voltage

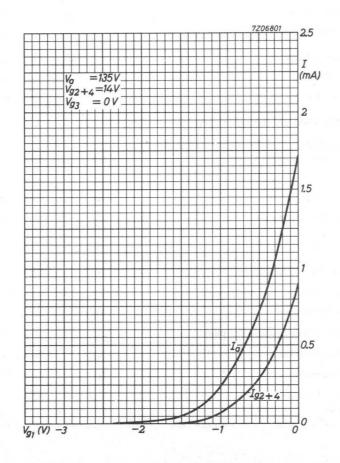
Cathode current

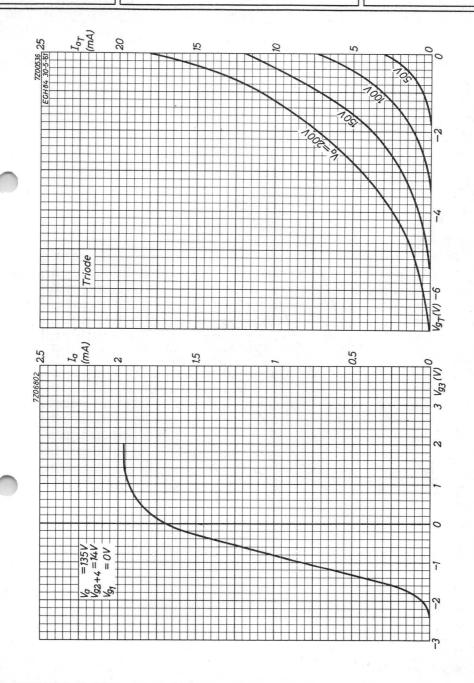
This value applies to an average tube operated under the worst probable conditions.

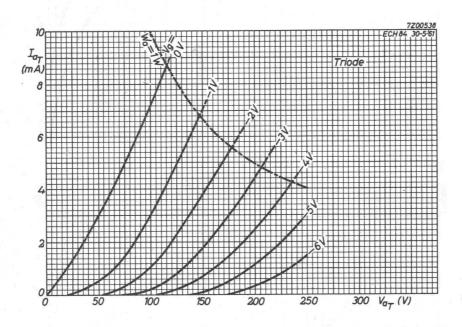
LIMITING VALUES (continued)

Triode section	on
----------------	----

Anode voltage	v_{a_0}	max.	550	V
	Va	max.	250	V
Anode dissipation	w_a	max.	1.3	W
Grid voltage, negative peak	-v _{gp}	max.	200	V
Grid resistor	Rg	max.	3	$M\Omega$
Cathode current	I_k	max.	10	mA
Cathode to heater voltage	v_{kf}	max.	100	V







TRIODE-HEPTODE

Triode-heptode; triode section intended for use as pulse amplifier and heptode section for use as noise gated sync. separator.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage Heater current

6.3 V $V_{\mathbf{f}}$ 435 mA

If

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage

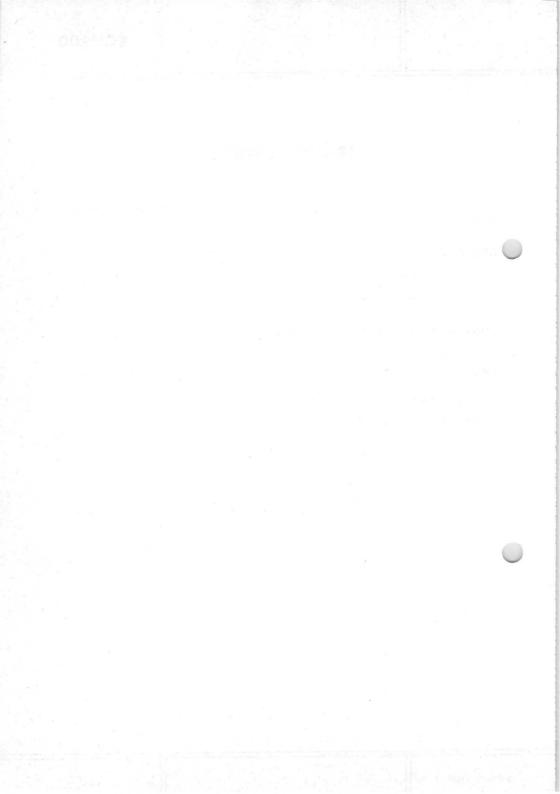
 V_{kf} max. 100 V

Heptode section

Cathode to heater voltage

 v_{kf} max. 100 V

For further data and curves of this type please refer to type PCH200



TRIODE-OUTPUT PENTODE

The triode section is intended for use as frame oscillator and A.F. amplifier. The pentode section is intended for use as frame output tube and A.F. power amplifier.

QUICK REFERENCE DATA							
Triode section							
Anode current	Ia	3.5	mA				
Transconductance	S	2.2	mA/V				
Amplification factor	μ	70	_				
Pentode section							
Anode peak voltage	V _{ap} ma	x. 2.5	kV				
Anode current	I _a	41	mA				
Transconductance	S	7.5	mA/V				
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	9.5	- 397				
Output power	Wo	3.5	W				

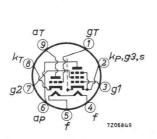
HEATING: Indirect by A.C. or D.C.; parallel supply

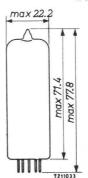
Heater voltage Heater current $\frac{V_{\rm f}}{I_{\rm f}}$ 6.3 V $\frac{V_{\rm f}}{780}$ mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





ECL82

			-	
CAPACITANCES				_
Triode section				
Anode to all except grid	Ca(g)	4.3	pF	
Grid to all except anode	Cg(a)	2.7	pF	
Anode to grid	Cag	4.4	pF	
Grid to heater	C_{gf}	max. 0.1	pF	
Pentode section				
Anode to all except grid No.1	$C_{a(g_1)}$	8.0	pF	
Grid No.1 to all except anode	$Cg_1(a)$	9.3	pF	
Anode to grid No.1	C_{ag_1}	max. 0.3	pF	
Grid No.1 to heater	c_{g_1f}	max. 0.3	pF	
Between triode and pentode sections				
Anode triode to grid No.1 pentode	CaTg ₁ P	max. 0.02	pF	
Grid triode to anode pentode	C_{gTaP}	max. 0.02	pF	
Grid triode to grid No.1 pentode	C_gTg_1P	max.0.025	pF	
Anode triode to anode pentode	$C_{a}T_{a}P$	max. 0.25	pF	
TYPICAL CHARACTERISTICS				
Triode section				
Anode voltage	Va	100	V	
Grid voltage	V_g	0	V	
Anode current	I_a	3.5	mA	
Transconductance	S	2.2	mA/V	
Amplification factor	μ	70		
Pentode section				0
Anode voltage	Va	170	V	
Grid No.2 voltage	v_{g_2}	170	V	
Grid No.1 voltage	v_{g_1}	-11.5	V	
Anode current	Ia	41	mA	
Grid No.2 current	I_{g_2}	9	mA	
Transconductance	S	7.5	mA/V	
Amplification factor	$\mu_{g_2g_1}$	9.5	-	
Internal resistance	Ri	16	$k\Omega$	

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier

Ir	lode section as A.F. amplific	er					
Α.	Signal source resistance			R_s	0.	22	МΩ
	Grid resistor			Rg		3	$M\Omega$
	Grid resistor of next stage			R_g	0.	68	$M\Omega$
	Supply voltage			v_b	200	170	V
	Cathode resistor			$R_{\mathbf{k}}$	2.2	2.7	$k\Omega$
	Anode resistor			Ra	220	220	kΩ
	Anode current			Ia	0.52	0.43	mA
	Voltage gain			V_o/V_i^{-1})	52	51	_
	Max. output voltage			$v_{o\ max}$	26	25	V _{RMS}
	Distortion			d_{tot}^{2}	1.6	2.3	%
В.	Signal source resistance	Rs		0.2	2		МΩ
	Grid resistor	Rg		2	2		$M\Omega$
	Grid resistor of next stage	Rg'		0.6	8		МΩ
	Supply voltage	V_b	200	200	170	170	v
	Cathode resistor	$R_{\mathbf{k}}$	0	0	0	0	Ω
	Anode resistor	Ra	100	220	100	220	kΩ
	Anode current	Ia	1.05	0.61	0.86	0.50	МΩ
	Voltage gain	V_0/V_i^{-1}	50	55	49	53	
	Max. output voltage	v_{omax}	24	25	19	20	VRMS
	Distortion	d _{tot} 3)	1.5	1.4	1.4	1.4	%

MICROPHONY AND HUM

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage of minimum $10~mV_{RMS}$ is required for an output of 50 mW of the output stage. $Z_{\rm g}$ (50 Hz) = 0.25 $M\Omega$.

¹⁾ Measured at small input voltage.

²⁾ At lower output voltages the distortion is proportionnally lower.

³⁾ At lower output voltages down to 5 V_{RMS} the distortion is approximately constant. At values below 5 V_{RMS} the distortion is approximately proportional to V_{O} .

OPERATING CHARACTERISTICS

Pentode section

A.F.	power	amplifier,	class A	(measured	with	V_k	constant)
------	-------	------------	---------	-----------	------	-------	-----------

Supply voltage	V _{ba} = V _{bg}	52	200			272		V
Grid No.2 series re (non-decoupled)	esistor R _{g2}		470			2200		Ω
Cathode resistor	R_k	e.	330			650		Ω
Load resistance	Ra	C	4.5			8		$k\Omega$
Grid No.1 driving v	oltage V _i	0	0.66	6.7	0	0.9	9.5	v_{RMS}
Anode current	I_a	35		37	28		27	mA
Grid No.2 current	I_{g_2}	7.8		13.3	6.5		10.8	mA
Output power	Wo	0	0.05	3.3	0	0.05	3.5	W
Distortion	d_{tot}	-	-	10	1_	-	10	%

A.F. power amplifier, class AB, two tubes in push-pull

V
Ω
$k\Omega$
5 V _{RMS}
31 mA
3 mA
5 W
.8 %
3

Frame output application

The circuit should operate satisfactorily with a peak anode current I_{ap} = 85 mA at V_a = 50 V, V_{g_2} = 170 V, V_f = 6.3 V. The minimum available I_{ap} at end of life is;

70 mA at
$$V_a$$
 = 50 V, V_{g_2} = 170 V, V_f = 5.5 V 80 mA at V_a = 50 V, V_{g_2} = 190 V, V_f = 5.5 V.

LIMITING VALUES (Design centre rating system)

Triode section				
Anode voltage	v_{a_0}	max.	550	V
	Va	max.	300	V
Anode peak voltage	v_{a_p}	max.	600	V^1)
Anode dissipation	Wa	max.	1	W
Cathode current, average	I_k	max.	' 15	mA
peak	I_{k_p}	max.	100	mA 1)
Grid resistor for fixed bias	Rg	max.	1	МΩ
for automatic bias	R_g	max.	3	$M\Omega$
Grid impedance at 50 Hz	z_g	max.	0.5	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	100	V
Pentode section				
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	300	V
Anode peak voltage, positive	Vap	max.	2.5	kV 1)
negative	-Vap	max.	500	V
Anode dissipation for frame ouput application	Wa	max.	5	W
for A.F. output application	w_a	max.	7	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	300	V
Grid No.2 dissipation, average	w_{g_2}	max.	2	W
peak	$w_{g_{2p}}$	max.	3.2	W
Cathode current	I_k	max.	50	mA
Grid No.1 resistor for fixed bias	R_{g_1}	max.	1	$M\Omega$
for automatic bias	R_{g_1}	max.	2	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	150	V

For curves of the ECL82 please refer to PCL82

¹⁾ Max. pulse duration 4% of a cycle with a maximum of 0.8 msec.

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TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes

The triode section is intended for use in circuits for keyed AGC, sync separation, sync amplification and noise suppression.

The pentode section is intended for use as video output tube.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage

Vkf max. 200 V

For further data and curves please refer to PCL84

TRIODE-OUTPUT PENTODE

Triode pentode with separate cathodes.

Triode intended for use as frame oscillator or pulse amplifier.

Pentode intended for use as frame output tube.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_{\rm f}}{I_{\rm f}} = \frac{6.3 \text{ V}}{875 \text{ mA}}$

OPERATING CHARACTERISTICS OF THE PENTODE SECTION

Hum

The equivalent pentode grid hum voltage without negative feedback and without A.C. voltage between heater and cathode is max. 10 mV $_{RMS}$ when $\rm Z_{g_1}$ (at f = 50 Hz) \leq 0.5 M Ω and C $_{g_1-f}$ = 0.2 pF.

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage V_{kf} max. 100 V D.C. component during warming up V_{kf} (k pos) max. 315 V

Pentode section

Cathode to heater voltage Vkf max. 100 V

For further data and curves please refer to PCL85/PCL805

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TRIODE-OUTPUT PENTODE

Triode pentode with separate cathodes.

The triode section is intended for use as A.F. amplifier.

The pentode section is intended for use as A.F. power amplifier.

N. G.	QUICK REFERE	NCE DATA	41 TH 2	4
Triode section			i, The	
Anode current		I _a	1.2	mA
Transconductance		S	1.6	mA/V
Amplification factor		μ	100	- 1 = 11
Pentode section				
Anode current		Ia	36	mA
Transconductance		S	10	mA/V
Amplification factor		$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	21	- 12.04.14
Output power		Wo	4.0	W

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

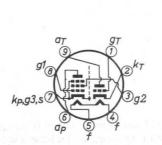
Heater current

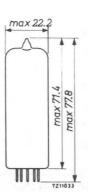
 $\frac{V_f}{I_f}$ 6.3 V $\frac{6.3 \text{ V}}{660 \text{ mA}}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACI	TANCES

CAPACITANCES			
Triode section			
Anode to all except grid	Ca(g)	2.5	pF
Grid to all except anode	Cg(a)	2.3	pF
Anode to grid	Cag	1.4	pF
Grid to heater	$C_{ m gf}$	max. 0.006	pF
Pentode section			
Grid No.1 to all except anode	$C_{g_1(a)}$	10	pF
Anode to grid No.1	C_{ag_1}	max. 0.4	pF
Grid No.1 to heater	C_{g_1f}	max. 0.24	pF
Between triode and pentode sections			
Anode triode to grid No.1 pentode	$C_{aTg_1}P$	max. 0.2	pF
Grid triode to grid No.1 pentode	C_{gTg_1P}	max. 0.02	pF
Anode triode to anode pentode	C_{aTaP}	max. 0.15	pF
Grid triode to anode pentode	C_{gTaP}	max. 0.006	pF ¹)
TYPICAL CHARACTERISTICS			
Triode section			
Anode voltage	v_a	250	V
Grid voltage	$V_{\mathbf{g}}$	-1.9	V
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	-
Pentode section			
Anode voltage	Va	250	V
Grid No.2 voltage	v_{g_2}	250	V
Grid No.1 voltage	v_{g_1}	-7	V
Anode current	Ia	36	mA
Grid No.2 current	I_{g_2}	6	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	21	-
Internal resistance	R_{i}	48	$k\Omega$

 $[\]overline{\mbox{1}}$) The capacitance between triode grid and pentode anode ($\mbox{CgT-aP}$) can be reduced to a value of less than 0.002 pF by using a shielding ring with a diameter of 22.5 mm and a height of 15 mm with respect to the tube base.

OPERATING CHARACTERISTICS

Triode	section

	as A.F. amplifier						
	Supply voltage	V_b	200	250	250	300	V
	Cathode resistor	R _k	2.6	1.75	1.75	1.2	kΩ
	Anode resistor	Ra	220	220	220	220	kΩ
	Grid resistor of following stage	Rg'	0.68	0.68	10	10	$M\Omega$
	Anode current	Ia	0.42	0.6	0.6	0.8	mA
)	Output voltage	Vo	3.2	3.2	5	9	v_{RMS}
	Voltage gain	V_{o}/V_{i}	66	70	75	80	-
	Distortion	d _{tot}	0.6	0.4	0.4	0.4	%
	A.F. amplifier with grid current bia	asing					
	Supply voltage	V _b	200	250	250	300	V
	Cathode resistor	R_k	0	0	0	0	Ω
	Anode resistor	Ra	220	220	220	220	kΩ
	Grid resistor	R_g	10	10	10	10	$M\Omega$
	Grid resistor of following stage	Rg'	0.68	0.68	10	10	ΜΩ
	Signal source resistance	R_s	47	47	47	47	$k\Omega$
	Anode current	Ia	0.42	0.6	0.6	0.8	m A
	Output voltage	V_{o}	3.2	3.2	5	9	v_{RMS}
	Voltage gain	v_o/v_i	66	70	75	80	-
	Distortion	d_{tot}	0.6	0.4	0.4	0.4	%

MICROPHONY

The triode section can be used without special precautions against microphonic effect in circuits in which an output of 50 mW is obtained at an input voltage of not less than 4 mVRMS.

HUM

The hum level will be better than 60 dB under the following conditions: Input voltage minimum 10 mVRMS for 50 mW output.

Grid circuit impedance max. 0.5 M Ω at 50 Hz.

Cathode decoupling capacitor minimum 100 μ F.

Pin 4 connected to earth.

OPERATING CHARACTERISTICS (continued)

Pentode	secti	ion
---------	-------	-----

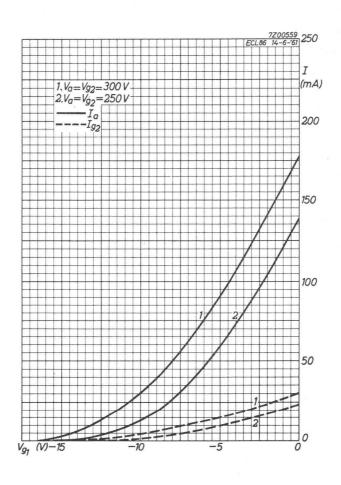
Class A	(Measured	with	$V_{\mathbf{k}}$	constant)	
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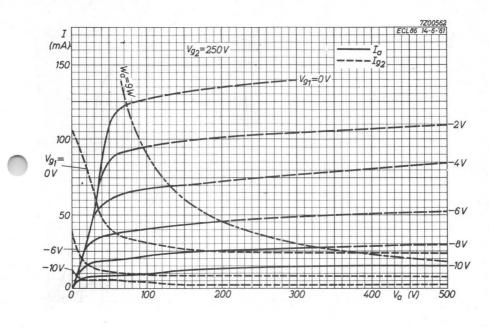
Class A (Measured	with V _k	constant))					
Anode voltage	v_a		250			250		V
Grid No.2 voltage	v_{g_2}		250			250		V
Cathode resistor	R_k		170			270		Ω
Load resistance	${\rm R}_{\rm a_{\sim}}$		7			10		kΩ
Grid No.1 driving voltage	v_i	0	0.3	3.2	0	0.28	2.7	v_{RMS}
Anode current	Ia	36	-	37	26	-	27	mA
Grid No.2 current	I_{g_2}	6	-	10.2	4.4	-	8.0	mA
Output power	Wo	0	0.05	4.0	0	0.05	2.8	W
Distortion	d_{tot}	-	0.95	10		1.1	10	%
Class AB, two tubes	in push-	pull						
Supply voltage	V_b		250			300		V
Common cathode resistor	R_k		90			130		Ω
Load resistance	$R_{aa_{\sim}}$		8.2			9.1		kΩ
Grid No.1 driving								
voltage	v_i	0	0.24	5.5	0	0.26	8.4	v_{RMS}
Anode current	Ia	2x32.5	-	2x35.5	2x31	-	2x36.5	mA
Grid No.2 current	I_{g_2}	2x5.6	-	2x8.9	2x5.5	-	2x11	mA
Output power	W_{O}	0	0.05	10	0	0.05	13.6	W
Distortion	d_{tot}	-	<0.4	5.0	-	<0.4	4.0	%

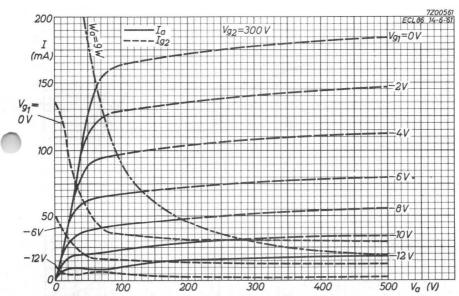
Tr	iode	section	
TT	rouc	Beetion	

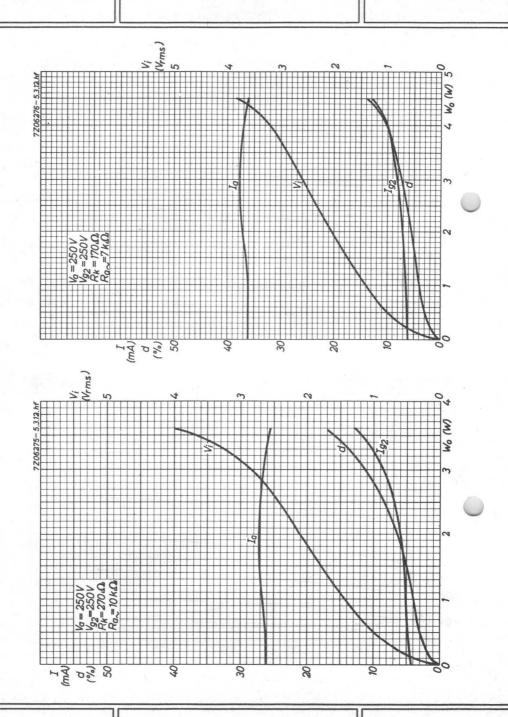
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	300	V
Anode dissipation	Wa	max.	0.5	W
Cathode current	I_k	max.	4	mA
Grid resistor	R_g	max.	1	$M\Omega^{-1}$)
Cathode to heater voltage	$v_{\rm kf}$	max.	100	V
Pentode section				
Anode voltage	V_{a_0}	max.	550	V
	Va	max.	300	V
Grid No.2 voltage	$v_{g_{2_0}}$	max.	550	V
	V_{g_2}	max.	300	V
Anode dissipation	Wa	max.	9	W
Grid No.2 dissipation				
average	w_{g_2}	max.	1.8	W
peak	$w_{g_{2p}}$	max.	3.25	W
Cathode current	I_k	max.	55	mA
Grid No.1 resistor	R_{g_1}	max.	0.5	$M\Omega^{-1}$)
Cathode to heater voltage	Vkf	max.	100	V

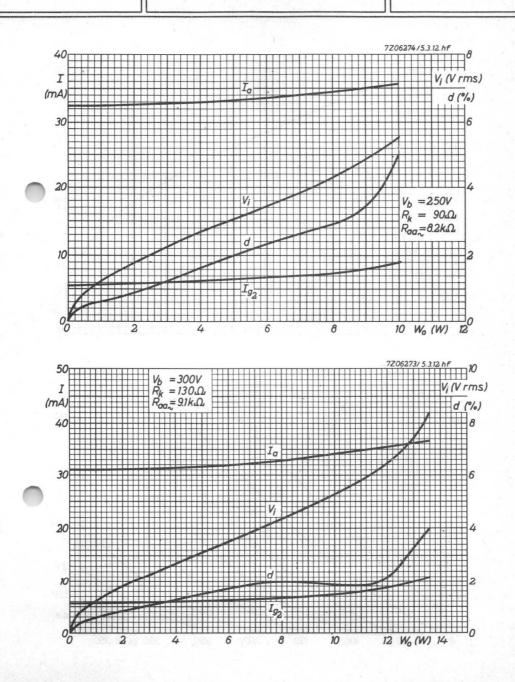
¹) This value applies to operation with fixed bias. It may be multiplied by the D.C. inverse feedback factor resulting from e.g. cathode, screen grid or anode resistors, to a maximum of 10 M Ω .



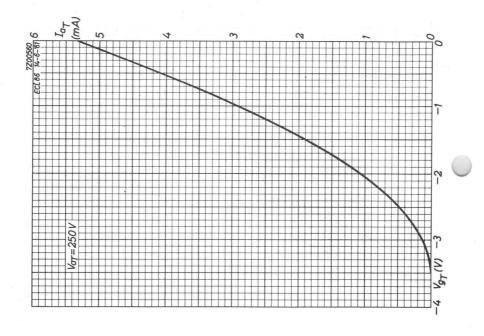


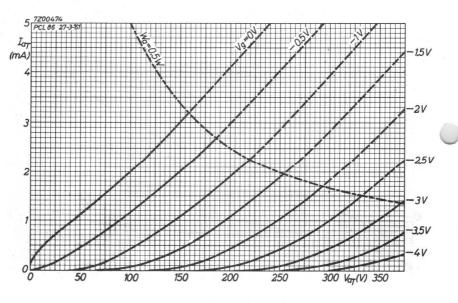






ECL86





SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use as in colour TV receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_f}{I_f}$ 6.3 V $\frac{350}{MA}$

For further data and curve of this type please refer to type PD500

Apply to the make

R.F. PENTODE

Pentode intended for use as R.F., I.F. or video amplifying tube or as mixing tube in television receivers.

QUICK REFI	ERENCE DATA	=2	
Anode current	Ia	10	mA
Transconductance	S	7.4	mA/V
Amplification factor	$\mu_{ exttt{g}_2 exttt{g}_1}$	50	-
Internal resistance	R_{i}	500	kΩ

HEATING: Indirect by A.C. or D.C.; series or parallel supply

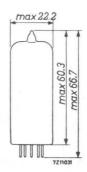
Heater voltage Heater current V_f 6.3 V I_f 300 mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Grid No.1 to all except anode	$C_{g_1(a)}$	6.9	pF
Anode to all except grid No.1	$C_{a(g_1)}$	3.1	pF
Anode to grid No.1	C_{ag_1}	max. 0.007	pF
Anode to cathode	C_{ak}	max. 0.012	pF
Grid No.2 to all	C_{g_2}	5.4	pF
Grid No.1 to grid No.2	$C_{g_1g_2}$	2.6	pF
Grid No.1 to heater	C_{g_1f}	max. 0.15	pF
Cathode to heater	C_{kf}	5.0	pF

REMARK

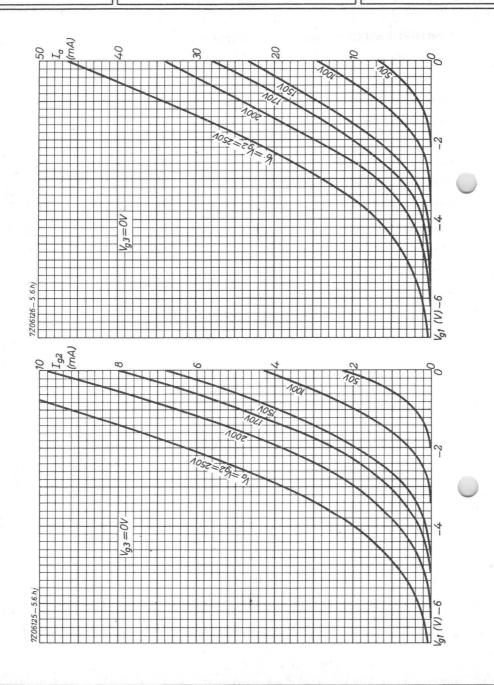
When using the EF80 as video amplifier the amplification between the input grid of the EF80 and the input of the cathode ray tube should not exceed a value of 25, in order to prevent microphonic effect.

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	Va	170	200	250	V
Grid No.3 voltage	v_{g_3}	0	0	0	V
Grid No.2 voltage	v_{g_2}	170	200	250	V
Grid No.1 voltage	v_{g_1}	-2.0	-2.55	-3.5	V
Anode current	Ia	10	10	10	mA
Grid No.2 current	I_{g_2}	2.5	2.6	2.8	mA
Transconductance	S	7.4	7.1	6.8	mA/V
Internal resistance	R_{i}	0.5	0.55	0.65	$M\Omega$
Amplification factor	$\mu_{\mathrm{g}_2\mathrm{g}_1}$	50	50	50	-
Equivalent noise resistance	Req	1000	1100	1200	Ω
Grid No.1 input resistance f = 50 MHz, pin 1 connected to pin	3 r _{g1}	10	12	15	kΩ

LIMITING	VALUES	(Degion	centre	rating	gystem)

Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	300	V	
Anode dissipation	w_a	max.	2.5	W	
Grid No.2 voltage	$v_{\rm g_{2o}}$	max.	550	V	
	v_{g_2}	max.	300	V	
Grid No.2 dissipation	w_{g_2}	max.	0.7	W	
Grid No.2 dissipation ($W_a < 1.8 W$)	w_{g_2}	max.	0.9	W	
Grid No.1 resistor	R_{g_1}	max.	1	МΩ	
Cathode current	I_k	max.	15	mA	
Heater to cathode voltage	$V_{\mathbf{kf}}$	max.	150	V	



R.F. PENTODE

 $R.\,F.$ pentode with variable transconductance intended for use as wide-band amplifier.

QUICK REFERENCE DATA								
Anode current	Ia	10	mA					
Transconductance	S	6.0	mA/V					
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	26	-					
Internal resistance	R_i	600	kΩ					

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

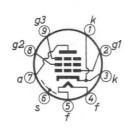
Heater current

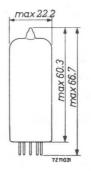
V_f 6.3 V I_f 300 mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Grid No.1 to heater

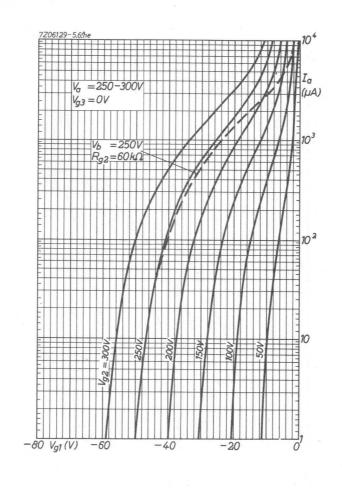
$C_a(g_1)$	3.2	2 pF
$C_{g_1(a)}$	6.	9 pF
Cag1	max. 0.00	7 pF
C_{g_1f}	max. 0.1	5 pF

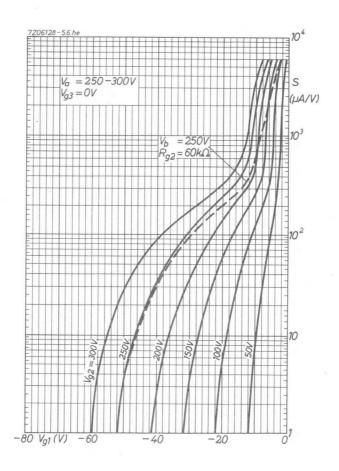
EF85

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode and supply voltage	$v_a = v_b$	25	60	V	
Grid No.3 voltage	v_{g_3}		0	V	
Grid No.2 resistor	R_{g_2}	6	00	kΩ	
Grid No.1 voltage	v_{g_1}	- 2	-35	V	
Grid No.2 voltage	v_{g_2}	100	-	V	
Anode current	I_a	10	-	mA	
Grid No.2 current	I_{g_2}	2.5	-	mA	
Transconductance	S	6.0	0.06	mA/V	
Internal resistance	R_i	0.6	>5	$M\Omega$	
Amplification factor	$^{\mu}$ g $_2$ g $_1$	26	-		
Equivalent noise resistance	R_{eq}	1.4	-	$k\Omega$	
Grid No.1 input resistance, f = 50 MHz	r_{g_1}	9	-	$k\Omega$	

Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	w_a	max.	2.5	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.65	W
Grid No.1 resistor	R_{g_1}	max.	3	$M\Omega$
Cathode current	I_k	max.	15	mA (
Heater to cathode voltage	$v_{\mathbf{k}\mathbf{f}}$	max.	150	V





A.F. PENTODE

Pentode intended for use as A.F. amplifier

QUICK REFERENCE DATA								
Anode current	Ia	3.0	mA					
Transconductance	S	2.2	mA/V					
Amplification factor	μ_{g2g1}	38	-					
Internal resistance	Ri	2.5	$\mathrm{M}\Omega$					

HEATING: Indirect by A.C. or D.C.; series or parallel supply

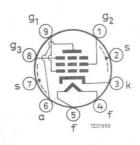
Heater voltage

Heater current

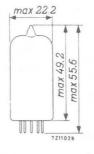
V_{f}	6.3	V
I_{f}	200	mA

DIMENSIONS AND CONNECTIONS

Base: Noval



Dimensions in mm



CAPACITANCES

Grid No.1 to all except anode Anode to all except grid No.1

Anode to grid No.1

Grid No.1 to heater

 $Cg_1(a)$

3.8 pF

 $C_{a(g_1)}$

5.1 pF

 C_{ag_1}

max.

0.05 pF

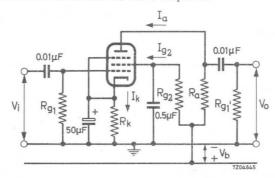
 C_{g_1f}

max. 0.0025 pF

TYPICAL CHARACTERISTICS

Anode voltage	v_a	250	V	
Grid No.3 voltage	v_{g_3}	0	V	
Grid No.2 voltage	v_{g_2}	140	V	
Grid No.1 voltage	v_{g_1}	-2.2	V	
Anode current	Ia	3.0	mA	
Grid No.2 current	I_{g_2}	0.6	mA	
Transconductance	S	2.2	mA/V	
Amplification factor	$\mu_{g_2g_1}$	38	-	
Internal resistance	R_i	2.5	$M\Omega$	

OPERATING CHARACTERISTICS as A.F. amplifier



Supply voltage	V_b	400	350	300	250	200	150	V	
Anode resistor	R_a	100	100	100	100	100	100	$k\Omega$	
Grid No.2 resistor	R_{g_2}	390	390	390	390	390	390	$k\Omega$	
Cathode resistor	R_k	1000	1000	1000	1000	1000	1000	Ω	
Grid resistor next stage	Rg1'	330	330	330	330	330	330	$k\Omega$	
Cathode current	$I_{\mathbf{k}}$	3.2	2.75	2.4	2.0	1.55	1.05	mA	
Voltage gain 1)	v_{o}/v_{i}	140	134	129	123	117	110	-	
Output voltage	V_{o}	85	74	62	50	38	27	v_{RMS}	
Total distortion	d _{tot}	5	5	5	5	5	5	%	

¹⁾ Measured at small input voltages

OPERATING CHARACTER	ISTICS	(conti	nued)					
Supply voltage	V _b	400	350	300	250	200	150	V
Anode resistor	~	220	220	220	220	220	220	kΩ
198 1 18 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	Ra				1	1	1	MΩ
Grid No.2 resistor	Rg ₂	2200	1 2200	1 2200	2200	2200	2200	Ω
Cathode resistor	Rk	680	680	680				
Grid resistor next stage	Rg'	1.45		1.1	680	680 0.75	680	kΩ mA
Cathode current	I _k		1.3		185	173	0.5 147	IIIA
Voltage gain 1)	V_0/V_i	210 72	205	194		35	22	17
Output voltage Total distortion	V _o	5	5	5	44	5	5	V _{RM}
As triode connected A.F.		ier (g ₂	connec	cted to	anode	, ga to	catho	di san
Supply voltage		V _b	400	350	300	250	200	v
Anode resistor		Ra	47	47	47	47	47	kΩ
Cathode resistor		Rk	1200	1200	1200	1200	1200	Ω
Grid resistor next stage		Rg'	150	150	150	150	150	kΩ
Anode current		I_a	3.6	3.15	2.7	2.25	1.8	mA
Voltage gain		V_0/V_i	26	25	25	25	24	_
Output voltage ($I_g = 0.3 \mu A$))	V_0	68	58	46	36	24	VRMS
Total distortion		d _{tot}	5	5	5	5	5	%
Supply voltage		V _b	400	350	300	250	200	V
Anode resistor		Ra	100	100	100	100	100	kΩ
Cathode resistor		Rk	2200	2200	2200	2200	2200	Ω
Grid resistor next stage		Rg'	330	330	330	330	330	kΩ
Anode current		I_a	2.0	1.8	1.5	1.25	1.0	mA
Voltage gain		V_0/V_i	28	28	27.5	27.5	27	_
Output voltage $(I_g = 0.3 \mu A)$)	V_{o}	75	63	51	42	30	VRMS
Total distortion		d _{tot}	5	5	5	5	5	%
Supply voltage		V _b	400	350	300	250	200	V
Anode resistor		Ra	220	220	220	220	220	$k\Omega$
Cathode resistor		R_k	3900	3900	3900	3900	3900	Ω
Grid resistor next stage		Rg ₁ '	680	680	680	680	680	$\mathbf{k}\Omega$
Anode current		Ia	1.1	0.95	0.8	0.7	0.55	mA
Voltage gain		v_o/v_i	29	29	29	28	28	-
Output voltage ($I_g = 0.3 \mu A$)		Vo	71	60	52	42	30	VRMS
Total distortion		d _{tot}	5	5	5	5	5	%

OPERATING CHARACTERISTICS (continued)

Microphonic effect

A sensitivity of 0.5 mV for an output of 50 mW (or 5 mV for an output of 5 W) is permissible in those equipments where an output of 50 mW in the loudspeaker does not produce an average acceleration on the tube higher than 0.015 g at any frequency higher than 500 Hz or higher than 0.06 g at any frequency lower than 500 Hz.

Hum level

The hum disturbance level will be $3\,\mu\mathrm{V}$ (max. $5\,\mu\mathrm{V}$) when $\mathrm{Z}\,\mathrm{g}_1$ is smaller than 0.5 M Ω at f = 50 Hz, the cathode resistor is decoupled by a capacitor of at least $100\,\mu\mathrm{F}$ and pin 4 is earthed. With the centre tap of the heater supply earthed this value will be $1\,\mu\mathrm{V}$ (max. $2\,\mu\mathrm{V}$).

Noise voltage

The equivalent noise voltage on g1 is approximately 2 μV for the frequency range from 25 to 10000 Hz at $V_{\rm b}$ = 250 V and R_a = 100 $k\Omega$.

Anode voltage		v_{a_o}	max.	550	V	
		v_a	max.	300	V	
Anode dissipation	on	w_a	max.	1.0	W	
Grid No.2 volta	ge	$V_{g_{2o}}$	max.	550	V	
		v_{g_2}	max.	200	V	
Grid No.2 dissi	pation	W_{g_2}	max.	0.2	W	
Grid No.1 circu	it resistor	-				
	if $W_a < 0.2 W$	R_{g_1}	max.	10	$M\Omega$	1
	if $W_a > 0.2 W$	R_{g_1}	max.	3	$M\Omega$	
with	grid current biasing	R_{g_1}	max.	22	$M\Omega$	
Cathode current		I_k	max.	6	mA	
Cathode to heate	er voltage					
	cathode positive	v_{kf}	max.	100	V	
	cathode negative	$V_{\mathbf{k}\mathbf{f}}$	max.	50	V	

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. or I.F. amplifier.

QUICK REFER	RENCE DATA		
Anode current	Ia	9	mA
Transconductance	S	4.0	mA/V
Amplification factor	$^{\mu}$ g $_2$ g $_1$	21	-
Internal resistance	R_i	750	$k\Omega$

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

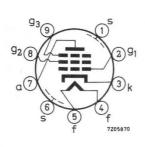
Heater current

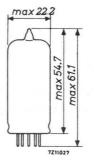
$V_{\mathbf{f}}$	6.3	V
$\overline{I_{\mathrm{f}}}$	200	mA

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Grid No.1 to heater

$C_{a}(g_{1})$	5.1	pF
$C_{g_1(a)}$	5.5	pF
C_{ag_1}	max. 0.002	pF
C_{g_1f}	0.05	pF

TYPICAL CHARACTERISTICS

Anode voltage	Va	250	250	170	V	
Grid No.2 voltage	v_{g_2}	100	85	100	V	
Grid No.3 voltage	v_{g_3}	0	0	0	V	
Anode current	I_a	9	9	12	mA	
Grid No.1 voltage	v_{g_1}	-2	-1.2 ¹)	-1.2 1) V	
Grid No.2 current	I_{g_2}	3	3.2	4.4	mA	
Transconductance	S	3.6	4.0	4.4	mA/V	
Internal resistance	$R_{\mathbf{i}}$	0.9	0.75	0.4	$M\Omega$	
Amplification factor	$\mu_{g_2g_1}$	-	21	-	-	

OPERATING CHARACTERISTICS

Anode voltage, supply voltage	$v_a = v_b$	2	50	20	00	V	
Grid No.3 voltage	v_{g_3}		0		0	V	
Grid No.2 resistor	R_{g_2}		51		24	$k\Omega$	
Cathode resistor	$R_{\mathbf{k}}$	1	60	13	30	Ω	
Grid No.1 voltage	v_{g_1}	-1.95	-20	-1.95	-20	V	
Anode current	I_a	9	- ,	11.1	-	mA	
Grid No.2 current	I_{g_2}	3	-	3.8	-	mA	
Transconductance	S	3.5	0.24	3.85	0.16	mA/V	
Internal resistance	R_{i}	0.9	115 ±	0.55	-	$M\Omega$	
Equivalent noise resistance	R_{eq}	4.2	-	4.2	-	$k\Omega$	
Input conductance (f = 50 MHz)	g	95	_	102	-	$\mu A/V$	1

 $^{^{1}}$) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.

OPER ATING	CHARACTERISTICS	(continued)	
ULEKATING	CHARACTERISTICS	(Continued)	,

Anode voltage, supply voltage	$v_a = v_b$	25	50 ¹)	20	01)	V
Grid No.3 voltage	V_{g_3}		0		0	V
Grid No.2 resistor	R_{g_2}	6	52	3	3	$k\Omega$
Cathode resistor	$R_{\mathbf{k}}$		0		0	Ω
Grid No.1 resistor	R_{g_1}]	10	1	0	$M\Omega$
Control voltage	$V_{R(g_1)}$	0	-20	0	-20	V
Anode current	Ia	9	-	11.25	-	mA
Grid No.2 current	I_{g_2}	2.9	-	3.9	-	mA
Transconductance	S	4.7	0.22	5.15	0.15	mA/V
Internal resistance	R_{i}	825	-	550	-	$k\Omega$
Equivalent noise resistance	Req	2.4	-	2.5	-	$\mathbf{k}\Omega$

Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	3 00	V	
Anode dissipation	w_a	max.	2.25	W	
Grid No.2 voltage	$v_{g_{2_0}}$	max.	550	V	
	v_{g_2}	max.	3 00	V	
Grid No.2 dissipation	W_{g_2}	max.	0.45	W	
Cathode current	$I_{\mathbf{k}}$	max.	16.5	mA	
Grid No.1 resistor	R_{g_1}	max.	3	$M\Omega$	
Grid No.3 resistor	R_{g_3}	max.	10	kΩ	
Cathode to heater voltage	v_{kf}	max.	100	V	

 $^{^{1}}$) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.

I.F. PENTODE

Pentode with variable transconductance intended for use as I.F. amplifier in television receivers.

QUICK REFER	ENCE DATA	- For 19
Anode current	I _a · 1	2 mA
Transconductance	S 12.	5 mA/V
Internal resistance	R _i 50	OkΩ

HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage

Heater current

v_{f}	6.3	V
If	300	mA

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval



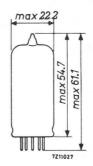
CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Grid No.1 to grid No.2



 $C_a(g_1)$

3 pF

 $C_{g_1(a)}$

9.5 pF

 C_{ag_1}

max. 0.005 pF

 $c_{g_1g_2}$

2.8 pF

TYPICAL.	CHARA	CTERISTICS

Anode voltage	v_a	200	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.2 voltage	v_{g_2}	90	V
Grid No.1 voltage	v_{g_1}	-2	V
Anode current	Ia	12	mA
Grid No.2 current	I_{g_2}	4.5	mA
Transconductance	S	12.5	mA/V
Internal resistance	R _i	500	$k\Omega$
<pre>Input resistance grid No.1 (f = 40 MHz)</pre>	r_{g_1}	13	kΩ
Equivalent noise resistance (f = 40 MHz)	Req	490	Ω

OPERATING CHARACTERISTICS

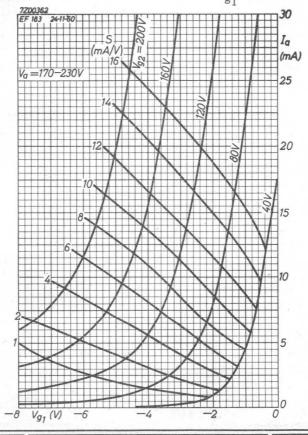
Anode voltage	v_a	1	70	200)	23	0	V	
Grid No.3 voltage	v_{g_3}		0	()		0	V	
Grid No.2 supply voltage	V_{bg_2}	1	70	200)	23	0	V	
Grid No.2 resistor	Rg_2		15	24	1	3	9	$k\Omega$	
Grid No.1 voltage	v_{g_1}	-1.8	-7.5	-2.0	-9.5	-2.1	-12	V	
Anode current	Ia	14	2.7	12	2.7	10.5	2.4	mA	
Transconductance	S	14	0.7	12.5	0.62	10.6	0.5	mA/V	

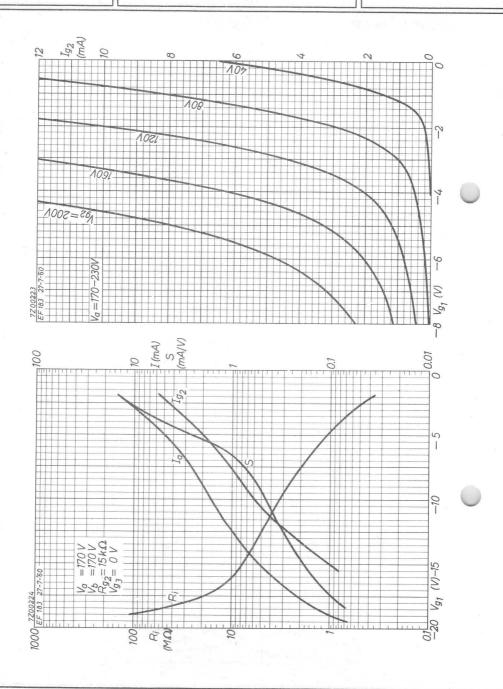
REMARK

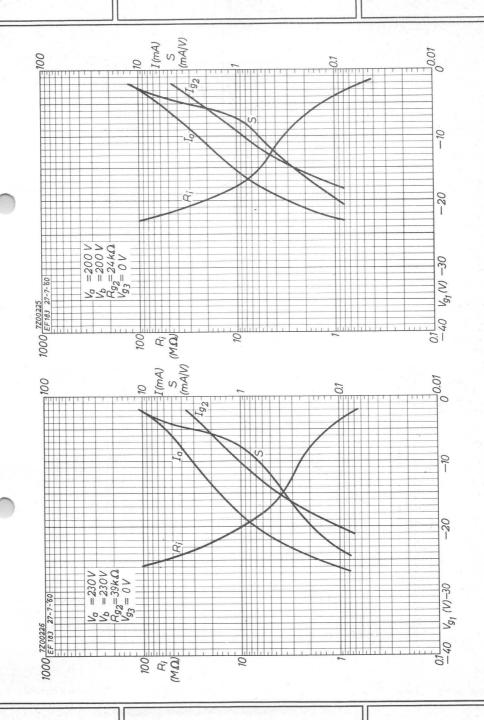
Operation with cathode bias resistor and/or screen grid resistor is recommended.

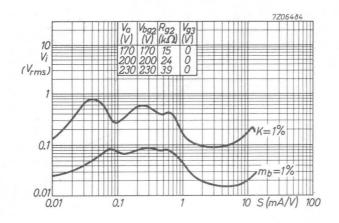
LIMITING	VALUES	Design	centre	ratino	system)
THINK THE	AVECTO	(DC21511	CCIICIC	Tattille	DV DCCIII)

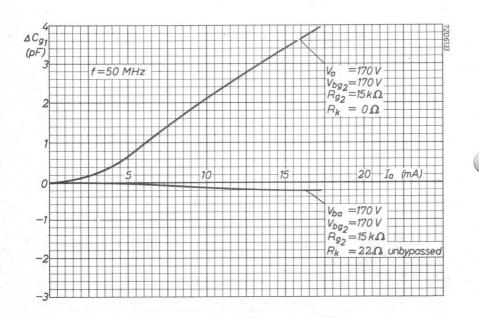
	Anode voltage	v_{a_0}	max.	550	V	
		v_a	max.	250	V	
	Anode dissipation	Wa	max.	2.5	W	
	Grid No.2 voltage	v_{g2_0}	max.	550	V	
		v_{g_2}	max.	250	V	
	Grid No.2 dissipation	W_{g_2}	max.	0.65	W	
	Grid No.1 voltage, negative peak	$-v_{g_{1p}}$	max.	50	V	
)	Cathode current	Ik	max.	20	mA	
	Cathode to heater voltage	v_{kf}	max.	150	V	
	Grid No.3 resistor	Rg3	max.	50	$\mathbf{k}\Omega$	
	Grid No.1 resistor	R_{g_1}	max.	1	$M\Omega$	

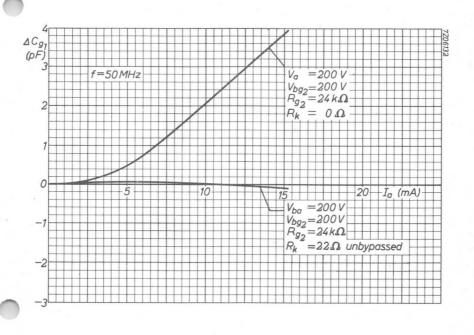


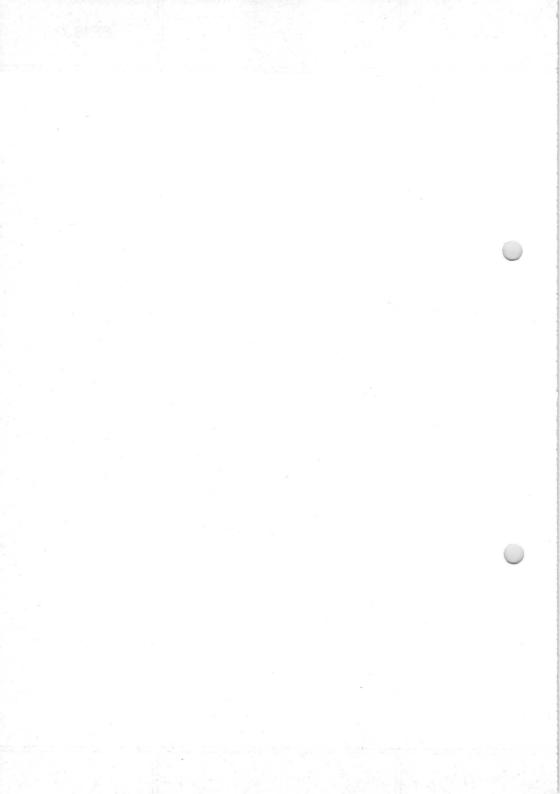












I.F. PENTODE

Pentode intended for use as I.F. amplifier in television receivers.

QUICK REFE	CRENCE DATA		
Anode current	Ia	10	mA
Transconductance	S	15	mA/V
Amplification factor	$\mu_{g_2g_1}$	60	_
Internal resistance	Ri	380	$k\Omega$

HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage

Heater current

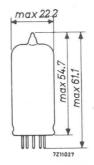
V_{f}	6.3 V		
$\overline{\mathrm{I}_{\mathrm{f}}}$	300	mA	

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Grid No.1 to grid No.2

 $C_{a(g_1)}$ 3 pF $C_{g_1(a)}$ 10 pF C_{ag_1} max. 0.0055 pF

 $C_{g_1g_2}$ 2.8 pF

TYPICAL CHARACTERISTICS

Anode voltage	Va	200	V
Grid No.3 voltage	v_{g_3}	0	V
Grid No.2 voltage	v_{g_2}	200	V
Grid No.1 voltage	v_{g_1}	-2.5	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g_2}	4.1	mA
Transconductance	S	15	mA/V
Internal resistance	Ri	380	kΩ
Amplification factor	$\mu_{g_2g_1}$	60	-
Input resistance grid No.1 (f = 40 MHz)	rg ₁	11	$k\Omega$
Equivalent noise resistance (f = $40~\mathrm{MHz}$)	Req	330	Ω

OPERATING CHARACTERISTICS

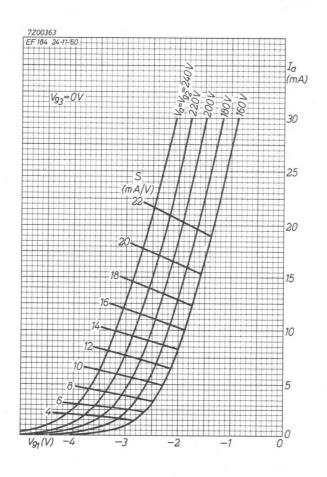
Anode supply coltage	V _{ba}	170	200	230	V
Grid No.3 voltage	v_{g_3}	0	0	0	V
Grid No.2 supply voltage	v_{bg_2}	170	200	230	V
Grid No.2 resistor	R_{g_2}	0	7.5	15	$k\Omega$
Cathode resistor	R_k	140	140	140	Ω
Anode current	Ia	10	10	10	mA
Grid No.2 current	I_{g_2}	4.1	4.1	4.1	mA
Transconductance	S	15.6	15.6	15.6	mA/V
Internal resistance	R_{i}	330	510	680	$k\Omega$
<pre>Input resistance grid No.1 f = 40 MHz</pre>	r_{g_1}	10	10	10	kΩ
Equivalent noise resistance f = 40 MHz	Req	300	300	300	Ω

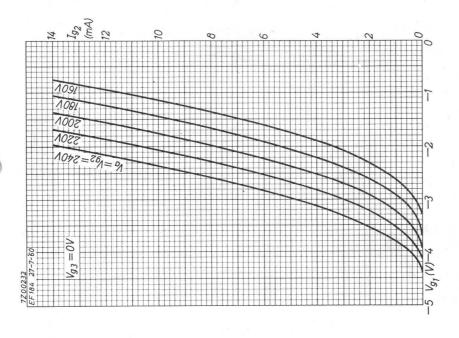
REMARKS

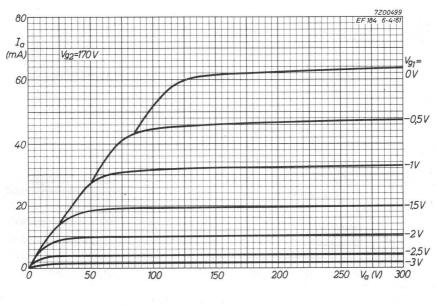
- 1. Operation with cathode bias resistor is recommended.
- In order to ensure a good performance with respect to cross-modulation and microphony this tube should not be used in circuits with automatic gain control. For such applications a tube with variable transconductance is recommended.

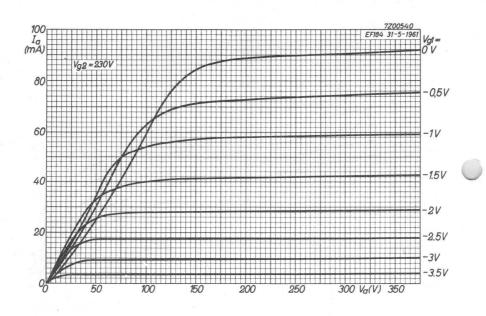
Anode voltage	V_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	Wa	max.	2.5	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.9	W^{1})
Grid No.1 voltage, negative peak	-Vg _{lp}	max.	50	V
Cathode current	Ik	max.	25	mA
Cathode to heater voltage	v_{kf}	max.	150	V
Grid No.1 resistor	R_{g_1}	max.	1	$M\Omega$

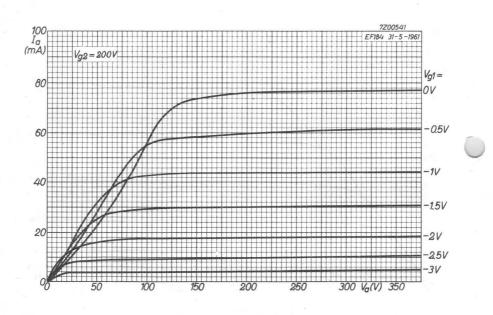
¹⁾ During a heating-up period not exceeding 15 seconds this value may be max. 1.5 W. At the values of ${\rm Rg}_2$ specified under "Operating characteristics" there will be no risk of exceeding the maximum permissible value of ${\rm Wg}_2$.











DOUBLE PENTODE

Double pentode intended for use as video output tube and as sync separator, A.G.C. amplifier or I.F. sound amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

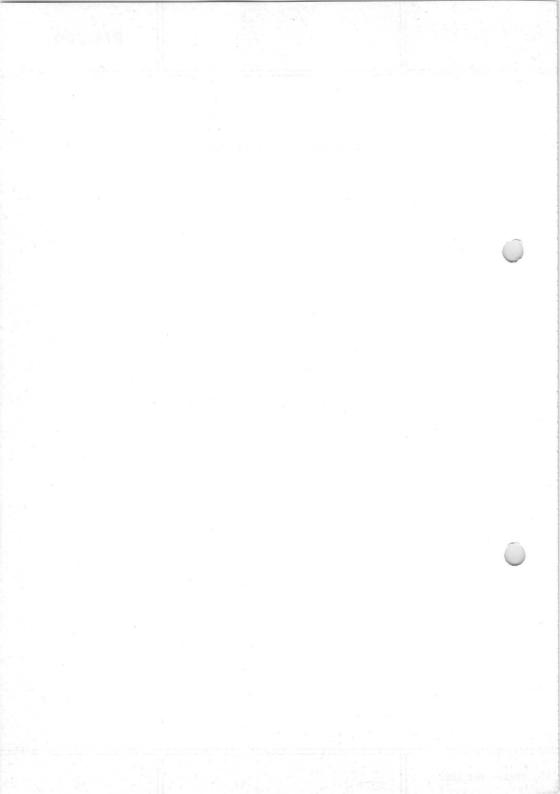
<u>V</u>f 6.3 V

810 mA

 I_f

Heater current

For further data and curves of this type please refer to type PFL200



A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFEI	RENCE DATA		
Anode current	Ia	100	mA
Transconductance	S	12.5	mA/V
Amplification factor	$\mu_{\mathbf{g_2g_1}}$	11	
Output power, class B		100	W

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

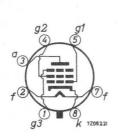
Heater current

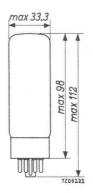
$V_{\mathbf{f}}$	6.3	V
I_f	1.5	Α

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Octal Socket: 5903/13



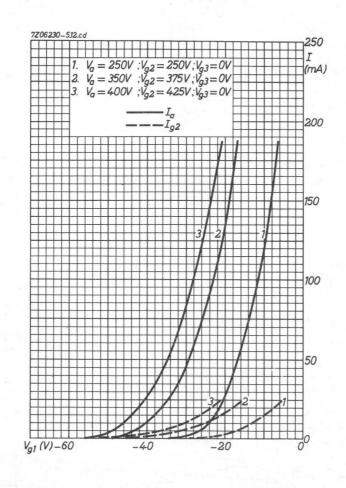


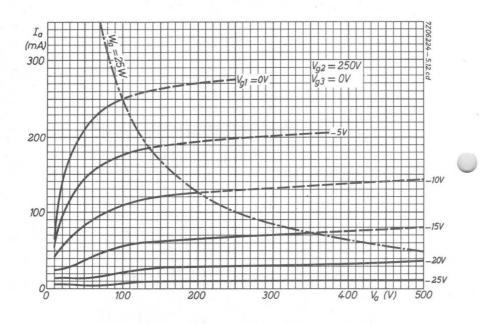
CAPACITANCES			
Anode to all except grid No.1	$C_{a(g_1)}$	8.4	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	15.2	pF
Anode to grid No.1	Cag ₁	max. 1.1	pF
Grid No.1 to heater	C_{g_1f}	max. 1.0	pF
Cathode to heater	Ckf	10	pF
OPERATING CHARACTERISTICS			
Class A			
Supply voltage	v_b	265 265	V
Anode voltage	v_a	250 250	V
Grid No.2 series resistor	R_{g_2}	2 0	$k\Omega$
Grid No.3 voltage	v_{g_3}	0 0	V
Grid No.1 voltage	v_{g_1}	-14.5 -13.5	V
Anode current	Ia	70 100	mA
Grid No.2 current	I_{g_2}	10 14.9	mA
Transconductance	S	11 12.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	11 11	
Internal resistance	Ri	20 17	$k\Omega$
Load resistance	$R_{a_{\infty}}$	3.0 2.0	kΩ
Grid No.1 driving voltage	$V_{\mathbf{i}}$	9.3 8.7	VRMS
Output power	W_{o}	8 11	W
Distortion	d_{tot}	10 10	%
Grid No.1 driving voltage for W _O = 50 mW	v _i	0.65 0.5	V _{RMS}

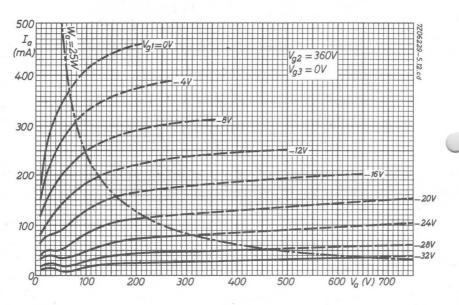
OPERATING CHARACT	TERISTIC	CS						
Class B, two tubes in push-pull								
Common grid No.2 series resistor (non decoupled)	R_{g_2}		1000			470		Ω
Grid No.1 voltage	v_{g_1}		-38			-32		V
Grid No.3 voltage	v_{g_3}		0			0		v
Grid No.1 driving voltage	Vi	0	27	27	0	22.7	22.7	V _{RM}
Load resistance	R _{aa} ~	-	3.4	4.0	_	2.8	3.8	kΩ
Supply voltage	V _b	425	425	400	375	375	350	V
Anode voltage	Va	420	400	375	370	350	325	V
Anode current	Ia	2x30	2x120	2x100	2x35	2x120	2x93	mA
Grid No.2 current	I_{g_2}	2x4.4	2x25	2x25	2x4.7	2x25	2x25	mA
Output power	Wo	0	55	45	0	44	36	W
Distortion	d _{tot}	***	5	6	-	5	6	%
Common grid No.2 series resistor	73		7.0		1	750		0
(non decoupled)	R_{g_2}		750			750		Ω
Grid No.1 voltage	v_{g_1}		-36			-39		V
Grid No.3 voltage	v_{g_3}		0			0		V
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0	25.8	25.8	0	23.4	23.4	V _{RM}
Load resistance	$R_{aa_{\sim}}$		4	5	-	11	11	$k\Omega$
Anode supply voltage	v_{ba}	500	500	475	800	800	750	V
Anode voltage	Va	495	475	450	795	775	725	V
Grid No.2 supply voltage	$v_{\rm bg_2}$	400	400	375	400	400	375	V
Anode current	Ia	2x30	2x125	2x102	2x25	2x91	2x84	mA
Grid No.2 current	I_{g_2}	2x4	2x25	2x25	2x3	2x19	2x19	mA
Output power	Wo	0	70	58	0	100	90	W
Distortion	dtot	-	5	6	-	5	6	- %

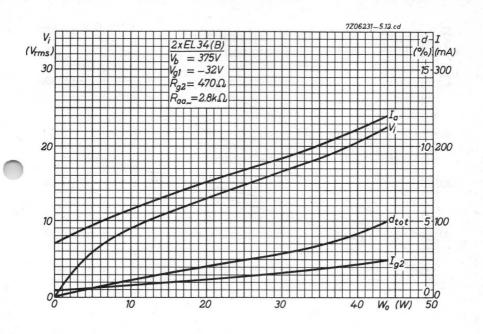
OPERATING CHARACTERISTICS

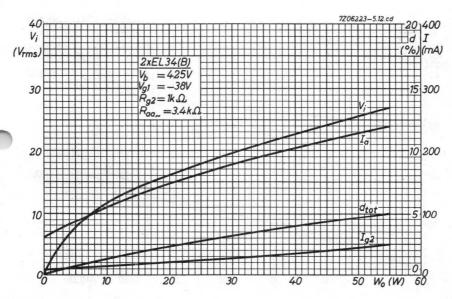
OPERATING CHARACTERISTICS						
Class AB, two tubes in push-pull						
Load resistance	R_{aa}		3.4		$k\Omega$	
Common grid No.2 series resistor (non decoupled)	R_{g_2}		470		Ω	
Common cathode resistor	R_k		130		Ω	
Grid No.3 voltage	v_{g_3}		0		V	
Grid No.1 driving voltage	v_i		0	21	v_{RMS}	
Supply voltage	v_b	37	5	375	V	
Anode to earth voltage	$v_a + v_{Rk}$	35	5	350	V	
Anode current	Ia	2x7	5	2x95	mA	
Grid No.2 current	I_{g_2}	2x11.	5 2	2x22.5	mA	
Output power	W_{O}		0	35	W	
Distortion	d_{tot}	-		5	%	
LIMITING VALUES (Design centre	rating sys	tem)				
Anode voltage		v_{a_0}	max.	2000	V	
		Va	max.	800	V	
Grid No.2 voltage		$v_{g_{2_0}}$	max.	800	V	
		v_{g_2}	max.	500	V	
Anode dissipation						
at $V_i = 0$		Wa	max.	25	W	
at $V_i > 0$		w_a	max.	27.5	W	
Grid No.2 dissipation		W_{g_2}	max.	. 8	W	
Cathode current		I _k	max.	150	mA	
Grid No.1 resistor						
for class A and AB		R_{g_1}	max.	0.7	$M\Omega$	
for class B		R_{g_1}	max.	0.5	. MΩ	
Cathode to heater voltage		v_{kf}	max.	100	V	

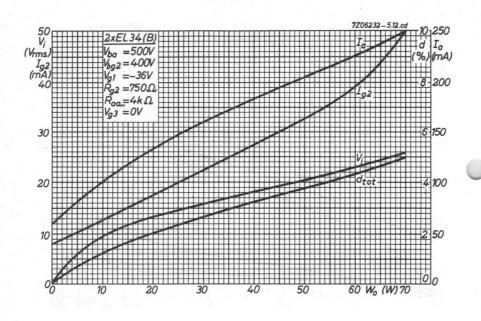


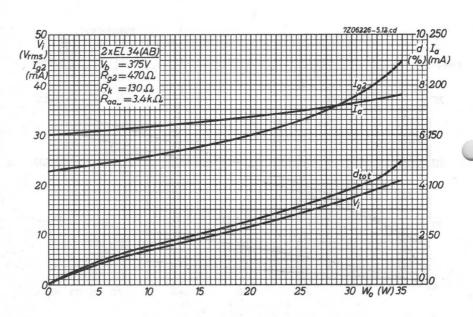












LINE AND A.F. OUTPUT PENTODE

Pentode intended for use as line output tube in television receivers and as A.F. power amplifier.

HEATING:	Indirectly	by A	C. c	or D.	C.;	parallel	supply
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Heater voltage	V_{f}	6.3	V
Heater current	$I_{\mathbf{f}}$	1.25	A

OPERATING CHARACTERISTICS

A.F. amplifier, Class B, two tubes in push pull

Anode voltage	v_a	300	V
Grid No.2 voltage	v_{g_2}	150	V
Grid No.1 voltage	v_{g_1}	-29	V
Load resistance	Raa∼	3.5	$k\Omega$
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0 20	V _{RMS}
Anode current	I_a	2x18 2x100	mA
Grid No.2 current	I_{g_2}	2x0.5 2x19	mA
Output power	W_{O}	0 44.5	W
Distortion	d_{tot}	- 7.2	%

LIMITING VALUES (Design centre rating system)

Anode voltage	v_a	max.	250	V
Anode voltage for class B operation	v_a	max.	300	V
Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	100	V

For further data and curves of this type please refer to PL36 $\,$

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OUTPUT PENTODE FOR LINE DEFLECTION AND A.F. OUTPUT PENTODE

Output pentode intended for use as horizontal deflection amplifier in small screen television receivers and as A.F. power amplifier.

QUICK REFERE	NCE DATA			
Anode peak voltage	V _{ap}	max.	7	kV
Cathode current	$I_{\mathbf{k}}$	max.	180	mA
Output power, class B two tubes	W_{O}		20	W

HEATING: Indirect by A.C. ot D.C.; parallel supply

Heater voltage

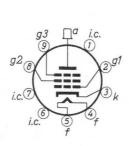
Heater current

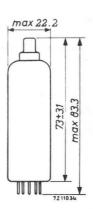
 $\frac{V_{\mathrm{f}}}{I_{\mathrm{f}}} \quad \frac{6.3}{1.05} \quad \frac{V}{A}$

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES					
Anode to all except grid No.1	$C_{a(g_1)}$		6	pF	
Grid No. 1 to all except anode	$C_{g_1(a)}$		14	pF	
Anode to grid No. 1	Cag1	max.	0.8	pF	
Anode to cathode	C_{ak}	max.	0.1	pF	
Grid No. 1 to heater	C_{g1f}	max.	0.2	pF	
TYPICAL CHARACTERISTICS					
A)					
Anode voltage	v_a		170	V	
Grid No. 3 voltage	V_{g_3}		0	V	
Grid No. 2 voltage	v_{g_2}		170	V	
Grid No. 1 voltage	v_{g_1}		-24	V	
Anode current	I_a		45	mA	
Grid No. 2 current	Ig2		2.4	mA	
Transconductance	S		6.3	mA/V	
Internal resistance	R_i		11	kΩ	
Amplification factor	$\mu_{g_2g_1}$		5.0		
B) (Measured under pulse conditions)					
Anode voltage	v_a		40	V	
Grid No. 3 voltage	v_{g_3}		0	V	
Grid No. 2 supply voltage	V_{bg2}		190	V	
Grid No. 2 series resistor	R _{g2}		4.7	$\mathbf{k}\Omega$	6
Grid No. 1 voltage	v_{g_1}		0	V	
Anode current	Ia		180	mA	
Grid No. 2 current	Ig2		18	mA	

OPERATING CONDITIONS

Stabilized circuits (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage (-V $_{g1}$) during flyback is 120 V at V $_{a}$ = 6000 V, V $_{g2}$ = 190 V, and Z $_{g1}$ = 1 k Ω at line-frequency.

Supply-voltage: See page 5

Minimum required value of the screengrid voltage and of the anode voltage, when the tube is used in a line output stage.

The graphs refer to nominal mains voltage provided the specified values of $\rm I_a$ at $\rm V_a$ min, will be available throughout life of the tube at supply voltage values 10% below nominal.

In order to prevent Barkhausen interferences and less of stabilisation, care should be taken that the anode voltage never drops below the specified V_a min during the scanning period.

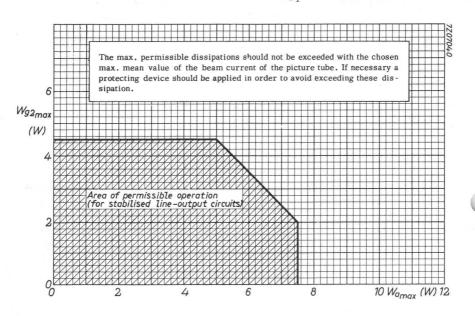
OPERATING CHARACTERISTICS as class B push-pull A.F. power amplifier, two tubes.

Anode voltage	V_a	1	70			200	V
Grid No. 3 voltage	V_{g3}		0			0	V
Grid No. 2 supply voltage	V _{bg} 2	1	70			200	V
Common Grid No. 2 series resistor	Rg2		1			1	kΩ
Grid No. 1 voltage	v_{g1}		27			31.5	V
Load resistance	$R_{aa} \sim$	2	. 5			2.5	kΩ
Grid No.1 driving voltage	v_i	0	16.5		0	21.5	V _{RMS}
Anode current	Ia	2x25	2x72		2x27	2x84	mA
Grid No. 2 current	Ig2	2x1.5	2x10		2x2.0	2x11.0	mA
Output power	Wo	0	13.0		0	20	W
Distortion	d _{tot}	- 1	5.2		,	6.5	%

January 1971

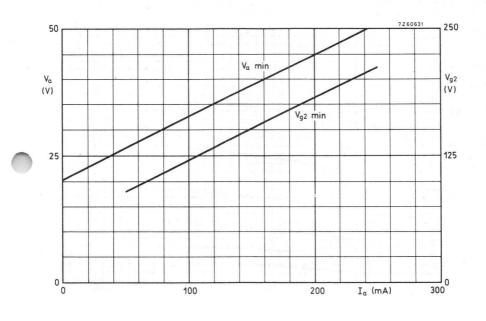
LIMITING VALUES (Design centre rating system)

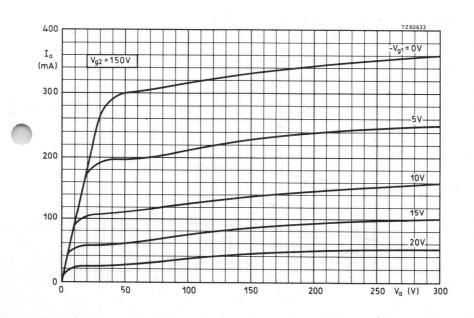
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 250	V
Anode voltage, peak	v_{a_p}	max. 7	kV^{1})
negative peak	-v _{ap}	max. 7	kV ¹)
Anode dissipation	Wa		
Grid No. 2 dissipation	W_{g2}^{2}	See figure below	
Anode + grid No.2 dissipation	$W_a + W_{g2}$		6
Grid No. 2 voltage	V_{g2}	max. 550	V
	v_{g_2}	max. 250	V
Cathode current	I_k	max. 180	mA
Cathode to heater voltage	v_{kf}	max. 100	V
Grid No. 1 resistor	R_{g_1}	max. 0.5	$M\Omega$

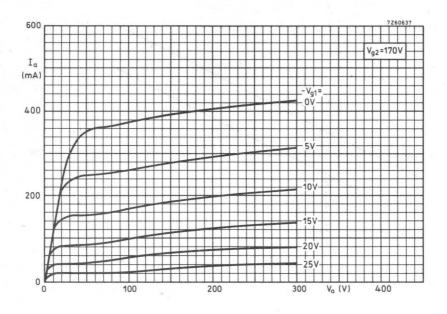


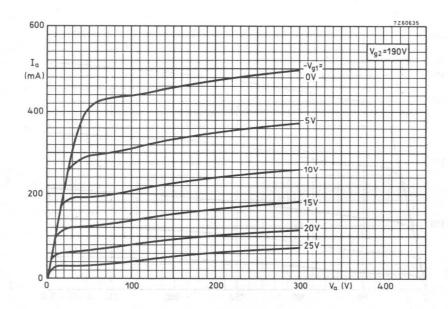
 $^{^{1})}$ Maximum pulse duration 22 % of a cycle but maximum 18 μs .

 $^{^2}$) During the heating-up of the cathode W_{g2} = max. 6 W.









A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

2.7	QUICK F	REFERENCE DAT	'A		
Anode current	70		Ia	48	mA
Transconductance			S	11.3	mA/V
Amplification factor			$\mu_{g_2g_1}$	19	
Output power			W_{O}	6.0	W

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

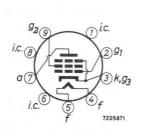
Heater current

 $\frac{V_f}{I_f}$ 6.3 V $\frac{V_f}{I_f}$ 760 mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

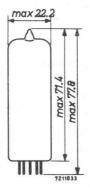
Base: Noval



CAPACITANCES

Anode to all except grid No.1 Grid No.1 to all except anode Anode to grid No.1

Grid No.1 to heater



$C_{a(g_1)}$	6.5	pF
$C_{g_1(a)}$	10.8	pF
C_{ag_1}	max. 0.5	pF
Cg_{1f}	max.0.25	pF

OFERATING CHARACTERISTI	CO							
Class A								
Anode voltage	Va			250			V	
Grid No.2 voltage	v_{g_2}			250			V	
Grid No.1 voltage	v_{g_1}		7	-7.3			V	
Cathode resistor	R _k			135			Ω	
Load resistance	$R_{a\sim}$			5.2			$k\Omega$	
Grid No.1 driving voltage	V_{i}	0	0.3	3.4	4.3	4.72)	VRMS	
Anode current	Ia	48	-	-	49.5	49.2	mA	1
Grid No.2 current	I_{g_2}	5.5	-		10.8	11.6	mA	
Transconductance	S	11.3	-	_	-	_	mA/V	
Amplification factor	$\mu_{g_2g_1}$	19	-	_	-	_		
Internal resistance	Ri	38	, , , -	-	-	~	kΩ	
Output power	W_0^{-1})	0	0.05	4.5	5.7	6.0	W	
Distortion, total	d _{tot} 1)	_	_	6.8	10	-	%	
second harmonic	d_2 1)	-	-	3.0	2.0	_	%	
third harmonic	d ₃ 1)	_	-	5.8	9.5	-	%	
Anode voltage	Va			250			V	
Grid No.2 voltage	v_{g_2}			250			V	
Grid No.1 voltage	v_{g_1}			-7.3			V	
Cathode resistor	R_k			135			Ω	
Load resistance	R _a ∼			4.5			kΩ	
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0	0.3	3.5	4.4	4.82	V_{RMS}	
Anode current	I_a	48	-	-	50.6	50.5	mA	
Grid No.2 current	I_{g_2}	5.5	-	4	10	11	mA	-
Transconductance	S	11.3	-	_	_	-	mA/V	
Amplification factor	$\mu_{g_2g_1}$	19	-	-	-	-		
Internal resistance	Ri	38	-	_	-	-	kΩ	
Output power	W_0^{-1})	0	0.05	4.5	5.7	6.0	W	
Distortion, total	d _{tot} 1)	_	-	7.5	10	7.	%	
second harmonic								
second narmonic	d_2 1)	-	-	5.7	5.0	ng - 7 p. n	%	

 $[\]overline{^{1})}$ Measured with fixed bias 2) At Ig $_{1}$ = +0.3 μA

Class A (continued) Anode voltage	V_a		25	50		V
Grid No.2 voltage			25			V
Grid No.1 voltage	v_{g_2}		-8.			V
Cathode resistor	v_{g_1}		21			Ω
Load resistance	R _a ~			7		$k\Omega$
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0	0.3	3.5	5.52	V _{RMS}
Anode current	I_a	36	-	36.8	36	mA
Grid No.2 current	I_{g_2}	4.1	; - ;	8.5	14.6	mA
Transconductance	S	10	-	-	_	mA/V
Amplification factor	$\mu_{g_2g_1}$	19	-	_	_	
Internal resistance	Ri	40	-	-	-	$k\Omega$
Output power	W_0^{-1})	0	0.05	4.2	5.6	W
Distortion, total	d_{tot}^{1})	-	-	10	_	%
second harmonic	d ₂ 1)	_	-	1.7		%
third harmonic	d ₃ 1)	_	-	8.7	-	%
Anode voltage	Va		25	50		V
Grid No.2 voltage	v_{g_2}		2	10		V
Grid No.1 voltage	v_{g_1}		-6	. 4		V
Cathode resistor	$R_{\mathbf{k}}$		10	50		Ω
Load resistance	R_{a}			7		kΩ
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0	0.3	3.4	3.82) V _{RM}
Anode current	I_a	36	-	36.6	36.5	mA
Grid No.2 current	I_{g_2}	3.9	-	7.3	8.0	mA
Transconductance	S	10.4	-	-	_	mA/
Amplification factor	$\mu_{ exttt{g2g1}}$	19	-	-	-	
Internal resistance	Ri	40	_	-	_	$k\Omega$
Output power	W_0^{-1})	0	0.05	4.3	4.7	W
Distortion, total	d_{tot}^{1})	-	-	10	_	%
	d_2 1)	_	-	1.8	_	%
second harmonic	d_2 d_3 d_3			1,0		%

¹⁾ Measured with fixed bias 2) At I_{g_1} = +0.3 μA

OPERATING CHARACTERIS	TICS (co	ontinued)	rangeli.	nwswi	à la		
Class B, two tubes in push-p	oull						
Anode voltage	Va	25	0	30	0	V	
Grid No.2 voltage	v_{g_2}	25	0	30	0	V	
Grid No.1 voltage	v_{g_1}	-11.	6	-14.	7	V	
Load resistance	R _{aa} ~		8		8	kΩ	
Grid No.1 driving voltage	v_i	0	8	0	10	v_{RMS}	
Anode current	I_a	2x10	2x37.5	2x7.5	2x46	mA	
Grid No.2 current	I_{g_2}	2x1.1	2x7.5	2x0.8	2x11	mA	1
Output power	W_{o}	0	11	0	17	W	
Distortion	d_{tot}	_	3	-, 2	4	%	
Class AB, two tubes in push	-pull						
Anode voltage	V_a	25	0	30	00	V	
Grid No.2 voltage	V_{g_2}	25	0	30	00	V	
Common cathode resistor	R_k	13	0	13	30	Ω	
Load resistance	R_{aa}		8		8	kΩ	
Grid No.1 driving voltage	V_{i}	0	8	0	10	V _{RMS}	
Anode current	I_a	2x31	2x37.5	2x36	2x46	mA	
Grid No.2 current	I_{g_2}	2x3.5	2x7.5	2x4	2x11	mA	
Output power	Wo	0	11	0	17	W	

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Distortion

OPERATING CHARACTERISTICS IN TRIODE CONNECTION (g2 connected to a)

	Class A									
	Anode voltage					Va		250		V
	Cathode resistor					$R_{\mathbf{k}}$		270		Ω
	Load resistance					$R_{a\sim}$		3.5		$k\Omega$
	Grid No.1 driving	oltage				V_i	0	1.0	6.7	VRMS
h	Anode current					I_a	34	_	36	mA
	Output power					W_{o}	-	0.05	1.95	W
	Distortion					d_{tot}	-	- 6	9	%
	Class AB, two tube	s in pu	sh-pu	11						
	Anode voltage	v_a			250			300		V
	Common cathode resistor	R_k			270			270		Ω
	Load resistance	R _{aa} ∼			10			10		$k\Omega$
	Grid No.1 driving voltage	v_i		0		8.3		0	10	v_{RMS}
	Anode current	Ia		2x20		2x21.7	$2x^2$	24	2x26	mA
	Output power	W_{o}		0		3.4		0	5.2	W
	Distortion	d_{tot}		-		2.5	-		2.5	%
	Grid No.1 driving voltage for									

0.95

 $W_0 = 50 \text{ mW}$ V_i

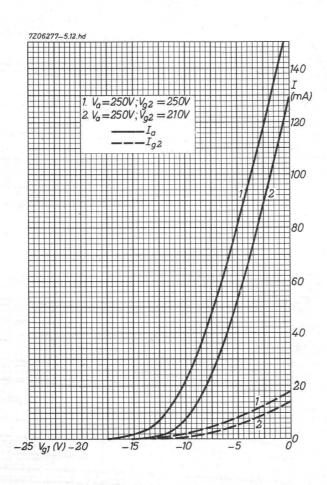
VRMS

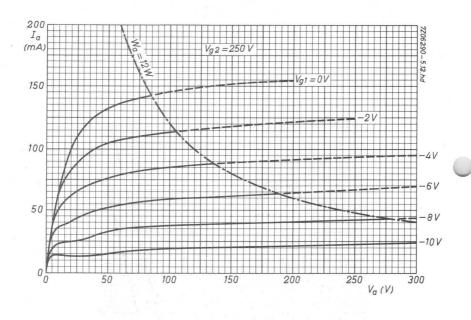
0.9

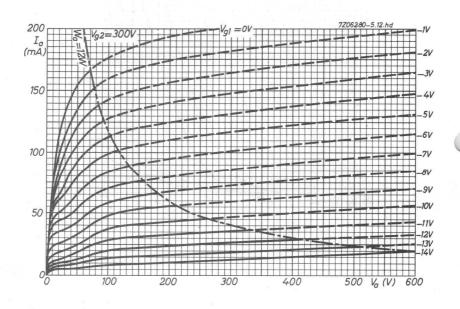
LIMITING V	ALUES (Design	centre	rating	system)
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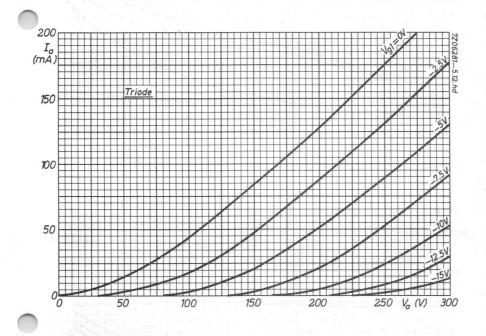
Anode v	voltage	v_{a_0}	max.	550	V	
		Va	max.	300	V 1)	
Anode o	dissipation	w_a	max.	12	W^1)	
Grid No	o.2 voltage	$v_{\rm g_{2o}}$	max.	550	V	
		v_{g_2}	max.	300	V 1)	
Grid No	o.2 dissipation	W_{g_2}	max.	2	W	
		$w_{g_{2p}}$	max.	4	W	
Grid No	o.l voltage	$-v_{g_1}$	max.	100	V	
Cathode current		I_k	max.	65	mA	
Grid No	o.l resistor					
for automatic bias		R_{g_1}	max.	, 1	$M\Omega$	
for fixed bias		R_{g_1}	max.	0.3	$M\Omega$	
Cathode to heater voltage		$v_{ m kf}$	max.	100	V	

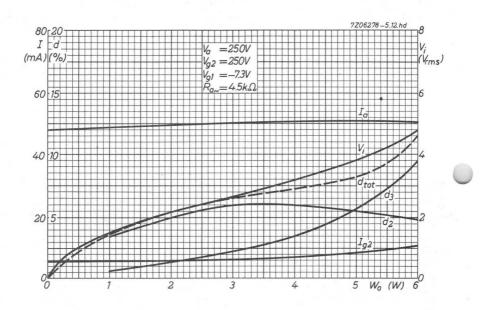
 $[\]overline{\mbox{1}})$ When the heater and positive voltages are obtained from a storage battery by means of a vibrator, the max. values of \mbox{V}_a and \mbox{V}_{g_2} are 250 V and that of \mbox{W}_a is 9 W.

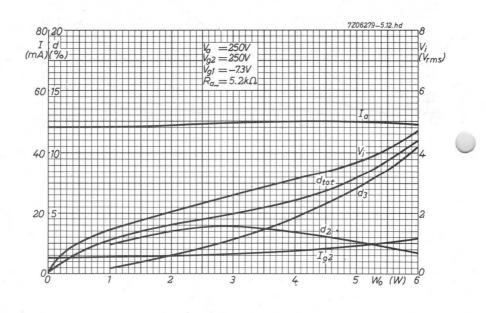


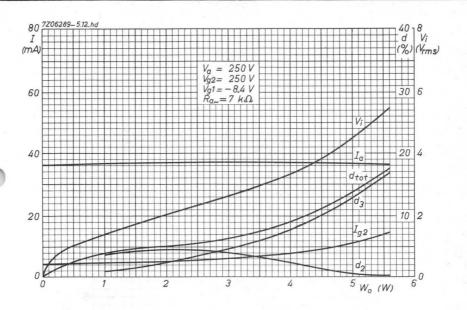


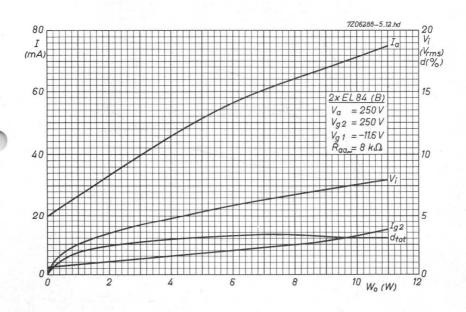




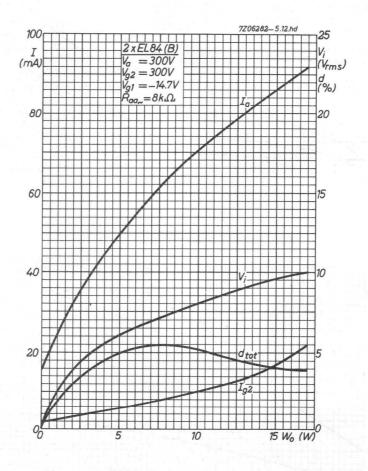


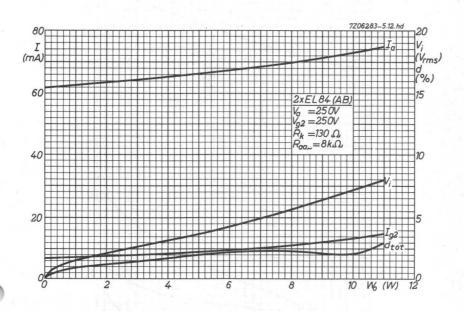


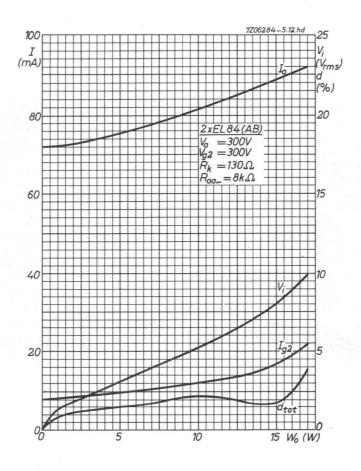




January 1969







FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as A.F. power amplifier.

QUICK REFERENCE DATA							
Anode peak voltage	V _{ap} n	nax.	2	kV			
Cathode current	I _k n	nax. 10	0	mA			
Output power	W_{o}	5.	3	W			

HEATING: Indirect by A.C. or D.C.; parallel supply

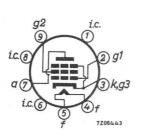
Heater voltage

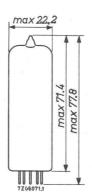
Heater current

 $\frac{V_{\mathbf{f}}}{I_{\mathbf{f}}} \quad \begin{array}{ccc} 6.3 & V \\ \hline 760 & \text{mA} \end{array}$

DIMENSIONS AND CONNECTIONS

Base: Noval





Dimensions in mm

CAPACITANCES

Anode to all except grid No.1 Grid No.1 to all except anode Anode to grid No.1

Grid No.1 to heater

 $C_{a(g_1)}$

6.8 pF

 $C_{g_1(a)}$

13 pF

 C_{ag_1}

max. 0.6 pF

 C_{g_1f}

max. 0.25 pF

OPTIMUM PEAK ANODE CURRENT IN FRAME OUTPUT OPERATION

The circuit should be designed so that the peak anode current does not exceed:

145 mA at
$$V_a$$
 = 60 V, V_{g_2} = 170 V, V_f = 6.3 V 190 mA at V_a = 70 V, V_{g_2} = 200 V, V_f = 6.3 V 220 mA at V_a = 80 V, V_{g_2} = 220 V, V_f = 6.3 V

The minimum available value of the peak anode current at end of life and $V_f = 5.7 \ \mathrm{V}$ is:

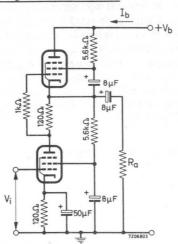
125 mA at
$$V_a$$
 = 60 V, V_{g_2} = 170 V
160 mA at V_a = 70 V, V_{g_2} = 200 V
185 mA at V_a = 80 V, V_{g_2} = 220 V

OPERATING CHARACTERISTICS

A.F. power amplifier, class A (Mea	sured with	V _k const	tant)			
Supply voltage	v_b		200		V	
Grid No.2 series resistor (non decoupled)	R_{g_2}		470		Ω	
Cathode resistor	$R_{\mathbf{k}}$		215		Ω	
Load resistance	R_{a} \sim		2.5		$k\Omega$	
Grid No.1 driving voltage	v_i	0	0.52	7.0	v_{RMS}	
Anode current	Ia	65	-	64	mA	
Grid No.2 current	I_{g_2}	3.2	-	11.4	mA	
Output power	Wo	0	0.05	5.3	W	
Distortion	d _{tot}	-	-	10	%	
A.F. power amplifier, class AB, two	tubes in pus	h-pull				
Anode supply voltage	V _{ba}		250		V	
Grid No.2 supply voltage	V_{bg_2}		200		V	
Common cathode resistor	$R_{\mathbf{k}}$		150		Ω	
Load resistance	Raa ~		5.5		$k\Omega$	
Grid No.1 driving voltage	v_i	0	0.37	13.0	VRMS	
Anode current	Ia	2x50		2x55	mA	
Grid No.2 current	I_{g_2}	2x2.0	-	2x13	mA	
Output power	Wo	0	0.05	18.5	W	
Distortion	d_{tot}	-	-	4.5	%	

OPERATING CHARACTERISTICS (continued)

A.F. power amplifier, single ended push-pull



a) Single tone input signal

Supply voltage	Vb		300		V	
Load resistance	$R_{a\sim}$		1		$k\Omega$	
Grid No.1 driving voltage	v_i	0	0.41	5.4	v_{RMS}	
Supply current	I_b	66	-	64	mA	
Output power	W_{o}	0	0.05	4.5	W	
Distortion	d_{tot}	-	- 1	9.3	%	
b) Double tone input signal						
Supply voltage	V_{b}		300		V	
Load resistance	$R_{a_{\sim}}$	_	1		kΩ	
Grid No.1 driving voltage	v_i	0		2.7	V_{RMS}^{1})	
Supply current	I_b	66		64	mA	
Output power	W_{o}	0		5.5	W	
Distortion	d_{tot}	-		8.5	%	

¹⁾ Value of each tone separately.

REMARK

Single tone data are obtained with a pure sinusoidal input voltage. However such an input voltage is in general not representative for the reproduction of music and speech, since a purely sinusoidal tone seldom occurs.

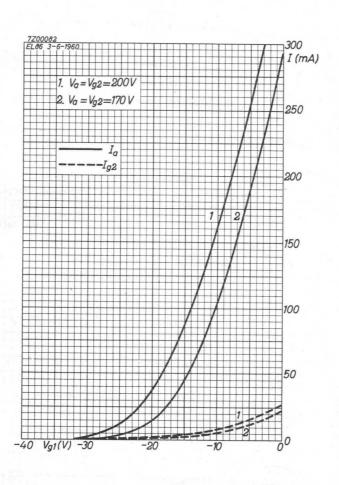
The double tone data are obtained with two sinusoidal signals of different frequencies but of the same amplitude. This appears to be far better in agreement with practice. In the case of full drive with two sinusoidal signals different in frequency but having the same amplitude, the output power is half the value obtained at full drive with a single sinusoidal input voltage of twice this amplitude. To make comparison possible the obtained output power with double tone has therefore been multiplied by 2.

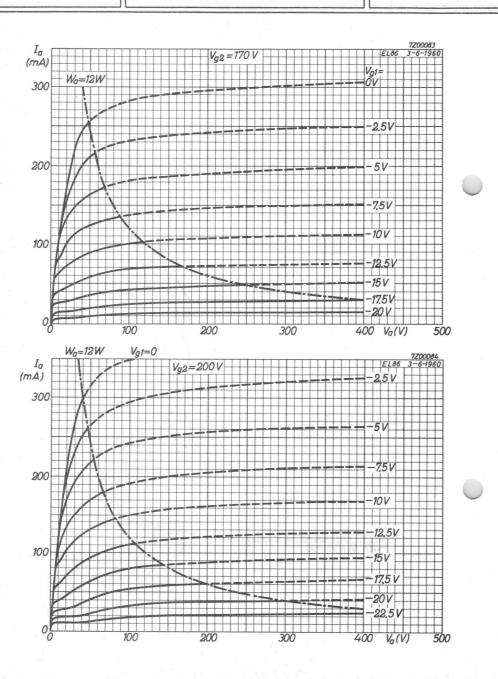
LIMITING VALUES (Design centre rating system)

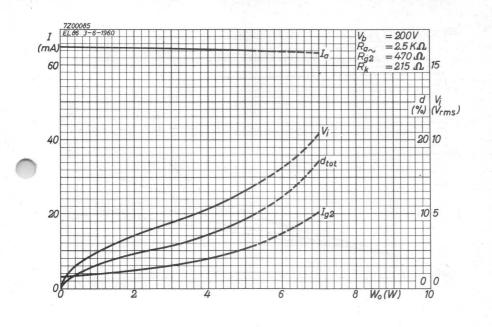
Anode voltage	V_{a_0}	max.	550	V
	v_a	max.	250	V
Anode peak voltage	v_{a_p}	max.	2	kV^{1})
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	12	W^2)
Grid No.2 dissipation:				
average	w_{g_2}	max.	1.75	W
peak	$W_{g_{2p}}$	max.	6	W
Cathode current	I_k	max.	100	mA
Grid No.1 resistor:				
automatic bias	R_{g_1}	max.	1	$M\Omega$
frame output application				
with automatic bias	R_{g_1}	max.	2	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	200	V

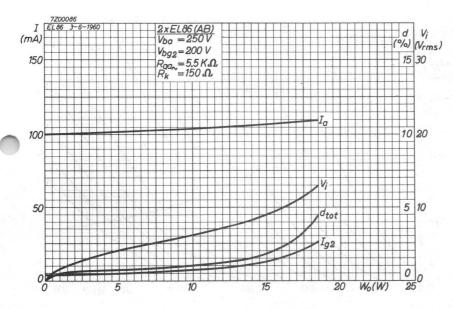
 $^{^1)}$ Valid for application in frame output circuits where the max. pulse duration is 4% of a cycle with a max. of 0.8 ms.

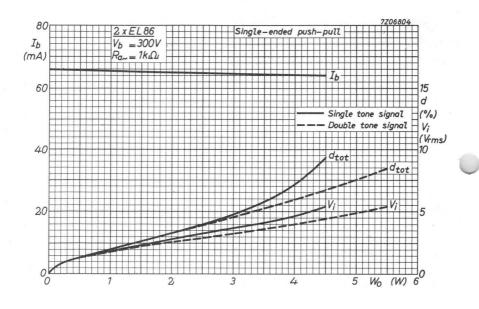
 $^{^2}$) For frame output application W_a = max. 10 W.

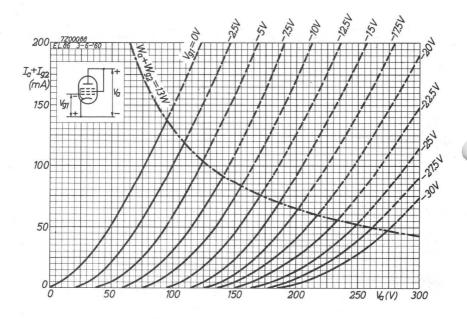












A.F. OUTPUT PENTODE

HEATING: Indirect by A.C. or D.C.; parallel supply Heater voltage V_f 6.3 V Heater current I_f 200 mA LIMITING VALUES (Design centre rating system) Cathode to heater voltage V_{kf} max. 100 V

Pentode intended for use as A.F. power amplifier:

For further data and curves of this type please refer to type PL95

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LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

6.3 V 1.38

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage

DC + peak, k positive

 V_{kf}

max. 200 V

k negative

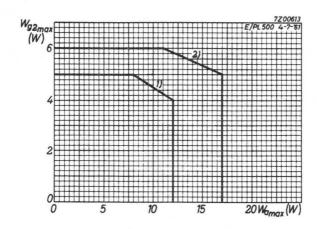
 $-V_{kf}$

max. 200 V^{3})

Anode dissipation

Grid No. 2 dissipation

See graph below



1) Design centre limits for W_a and W_{g_2} . 2) These limits for W_a and W_{g_2} should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.

3) D.C. component max. 100 V.

For further data and curves of this type please refer to type PL 504

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A.F. OUTPUT PENTODE

Beam pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA					
Anode current	Ia	110	mA		
Transconductance	S	23	mA/V		
Amplification factor	$^{\mu}$ g $_2$ g $_1$	13			
Output power (class AB)	W_{o}	40	W		

HEATING: Indirect by A.C. or D.C.; parallel supply

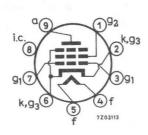
Heater voltage

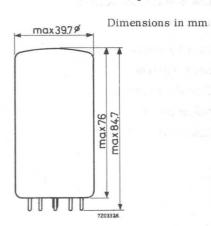
Heater current

 $\frac{V_{f}}{I_{f}} = \frac{6.3 \text{ V}}{1.05 \text{ A}}$

DIMENSIONS AND CONNECTIONS

Base: Magnoval





CAPACITANCES

Anode to all except grid No.1 Grid No.1 to all except anode Anode to grid No.1 Grid No.1 to heater $\begin{array}{cccc} C_{a}(g_{1}) & 13.5 & pF \\ C_{g_{1}}(a) & 22.5 & pF \\ C_{ag_{1}} & 1.7 & pF \\ C_{g_{1}f} & 0.325 & pF \end{array}$

EL503

TYPICAL CHARACTERISTICS					
Anode voltage	v_a		250	V	
Grid No.2 voltage	v_{g_2}		250	V	
Grid No.1 voltage	v_{g_1}		14.0	V	
Anode current	Ia		110	mA	
Grid No.2 current	I_{g_2}		7.0	mA	
Transconductance	S		23	mA/V	
Amplification factor	$^{\mu}\mathrm{g}_{2}\mathrm{g}_{1}$		13		é
Internal resistance	R_i		5.4	$k\Omega$	
OPERATING CHARACTERISTICS Class AB, two tubes in push-pull					
Anode supply voltage	V_{ba}	26	5	V	
Grid No.2 supply voltage	$v_{ m bg_2}$	26	5	V	
Common cathode resistor	$R_{\mathbf{k}}$	5	6	Ω	
Load resistance	R_{aa}	2.	4	$k\Omega$	
Grid No.1 driving voltage	v_i	0	12.2	v_{RMS}	
Anode current	Ia	2x115	2x125	mA	
Grid No.2 current	I_{g_2}	2x7.5	2x35.0	mA.	
Output power	Wo	0	40	W	

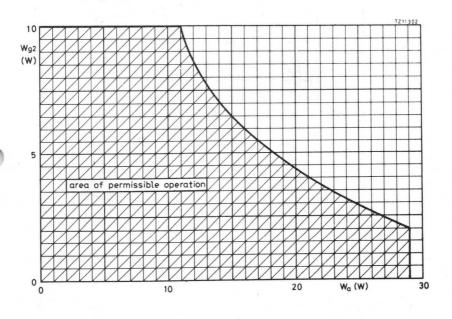
 d_{tot}

Distortion

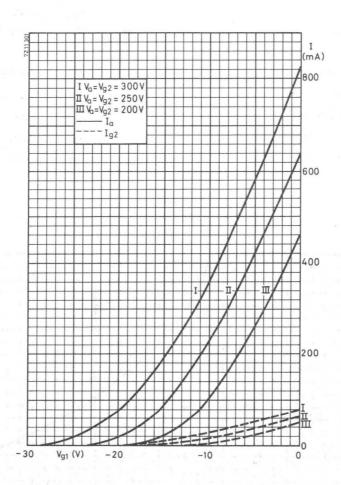
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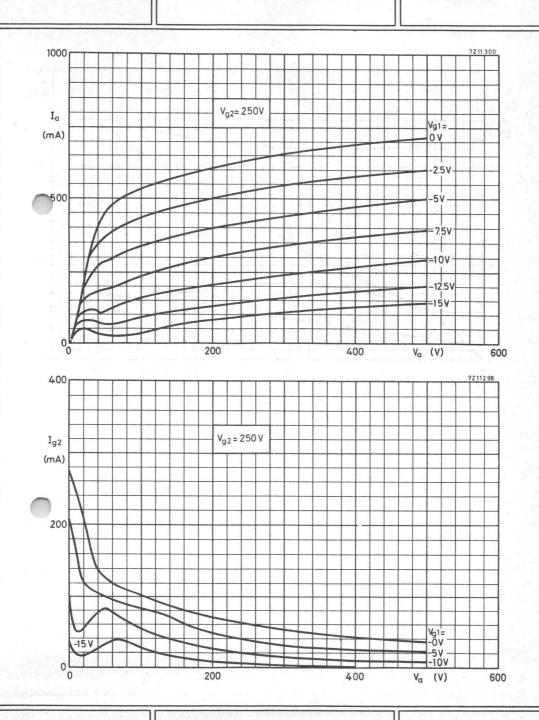
Vkf max. 100 V

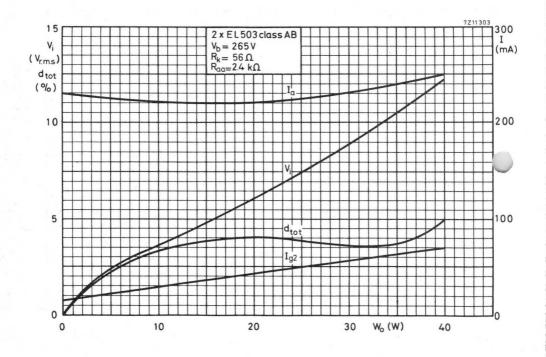
	LIMITING VALUES (Design centre rating system)			
	Anode voltage	v_{a_0}	max. 550	V
		v_a	max. 300	V
	Grid No.2 voltage	$v_{g_{2o}}$	max. 550	V
		v_{g_2}	max. 300	V
	Anode dissipation	w_a	see below	
	Grid No.2 dissipation			
6	average	w_{g_2}	see below	
,	peak	$w_{g_{2p}}$	see below	
	Cathode current	Ik	max. 200	mA
	Grid No.1 resistor, automatic bias	R_{g_1}	max. 0.5	$M\Omega$



Cathode to heater voltage







LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_{f}}{I_{f}} \qquad \frac{6.3 \quad V}{1.38 \quad A}$

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive

 V_{kf}

max. 200 V

k negative

 $-V_{kf}$

 200 V^{1}

For further data and curves of this type please refer to type PL 504

¹⁾ DC component max. 100 V.

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FRAME OUTPUT PENTODE

Pentode intended for use as frame output amplifier in colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

 $\frac{V_f}{I_f} = \frac{6.3 \text{ V}}{825 \text{ mA}}$

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage

Vkf max. 100 V

For further data of this type please refer to type PL508 $\,$

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LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater voltage

 $\frac{V_f}{I_f}$ 6.3 V

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive

 V_{kf}

max. 200 V

k negative

 $-V_{kf}$

max. $200 V^{1}$)

For further data and curves of this type please refer to type PL 509

¹⁾ DC component max. 100 V.

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LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater voltage

6.3 V_f

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive

Vkf

max. 200

k negative

 $-V_{kf}$

max. 200 V 1)

For further data and curves of this type please refer to type PL519

¹⁾ DC component max. 100 V.

VIDEO OUTPUT PENTODE

Luminance output tube in colour TV receivers

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage

Vkf max. 100 V

For further data of this type please refer to type PL802

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TUNING INDICATOR

Indicator tube with triode amplifier intended for use as tuning indicator or for modulation control.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

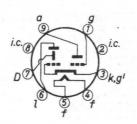
v_f	6.3	V
$I_{\mathbf{f}}$	210	mA

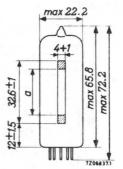
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval







The arrow near pin 7 indicates the viewing direction.

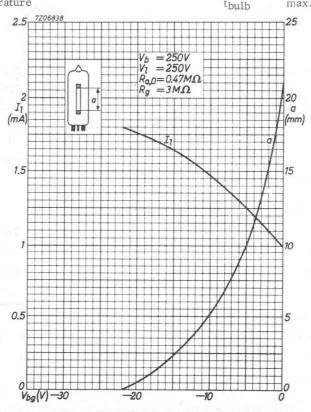
OPERATING CHARACTERISTICS (D connected to a)

Supply voltage		v_b	25	60	v	
Luminescent screen vol	tage	V_{ℓ}	250 470		V	
Anode and deflection ele	ectrode resistor	Ra, D			kΩ	
Grid resistor		R_g		3	МΩ	
Grid supply voltage		V_{bg}	0	-22	V	
Anode and deflection ele	ectrode current	I_{a+D}	0.45	0.06	mA	
Luminescent screen cur	rrent	Iq	1.0	1.8	mA	
Shadow length		a	21±5	0	mm	

EM84

LIMITING VALUES (Design centre rating system)

Anode voltage	v_{a_0}	max.5	50	V	
	v_a	max. 3	00	V	
Anode dissipation	Wa	max. 0	.5	W	
Deflection electrode voltage	v_{D_0}	max. 5	50	V	
	v_D	max. 3	00	V	
Luminescent screen voltage	V _L o	max. 5	50	V	
	V_{ℓ}	max. 3	00	V	
	V_{ℓ}	min. 1	70	V	
Cathode current	I_k	max.	3	mA	
Grid resistor	R_g	max.	3	$M\Omega$	
Cathode to heater voltage	V _{kf}	max. 1	00	V	
Bulb temperature	thulb	max. 1	20	°C	



TUNING INDICATOR

Tuning indicator tube.

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage

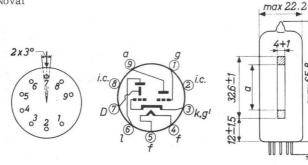
Heater current

v_{f}	6.3	V
If	300	m.A

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval



The arrow near pin 7 indicates the viewing direction.

OPERATING CHARACTERISTICS (D connected to a)

	Supply voltage	v_b		250		V
	Luminescent screen voltage	V_{ℓ}		250		V
	Anode and deflection electrode resistor	R _{a,D}		100		$k\Omega$
)	Grid resistor	R_g		3		$M\Omega$
	Grid supply voltage	V_{bg}	0	-10	-15	V
	Anode and deflection electrode current	I_{a+D}	2.0	0.5	0.2	mA
	Luminescent screen current	I_{ℓ}	1.0	1.8	2.0	mA
	Shadow length	а	21	0	-1.5	mm^1)

¹⁾ A negative value of "a" means overlapping:

The grid bias for a = 0 is reduced by decreasing V_{ℓ} .

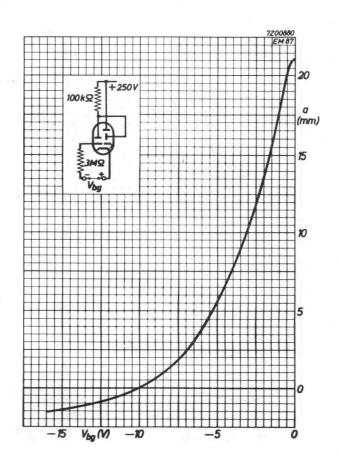
The measure of overlapping at V_g = -15 V will then increase (see page 4).

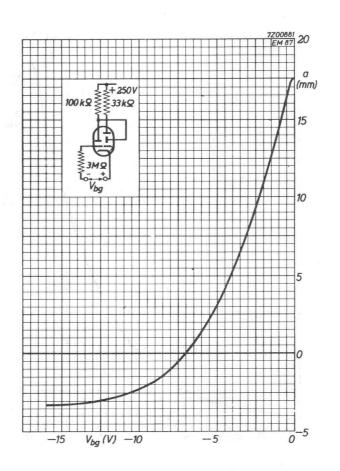
EM87

Bulb temperature

LIMITING VALUES (Design centre rating s	system)			
Anode voltage	v_{a_0}	max. 550	V	
	v_a	max. 300	V	
Anode dissipation	Wa	max. 0.6	W	
Deflection electrode voltage	v_{D_0}	max. 550	V	
	v_D	max. 300	V	
Luminescent screen voltage	$v_{\ell_{O}}$	max. 550	V	
	v_{ℓ}	max. 300	V	ĺ
	V_{ℓ}	min. 170	V	-
Grid resistor	$R_{\mathbf{g}}$	max. 3	$M\Omega$	
Cathode current	I_k	max. 5	mA	
Cathode to heater voltage	v_{kf}	max. 250	V	

t_{bulb} max. 120 °C





BOOSTER DIODE

Booster diode intended for use in line time-base circuits of television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater current

Heater voltage

V_{f}	6.3	V
I_f	810	mA

For further data and curves please refer to type PY81

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BOOSTER DIODE

Booster diode intended for use in line time base circuits of television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

v_f	6.3	V
I_f	1.55	A

For further data and curves of this type please refer to type PY88

BOOSTER DIODE

Booster diode intended for use in time base circuits of colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

V_{f}	6.3	V
$I_{\mathbf{f}}$	2.1	Α

For further data and curves of this type please refer to type PY500

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BOOSTER DIODE

Booster diode intended for use in time base circuits of colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

Heater current

<u>V</u> f	6.3	V
I_{f}	2.1	A

For further data and curves of this type please refer to type PY500A

August 1970

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DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube

QUIC	CK REFERENCE DATA			
Transformer voltage	v_t	r 2x	350	V _{RMS}
D.C. current	Io		90	mA

HEATING: Indirect by A.C.; parallel supply

Heater voltage

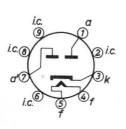
Heater current

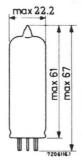
V_{f}	6.3	V
$\overline{I_{f}}$	600	mA

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





$\begin{cal}OPERATING\ CHARACTERISTICS\ as\ two-phase\ half-wave\ rectifier\end{cal}$

Transformer voltage	v_{tr}	2x250.	2x275	2x300	2x350	v_{RMS}
D.C. output voltage	V_{o}	260	285	310	360	V
D.C. current	Io	90	90	90	90	mA
Protecting resistance	R_t	2x125	2x175	2x215	2x300	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μF

December 1969

LIMITING VALUES (Design centre rating system)

Transformer voltage	v_{tr}		max.	2x350	v_{RN}	AS.		
D.C. current	Io		max.	90	mA			
Cathode to heater voltage, peak, k pos	v_{kf_p}		max.	500	v			
Input capacitor of smoothing filter	C_{filt}		max.	50	μF			
Protecting resistance at transformer voltage	R _t min. V _{tr}	2x125			215 300	2x300 2x350	$_{V_{RMS}}^{\Omega}$	

DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube.

QUICK REFE	ERENCE DATA		
Transformer voltage	V _{tr}	2x450	VRMS
D.C. current	I_{O}	100 -	mA

HEATING: Indirect by A.C.; parallel supply

Heater voltage

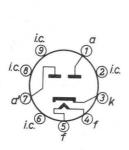
Heater current

V_{f}	6.3	V
I_{f}	1	A

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





OPERATING CHARACTERISTICS

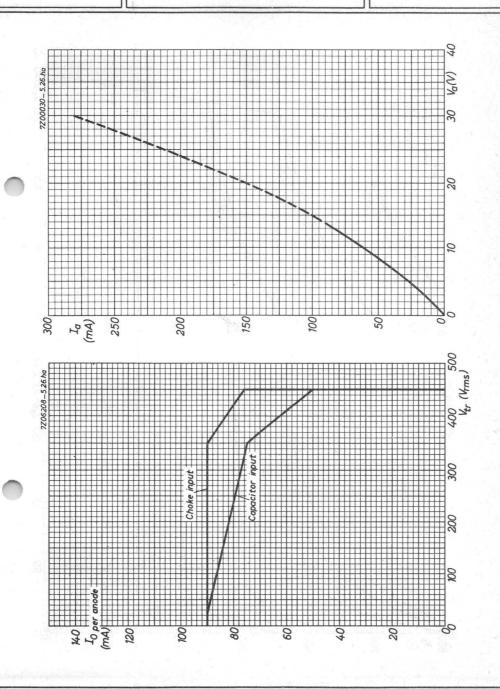
As two-phase half-wave rectifier	with capacitor input filter	See page 4 upper fig.
----------------------------------	-----------------------------	-----------------------

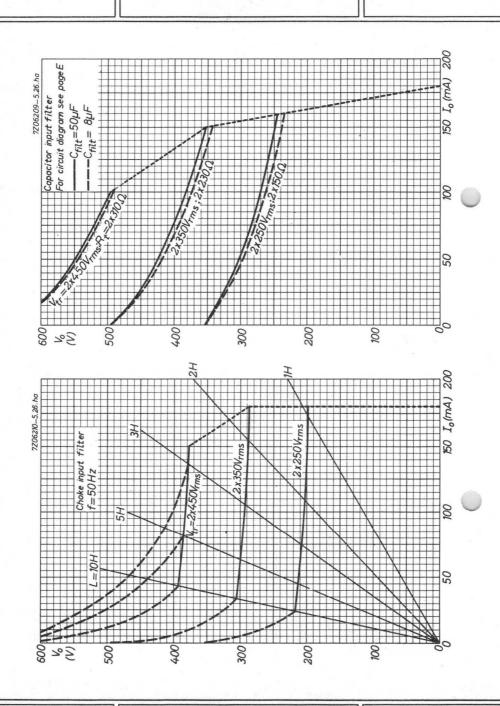
Transformer voltage	Vtr	2x250	2x350	2 x 450	VRMS
D.C. output voltage	Vo	245	352	497	V
D.C. current	I_{o}	160	150	100	mA
Protecting resistance	R _t	2x150	2x230	2x310	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	μ F

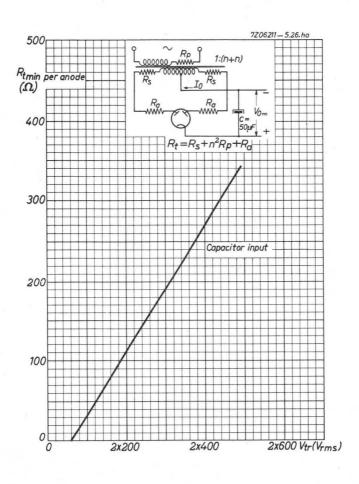
As two-phase half-wave rectifi	ier with choke i	nput filter	See	page 4	lower fi
Transformer voltage	v_{tr}	2x250	2x350	2x450	v_{RMS}
D.C. output voltage	V_{o}	199	288	378	V
D.C. current	Io	180	180	150	mA
Choke	L	10	10	10	Н

LIMITING VALUES (Design centre rating system)

Anode voltage, peak inverse	$v_{a_{inv_p}}$	max.	1300	V	
D.C. current	I_{O}	See pa	ge 3		
Transformer voltage	v_{tr}	lower figure			
Anode current, peak	I_{a_p}	max.	500	mA	
surge	I _{asurge}	max.	1.8	A	
Cathode to heater voltage, k pos	v_{kf}	max.	500	V	
Input capacitor of smoothing filter	c_{filt}	max.	50	μ F	
Protecting resistance	R _{t min.}	See pa	age 5		
Choke	L min.	See page 4 lower fi		ig.	







SINGLE ANODE E.H.T. RECTIFYING TUBE

Single anode E.H.T. rectifying tube intended for use in colour television receivers.

The GY501 has a chemically treated envelope to avoid flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

QUICK REFERE	ENCE DATA		
D.C. output voltage	v _o	25	kV
Anode current	I_a	1.5	mA

HEATING: Indirect by A.C. or D.C.; parallel supply

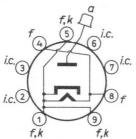
Heater voltage

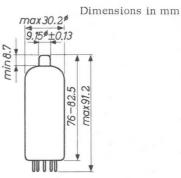
Heater current

 $\frac{V_f}{I_f}$ 3.15 $\frac{V}{V}$ 1)

DIMENSIONS AND CONNECTIONS

Base: Magnoval





Pins 1, 5 and 9 may be used to connect an anti-corona ring.

Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.

<u>Precaution:</u> X-ray shielding may be required to give protection against excessive radiation.

 $^{^1)}$ Under nominal operating conditions and with the longterm average value of $\rm I_a$ to be expected in practice, $\rm V_{f\,RMS}$ should be 3.15 V.

The heater voltage deviation resulting from spread or variation of operating conditions should be limited to the values indicated by the diagram in fig.A.

GY501

CAPACITANCES

Anode to cathode C_{ak} 1.2 pF

OPERATING CHARACTERISTICS

Output voltage $V_{\rm O}$ 25 kV Anode current $I_{\rm a}$ 1.5 mA

LIMITING VALUES (Design centre rating system)

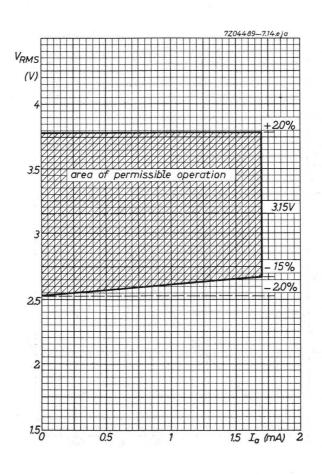
Peak inverse vol	ltage (absolute max.)	V_{ainv_p}	max.	35	kV 1)
Output voltage	(absolute max.)	V_{o}	max.	27.5	kV
Output current,	average	I_{O}	max.	1.7	mA
	peak	I_{op}	max.	100	mA^{2})

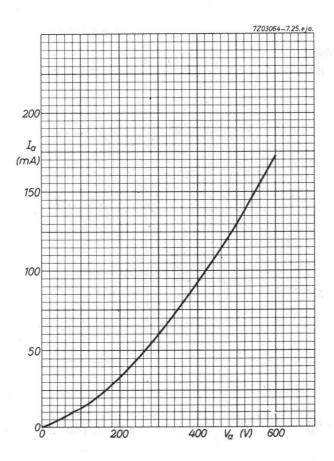
Max. pulse duration 10% of a line scanning cycle with a max. of 10 $\mu s.$

 $^{^{\}mathrm{l}}$) The negative peak due to ringing in the line output transformer should be taken into account.

Max. pulse duration 22% of a cycle and 18 μ s.

²⁾ Design max. rating system





DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube.

	QUICK F	REFERENCE	DATA		
Transformer voltage	11 1 M		V _{tr}	2x450	V _{RMS}
D.C. current	~ I'	¥.	I_{o}	250	mA

HEATING: Indirect by A.C.; parallel supply

Heater voltage

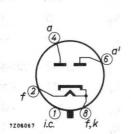
Heater current

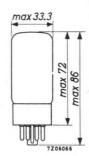
 $\frac{V_f}{I_f} \qquad \frac{5}{1.9} \quad \frac{V}{A}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Octal





OPERATING CHARACTERISTICS

As two-phase half-wave rectifier with capacitor input					
Transformer voltage	V _{tr}	2x300	2x350	2x400	v_{RMS}
D.C. output voltage	V_{o}	330	380	430	V
D.C. current	I_{O}	250	250	250	m A
Protecting resistance	Rt	2x75	2x100	2x125	Ω
Input capacitor of smoothing filter	C_{filt}	60	60	60	$\mu \mathrm{F}$
Transformer voltage	V_{tr}	2x450	2x500	2x550	v_{RMS}
D.C. output voltage	V_{o}	480	560	640	V
D.C. current	I_{o}	250	200	160	mA
Protecting resistance	R _t	2x150	2x175	2x200	Ω
Input capacitor of smoothing filter	C_{filt}	60	60	60	μ F
As two-phase half-wave rectifier with	choke	input			
As two-phase half-wave rectifier with Transformer voltage	choke V _{tr}	input 2x300	2x350	2x400	v_{RMS}
			2x350 290	2x400 330	V _{RMS}
Transformer voltage	V _{tr}	2x300			
Transformer voltage D.C. output voltage	v _{tr} v _o	2x300 250	290	330	V
Transformer voltage D.C. output voltage D.C. current	V _{tr} V _o	2x300 250 250	290 250	330 250	V mA
Transformer voltage D.C. output voltage D.C. current Protecting resistor	V _{tr} V _o I _o R _t	2x300 250 250 0	290 250 0	330 250 0	V mA Ω
Transformer voltage D.C. output voltage D.C. current Protecting resistor Choke	V _{tr} V _o I _o R _t L	2x300 250 250 0	290 250 0 10	330 250 0 10	V mA Ω H
Transformer voltage D.C. output voltage D.C. current Protecting resistor Choke Transformer voltage	V _{tr} V _o I _o R _t L V _{tr}	2x300 250 250 0 10 2x450	290 250 0 10 2x500	330 250 0 10 2x550	V mA Ω H V_{RMS}
Transformer voltage D.C. output voltage D.C. current Protecting resistor Choke Transformer voltage D.C. output voltage	$egin{array}{c} V_{tr} \\ V_{o} \\ I_{o} \\ R_{t} \\ L \\ V_{tr} \\ V_{o} \\ \end{array}$	2x300 250 250 0 10 2x450 375	290 250 0 10 2x500 420	330 250 0 10 2x550 465	V mA Ω H V_{RMS} V

LIMITING VALUES (Design centre rating system)

See also page 4

Capacitor input

Anode voltage,

peak inverse

 v_{ainv_p}

max. 1500 V

D.C. current Anode peak current I_{o}

max. See page 4

 I_{ap}

max. 750 mA

Input capacitor of smoothing filter

 C_{filt}

max. 60 μF

Protecting resistance

Rt min.

2x50 2x75 2x100 2x125 2x150 2x175 Ω

at transformer voltage

 V_{tr}

2x300 2x350 2x400 2x450 2x500 2x550 V_{RMS}

Choke input

Anode voltage,

peak inverse

Vainvp

max. 1500 V

D.C. current

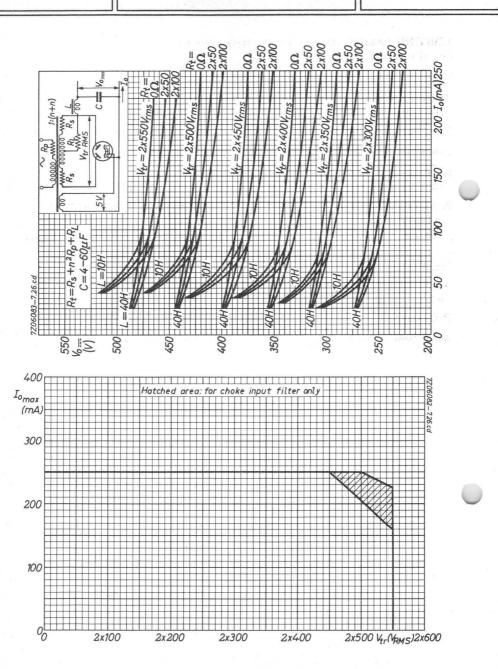
 I_{o}

max. See page 4

Anode peak current

 I_{ap}

max. 750 mA



TRIPLE DIODE-TRIODE

Triple diode-triode, intended for video and FM and AM audio signal detection and A.F. signal amplification.

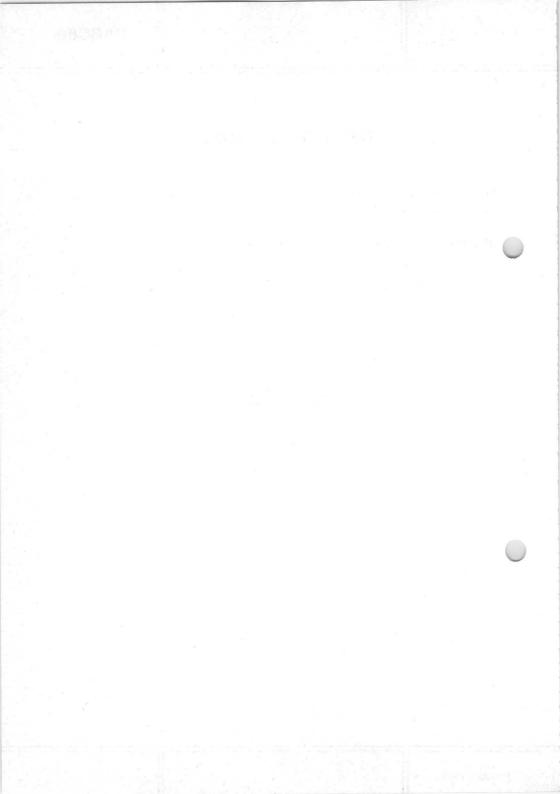
HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

 $\begin{array}{ccc} \underline{I_f} & 300 & \text{mA} \\ \underline{V_f} & 9.5 & \underline{V} \end{array}$

For further data and curves please refer to UABC80



U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier, oscillator or mixer for bands ${\rm IV}$ and ${\rm V.}$

QUICK REFER	ENCE DATA		7
Anode current	I _a	12	m A
Transconductance	S	14	mA/V
Amplification factor	μ	68	-

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

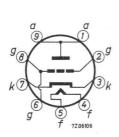
Heater voltage

If	300	mA
V_{f}	3.8	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





OPERATING CHARACTERISTICS			
As grounded grid amplifier			
Anode voltage	v_a	175	V
Cathode resistor	R_k	125	Ω
Anode current	I_a	12	mA
Transconductance	S	14	mA/V
As self-oscillating mixer			
Supply voltage	v_{b_a}	220	V
Anode resistor	Ra	5.6	kΩ
Grid resistor	R_g	47	kΩ
Anode current	Ia	12	mA
Grid current	I_g	50	μΑ
LIMITING VALUES (Design centre rating systematics)	em)		
Anode voltage	v_{a_0}	max. 550	V
	Va	max. 220	V
Anode dissipation	Wa	max. 2.2	W
Cathode current	I_k	max. 20	mA

-Vg

 R_g

Vkf(kpos)

max. 50 V

max. 1 $M\Omega$

max. 100; V 1)

Grid voltage

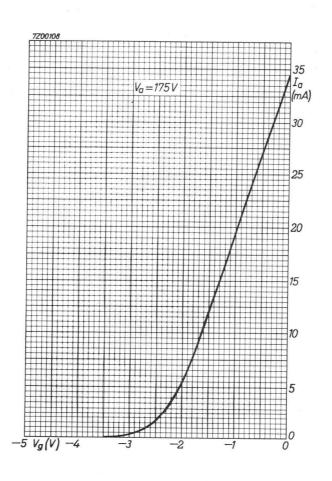
Grid resistor

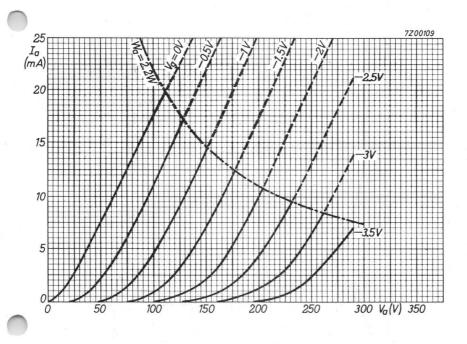
Cathode to heater voltage

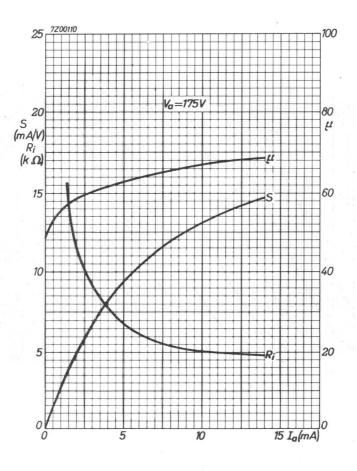
 $^{^{1})}$ A.C. component max. 50 $V_{\mbox{RMS}}$.

C_{ag}	2.2	pF
C_{ak}	0.24	pF
C_{gk}	3.5	pF
$C_{ m gf}$	0.27	pF
C _{k/gf}	6.3	pF
Cg/kf	3.8	pF
C _{a/kf}	0.35	pF
Ca/gf	2.3	pF
Ca/gs	3.3	pF
C _{kf/gs}	4.1	pF
Ca/kf	0.3	pF
v_a	175	V
V_g	-1.5	V
Ia	12	mA
S	14	mA/V
μ	68	_
Req	230	Ω
ΔC_g	2	pF ¹)
	Cgk Cgf Ck/gf Cg/kf Cg/kf Ca/kf Ca/gf Ca/gs Ckf/gs Ca/kf Va Vg Ia S Req	Cak 0.24 Cgk 3.5 Cgf 0.27 Ck/gf 6.3 Cg/kf 3.8 Ca/kf 0.35 Ca/gf 2.3 Ca/gs 3.3 Ckf/gs 4.1 Ca/kf 0.3 Va 175 Vg -1.5 Ia 12 S 14 μ 68 Req 230

 $^{^{\}rm l}$) Difference between ${\rm C}_{\rm g}$ of cold and hot tube.







U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier for bands IV and V.

QUICK REF	ERENCE DATA		
Anode current	Ia	12.5	mA
Transconductance	S	13.5	mA/V
Amplification factor	μ	65	

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

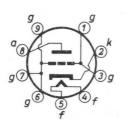
Heater voltage

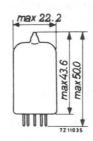
I_f 300 mA V_f 3.8 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Without external screen

Anode to grid $C_{\mbox{ag}}$ 1.2 pF

TYPICAL CHARACTERISTICS

Anode voltage	Va	160	V	¹)
Cathode resistor	R_k	100	Ω	¹)
Anode current	Ia	12.5	mA	
Transconductance	S	13.5	mA/	V.
Amplification factor	μ	65		
Equivalent noise resistance	Req	240	Ω	
Noise figure at f = 850 MHz	F	10	dB	
Anode voltage	Va	0	V	
Grid current, positive	I_g	0.3	μ A	
Grid voltage	-V _g	max. 1.3	V	

Series resonance frequencies

Measured between a point on the relevant tube pin close to the tube bottom and a point close to the relevant pin on a metal reference plane, placed against the tube bottom.

All the pins, except the relevant one, are connected to the reference plane with a negligible impedance.

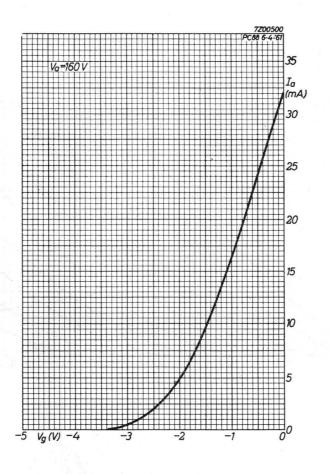
The tube is screened by a metal screen with an inside diameter of $22.2\ \mathrm{mm}$ placed upon the metal reference plane.

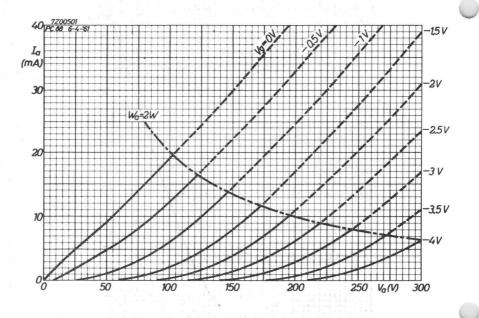
Heater voltage	${ m v_f}$	0	V
Anode voltage	Va	0	V
Anode resonance frequency	${ m f_{0a}}$	1700	MHz
Cathode resonance frequency	f_{Ok}	1000	MHz

LIMITING VALUES (Design centre rating system)

Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	175	V
Anode dissipation	Wa	max.	2	W
Cathode current	I_k	max.	13	mA
Grid voltage	-Vg	max.	50	V
Grid resistor (R_k = 100 Ω)	R_g	max.	1	$M\Omega$
Cathode to heater voltage	V_{kf}	max.	100	V^{-1})

 $^{^{\}rm l})$ To fulfil the modulation hum requirements, the A.C. component should not exceed 50 $V_{\rm RMS}.$





H.F. TRIODE

Triode intended for use as H.F. amplifier, oscillator, mixer and in frame deflection circuits and line deflection circuits of TV receivers.

a was a second	QUICK RE	FERENCE DATA	To the same for the	Ny il	, " E WIL
Anode current	3 4%		Ia	12	mA
Transconductance			S	7.2	mA/V
Amplification factor			μ	67	1.240 (0.15)

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

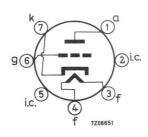
Heater voltage

 $\begin{array}{ccc} \underline{I_f} & 300 \text{ mA} \\ \hline V_f & 3.1 \text{ V} \end{array}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: 7 pin miniature





LIMITING VALUES (Design centre rating system)

Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	250	V	
Anode dissipation	Wa	max.	2.5	W	
Grid voltage	-Vg	max.	50	V	
Cathode current, average	I_k	max.	15	mA	
peak	I_{k_p}	max.	150	mA^3)	
Cathode to heater voltage (k pos.)	v_{kf}	max.	250	V 1)	- 4
(k neg.)	v_{kf}	max.	250	V	1
	(D.C. co	mponent	max.	100 V)	
Grid resistor (automatic bias)	R_g	max.	1	$M\Omega$	

OPERATING CONDITIONS AS BLOCKING OSCILLATOR

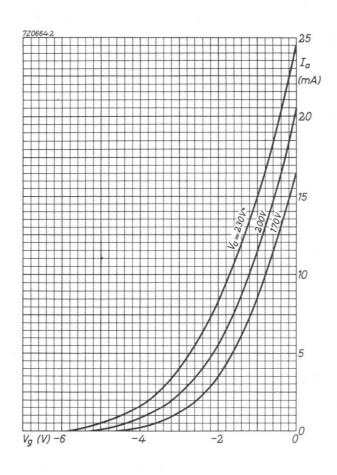
To take into account the tube tolerances, the decrease of the characteristics during life and the decrease of the emission at underheating, the circuit should be designed so that acceptable performance is obtained with a cathode peak current of 100 mA 2) (150 mA 3). It is recommended to limit the peak current of new tubes by an automatic amplitude limiting circuit e.g. by the use of non by-passed grid and anode resistors.

¹⁾ During the warm-up period of the tubes V_{kf} (k pos.) (D.C. component) max. 315 V.

 $^{^{2}}$) Pulse duration 4% of a cycle and max. 0.8 ms.

 $^{^3}$) Pulse duration 1% of a cycle and max. 0.2 ms.

CAPACITANCES						
Grounded cathode circuit						
without external shield						
Input			C_{i}		2.8	pF
Output			C_{o}		0.55	pF
Anode to grid			C_{ag}		1.8	pF
With external shield 19.5 mm d	liameter					
Anode to cathode, heater and sh	ield		C _{a/kfs}		1.4	pF
Cathode to grid, heater and shie	eld		C _{k/gfs}	3	4.7	pF
Anode to grid, heater and shield	l		C _{a/gfs}	3	2.9	pF
Grounded grid circuit						
without external shield						
Input			C_{i}		4.6	pF
Output			Co		2.0	pF
Anode to cathode			C_{ak}		0.24	pF
Cathode to heater			C_{kf}		2.0	pF
Grid to heater			C_{gf}	max	.0.15	pF
TYPICAL CHARACTERISTICS						
Anode voltage	Va	100	170	200	230	V
Grid voltage	Vg	-0.9	-1.0	-0.9	-1.6	V
Anode current	Ia	3.0	8.5	12.0	10.5	mA
Transconductance	S	3.8	6.0	7.2	6.0	mA/V
Amplification factor	μ	58	65	67	62	-
Equivalent noise resistance	Req		0.5	0.4	0.5	$k\Omega$



V.H.F. TRIODE

Triode intended for use as R.F. amplifier in V.H.F. television receivers.

QUICK REFERE	ENCE DATA		
Cathode current	I _k max.	20	mA
Transconductance	S	20	mA/V
Amplification factor	μ	84	

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

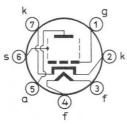
Heater voltage

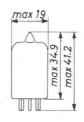
<u>If</u> 300 mA V_f 3.9 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Miniature 7p





CAPACITANCES (with external shield, internal diameter 19.1 mm, connected to cathode)

Anode to all except grid	Ca(g)	3.0	pF
Grid to all except anode	$C_{g(a)}$	4.5	pF
Anode to grid	C_{ag}	0.365	pF
Anode to cathode	C_{ak}	0.08	pF
Grid to cathode	C_{gk}	3.3	pF
Grid to heater	$C_{ m gf}$	max. 0.07	pF
Cathode to heater	C_{kf}	2.3	pF

TYPICAL CHARACTERISTICS

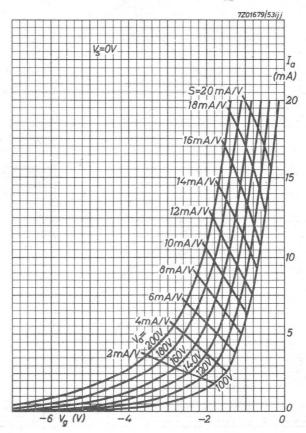
Anode voltage	v_a		135		V
Shield voltage	V_s		0		V
Grid voltage	Vg	-1	-2.8	-5.9	V
Anode current	Ia	11.5	-	-	mA
Transconductance	S	14.5	1.45	0.145	mA/V
Amplification factor	μ	76	_	-	

OPERATING CHARACTERISTICS

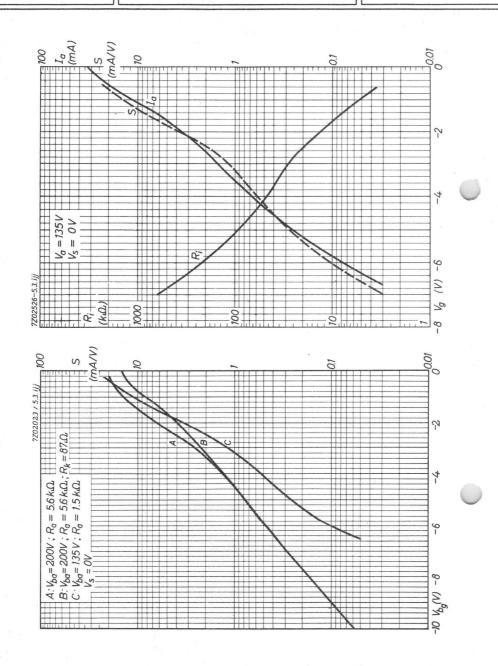
Anode supply voltage	v_{ba}	135	200	200	V
Anode resistor	Ra	1.5	5.6	5.6	kΩ
Shield voltage	Vs	0	0	0	V
Cathode resistor	R _k	0	0	87	Ω
Anode current	Ia	16.5	16.5	11.5	mA
Grid current	I_g	20	20	-	μ A
Transconductance	S	20	20	14.5	mA/V
Amplification factor	μ	84	84	76	
Transconductance	S	. 2	2	1.45	mA/V
Grid voltage	Vg	-2.3	-3.2	-3.8	V
Transconductance	S	0.2	0.2	0.145	mA/V
Grid voltage	V	-5.3	-7.7	-8.3	V

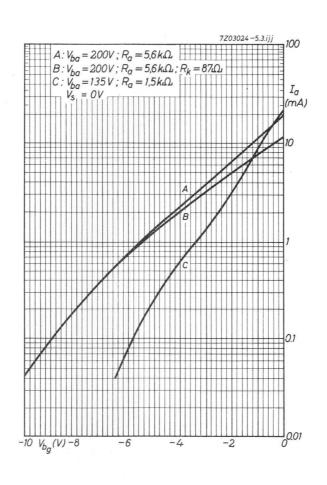
LIMITING VALUES (Design centre rating system)	LIMITING	VALUES	(Design	centre	rating	system)
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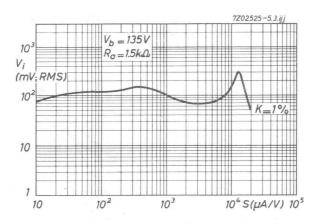
	Anode voltage	v_{a_0}	max.	550	V
		V _a	max.		V
	Anode dissipation	Wa	max.	2.2	W
	Cathode current	I_k	max.	20	mA
	Negative grid voltage	-V _g	max.	50	V
	Grid resistor	Rg	max.	1	$M\Omega$
	Grid resistor in A.G.C. circuits	Rg	max.	3	$M\Omega$
)	Cathode to heater voltage	v_{kf}	max.	100	V^{1})

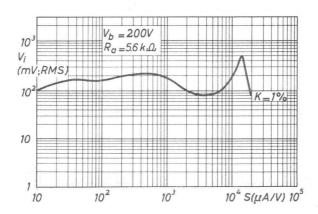


 $^{^{\}rm 1}\mbox{)}$ To fulfil the modulation hum requirements, \mbox{V}_{kf} should not exceed 55 $\mbox{V}_{RMS}.$









R.F. DOUBLE TRIODE

Double triode intended for various applications in television receivers.

QUICK REFE	RENCE DATA	
Anode current	Ia	10 mA
Transconductance	S 6	.7 mA/
Amplification factor	μ	48 -

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

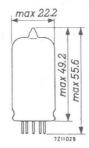
Heater voltage

If	300	mA
V_f	9.0	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm





PCC85

CAPACITANCES (each unit unless otherwise specified)

Anode to grid	C_{ag}		1.5	pF
Anode to cathode	Cak		0.18	pF
Anode to cathode + heater + screen	C _{a/kfs}		1.2	pF
Grid to cathode + heater + screen	$C_{g/kfs}$		3.1	pF
Anode to cathode + heater + screen (measured with external screen of 22.5 mm diam.)	C _{a/kfs}		1.8	pF
Anode to anode other unit	C _{aa} •	max.	0.04	pF
Anode to anode other unit (measured with external screen of 22.5 mm diam.)	C _{aa} '	max.	0.008	pF
Grid to grid other unit	Cgg'	max.	0.003	pF
Anode to grid other unit	Cag'	max.	0.008	pF
Anode to grid other unit	Ca'g	max.	0.008	pF
Anode to cathode other unit	Cak'	max.	0.008	pF
Anode to cathode other unit	Ca'k	max.	0.008	pF
Grid to cathode other unit	Cgk'	max.	0.003	pF
Grid to cathode other unit	Cg'k	max.	0.003	pF

TYPICAL CHARACTERISTICS (each unit)

Anode voltage	v_a	100	170	200	V
Grid voltage	V_g	-1.2^{1})	-1.75	-2.4	V
Anode current	Ia	4.5	10	10	mA
Transconductance	S	4.8	6.7	6	mA/V
Amplification factor	μ	46	48	46	

REMARK

Microphony

This tube can be used without special precautions against microphony in A.F. applications in which the input voltage $V_i \geq 5~\text{mV}$ for an output of 50~mW (or 50~mV for an output 5~W) provided the peak acceleration of the tube is not greater than indicated in the section "Microphony" of the "General Operational Recommendations".

¹⁾ In this case grid current may occur. If this is not permissible, a condition with a bias of -1.5 V should be chosen.

OPERATING CHARACTERISTICS (each unit)

Anada gunnly valtaga	17.	100	170	200	V
Anode supply voltage	V_{b}				
Anode resistor	Ra	4.7	4.7	8.2	kΩ
Grid resistor	Rg	1	1	1	$M\Omega$
Oscillator voltage	Vosc.	1.8	2.8	2.8	v_{RMS}
Anode current	Ia	2.7	5.5	6	mA
Conversion conductance	S_{C}	2.2	2.8	2.9	mA/V
Internal resistance	$R_{\mathbf{i}}$	19	15	14	$k\Omega$
Grid input resistance (f = 100 MHz)	r _g		15		kΩ
As oscillator in television receivers					
Anode supply voltage	V_b			180	V
Anode resistor	Ra			4.4	$k\Omega$
Grid resistor	R_g			22	$k\Omega$
Oscillator voltage	Vosc.			9	v_{RMS}
Anode current	Ia			7.4	mA
Anode dissipation	Wa			1.2	W
LIMITING VALUES (each unit) (Desig	n centre ratin	g syste	em)		
Anode voltage	v_{a_0}		max.	550	V
	v_a		max.	250	V
Anode dissipation	W_a		max.	2.5	W
Anode dissipation, total	Wa+Wa'		max.	4.5	W
Cathode current	I_k		max.	15	mA
Cathode to heater voltage	v_{kf}		max.	90	V
Grid voltage, negative	-V _g		max.	100	V

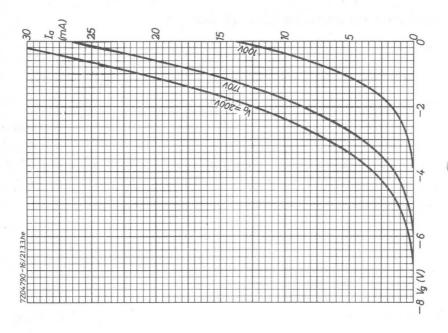
January 1969

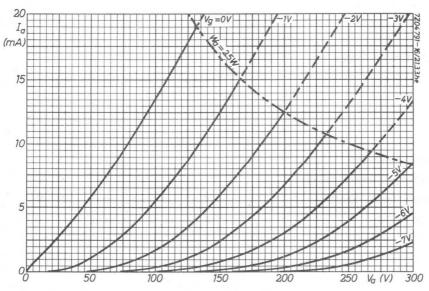
Grid resistor

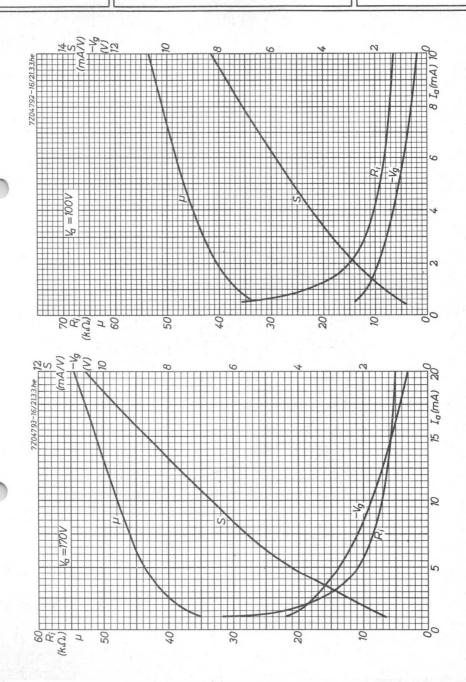
Rg

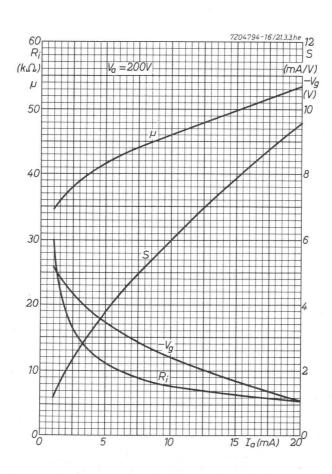
max. 1 $M\Omega$

3









R.F. DOUBLE TRIODE

Double triode intended for use as cascode amplifier in television tuners.

	QUICK REFERENCE DATA (Each unit)			
Anode current		Ia	15	mA
Transconductance		S	12.5	mA/V
Amplification factor		μ	33	-

HEATING: Indirect by A.C. or D.C.; series supply

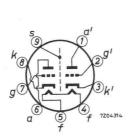
Heater current

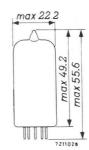
Heater voltage

I_f	300	mA
V_{f}	7.6	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm





CAPACITANCES	wi	thout external	with external		
		screen	screen		
Anode to grid	C_{ag}	1.4	1.4	pF	
Grid to cathode + heater + screen	Cg/kfs	3.3	3.3	pF	
Anode to cathode + heater + screen	C _a /kfs	1.8	2.5	pF	
Grid to heater	C_{gf}	0.13	0.13	pF	
Anode to grid	Ca'g'	1.4	1.4	pF	
Cathode to grid + heater + screen	Ck'/g'fs	6	6	pF	
Anode to grid + heater + screen	Ca'/g'fs	2.8	3.7	pF	
Cathode to heater	Ck'f	2.7	2.7	pF	
Anode to cathode	Ca'k'	0.18	0.16	pF	
Anode to anode	Caa'	max.0.045	max.0.015	pF	
Grid to anode other unit	Cga'	max.0.005	max.0.005	pF	

REMARK

The unit a, g, k should be used as the grounded cathode input section and unit a, g, k as the grounded grid output unit.

TYPICAL CHARACTERISTICS

Anode voltage	v_a	90	V
Grid voltage	Vg	-1.3	V
Anode current	Ia	15	mA
Transconductance	S	12.5	mA/V
Amplification factor	μ	33	-
Equivalent noise resistance	Req	300	Ω

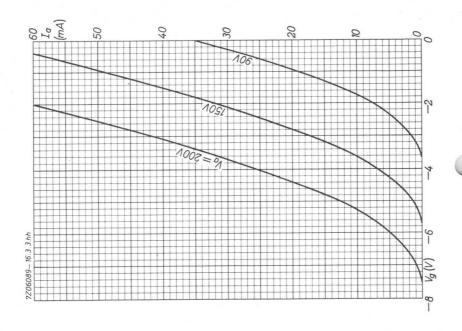
LIMITING VALUES (Design centre rating system) (each unit, unless otherwise stated)

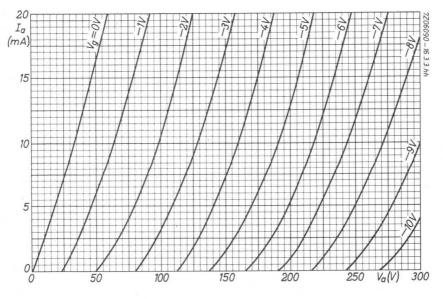
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	130	V
Anode dissipation	Wa	max.	1.8	W
Cathode current	I_k	max.	25	mA
Grid voltage	-Vg	max.	50	V
Grid resistor	R_g	max.	1	$M\Omega$
Cathode to heater voltage	$V_{\mathbf{kf}}$	max.	50	V
	Vk'f(k'pos)	max.	150	V^1)

REMARK

In order not to exceed the maximum permissible anode voltage when the cascode amplifier is controlled, it is necessary to use a voltage divider for the grid of the grounded grid section. With grid current biasing for the grounded cathode section the anode voltage across this section should not be more than $75~\rm V$ in the not controlled condition.

¹⁾ D.C. component max. 130 V.





R.F. DOUBLE TRIODE

Double triode with variable transconductance intended for use as V.H.F. cascode amplifier in television receivers.

QUICK REFEREN	CE DATA		
Anode current	Ia	15	mA
Transconductance	S	12.5	mA/V
Amplification factor	μ	31	-

HEATING: Indirect by A.C. or D.C.; series supply

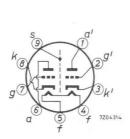
Heater current

Heater voltage

I_{f}	300	mA
$\overline{V_f}$	7.6	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm





PCC189

CAPACITANCES	with external s		witho external	
Grid to cathode + heater + screen	C_g/kfs 3.	5	3.	5 pF
Anode to cathode + heater + screen	C _{a/kfs} 2.	3	1.	7 pF
Anode to grid	C _{ag} 1.	9	1.	.9 pF
Grid to heater	Cgf max.0.2	8	max. 0.2	28 pF
Cathode to grid + heater + screen	$C_{k'/g'fs}$ 6.	0	6.	0 pF
Anode to grid, heater + screen	$C_{a'/g'fs}$ 4.	0	3.	4 pF
Anode to cathode	Ca'k' 0.1	7	0.1	.8 pF
Cathode to heater	Ck'f 2.	7	2.	.7 pF
Anode to grid	Ca'g' 1.	9	1.	9 pF
Anode to anode	Caa' max. 0.01	5	max.0.04	5 pF
Grid to anode other unit	Cga' max. 0.00	4	max.0.00)4 pF
TYPICAL CHARACTERISTICS (each	unit)			
Anode voltage		Va	90	V
Grid voltage		Vg	-1.4	V
Anode current		I_a	15	mA
Transconductance		S	12.5	mA/V
Internal resistance		R_i	2.5	$k\Omega$
Grid voltage		v_g	- 5	V
Transconductance		S	0.625	mA/V
Grid voltage		v_g	- 9	v
Transconductance		S	0.125	mA/V

LIMITING	VALUES	Design	centre	rating	system) (Each unit)
THAIR I HARL	VALUES	(Degizin	CCIICIC	Lating	System	/ (Lacir dille)

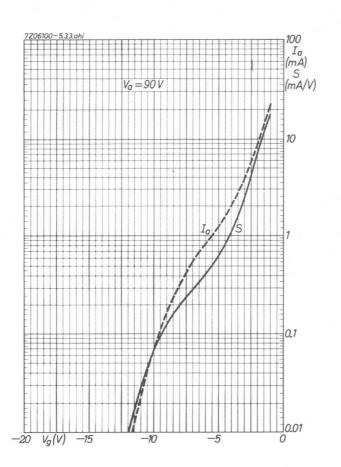
1.	Million Vallets (Seeign courts racing System)	(22.000.00				
Α	node voltage	v_{a_0}	max.	550	V	
		v_a	max.	130	V	
A	node dissipation	Wa	max.	1.8	W	£
G	rid voltage	-Vg	max.	50	• V	
G	rid resistor					
	unit a, g, k	$R_{\mathbf{g}}$	max.	1	$M\Omega$	
	unit a', g', k'	Rg'	max.	0.5	ΩM	
C	Cathode current	$I_{\mathbf{k}}$	max.	22	mA	
C	Cathode to heater voltage					
	unit a, g, k	Vkf	max.	80	V	
	unit a', g', k' (cathode positive)	Vk'f	max.	180	v 1)	

REMARKS

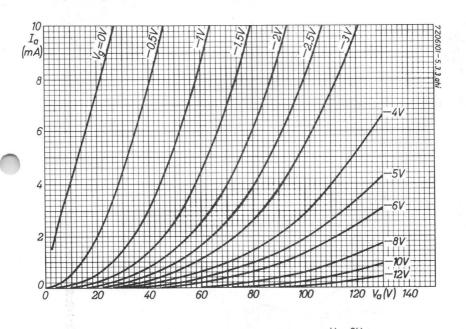
In order not to exceed the maximum permissible anode voltage when the tube is controlled, it is necessary to use a voltage divider for the grid of the grounded grid section.

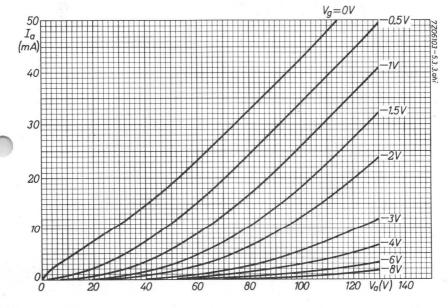
The system a, g, k should be used as the grounded cathode input section and the system a', g', k' as the grounded grid output section.

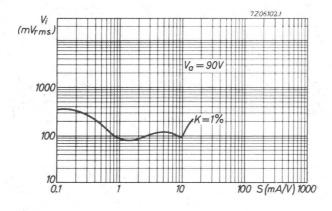
¹⁾ D.C. component max. 130 V.



5







TRIODE PENTODE

Triode pentode with separate cathodes intended for use as frequency changer in television receivers.

QUICK RI	EFERENCE DATA
Triode section	and the same the same
Anode current	I _a 14 mA
Transconductance	S 5 mA/V
Amplification factor	μ 20 -
Pentode section	
Anode current	I _a 10 mA
Transconductance	S 6.2 mA/V
Amplification factor	$\mu_{g_2g_1}$ 47 –

HEATING: Indirect by A.C. or D.C.; series supply

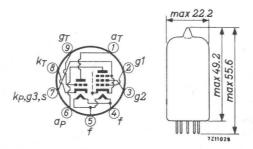
Heater current

Heater voltage

If	300	mA
$V_{\mathbf{f}}$	9	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm



PCF80

CAPACITANCES						
Triode section (numbers denote pin number)						
Anode to all except grid (1-4+5+7+8)	$C_{a(g)}$		1	.8	pF	
Grid to all except anode (9-4+5+7+8)	C _{g(a)}		2	.5	pF	
Anode to grid	C_{ag}		1	.5	pF	
Pentode section						
Anode to all except grid No.1	$C_{a(g_1)}$		3	.4	pF	
Grid No.1 to all except anode	$C_{g_1}(a)$		5	. 2	pF	
Anode to grid No.1	C_{ag_1}	max	. 0.0	25	pF	
Between triode and pentode sections						
Anode triode to grid No.1 pentode	$C_{a_Tg_1P}$	max	. 0.	16	pF	
Grid triode to anode pentode	$C_{g_{T}a_{P}}$	max	. 0.	02	pF	
Anode triode to anode pentode	$C_{a_{T}a_{P}}$	max	. 0.	07	pF	
TYPICAL CHARACTERISTICS						
Triode section						
Anode voltage	v_a		100	V		
Grid voltage	V_g		-2	V		
Anode current	I_a		14	m	A	
Transconductance	S		5	m	A/V	
Amplification factor	μ		20			
Pentode section						
Anode voltage	v_a		170	V		
Grid No.2 voltage	v_{g_2}		170	V		
Grid No.1 voltage	v_{g_1}		-2	V		
Anode current	Ia		10	m.	A	
Grid No.2 current	I_{g_2}		2.8	m.	A	
Transconductance	S		6.2	m.	A/V	
Amplification factor	$\mu_{g_2g_1}$		47	-		
Internal resistance	R _i		0.4	M	2	
Grid No.1 impedance						
(Frequency 50 MHz)	r_{g_1}		10	kΩ		
Equivalent noise resistance	Req		1.5	kΩ	?	

OPERATING CONDITIONS

As frequency changer (It is recommended to employ the triode in a Colpitts type of circuit and not in a Hartley type)

	Anode voltage	v_a	170	170	V
(Grid No.2 voltage	v_{g_2}	170	170	V
(Grid No.1 resistor	R_{g_1}	0.1	0.1	$M\Omega$
(Cathode resistor	R_k	330	820	Ω
(Oscillator voltage	V_{osc}	3.5	3.5	v_{RMS}
) -	Anode current	Ia	6.5	5.2	mA
-	Grid No.2 current	I_{g_2}	2.0	1.5	mA
-	Grid No.1 current	I_{g_1}	20	0	μ A
(Conversion conductance	S_c	2.2	2.1	mA/V
]	Internal resistance	R_i	800	870	$k\Omega$

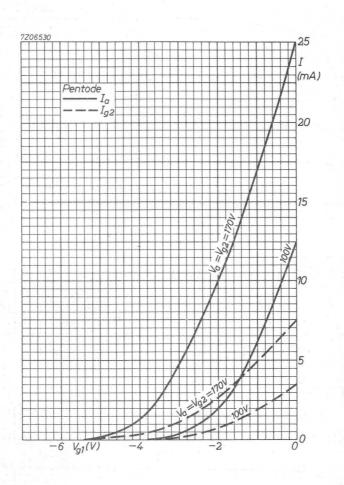
Frame output application (Optimum peak cathode current of the triode section)

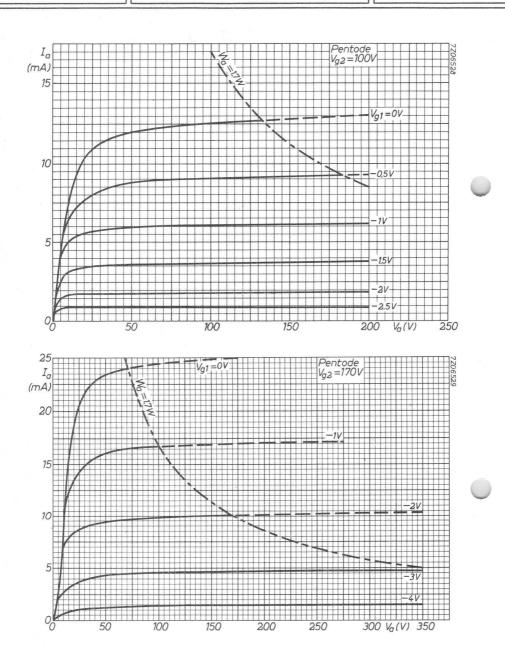
To allow for tube spread, for deterioration during life and for emission drop at underheating the equipment should be so designed that it still operates satisfactorily with a peak cathode current of 100~mA (max. pulse duration 4~% of a cycle, but maximum 0.8~ms). The amplitude of the peak current occurring with new tubes should be limited automatically to this max. value of 100~mA. (E.g. by non-bypassed resistances in the grid lead.)

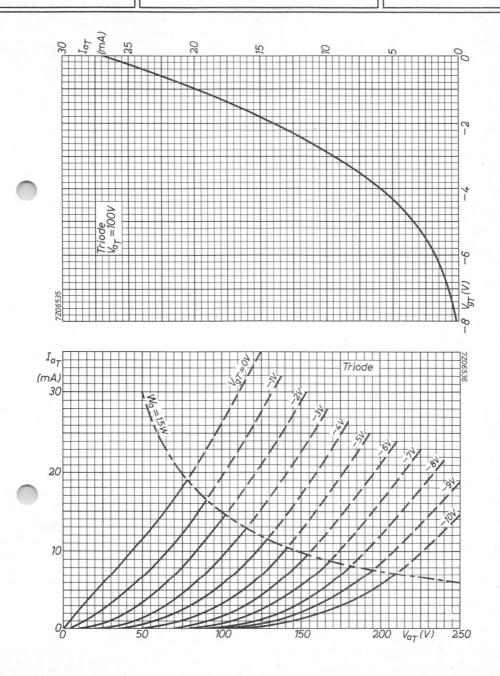
PCF80

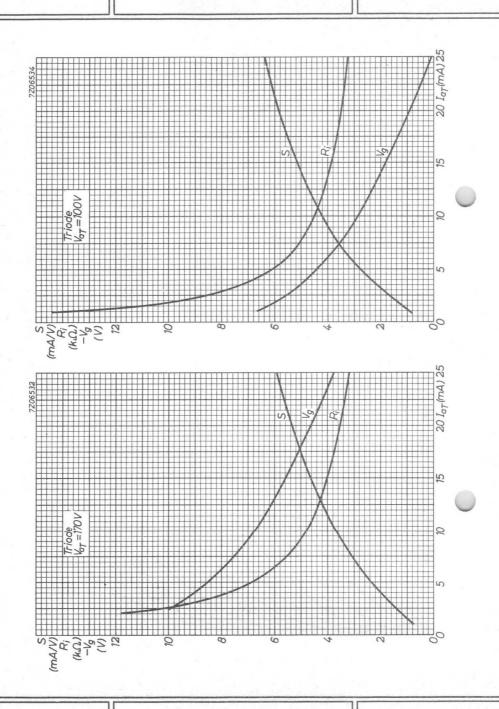
LIMITING VALUES	(Design centre rating system)
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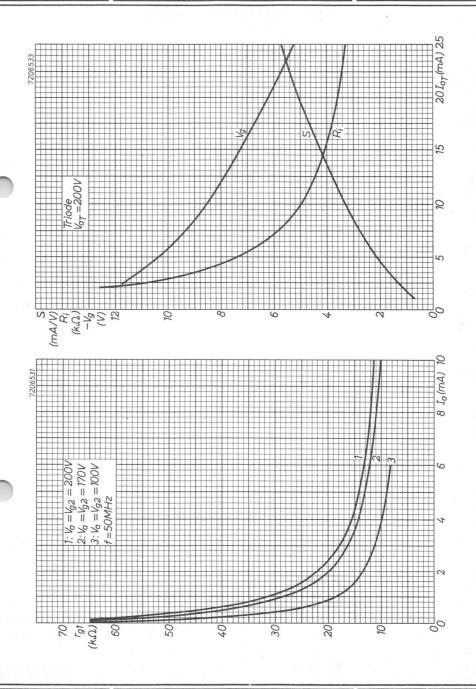
Emiliate vineons (Bosign co.	ice of acting by seemy				
Triode section					
Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	250	V	
Anode dissipation	Wa	max.	1.5	W	
Cathode current					
average	I_k	max.	14	mA	
peak	Ikp see under "fr	ame output app	olicati	ons"	1
Grid resistor	R_g	max.	0.5	$M\Omega$	1
Cathode to heater voltage					
cathode neg	v_{kf}	max.	100	V	
cathode pos	v_{kf}	max.	200	V	
	D.C. co	mponent max.	120	V	
Pentode section					
Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	250	V	
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V	
$I_k = 14 \text{ mA}$	v_{g_2}	max.	175	V	
$I_k = max. 10 mA$	v_{g_2}	max.	200	V	
Anode dissipation	Wa	max.	1.7	W	
Grid No.2 dissipation					
at $W_a = \min. 1.2 W$	w_{g_2}	max.	0.5	W	
at $W_a = max. 1.2 W$	w_{g_2}		0.75	W	
Cathode current	I_k	max.	14	mA	
Grid resistor					
fixed bias	R_{g_1}	max.	0.5	$M\Omega$	
automatic bias	R_{g_1}	max.	. 1	$M\Omega$	
Cathode to heater voltage					
cathode neg	v_{kf}	max.	100	V	
cathode pos	V _{kf}	max. mponent max.	200 120	V V	

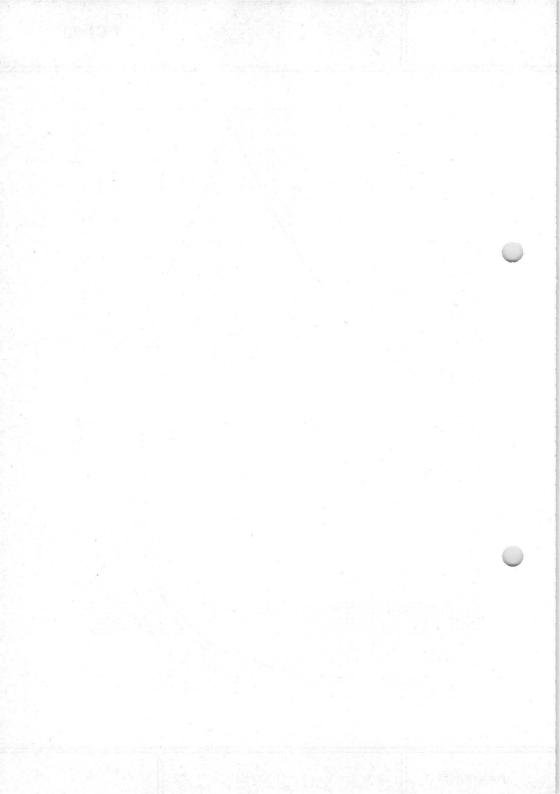












TRIODE-PENTODE

Triode pentode intended for use as frequency changer in $V.H.\,F.$ television tuners.

QUICK REFERENCE DATA					
Triode section					
Anode current		Ia	14	mA	
Transconductance		S	5.7	mA/V	
Amplification factor		μ	17	-	
Pentode section					
Anode current		I_a	10	mA	
Transconductance		S	12	mA/V	
Amplification factor		$^{\mu}$ g $_{2}$ g $_{1}$	70	- ;	

HEATING: Indirect by A.C. or D.C.; series supply

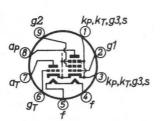
Heater current

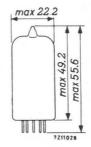
Heater voltage

I_f	300	mA
$\overline{V_{f}}$	8	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm





CAPACITANCES					
Triode section					
Anode to all except grid	$C_{a(g)}$		1.1	pF	
Grid to all except anode	$C_{g(a)}$		2.4	pF	
Anode to grid	C_{ag}		2.0	pF	
Pentode section					
Anode to all except grid No. 1	$C_{a(g_1)}$		3.5	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$		5.8	pF	
Anode to grid No.1	C_{ag_1}	(0.012	pF	
Grid No.1 to grid No.2	$C_{g_1g_2}$		1.7	pF	
Between triode and pentode sections	0102				
Anode triode to anode pentode	$C_{a_{\mathrm{T}}a_{\mathrm{P}}}$		0.125	pF	
Grid triode to anode pentode	$C_{g_{T}a_{P}}$		0.014	pF	
Anode triode to grid No.1 pentode	C _{aTg1P}	max.	0.010	pF	
Grid triode to grid No.1 pentode	$C_{g_Tg_{1P}}$	max.	0.010	pF	
TYPICAL CHARACTERISTICS					
Triode section					
Anode voltage	V_a		100	V	
Grid voltage	Vg		-3	V	
Anode current	Ia		14	mA	
Transconductance	S		5.7	mA/V	
Amplification factor	μ		17	-	
Pentode section					
Anode voltage	Va		170	V	
Grid No.2 voltage	v_{g_2}		150	V	
Grid No.1 voltage	v_{g_1}		-1.2	V	
Anode current	Ia		10	mA	
Grid No.2 current	I_{g_2}		3.8	mA	
Transconductance	S		12	mA/V	
Amplification factor	$\mu_{g_2g_1}$		70	_	
Internal resistance	Ri	min.	350	$k\Omega$	
Equivalent noise resistance	Req		1	$k\Omega$	
	× 04				

OPERATING CHARACTERISTICS

	Triode section as oscillator			
	Anode supply voltage	V _{ba}	190	V
	Anode resistor	Ra	8.2	kΩ
	Grid resistor	Rg	10	$k\Omega$
	Oscillator voltage	Vosc	4.5	VRMS
	Anode current	Ia	12	mA
)	Effective transconductance	$S_{ ext{eff}}$	3.5	mA/V
	Pentode section as mixer			
	Anode supply voltage	V _{ba}	190	V
	Grid No.2 supply voltage	v_{bg_2}	190	V
	Grid No.2 resistor	R_{g_2}	18	$k\Omega$
	Grid No.1 resistor	R_{g_1}	100	kΩ
	Oscillator voltage	Vosc	2.3	V_{RMS}
	Anode current	I_a	8.5	mA
	Grid No.2 current	I_{g_2}	3.0	mA
	Grid No.1 current	I_{g_1}	30	μ A
	Conversion conductance	S _c	4.5	mA/V
	Internal resistance	R_i	0.6	$M\Omega$

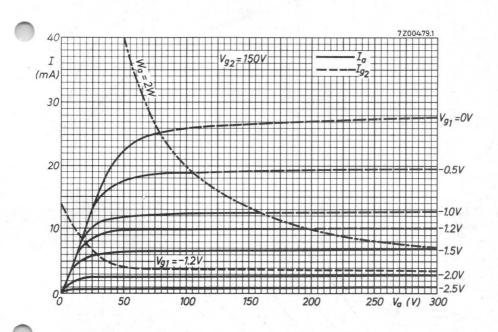
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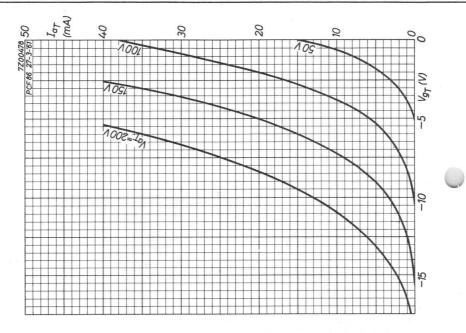
LIMITING VALUES

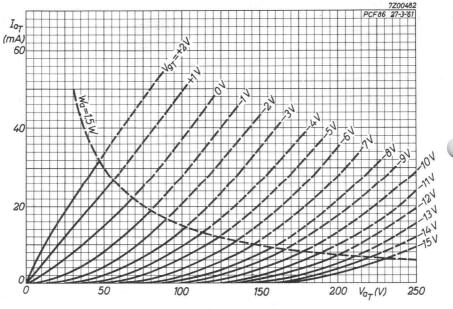
Triode section			
Anode voltage	V_{a_0}	max. 550	V
	V_a	max. 250	V
Anode dissipation	W_a	max. 1.5	W
Cathode current	Ik	max. 15	mA
Grid resistor	Rg	max. 0.5	$M\Omega$
Cathode to heater voltage	V _{kf}	max. 100	V 1)
Pentode section			
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 250	V
Grid No.2 voltage	$v_{g_{2_0}}$	max. 550	V
	v_{g_2}	max. 150	V
Anode dissipation	W_a	max. 2.0	W
Grid No.2 dissipation	w_{g_2}	max. 0.5	W
Cathode current	I_k	max. 18	mA
Grid No.1 resistor	R_{g_1}	max. 0.5	$M\Omega$
Cathode to heater voltage	v_{kf}	max. 100	V 1)

ceed 50 VRMS.

 $^{^1)}$ To fulfil the modulation hum requirements in intercarrier receivers, V_{kf} should not exceed 75 $V_{RMS}.$ With respect to modulation hum in A.M. sound receivers, V_{kf} should not ex-







TRIODE-PENTODE

Triode-pentode intended for use in television receivers; triode section as limiter, noise detector, A.G.C. amplifier, sync. separator and pulse-amplifier; pentode section as sound I.F. amplifier and video I.F. amplifier.

QUICK REFERENCE DATA							
Pentode section							
Anode current		Ia	13	mA			
Transconductance		S	14	mA/V			
Amplification factor		$\mu_{\mathrm{g}_2\mathrm{g}_1}$	53	-			
Triode section							
Anode current		Ia	8.5	mA			
Transconductance		S	5.2	mA/V			
Amplification factor		μ	57	-			

HEATING: Indirect by A.C. or D.C.; series supply

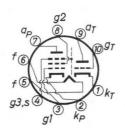
Heater current

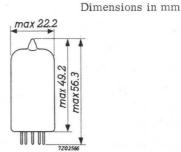
Heater voltage

If	300	mA	
V_f	8.5	V	

DIMENSIONS AND CONNECTIONS

Base: Decal





-				-	-
	CAPACITANCES				
	Triode section				
	Grid to all except anode	$C_{g(a)}$	2.1	pF	
	Anode to all except grid	Ca(g)	3.0	pF	
	Anode to grid	Cag	2.2	pF	
	Pentode section				
	Grid No.1 to all except anode	Cg1(a)	6.0	pF	
	Anode to all except grid No.1	$C_{a(g_1)}$	3.3	pF	-
	Anode to grid No.1	C_{ag_1}	0.0056	pF	
		Cag ₁ max.	0.008	pF	
	Grid No.1 to grid No.2	$C_{g_1g_2}$	1.7	pF	
	Grid No.1 to cathode	C_{g_1k}	3.7	pF	
	Between triode and pentode sections	01			
	Pentode anode to triode anode	CaP-aT	max. 0.015	pF	
	Pentode grid No.1 to triode anode	Cg1P-aT	max. 0.0012	pF	
	Pentode grid No.1 to triode grid	C_{g_1P-gT}	max. 0.0015	pF	
	TYPICAL CHARACTERISTICS				
	Pentode section				
	Anode voltage	v_a	160	V	
	Grid No.3 voltage	v_{g_3}	0	V	
	Grid No.2 voltage	v_{g_2}	135	V	
	Grid No.1 voltage	v_{g_1}	-1.7	V	
	Anode current	Ia	13	mA	
	Grid No.2 current	I_{g_2}	5.3	mA	
	Transconductance	S	14	mA/V	
	Amplification factor	$\mu_{g_2g_1}$	53	-	
	Triode section				
	Anode voltage	Va	170	V	
	Grid voltage	V_g	-1.0	V	
	Anode current	Ia	8.5	mA	
	Transconductance	S	5.2	mA/V	
	Amplification factor	μ	57	-	

OPERATING CHARACTERISTICS

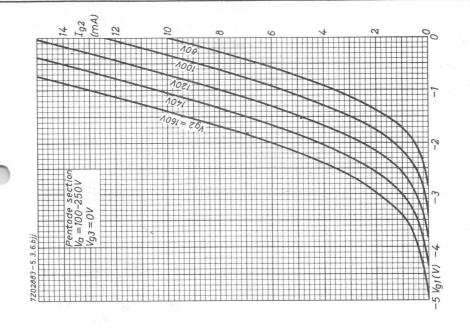
Pentode section as sound or video I.F. amplifie	nected to	earth)			
Supply voltage	v_b	210	230	V	
Anode resistor	Ra	3.9	5.6	$k\Omega$	
Grid No.2 resistor	R_{g_2}	15	22	kΩ	
Cathode resistor	Rk	91	83	Ω	
Anode current	I_a	13.0	12.5	mA	
Grid No.2 current	I_{g_2}	5.3	5.1	mA	
Transconductance	S	14	14	mA/V	
Input resistance at 40 MHz	r_{g_1}	6.6	6.6	$k\Omega$	
Triode section as sync separator					
Anode supply voltage	v_b	130 t	to 150	V	
Anode resistor	R_a	3	33	kΩ	
Grid current	I_g		1	μΑ	
Anode current	Ia	min.	2	mA	

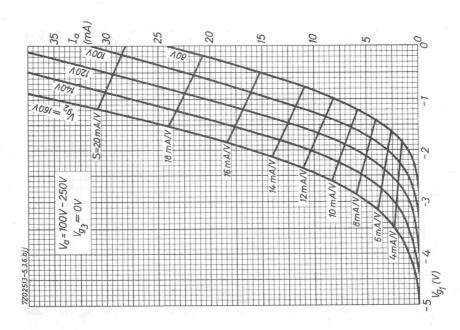
December 1969

LIMITING VALUES (Design centre rating system)

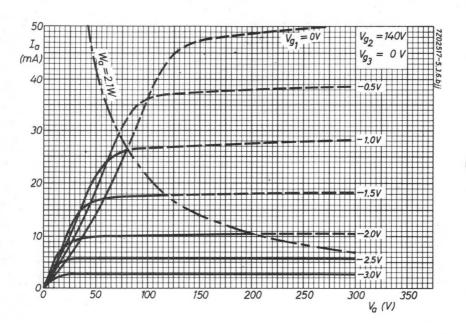
Pentode section			
Anode voltage	v_{ao}	max. 550	V
	v_a	max. 250	V
Anode dissipation	w_a	max. 2.1	W
Cathode current	I_k	max. 20	mA
Grid No.2 voltage	$V_{g_{2_0}}$	max. 550	V
	v_{g_2}	max. 250	V
Grid No.2 dissipation	w_{g_2}	max. 0.75	W
Cathode to heater voltage	v_{kf}	max. 150	V
Grid No.1 resistor	R_{g_1}	max. 1	ΜΩ
Triode section			
Peak anode voltage ($I_a < 0.1 \text{ mA}$)	v_{a_p}	max. 600	V 1)
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 250	V
Anode dissipation	w_a	max. 1.5	W
Cathode current	I_k	max. 18	mA
Grid resistor	R_g	max. 1	$M\Omega$
Cathode to heater voltage:	8		
cathode negative with respect to heater	v_{kf}	max. 150	V
cathode positive with respect to heater	v_{kf}	max. 200 + max. 150	v_{RMS}

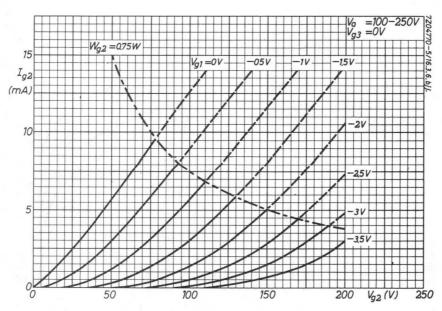
 $^{^{1})}$ Max. pulse duration is 18 % of a cycle but max. 18 $\mu \mathrm{sec}$.

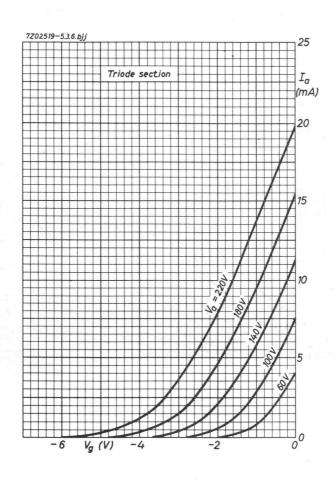


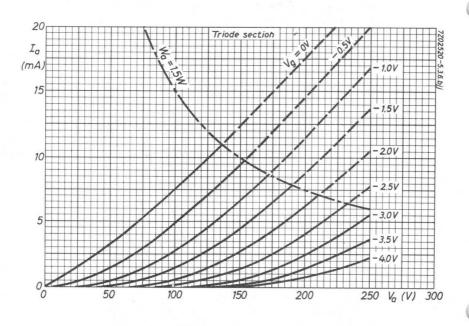


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TRIODE-PENTODE

Triode pentode intended for use in T.V. receivers; triode section as line-blocking oscillator, part of a multivibrator, sync separator, pulse amplifier or A.G.C. delay diode; pentode section with remote cut-off as video I.F. amplifier.

QUICK REFERENCE DATA							
Pentode section	1		-				
Anode current	Ia	13	mA				
Transconductance	S	12.6	mA/V				
Amplification factor	$\mu_{\mathrm{g_2g_1}}$	45	-				
Triode section							
Anode current	Ia	14	mA				
Transconductance	S	4.8	mA/V				
Amplification factor	μ	17.5	-				
Cathode peak current	I_{k_p}	max. 50	mA				

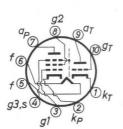
HEATING: Indirect by A.C. or D.C.; series supply

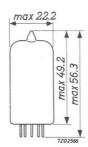
Heater current Heater voltage $\frac{I_{\rm f}}{V_{\rm f}} = \frac{300 \quad \text{mA}}{8.5 \quad \text{V}}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Decal





CAPACITANCES				
Pentode section				
Anode to all except grid No.1	$C_{a(g_1)}$	3.3	pF	
Grid No.1 to all except anode	Cg ₁ (a)	6.0	pF	
Grid No.1 to cathode	C_{kg_1}	3.7	pF	
Anode to grid No.1	C_{ag_1} C_{ag_1}	0.0056 max. 0.008	pF pF	
Grid No.1 to grid No.2	$C_{g_1g_2}$	1.7	pF	
Triode section				
Anode to all except grid	Ca(g)	3.0	pF	
Grid to all except anode	Cg(a)	2.1	pF	
Anode to grid	C_{ag}	2.0	pF	
Between pentode and triode sections				
Pentode anode to triode anode	C_{aPaT}	max. 0.015	pF	
Pentode grid No.1 to triode anode	C_{g_1PaT}	max.0.0012	pF	
Pentode grid No.1 to triode grid	C_{g_1PgT}	max.0.0015	pF	
TYPICAL CHARACTERISTICS				
Pentode section				
Anode voltage	V_a	160	V	
Grid No.3 voltage	v_{g_3}	0	V	
Grid No.2 voltage	v_{g_2}	110	V	
Grid No.1 voltage	v_{g_1}	-1.4	V	
Anode current	Ia	13	mA	
Grid No.2 current	I_{g_2}	5.3	mA	
Transconductance	S	12.6	mA/V	
Amplification factor	$\mu_{g_2g_1}$	45	-	
Triode section				
Anode voltage	Va	100	V	
Grid voltage	Vg	-2	V	
Anode current	Ia	14	mA	
Transconductance	S	4.8	mA/V	
Amplification factor	μ	17.5	-	

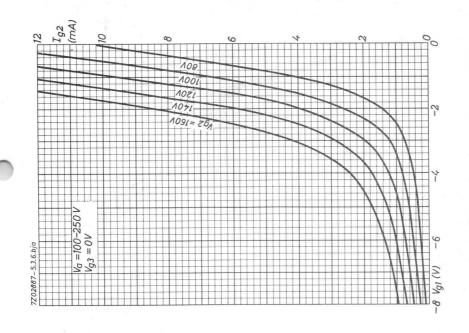
OPED	ATING	CHARA	CTERIST	POL
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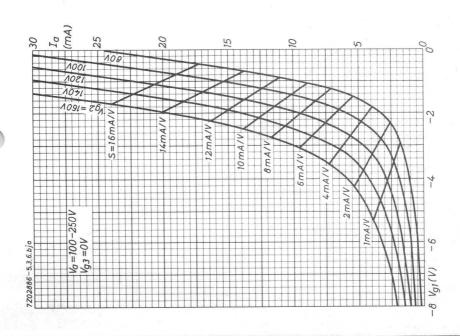
Supply voltage	V_{b}	210	230	250	V
Anode resistor	Ra	3.9	5.6	6.8	$k\Omega$
Grid No.2 resistor	R_{g_2}	18	22	27	$k\Omega$
Cathode resistor	R_k	79	79	76	Ω
Anode current	Ia	13.2	13.2	12.8	mA
Grid No.2 current	I_{g_2}	5.4	5.4	5.2	mA
Transconductance	S	12.6	12.6	12.6	mA/V
Grid No.1 voltage at 0.1 S	v_{g_1}	-5.1	-5.4	-5.7	V
Grid No.1 voltage at 0.01 S	v_{g_1}	-19	-20.5	-22	V
Grid No.1 input resistance at 40 MHz	r_{g_1}	7.4	7.4	7.4	$k\Omega$
Triode section as line-blocking oscillate	or				
Anode voltage			Va	30	V
Peak cathode current			I_{k_D}	40	mA
Peak anode current			I_{a_p}	25	mA
Peak grid current			I_{g_p}	15	mA
Triode section as sync. separator					
Anode supply voltage			V _{ba} 130	to 150	V
Anode resistor			Ra	33	$k\Omega$
Grid current			I_g	1	μ A
Anode current				min. 2	mA

LIMITING VALUES (Design centre rating system)

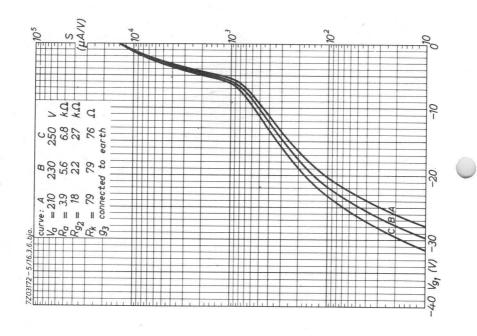
Pentode section				
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	W_a	max.	2.1	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Grid No.2 dissipation	w_{g_2}	max.	0.7	W
Grid No.1 resistor	R_{g_1}	max.	1	$M\Omega$
Cathode current	I_k	max.	20	mA
Cathode to heater voltage	V_{kf}	max.	150	V
Triode section				
Anode voltage	v_{a_0}	max.	550	V
	Va	max.	250	V
Anode dissipation	w_a	max.	1.5	W
Grid resistor	Rg	max.	1	ΜΩ
Cathode current	I_k	max.	18	mA
Peak cathode current	$I_{k_{D}}$	max.	50	mA^{1})
Cathode to heater voltage	$v_{\rm kf}$	max.	150	V

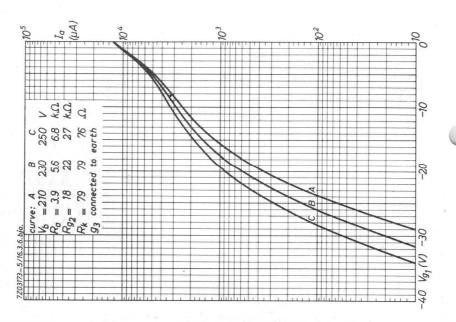
 $[\]overline{^{1})}$ Maximum pulse duration 10% of a cycle but max. 10 $\mu \mathrm{s}.$



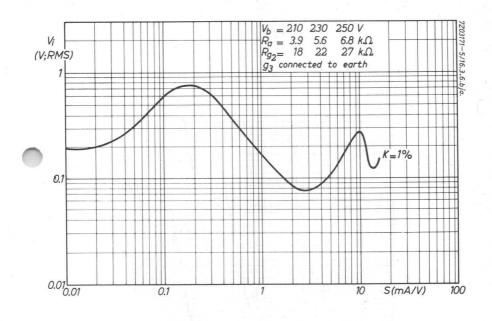


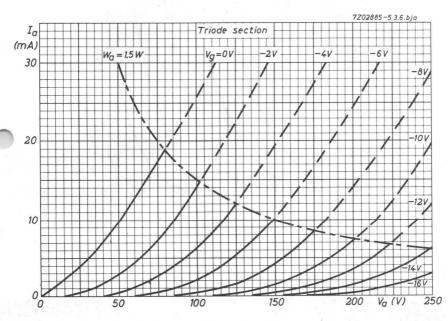
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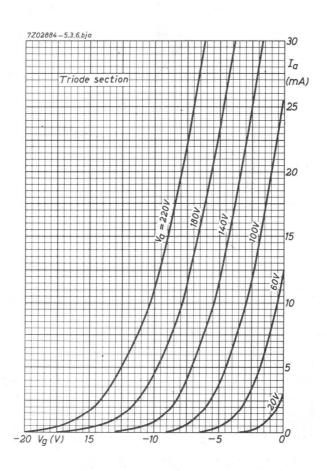


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December 1969



TRIODE-PENTODE

High transconductance triode and R.F. pentode intended for use as frequency changer in V.H.F. T.V. tuners.

QUICK REFERENCE DATA						
Pentode section						
Anode current	Ia 10	mA				
Transconductance	S 11	mA/V				
Amplification factor	$\mu_{g_2g_1}$ 55	- 100				
Internal resistance	R _i min. 350	$k\Omega$				
Triode section						
Anode current	I _a 15	mA				
Transconductance	S 9	mA/V				
Amplification factor	μ 20	-				

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

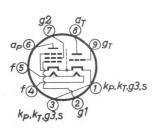
Heater voltage

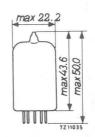
I_{f}		0.3	Α
\overline{V}_1	Ē	8.5	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES (with external shield)			
Pentode section			
Grid No.1 to all except anode	$C_{g_1(a)}$	5.9	pF
Anode to all except grid No. 1	$C_{a(g_1)}$	3.7	pF
Anode to grid No.1	${^{\mathrm{C}_{\mathrm{ag}}}}_{1}$	0.009 max. 0.012	pF pF
Grid No.1 to grid No.2	$c_{g_1g_2}$	1.6	pF
Triode section			
Grid to all except anode	$C_{g(a)}$	3.3	pF
Anode to all except grid	$C_{a(g)}$	1.7	pF
Anode to grid	C_{ag}	1.8	pF
Between pentode and triode sections			
Pentode anode to triode anode	C_{aPaT}	max. 0.025	pF
Pentode anode to triode grid	C_{aPgT}	max. 0.010	pF
Pentode grid No.1 to triode anode	C_{g1PaT}	max. 0.010	pF
Pentode grid No.1 to triode grid	$C_{g_{\mathrm{1PgT}}}$	max. 0.010	pF
TYPICAL CHARACTERISTICS			
Pentode section			
Anode voltage	v_a	170	V
Grid No.2 voltage	v_{g_2}	120	V
Grid No.1 voltage	v_{g_1}	-1.4	V
Anode current	Ia	10	mA
Grid No.2 current	I_{g_2}	3	mA
Transconductance	S	11	mA/V
Internal resistance	Ri	min. 350	$k\Omega$
Amplification factor	$\mu_{g_2g_1}$	55	
Equivalent noise resistance	Req	1.5	$k\Omega$

TYPICAL	CHARACTERISTICS	(continued)

Anode voltage	v_a	100	V
Grid voltage	v_g	-3	V
Anode current	I_a	15	mA
Transconductance	S	9	mA/V
Amplification factor	μ	20	-

OPERATING CHARACTERISTICS

Pentode section as I.F. amplifier

	Anode supply voltage	V _{ba}		200	V	
	Grid No.2 supply voltage	v_{bg_2}		200	V	
	Grid No.2 resistor	R_{g_2}		27	kΩ	
	Anode resistor	R_a	2.7	4.7	$\mathbf{k}\Omega$	
	Grid No.1 supply voltage	v_{bg_1}	-1.4	0	V	
	Grid No.1 resistor	R_{g_1}	0.1	1	$M\Omega$	
	Anode current	I_a	10	13	mA	
	Grid No.2 current	I_{g_2}	3.0	3.9	mA	
	Transconductance	S	11	14.5	mA/V	
	Input resistance at 50 MHz	r_{g_1}	10	10	$k\Omega$	
	Grid No.1 voltage	v_{g_1}	-12			
h	Transconductance	S	0.11	-	mA/V	

OPERATING CHARACTERISTICS (continued)

Pentode section as mixer

Anode supply voltage	V_{ba}	2	00	V	
Grid No.2 supply voltage	v_{bg_2}	2	00	V	
Grid No.2 resistor	R_{g_2}		27	$k\Omega$	
Anode resistor	Ra	2.7	4.7	$k\Omega$	
Grid No.1 supply voltage	v_{bg_1}	-1.4	0	V	6
Grid No.1 resistor	R_{g_1}	0.1	1	$M\Omega$	-
Oscillator voltage	V_{osc}	1.6	1.6	V.(RMS)	
Anode current	I_a	10	9.3	mA	
Grid No.2 current	I_{g_2}	3.0	2.9	mA	
Grid No.1 current	I_{g_1}	8	2.3	μ A	
Conversion conductance	S_{c}	5	4.7	mA/V	

OPERATING CHARACTERISTICS

Triode section as oscillator

Anode supply voltage	V_{b_a}	20	0	V	
Grid resistor	Rg	1	0	$k\Omega$	
Anode resistor	Ra	8.2	12	$k\Omega$	
Oscillator voltage	v_{osc}	4.5	3.3	V(RMS)	
Anode current	I_a	16	12	mA	
Effective transconductance (without higher harmonics)	Seff	3.7	3.7	mA/V	

LIMITING VALUES (Design centre rating system)

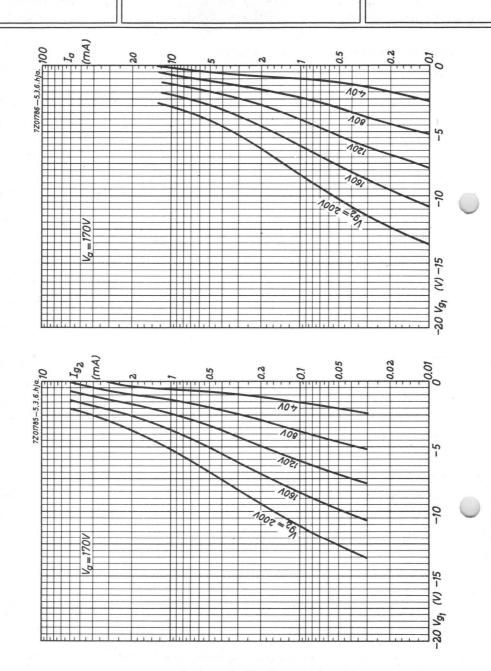
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Pentode section				
Anode voltage	v_{a_0}	max.	550	V
	Va	max.	250	V_{s}
Anode dissipation	Wa	max.	2.0	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
Grid No.2 supply voltage	V_{bg_2}	max.	250	V
Grid No.2 voltage	v_{g_2}	max.	250	V
Grid No.2 dissipation	See page	10		
Grid No.1 voltage	$-v_{g_1}$	max.	50	V
Grid No.1 resistor, fixed bias	R_{g_1}	max.	1	$M\Omega$
automatic bias	R_{g_1}	max.	2.2	ΩM
Cathode current	I_k	max.	18	mA
Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	100	V^{1})
Triode section				
Anode voltage	V_{a_0}	max.	550	V
Anode supply voltage	V_{b_a}	max.	250	V
Anode voltage	Va	max.	125	V
Anode dissipation	W_a	max.	1.5	W
Grid voltage	-Vg	max.	50	V
Grid resistor	Rg	max.	0.5	$M\Omega$
Cathode current	I_k	max.	20	mA

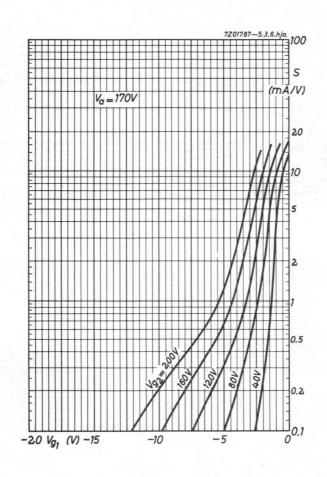
Cathode to heater voltage

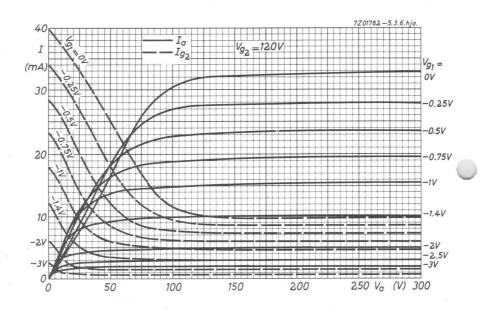
max. 100 V^{1})

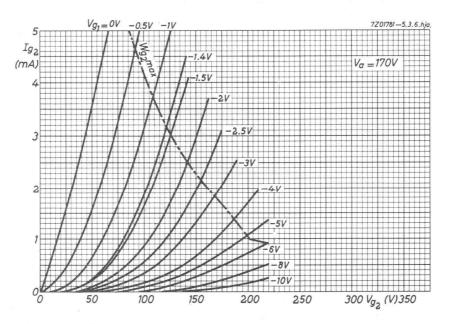
 V_{kf}

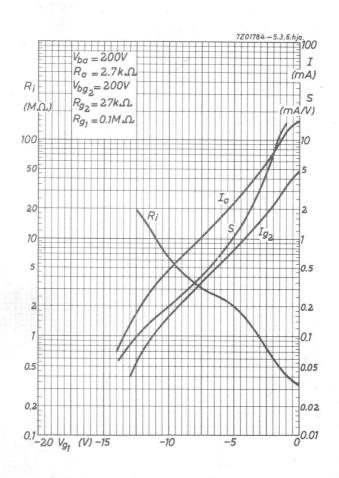
 $^{^1)}$ To fulfil the modulation hum requirements in intercarrier receivers, the voltage between heater and cathode should not exceed 100 V (RMS). With respect to modulation hum in A.M. sound receivers the voltage between heater and cathode should not exceed 50 V (RMS).



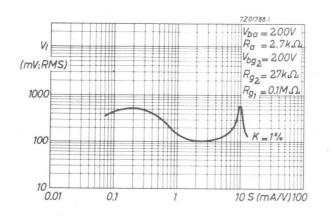


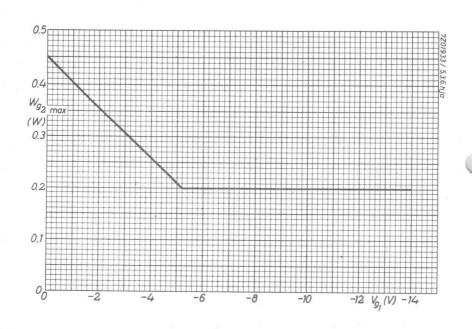


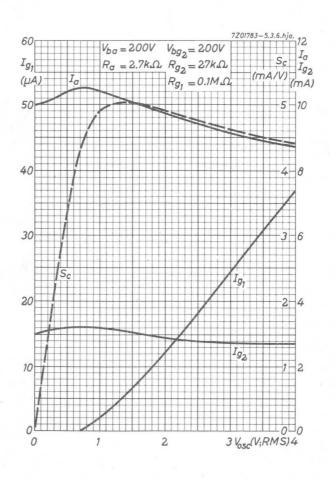




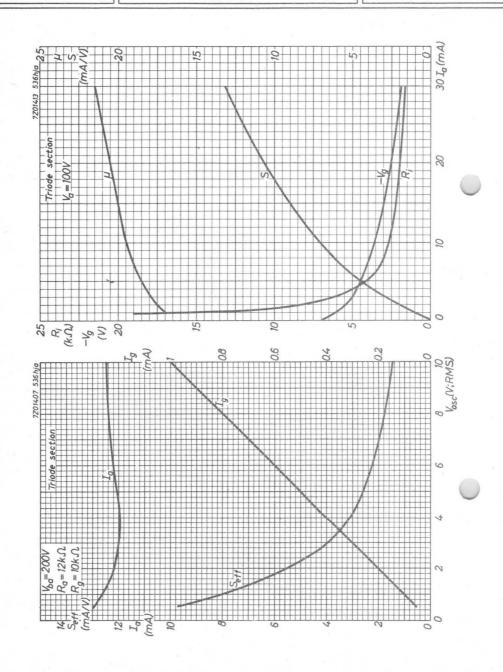
January 1970







January 1970



TRIODE-PENTODE

Triode pentode; triode section intended for use as reactance tube, pentode section intended for use as sine wave oscillator or pulse shaper in television receivers.

QUICK REFERENCE DATA						
Pentode section						
Anode current		Ia	6	mA		
Transconductance		S	5.5	mA/V		
Amplification factor		$\mu_{\mathrm{g_2g_1}}$	47	-		
Internal resistance		Ri	400	kΩ		
Triode section						
Anode current		Ia	3.5	mA		
Transconductance		S	3.5	mA/V		
Amplification factor		μ	70	-		

 $\ensuremath{\mathsf{HEATING}}\xspace$: Indirect by A.C. or D.C.; series supply

Heater current

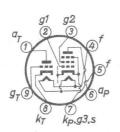
Heater voltage

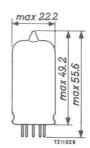
If	300	mA		
V_{f}	9	V		

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES

Pentode	section
---------	---------

Grid No.1 to all except anode	$c_{g_1(a)}$		5.4	pF	
Anode to grid No.1	C_{agl}		0.06	pF	
Grid No.1 to heater	C_{g_1f}	max.	0.1	pF	
Triode section					
Grid to all except anode	Cg(a)		2.4	pF	
Anode to grid	C_{ag}		1.5	pF	
Grid to heater	C_{gf}	max.	0.1	pF	

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	v_a	100	100	200	100	V
Grid No.2 voltage	v_{g_2}	100	100	200	100	V
Grid No.1 voltage	v_{g_1}	-1	0	max16	max1.3	V
Anode current	Ia	6	12.5	0.01	-	mA
Grid No.2 current	I_{g_2}	1.7	3.5		-	mA
Transconductance	S	5.5	-	-	-	mA/V
Internal resistance	R_i	400	-	_	-	$k\Omega$
Amplification factor	$\mu_{g_2g_1}$	47	-	-	_	-
Grid No.1 current	I_{g_1}	-	-	-	0.3	μ A
Triode section						
Anode voltage	v_a	200		200	200	V
Grid voltage	v_g	-2		_	max1.3	V
Anode current	Ia	3.5		10	_	mA
Transconductance	S	3.5		- ,	_	mA/V
Internal resistance	R_{i}	20		-	_	$k\Omega$
Amplification factor	μ	70		-	_	-
Grid current	I_g	-		10	0.3	μ A

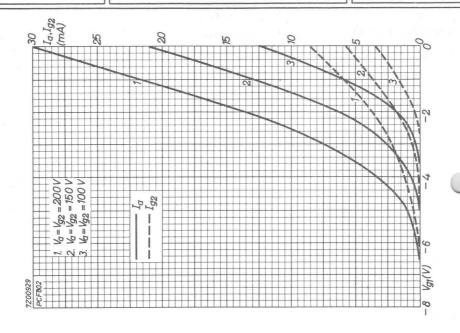
LIMITING VALUES (Design centre rating system)

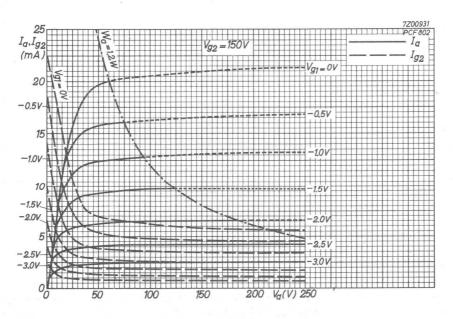
Pentode section				
Anode voltage	V_{a_0}	max.	550	V
	Va	max.	250	V
Anode dissipation	Wa	max.	1.2	W
Grid No.2 voltage	v_{g2o}	max.	550	V 1)
	v_{g2}	max.	250	V
Grid No.2 dissipation	w_{g_2}	max.	0.8	W
Grid No.1 voltage	-Vg1	max.	220	V^{1})
Grid resistor, fixed bias	R_{g1}	max.	0.56	$M\Omega$
automatic bias	R_{g_1}	max.	1	$\mathrm{M}\Omega$
Cathode current, average	I_k	max.	15	mA
peak $T_{\text{imp}} = \text{max. } 30 \ \mu\text{s}, \ \delta = \text{max. } 0.3$	I_{kp}	max.	50	mA
Cathode to heater voltage	v_{kf}	max.	100	V^2)
Grid circuit impedance	Z_{g1} (f = 50 Hz)	max.	300	$k\Omega^{-2}$)
Triode section				
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	W_a	max.	1.4	W
Grid resistor, fixed bias	Rg	max.	3	$M\Omega$
Cathode current	$I_{\mathbf{k}}$	max.	10	mA
Cathode to heater voltage	v_{kf}	max.	100	V ³)
Grid circuit impedance	Z_g (f = 50 Hz)	max.	50	$k\Omega^{3}$)

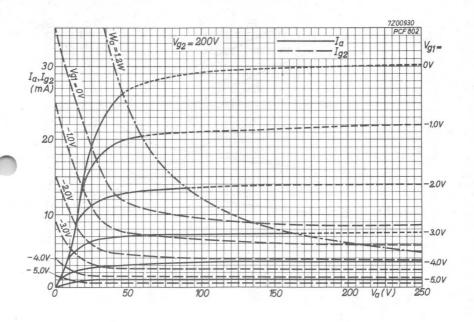
 $^{^{\}rm l})$ The instantaneous voltage between grid No.1 and grid No.2 should never exceed 550 V.

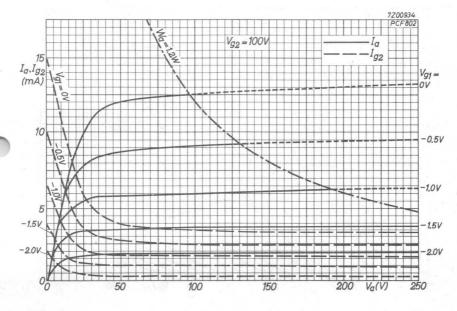
 $^{^2)}$ To avoid hum interference the A.C. component of $\rm V_{kf}$ should not exceed 65 V at the specified value of $\rm Z_{g1}$.

 $^{^3)}$ To minimise hum interference decoupling of R_k is recommended. Incircuits with undecoupled R_k the hum interference between grid and cathode will remain below $1000~\mu\text{V}$ when the A.C. component of V_{kf} does not exceed 25 V and the R_k is not higher than 1.2 $k\Omega$ at the specified value of Z_g .

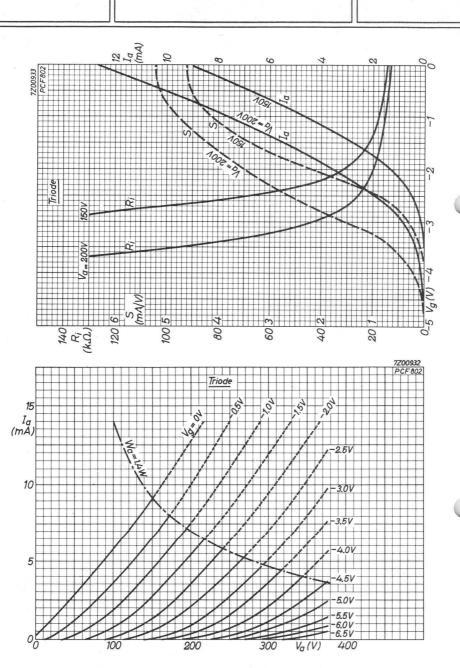








November 1969



TRIODE-HEPTODE

Triode-heptode; triode section intended for use as pulse amplifier and heptode section for use as noise gated sync. separator.

QUICK REFERENCE DATA						
Triode section						
Anode current		I_a		9		mA
Transconductance		S		8.8		mA/V
Amplification factor		μ		50		-
Heptode section						
Grid No.1 voltage		v_{g_1}	0	-1.8	0	V
Grid No.3 voltage		v_{g_3}	0	0	-1.8	V
Anode current		Ia	1500	20	20	μΑ

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

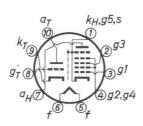
Heater voltage

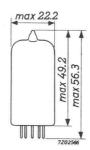
If	300	mA
$V_{\mathbf{f}}$	8.5	V

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: decal





PCH200

CAL ACITATIONS	CAPA	CITA	NCES
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CAPACITANCES				
Heptode section				
Grid No.1 to all except anode	$C_{g_1}(a)$	4.4	pF	
Anode to all except grid No.1	$C_{a(g_1)}$	5.4	pF	
Anode to grid No.1	C_{ag_1}	max. 0.1	pF	
Anode to grid No.3	C_{ag_3}	max. 0.25	pF	
Grid No.1 to grid No.3	$C_{g_1g_3}$	0.3	pF	
Triode section				
Grid to all except anode	Cg (a)	3.3	pF	
Anode to all except grid	Ca (g)	1.7	pF	
Anode to grid	Cag	1.8	pF	
Between heptode and triode sections				
Heptode grid No.1 to triode grid	$C_{g_1}H_gT$	max. 0.005	pF	
Heptode grid No.1 to triode anode	C_{g_1} HaT	max. 0.010	pF	
Heptode grid No.3 to triode grid	C_{g_3HgT}	max. 0.020	pF	
Heptode anode to triode anode	СаНаТ	max. 0.150	pF	

TYPICAL	CHARA	CTERISTICS

Triode section

Anode voltage	v_a	100	200	V
Anode current	I_a	9.0	0.1	mA
Grid voltage	v_g	-1	-7(<11)	V
Transconductance	S	8.8	-	mA/V
Amplification factor	μ	50		- 1

Heptode section

Anode voltage	v_a	14	14	14	V
Grids No.2 and 4 voltage	v_{g_2,g_4}	14	14	14	V
Grid No.3 voltage	v_{g_3}	0	0	-1.8(<2.2)) V
Grid No.1 voltage	v_{g_1}	0	-1.8	0	V
Anode current	Ia	1500	20	20	μA
Grids No.2 and 4 current	$I_{g_2+g_4}$	1300	-	-	μ A

OPERATING CHARACTERISTICS

Anode voltage

Heptode section as sync. separator

Grids No.2 and 4 voltage	v_{g_2,g_4}	14	14	14	14	V
Grid No.3 voltage	v_{g_3}		-	+25	-1.9(<2.3)	V
Grid No.1 voltage	v_{g_1}	-	-	-2	-	V
Anode current	Ia	750	>300	20	20	μ A
Grid No.3 current	I_{g_3}	1	1	-	-	μA
Grid No.1 current	I_{g_1}	100	100	-	100	μ A

V_a 14 1 14 14

PCH200

LIMITING VALUES (Design centre rating system)

Environd VALOES (Design centre rating	sy stelli)				
Triode section					
Anode voltage	V_{a_0}	max.	550	V	
	Va	max.	250	V	
Anode dissipation	Wa	max.	1.5	W	
Cathode current	I_k	max.	20	mA	
Grid resistor (fixed bias)	R_g	max.	2	$M\Omega$	
(automatic bias)	Rg	max.	3	$M\Omega$	
Grid voltage, negative peak	-V _{gp}	max.	200	V	
Cathode to heater voltage	$v_{ m kf}$	max.	70 +100	$_{ m V_{RMS}}^{ m 1)}$	
Heptode section					
Anode voltage	V_{a_0}	max.	550	V	
	Va	max.	100	V	
Grids No.2 and 4 voltage	$V_{(g_2, g_4)_0}$	max.	550	V	
	V_{g_2,g_4}	max.	50	V^2)	
Anode dissipation	Wa	max.	0.5	W	
Grids No.2 and 4 dissipation	$W_{g_2+g_4}$	max.	0.5	W	
Cathode current	I_k	max.	8	mA	
Grid No.1 resistor	R_{g_1}	max.	3	ΜΩ	
Grid No.3 resistor	R_{g_3}	max.	3	$M\Omega$	
Grid No.1 voltage, negative peak	-v _{glp}	max.	100	V	
Grid No.3 voltage, negative peak	-V _{g3p}	max.	150	V	
	оэр		. 00	**	

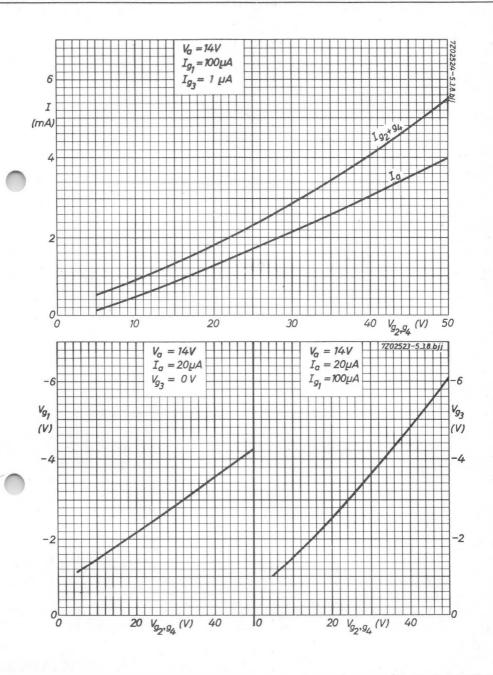
Cathode to heater voltage

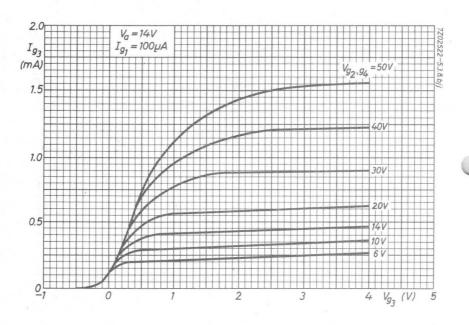
 v_{kf}

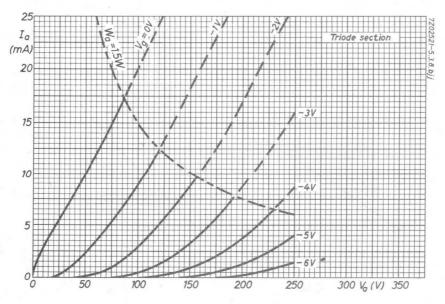
max. 100 V

 $^{^{}m l}$) Cathode positive with respect to heater.

²⁾ The grids No.2 and 4 voltage should not be less than 6 V with an average tube under the worst probable operating conditions.







TRIODE-OUTPUT PENTODE

The triode section is intended for use as frame oscillator and A.F. amplifier. The pentode section is intended for use as frame output tube and A.F. power amplifier.

QUICK REFERENCE DATA						
Triode section						
Anode current	Ia	3.5	mA			
Transconductance	S	2.2	mA/V			
Amplification factor	μ	70	-			
Pentode section						
Anode peak voltage	V _{ap} ma	x. 2.5	kV			
Anode current	Ia	41	mA			
Transconductance	S	7.5	mA/V			
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	9.5				
Output power	Wo	3.3	W			

HEATING: Indirect by A.C. or D.C.; series supply

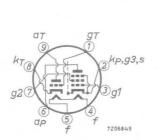
Heater current

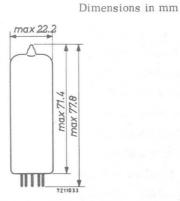
Heater voltage

I_{f}	300	mA
$\overline{v_f}$	16	V

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES				
Triode section				
Anode to all except grid	Ca(g)	4.3	pF	
Grid to all except anode	$C_{g(a)}$	2.7	pF	
Anode to grid	C_{ag}	4.4	pF	
Grid to heater	C_{gf}	max. 0.02	pF	
Pentode section				
Anode to all except grid No.1	$C_{a(g_1)}$	8.0	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$	9.3	pF	
Anode to grid No.1	C_{ag_1}	max. 0.3	pF	
Grid No.1 to heater	c_{g_1f}	max. 0.3	pF	
Between triode and pentode sections				
Anode triode to grid No.1 pentode	CaTg ₁ P	max. 0.02	pF	
Grid triode to anode pentode	C_{gTaP}	max. 0.02	pF	
Grid triode to grid No.1 pentode	CgTg ₁ P	max.0.025	pF	
Anode triode to anode pentode	СаТаР	max. 0.25	pF	
TYPICAL CHARACTERISTICS				
Triode section				
Anode voltage	Va	100	V	
Grid voltage	V_g	0	V	
Anode current	Ia	3.5	mA	
Transconductance	S	2.2	mA/V	
Amplification factor	μ	70	-	
Pentode section				
Anode voltage	Va	170	V	
Grid No.2 voltage	v_{g_2}	170	V	
Grid No.1 voltage	v_{g_1}	-11.5	V	
Anode current	Ia	41	mA	
Grid No.2 current	I_{g_2}	9	mA	
Transconductance	S	7.5	mA/V	
Amplification factor	$\mu_{\rm g2g1}$	9.5	-	
Internal resistance	Ri	16	$k\Omega$	

OPERATING CHARACTERISTICS

Triode	section	as A	A.F.	amplific	er
--------	---------	------	------	----------	----

11	rode section as A.F. ampinie	31					
Α.	Signal source resistance		Rs		0.	22	$M\Omega$
	Grid resistor		Rg			3	$M\Omega$
	Grid resistor of next stage		Rg	*	0.	68	$M\Omega$
	Supply voltage		v_b		200	170	V
	Cathode resistor		R_k		2.2	2.7	$k\Omega$
	Anode resistor		Ra		220	220	$k\Omega$
)	Anode current		Ia		0.52	0.43	mA
	Voltage gain			$/V_i^{-1}$)	52	51	-
	Max. output voltage		V_{C}	max	26	25	V_{RMS}
	Distortion		dto	ot 2)	1.6	2.3	%
В.	Signal source resistance	Rs		0.	22		ΜΩ
	Grid resistor	Rg			22		$M\Omega$
	Grid resistor of next stage	Rg'		0.	68		$M\Omega$
	Supply voltage	V_b	200	200	170	170	V
	Cathode resistor	$R_{\mathbf{k}}$	0	0	0	0	Ω
	Anode resistor	Ra	100	220	100	220	$k\Omega$
	Anode current	I_a	1.05	0.61	0.86	0.50	mA
	Voltage gain	V_{o}/V_{i}^{1}	50	55	49	53	_
	Max. output voltage	Vo max	24	25	19	20	v_{RMS}
	Distortion	d _{tot} 3)	1.5	1.4	1.4	1.4	%

MICROPHONY AND HUM

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage $V_i \geq 10~\text{mV}_{RMS}$ gives an output of 50 mW of the output stage. Z_g (50 Hz) = 0.25 MΩ. The A.C. voltage between pin 4 and cathode should not exceed 6.3 V. If the tube is used in television circuits where the frequency of the heater supply is not synchronized with the frame frequency, this may cause interference due to hum. At page 8 the relation is shown between the permissible value of Z_{g_1} of the pentode section and the A.C. voltage between pin 4 and the cathode. This curve applies to $C_{g1}f$ is 0.8 pF (inclusive of wiring and tube socket).

¹⁾ Measured at small input voltage

²⁾ At lower output voltages the distortion is proportionally lower.

 $^{^3)}$ At lower output voltages down to 5 $V_{R\,MS}$ the distortion remains approximately constant. At values below 5 $V_{R\,MS}$ the distortion is approximately proportional to V_{O} .

OPERATING CHARACTERISTICS

Pentode	section
---------	---------

A.F. power amplif	ier, cla	ass A	(mea	sured	with	V _k co	onstant)				
Supply voltage Vba	=V _{bg2}		170			200			230		V	
Grid No.2 series resistor (non- decoupled)	R_{g_2}		0			470			1200		Ω	
Cathode resistor	Rk		200			330			490		Ω	
Load resistance	$R_{a\sim}$		3.25			4.5			6		$k\Omega$	1
Grid No.1 driving voltage	v_i	0	0.61	5.9	0	0.66	6.7	0	0.75	7.8	v_{RMS}	
Anode current	Ia	42	-	44	35		37	30	-	31	mA	
Grid No.2 current	I_{g_2}	9.2	-	15.5	7.8	-	13.3	6.6	-	11.0	mA	
Output power	W_{O}	0	0.05	3.2	0	0.05	3.3	0	0.05	3.25	W	
Distortion	d_{tot}	-	-	10	-	-	10	-	~	10	%	

A.F. power amplifier, class AB, two tubes in push-pull

Anode supply voltage	V _{ba}	2	000	2	30	V
Grid No.2 supply voltage	v_{bg_2}	2	200	2	00	V
Common cathode resistor	R _k	1	70	Ż	00	Ω
Load resistance	R_{aa}	4	.5		7	$k\Omega$
Grid No.1 driving voltage	v_i	0	14.2	0	13.0	V _{RMS}
Anode current	I_a	2x35	2x42.5	2x30	2x34.5	mA
Grid No.2 current	I_{g_2}	2x8	2x16.5	2x6.2	2x13.5	mA
Output power	Wo	0	9.3	0	10	W
Distortion	d_{tot}	-	6.3	-	5.5	%

Frame output application

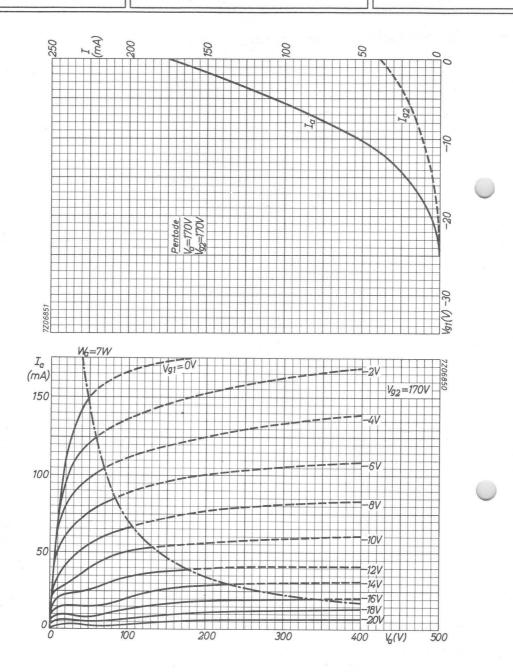
The circuit should operate satisfactorily with peak anode current $\rm I_{a_p}$ = 85 mA at $\rm V_a$ = 50 V, $\rm V_{g_2}$ = 170 V, $\rm I_f$ = 300 mA. The minimum available $\rm I_{a_p}$ value at end of life is

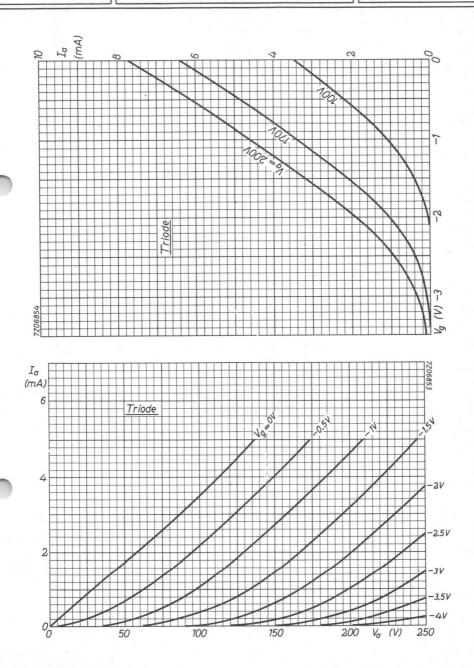
70 mA at
$$V_a$$
 = 50 V, V_{g_2} = 170 V, I_f = 280 mA 80 mA at V_a = 50 V, V_{g_2} = 190 V, I_f = 280 mA

LIMITING VALUES (Design centre rating system)

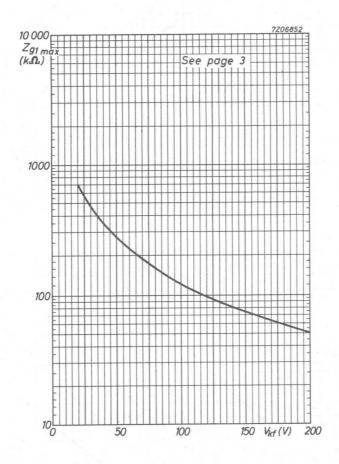
Triode section				
Anode voltage	V_{a_0}	max.	550	V
	Va	max.	250	V
Anode peak voltage	v_{a_p}	max.	600	V 1)
Anode dissipation	Wa	max.	1	W
Cathode current, average	I_k	max.	15	mA
peak	I_{k_p}	max.	100	mA 1)
Grid resistor, for fixed bias	Rg	max.	1	$M\Omega$
for automatic bias	R_g	max.	3	$M\Omega$
Grid impedance at 50 Hz	z_g	max.	0.5	ΩM
Cathode to heater voltage	v_{kf}	max.	200	V
Pentode section			V.	
Anode voltage	v_{a_0}	max.	550	V
	v _a	max.	250	V
Anode peak voltage, positive	v_{a_p}	max.	2.5	kV
negative	-Vap	max.	500	V
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Anode dissipation for frame output application	W_a	max.	5	W
for A.F. output application	W_a	max.	7	W
Grid No.2 dissipation, average	w_{g_2}	max.	1.8	W
average for frame output application (W_a max 4 W)	w_{g_2}	max.	2	W
peak	$W_{g_{2p}}$	max.	3.2	W
Cathode current	I_k	max.	50	mA
Grid No.1 resistor, for fixed bias	R_{g_1}	max.	1	$M\Omega$
for automatic bias	R_{g_1}	max.	2	ΜΩ
Cathode to heater voltage	v_{kf}	max.	200	V

 $[\]overline{\mbox{1}}$) Max. pulse duration 4% of a cycle with a maximum of 0.8 msec.





7



TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes.

Triode section intended for use in circuits for keyed A.G.C., sync. separation, sync. amplification and noise suppression.

Pentode section is intended for use as video output tube.

QUICK RI	EFERENCE DATA				. 81
Triode section			- 1		
Anode current		Ia		3	mA
Transconductance		S		4	mA/V
Amplification factor		μ		65	
Pentode section					
Anode current		Ia		18	mA
Transconductance		S		11	mA/V
Amplification factor		μ_{g_2g}	³ 1	36	-

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

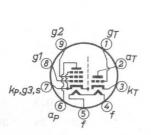
Heater voltage

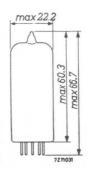
I_f	300	mA
$\overline{V_{\mathbf{f}}}$	15	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





_	Lancing Lancin	-			-		
			19				
	CAPACITANCES						
	Triode section						
	Anode to all except grid		Ca(g)		2.3	pF	
	Grid to all except anode		$C_{g(a)}$		3.8	pF	
	Anode to grid		C_{ag}		2.7	pF	
	Grid to heater		C_{gf}	max.	0.1	pF	
	Pentode section						
	Anode to all except grid No.1		$C_{a(g_1)}$		4.2	pF	
	Grid No.1 to all except anode		$C_{g_1(a)}$		8.7	pF	
	Anode to grid No.1		C_{ag_1}	max.	0.1	pF	
	Grid No.1 to heater		C_{g_1f}	max.	0.1	pF	
	Between triode and pentode sections						
	Anode triode to grid No.1 pentode		$C_{a_Tg_{1P}}$	max.	0.01	pF	
	Grid triode to grid No.1 pentode		$C_{g_Tg_{1P}}$	max.	0.01	pF	
	TYPICAL CHARACTERISTICS						
	Triode section						
	Anode voltage	Va			200	V	
	Grid voltage	Vg			-1.7	V	
	Anode current	I_a			3	mA	
	Transconductance	S			4	mA/V	
	Amplification factor	μ			65	- ,	
	Pentode section						
	Anode voltage	v_a	170	200	220	V_	
	Grid No. 2 voltage	v_{g_2}	170	200	220	V	
	Grid No. 1 voltage	v_{g_1}	-2.1	-2.9	-3.4	V	
	Anode current	Ia	18	18	18	mA	
	Grid No.2 current	I_{g_2}	3.0	3.0	3.0	mA	
	Transconductance	S	11	10.4	10	mA/V	

 $\mu_{\mathrm{g}2\mathrm{g}1}$

 $R_{i\,min}$

Amplification factor

Internal resistance

36

130

36

150 kΩ

36

100

OPERATING CHARACTERISTICS

Pentode section

Video output tube	
Supply voltage	V_b
Grid No. 2 voltage	$V_{\sigma_{\mathbf{Q}}}$

Grid No. 2 voltage	v_{g_2}	170	200	220	V	
Anode series resistor	Ra	3	3	3	$k\Omega$	
Grid No.1 voltage	v_{g_1}	- 2	-2.8	-3.3	V	
Anode current	I_a	18	18	18	mA	

170

200

220 V

Anode current I_a 18 18 mA Grid No.2 current I_{g_2} 3.2 3.1 3.1 mA Transconductance S 10.4 10.0 9.7 mA/V

LIMITING VALUES (Design centre rating system)

Triode section				
Anode voltage	V_{a_0}	max.	± 550	V
	Va	max.	± 300	V
Anode peak voltage (I _{a max.} 0.1 mA)	Vap	max.	600	V^{1})
Anode dissipation	Wa	max.	1	W
Cathode current	$I_{\mathbf{k}}$	max.	12	mA
Grid resistor, for fixed bias	Rg	max.	1	$M\Omega$
for automatic bias	Rg	max.	3	$M\Omega$
Cathode to heater voltage, cathode neg.	v_{kf}	max.	150	V
cathode pos.	v_{kf}	max.200 V =	+150	VRMS
Pentode section				
Anode voltage	v_{a_0}	max.	550	V

Va 300 V max. Grid No.2 voltage $V_{g_{20}}$ 550 V max. v_{g_2} 250 V max. Anode dissipation W_a 4 W max. Grid No. 2 dissipation Wg2 1.7 W max. Cathode current I_k 40 mA max. Grid No. 1 resistor, for fixed bias Rg₁ 1 M Ω max. for automatic bias Rg_1 $2 M\Omega$ max.

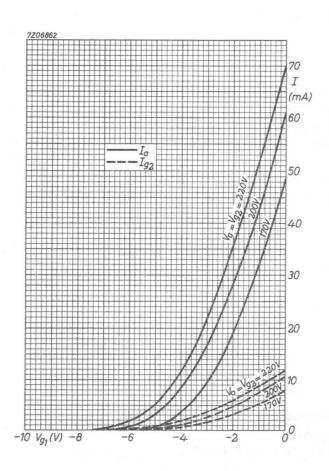
 V_{kf}

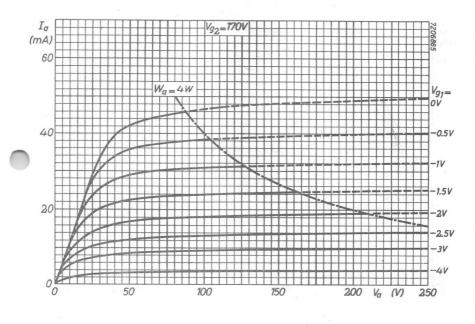
max.

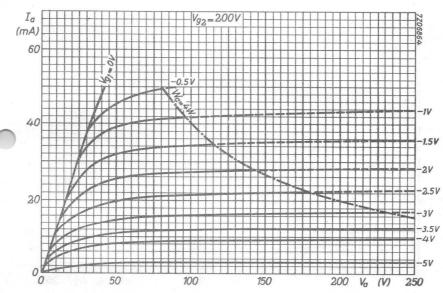
Cathode to heater voltage

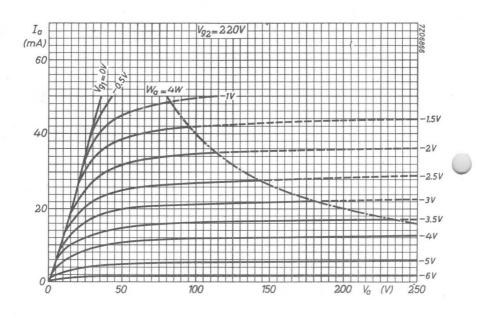
200 V

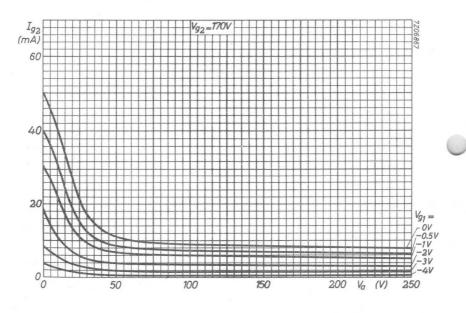
 $^{^{1})\,\}mathrm{Max.}$ pulse duration 18% of a cycle with a maximum of 18 $\mu\mathrm{sec.}$

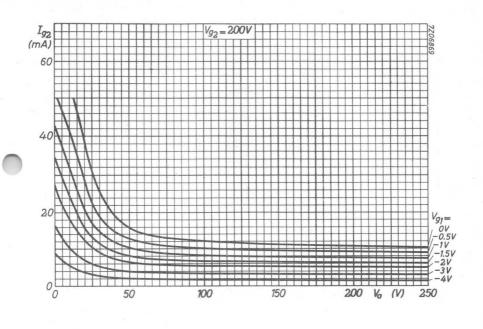


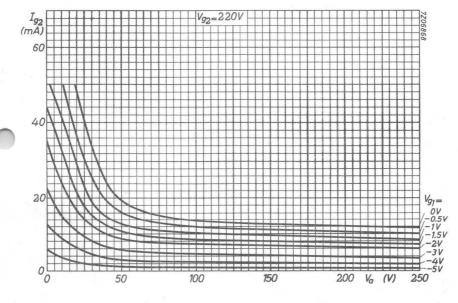


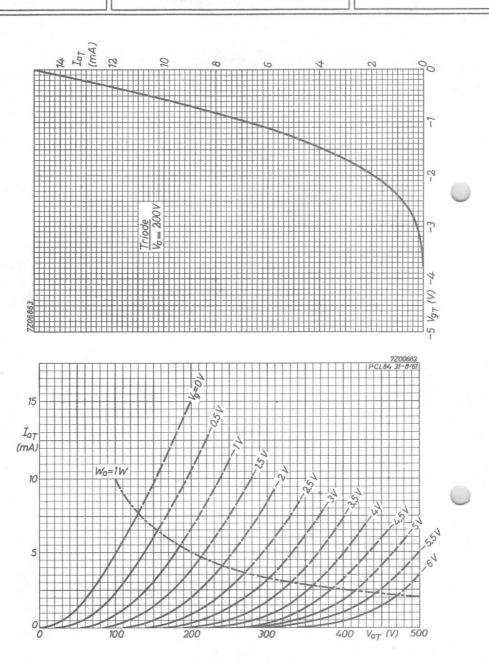












TRIODE-FRAME OUTPUT PENTODE

Triode-pentode with separate cathodes. Triode intended for use as frame oscillator or pulse amplifier.

Pentode intended for use as frame output tube.

QUICK REF	ERENCE DATA	100
Triode section		
Anode current	I _a 10.5	mA
Transconductance	S 7	mA/V
Amplification factor	μ 63	-
Cathode peak current	I _{kp} max. 150	mA
Pentode section		
Anode peak voltage	Vap max. 2	kV
Cathode current	I _k max. 75	mA
Anode dissipation	W _a max. 8	W

HEATING: Indirect by A.C. or D.C.; series supply

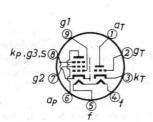
Heater current

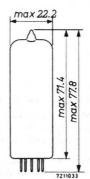
Heater voltage

$I_{\mathbf{f}}$	300	mA
$\overline{v_f}$	17.5	V

DIMENSIONS AND CONNECTIONS

Base: Noval





Dimensions in mm

PCL85 PCL805

CAPACITANCES

Grid triode to anode pentode	$C_{g_{\mathrm{T}^{a_{\mathrm{P}}}}}$	max.	0.05	pF
Grid triode to heater	C_{g_Tf}	max.	0.15	pF
Grid No.1 pentode to anode pentode	$C_{g_{1}p^{a}p}$	max.	1.0	pF
Grid No.1 pentode to anode triode	$C_{g_{1p}a_{T}}$	max.	0.08	pF
Grid No.1 pentode to heater	$C_{g_{1p^f}}$	max.	0.20	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	v_a	100	100	V
Grid voltage	v_g	-0.85	0	V
Anode current	I_a	5	10.	5 mA
Transconductance	S	5.5	7.0	mA/V
Amplification factor	μ	60	63	-
Internal resistance	R_i	11	9	$\mathbf{k}\Omega$

OPERATING CHARACTERISTICS

Pentode section

Frame output application

Anode voltage	v_a	50	65	V
Grid No.2 voltage	v_{g_2}	170	210	V
Grid No.1 voltage	v_{g_1}	-1	-1	V
Anode peak current	I_{a_p}	200	285	mA
Grid No.2 peak current	$I_{g_{2p}}$	35	45	mA

Remarks

The minimum $\rm I_{a_p}$ value to be expected as a result of spread of the tube characteristics, tube deterioration during life and decrease of the mains voltage to 10% below the nominal value, can be derived from the curves on page 9 by decreasing by 40% the $\rm I_a$ values of curve A-B at the $\rm V_{g_2}$ value occuring at the decreased mains voltage.

In order not to exceed the maximum permissible value of W_{g2} , the circuit should be designed such that at a mains voltage of 10% below nominal, V_a at the end of scan will not be lower than the value determined by curve A-B at the relevant V_{g2} value.

HUM

The equivalent pentode grid hum voltage without negative feedback is max.10 mV when Z_{g_1} (at f = 50 Hz) \leq 0.5 M Ω , C_{g_1} -f = 0.2 pF and V_{kf} = 150 V_{RMS} .

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	300	V
Anode dissipation	W_a	max.	0.5	W
Cathode current				
average	$I_{\mathbf{k}}$	max.	15	mA
peak	$I_{\mathbf{k_p}}$	max.	150	mA 1)
peak	$I_{\mathbf{k_p}}$	max.	100	mA^{2})
Grid resistor	P			
for fixed bias	$R_{\mathbf{g}}$	max.	1	$M\Omega$
for automatic bias	$R_{\mathbf{g}}$	max.	3.3	$M\Omega$
Cathode to heater voltage	$V_{\mathbf{kf}}$	max.	200	V^{3}

Remark

A cathode peak current of $100\ \mathrm{mA}$ will be available throughout life and at underheating.

 $^{^{1}}$) Max. pulse duration 2% of a cycle with a maximum of $400~\mu sec.$

 $^{^2)\,\}mathrm{Max}$. pulse duration 4% of a cycle with a maximum of $800~\mu\mathrm{sec}$.

 $^{^3}$) During warming up the D.C. component of V_{kf} = max. 315 V, k pos.

PCL85 PCL805

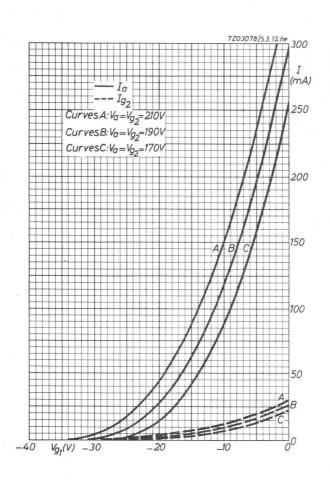
LIMITING VALUES (continued)

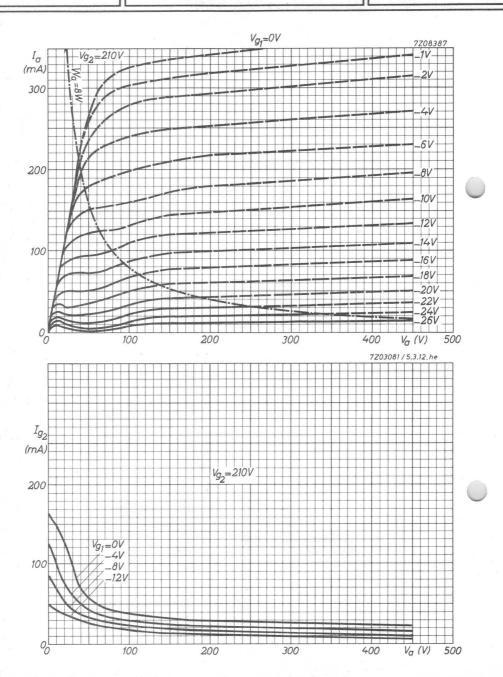
Pentode section					
Anode voltage		V_{a_0}	max.	550	V
		v_a	max.	300	V
Anode peak voltage		v_{a_p}	max.	2	kV^1)
Grid No.2 voltage		$v_{g_{2o}}$	max.	550	V
		v_{g_2}	max.	250	V
Anode dissipation		W_a	max.	8	W^{2})
Grid No.2 dissipation		W_{g_2}	max.	1.5	W^3)
Cathode current		Ik	max.	75	mA
Grid No.1 resistor					
for fixed bias		R_{g_1}	max.	1.0	$\mathrm{M}\Omega$
for automatic bias		R _{g1}	max.	2.2	$M\Omega$
Cathode to heater voltage		Vkf	max.	200	V

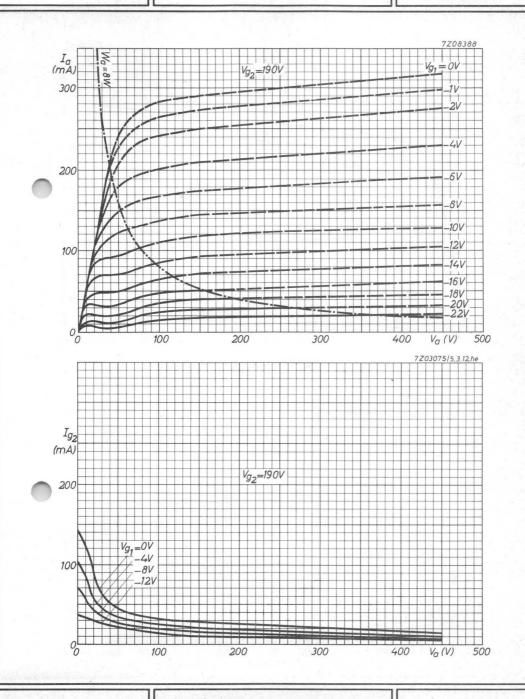
 $^{^{\}rm 1})\,{\rm Max.}$ pulse duration 5% of a cycle with a maximum of 1 ms.

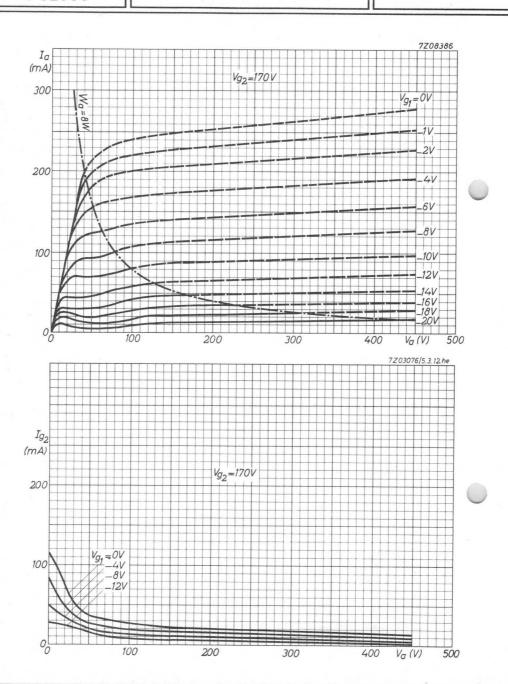
 $^{^2)\,} For a nominal tube at the worst probable operating conditions and at normal picture height <math display="inline">W_a$ should not exceed 10.5 W.

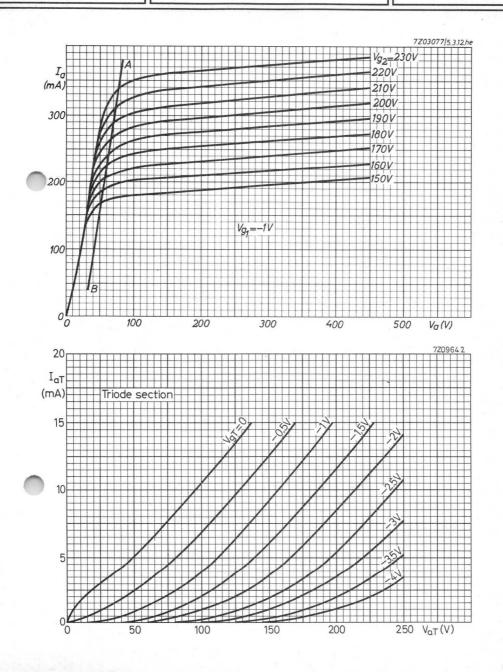
 $^{^3}$) For a nominal tube at the worst probable operating conditions and at normal picture height W_{g_2} should not exceed 2 W.

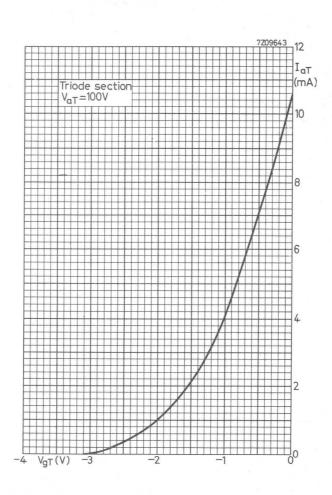












TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes.

The triode section is intended for use as A.F. amplifier.

The pentode section is intended for use as A.F. power amplifier.

QUICK REFERENCE DATA					
Triode section				a:	
Anode current			Ia	1.2	mA
Transconductance			S	1.6	mA/V
Amplification factor			μ	100	_
Pentode section					
Anode current			I_a	39	mA
Transconductance			S	10.5	mA/V
Amplification factor			μ_{g2g1}	21	-
Output power			Wo	4.1	W

HEATING: Indirect by A.C. or D.C.; series supply

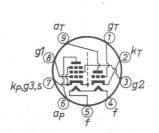
Heater current

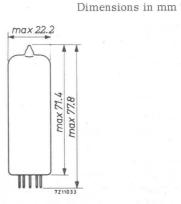
Heater voltage

$I_{\mathbf{f}}$	300	mA
$\overline{v_{f}}$	13.3	V

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES				
Triode section				
Anode to all except grid	$C_{a(g)}$	2.5	pF	
Grid to all except anode	Cg(a)	2.3	pF	
Anode to grid	Cag	1.4	pF	
Grid to heater	C_{gf}	max. 0.006	pF	
Pentode section	0			
Grid No.1 to all except anode	$C_{g_1(a)}$	10	pF	
Anode to grid No.1	C_{ag_1}	max. 0.4	pF	6
Grid No.1 to heater	C_{g_1f}	max. 0.24	pF	
Between triode and pentode sections				
Anode triode to grid No.1 pentode	$C_{a_Tg_{1P}}$	max. 0.2	pF	
Grid triode to grid No.1 pentode	C_{gTg_1P}	max. 0.02	pF	
Anode triode to anode pentode	$C_{a_{\mathrm{T}}a_{\mathrm{P}}}$	max. 0.15	pF	
Grid triode to anode pentode	$C_{g_{T}a_{P}}$	max. 0.006	pF 1)	
TYPICAL CHARACTERISTICS	OI I			
Triode section				
Anode voltage	Va	230	V	
Grid voltage	Vg	-1.7	V	
Anode current	Ia	1.2	mA	
Transconductance	S	1.6	mA/V	
Amplification factor	μ	100		
Pentode section				
Anode voltage	Va	230	V	
Grid No.2 voltage	v_{g_2}	230	V	
Grid No.1 voltage	v_{g_1}	-5. 7	V	
Anode current	la	39	mA	
Grid No. 2 current	Ig_2	6.5	nA	
Transconductance	S	10.5	mA/V	
Amplification factor	$\mu_{\mathrm{g}_2\mathrm{g}_1}$	21		
To a control of the c	D	4	10	

 R_i

Internal resistance

45 k Ω

 $^{^{\}rm I})$ The capacitance between triode grid and pentode anode (CgT-ap) can be reduced to a value of less than 0.002 pF by using a shielding ring with a diameter of 22.5 mm and a height of 15 mm with respect to the tube base.

OPERATING CHARACTERISTICS

Triode section

A.F. amplifie	er
---------------	----

Supply voltage	V_{b}		200	230	200	230	V
Cathode resistor	$R_{\mathbf{k}}$		0	0	2.6	2.1	kΩ
Anode resistor	R_a		220	220	220	220	$k\Omega$
Grid resistor	R_{g}		10	10	-	-	$M\Omega$
Grid resistor of following stage	Rg'		680	680	680	680	$k\Omega$
Signal source resistance	R_{s}		47	47	-	-	$k\Omega$
Anode current	Ia		0.42	0.52	0.42	0.52	mA
Output voltage	V_{o}		3.2	3.2	3.2	3.2	V_{RMS}
Voltage gain	V_0/V	i	66	68	66	68	
Distortion	d_{tot}		0.6	0.5	0.6	0.5	%

Microphony

The triode section can be used without special precautions against microphonic effect in circuits in which an output of 50 mW is obtained at an input voltage of not less than 10 $\rm mV_{RMS}$.

Hum

The hum level will be better than 60 dB under the following conditions;

Input voltage minimum 10 mV $_{RMS}$ for 50 mW output. Grid circuit impedance max. 0.5 M Ω at 50 Hz.

Cathode decoupling capacitor minimum 100 μ F.

Pin 4 connected to earth.

A.C. voltage between pin 4 and cathode max. 30 V_{RMS}.

OPERATING CHARACTERISTICS

Pentod	le section

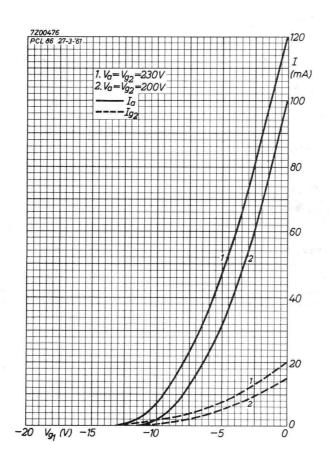
Class A (Measured with V_k constant)

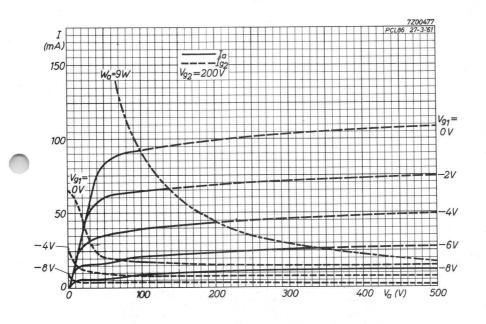
v_a	200	230	V
v_{g_2}	200	230	V
$R_{\mathbf{k}}$	115	125	Ω
v_{g_1}	-4.7	-5.7	V)
$R_{a_{ \sim}}$	5.6	5.1	kΩ
v_i	0 0.32 3.	2 0 0.34	3.6 V _{RMS}
I_a	35 - 3	4 39 -	40.7 mA
I_{g_2}	6.0 - 9.	0 6.5 -	10.5 mA
W_{o}	0 0.05 3.	0 0.05	4.1 W
d_{tot}	- 0.9 1	0 - 0.9	10 %
	V_{g_2} R_k V_{g_1} R_a V_i I_a I_{g_2} V_o	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

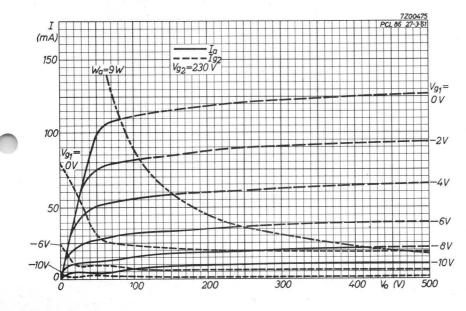
LIMITING VALUES (Design centre rating system)

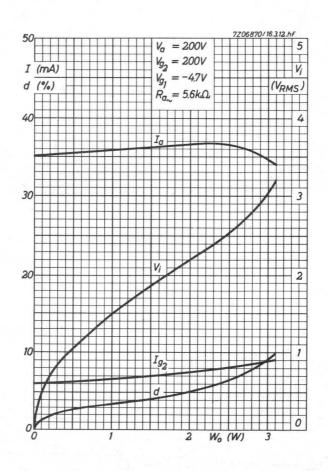
	THOUGE SECTION				
	Anode voltage	v_{ao}	max.	550	V
		Va	max.	300	V
	Anode dissipation	W_a	max.	0.5	W
	Cathode current	$I_{\mathbf{k}}$	max.	4	mA
	Grid resistor	Rg	max.	1	$M\Omega^{1}$)
)	Cathode to heater voltage	V _{kf}	max.	100	V
	Pentode section				
	Anode voltage	V_{a_0}	max.	550	V
		Va	max.	300	V
	Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
• /		v_{g_2}	max.	300	V
	Anode dissipation	W_a	max.	9	W
	Grid No.2 dissipation, average	Wg2	max.	1.8	W
	peak	$w_{g_{2p}}$	max.	3.25	W
	Cathode current	Ik	max.	55	mA
	Grid No.1 resistor, for automatic bias	R_{g_1}	max.	1	$M\Omega$
	Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	100	V

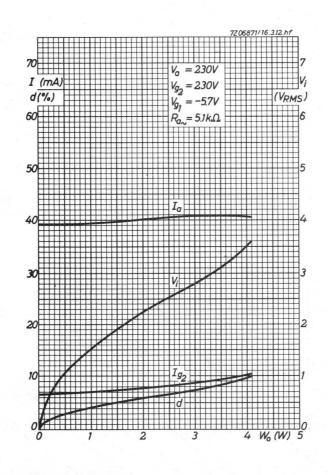
 $^{^1)\,} This \ value applies to operation with fixed bias. It may be multiplied by the D.C. inverse feedback factor resulting from e.g. cathode or anode resistors to a maximum of <math display="inline">10\ M\Omega$.

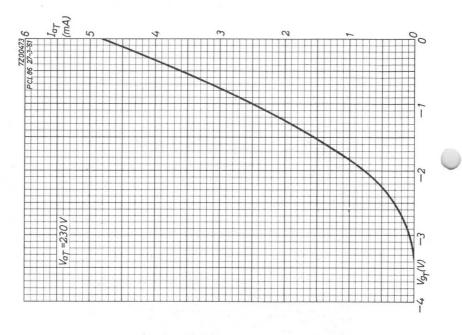


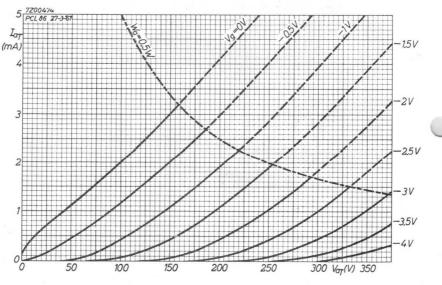












SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use as in colour TV receivers.

	QUICK REFERENCE DATA				
Anode voltage	8	Va		25	kV
Anode current		I_a	max.	1.6	mΑ

HEATING: Indirect by A.C. or D.C.; series supply

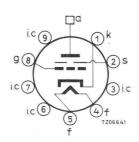
Heater current

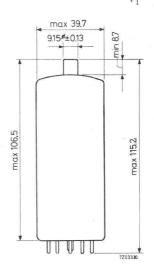
Heater voltage

I_f 300 mA V_f 7.3 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm
Base: Magnoval
Top cap: Type 2





Mounting: Additional supporting of the tube at the top is required.

To prevent corona-effects any metal screening applied around the tube should be at least 5 cm from the nearest point of the bulb. Adequate ventilation should be provided for.

TYPICAL CHARACTERISTICS

Anode voltage	Va		25	ΚV
Screen voltage	V_{S}		0	V
Grid voltage change for an anode current change from 0.1 to 1.5 mA	ΔVg	max.	10	V
Grid voltage at $I_a = 1.5 \text{ mA}$	v_g	- 7 to	-30	V
at $I_a = 0.1 \text{ mA}$	V_g	max.	-40	V

LIMITING VALUES (Design centre rating system unless otherwise specified)

Anode voltage	v_a	max.	25	kV
Anode voltage (absolute max.)	Va	max.	27.5	kV 1)
Anode current	I_a	max.	1.6	mA
Anode dissipation	w_a	max.	30	W .
Anode dissipation (absolute max.)	W_a	max.	40	W^2)
Negative grid voltage	-Vg	max.	150	V^{3})
Grid resistor	Rg	max.	5	$\mathrm{M}\Omega$
Cathode to heater voltage				
cathode positive	$V_{\mathbf{k}\mathbf{f}}$	max. 400 V	DC +25	0 V _A C
cathode negative	$-v_{kf}$	max.	250	V
Screen voltage	V_s	max.	0	V
	$-V_S$	max.	400	V 4)
Anode seal temperature				
(absolute max.)	ts	max.	200	°C

Precaution: x-ray shielding may be required to give protection against excessive radiation.

¹⁾ If due to a circuit failure the anode current becomes 0 mA the anode voltage should never exceed 45 kV (abs. max.)

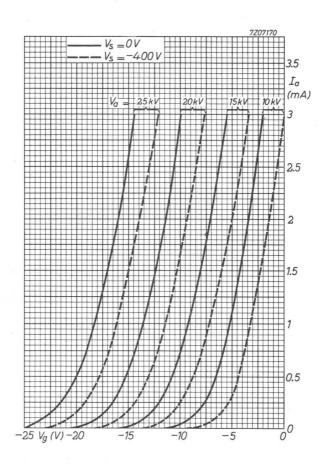
 $^{^2)}$ Permissible only during short periods; in total up to a maximum of 10% of the operation time of the tube.

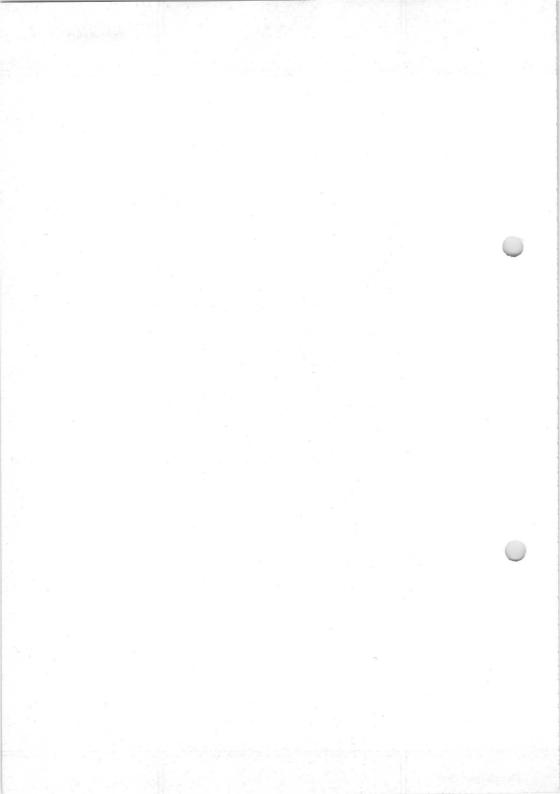
³⁾ During equipment warm-up and for brief interval during receiver adjustment this voltage may rise to 440 V max.

 $^{^4}$) The screen connected to pin 2 is provided to shield grid and cathode from the high anode voltage.

It is recommended to connect the screen directly to earth, with a minimum lead inductance.

The modulating influence of possible hum ripple of the screen to cathode voltage should be taken into account; the sensitivity for these variations in Vs/k is $2.5\,\mu\text{A/V}$ max.





SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use in colour TV receivers.

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

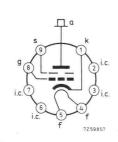
Heater voltage

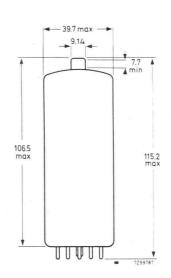
If	300	mA
$\overline{\mathrm{V_f}}$	7.3	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm.

Pase: Magnoval Fop cap: Type 2





Mounting: Additional supporting of the tube at the top is required. To prevent corona effects any metal screening applied around the tube should be at least 5 cm from the nearest point of the bulb. Adequate ventilation should be provided for.

TYPICAL CHARACTERISTICS

Anode voltage	v_a		25	kV
Screen voltage	V_s		0	V
Grid voltage change for an anode current change from 0.1 mA to 1.5 mA	ΔV_g	max.	10	V
Grid voltage at Ia = 1.5 mA	V_{g}	- 9 to	-28	V
at $I_a = 0.1 \text{ mA}$	Vg	max.	-38	V

Data based on pre-production tubes

LIMITING VALUES (Design centre rating system unless otherwise specified)

	Anode voltage	v_a	max.	25	kV
	Anode voltage (absolute max.)	v_a	max.	27.5	kV 1)
	Anode current	I_a	max.	1.6	mA
	Anode dissipation	Wa	max.	30	W
١	Anode dissipation (absolute max.)	w_a	max.	40	W^{2})
	Negative grid voltage	-Vg	max.	150	V 3)
	Grid resistor	R_g	max.	5	$M\Omega$
	Cathode to heater voltage				
	cathode positive	v_{kf}	max.	$400 \text{ V}_{DC} + 2$	$50 V_{ m AC}$
	cathode negative	$-v_{kf}$	max.	250	V
	Screen voltage	$^{\cdot}$ V_{S}	max.	0	V
		$-V_S$	max.	50	V 4)
	Anode seal temperature (absolute max.)	$t_{\mathbf{S}}$	max.	200	$^{ m o}{ m C}$

X-RAYS

When operating this tube will produce X-radiation, and a suitable screen may be required.

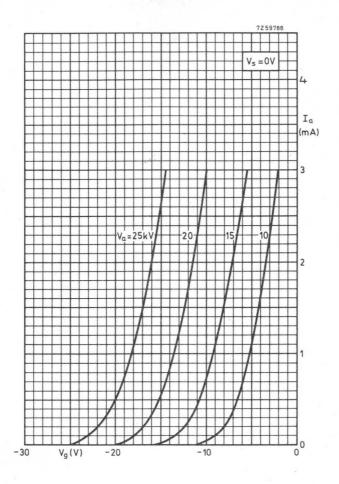
Because of the difference in X-ray characteristics the PD510 should never be replaced by a PD500 in equipment designed for the PD510.

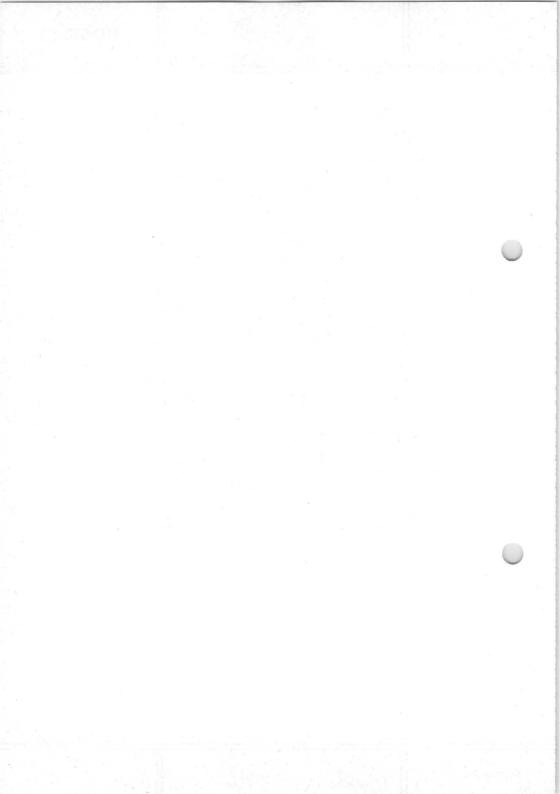
If due to a circuit failure the anode current becomes 0 mA the anode voltage should never exceed 45 kV (abs. max.)

 $^{^2}$) Permissible only during short periods; in total up to a maximum of 10% of the operation time of the tube.

³⁾ During equipment warm-up and for brief interval during receiver adjustment this voltage may rise to 440 V max.

⁴⁾ The screen connected to pin 9 is provided to shield grid and cathode from the high anode voltage. It is recommended to connect the screen directly to earth, with a minimum lead inductance.





PENTODE

Pentode intended for use in transitron circuits in television receivers.

QUICK REFER	RENCE DATA		
Anode current	Ia	3.0	mA
Transconductance	S	2.2	mA/V
Amplification factor	$^{\mu}$ g $_2$ g $_1$	38	-
Internal resistance	R_i	2.5	$M\Omega$

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

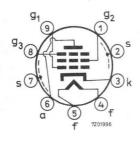
Heater voltage

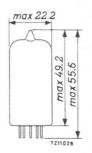
$I_{\mathbf{f}}$	300	mA
$\overline{V_f}$	4.5	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1
Grid No.1 except anode
Anode to grid No.1
Grid No.1 to heater

	5.1	pF
	3.5	pF
max.	0.07	pF
max.	0.03	pF

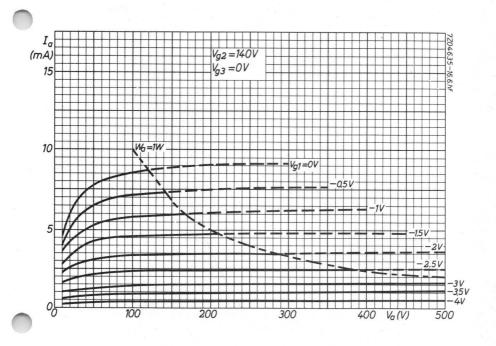
TYPICAL (CHARA	CTER	ISTICS
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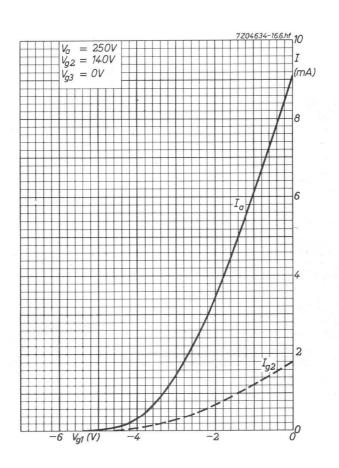
Anode voltage	v_a	100	250	V	
Grid No.3 voltage	v_{g_3}	-30	0	V	
Grid No.2 voltage	v_{g_2}	35	140	V	
Grid No.1 voltage	v_{g_1}	0	-2.2	V	
Anode current	I_a	max.0.01	3.0	mA	
Grid No.2 current	I_{g_2}		0.6	mA	
Transconductance	S		2.2	mA/V	
Amplification factor	$\mu_{g_2g_1}$		3 8	- 1	
Internal resistance	R_i		2.5	$M\Omega$	

LIMITING VALUES (Design centre rating system)

Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	300	V
Anode dissipation	W_a	max.	1	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	200	V
Grid No.2 dissipation	W_{g_2}	max.	0.2	W
Cathode current, average	$I_{\mathbf{k}}$	max.	4	mA
peak	I_{k_p}	max.	25	mA^{1})
Grid No.1 resistor ($W_a < 0.2 W$)	R_{g_1}	max.	10	$M\Omega$
$(W_a > 0.2 W)$	R_{g_1}	max.	3	$M\Omega$
Grid No.3 resistor	Rg3	max.	0.1	$M\Omega$
Cathode to heater voltage	$V_{\mathbf{kf}}$	max.	100	V

 $^{^{1}\}text{)}$ Max. pulse duration 4% of a cycle but max. 0.8 ms.





DOUBLE PENTODE

Double pentode intended for use as video output tube, sync. separator, A.G.C. amplifier or I.F. sound amplifier.

QUICK REFERE	ENCE DATA		
F section			
Anode current	I_a	10	mA
Transconductance	S	8.5	mA/V
Amplification factor	$^{\mu}$ g $_2$ g $_1$	38	-
Internal resistance	R_i	150	$k\Omega$
L section			
Anode current	I_a	30	mA
Transconductance	S	22	mA/V
Amplification factor	$^{\mu}$ g $_2$ g $_1$	38	-
Internal resistance	R _i	33	$k\Omega$

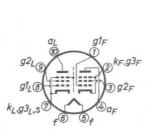
HEATING: Indirect by A.C. or D.C.; series supply

Heater current Heater voltage $\begin{array}{cccc} I_f & 300 & mA \\ \hline V_f & 17 & V \end{array}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Decal

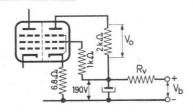




CAPACITANCES	L	section	F se	ection	1	
Anode to all except grid No.1	$C_{a}(g_{1})$	6.5	1	0.5	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$	12.5	1	0.5	pF	
Anode to grid No.1	C_{ag_1}	0.100	0	.15	pF	
Grid No.1 to heater	C_{g_1f}		max. 0	.15	pF	
Between the two pentode sections						
Anode L section to anode F section	$C_{a_L a_F}$		max. 0	.15	pF	
Grid No.1 L section to grid No.1 F section	$C_{g_1L}^{g_1}$		max. 0	.01	pF	0
Anode L section to grid No.1 F section	$C_{a_Lg_{1F}}$		max. 0	.10	pF	
Grid No.1 L section to anode F section	Cg _{1L} a _F		max. 0.	005	pF	
TYPICAL CHARACTERISTICS						
Output pentode (L section)						
Anode voltage		Va	170	V		
Grid No. 2 voltage		v_{g_2}	170	V		
Grid No.1 voltage		v_{g_1}	-2.7	V		
Anode current		I_a	30	m/	A	
Grid No. 2 current		I_{g_2}	7	m	A	
Transconductance		S	22	m	A/V	
Internal resistance		R_{i}	33	kΩ	?	
Amplification factor		$\mu_{g_2g_1}$	38	-		
Amplifier pentode (F section)						
Anode voltage		v_a	150	V		
Grid No.2 voltage		V_{g_2}	150	V		
Grid No.1 voltage		v_{g_1}	-2.1	V		
Anode current		I_a	10	m	A.	
Grid No.2 current		I_{g_2}	3.0	m	A	
Transconductance		S	8.5	m	A/V	
Internal resistance		R_{i}	150	kΩ	2	
Amplification factor		$\mu_{g_2g_1}$	38	-		

OPERATING CHARACTERISTICS

Output pentode (L section) as video output tube



Supply voltage $\mbox{ V}_{\mbox{b}}$ = 210 230 V Series resistor R $_{\mbox{v}}$ = 390 820 Ω R $_{\mbox{v}}$ should be added to avoid excessive dissipation

Input voltage (peak to peak)

Output voltage (peak to peak)

$$V_{ip-p} = 3.6 \text{ V}$$
 $V_{op-p} = 100 \text{ V}$

Amplifier pentode (F section)

		Sync Separa		A.G.C amplif			F. difier
Supply voltage	V _b 200	to 250	V				
Anode resistor	R_a	50	$k\Omega$				
Anode voltage	v_a			100 to 150	V	150	V
Grid No. 2 voltage	V_{g_2}	75	V	60	V	150	V
Grid No.1 resistor	Rg ₁	1	$M\Omega$				
Grid No.1 voltage	v_{g_1}	-2.7	V	-1.5	V	-2.1	V
Anode current	I_a	0.1	mA	1	mA	10	mA
Transconductance	S	0.2	mA/V	2.0	mA/V	8.5	mA/V

PFL 200

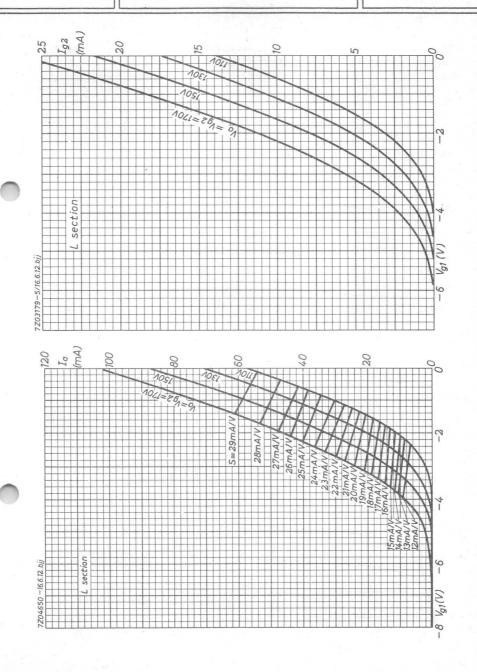
LIMITING VALUES (Design centre rating system)

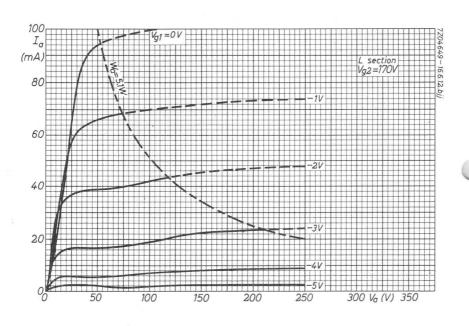
Zania viazeno (zenga entre zenga)				
Output pentode (L section)				
Anode voltage	V_{a_0}	max.	550	V
	Va	max.	250	V
Anode dissipation	Wa	max.	5.1	W
Grid No.2 voltage	$v_{g_{20}}$	max.	550	V
	v_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	2.5	W^1)
Grid No.1 resistor	Rg ₁	max.	1	$M\Omega$
Cathode current	I_k	max.	60	mA^2)
Cathode to heater voltage	v_{kf}	max.	200	V
Amplifier pentode (F section)				
Anode voltage, peak ($I_a < 0.1 \text{ mA}$)	v_{a_p}	max.	600	V^3)
	V_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	Wa	max.	1.5	W
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.5	W
Grid No.1 resistor	Rg ₁	max.	1	ΩM
Cathode current	$I_{\mathbf{k}}$	max.	15	mA
Cathode to heater voltage	v_{kf}	max.	200	V

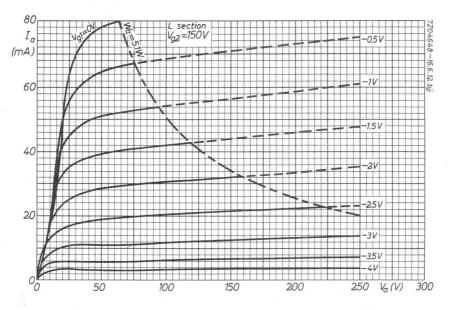
 $^{^{1}\}text{)}$ During short periods $\text{W}_{\text{g}_{2}}$ = max. 3.2 W

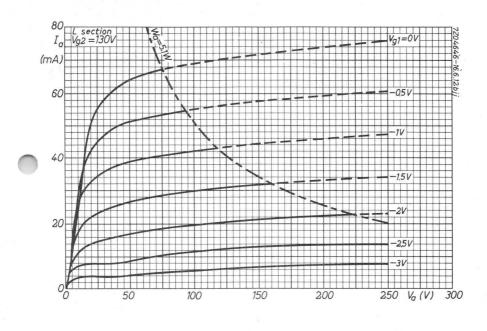
 $^{^{2}}$) During short periods I_{k} = max. 85 mA

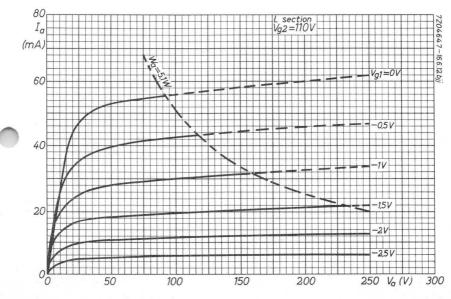
 $^{^3)\,\}mathrm{Max.}$ pulse duration 18% of a cycle, with a max. of 18 $\mu\mathrm{sec.}$

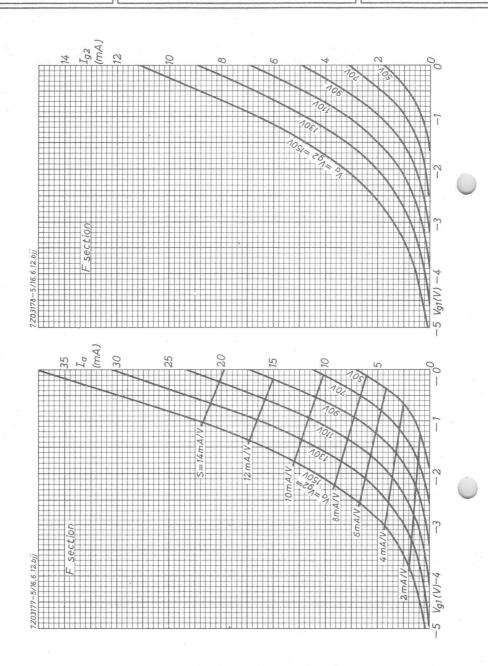


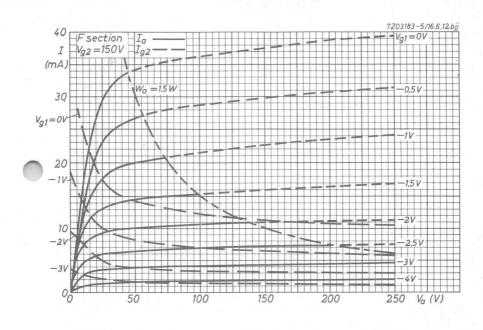


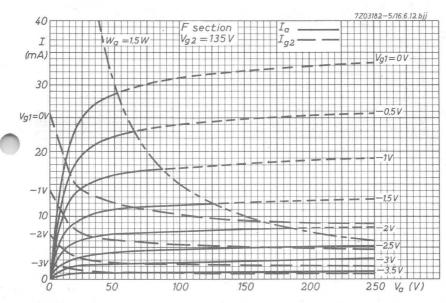




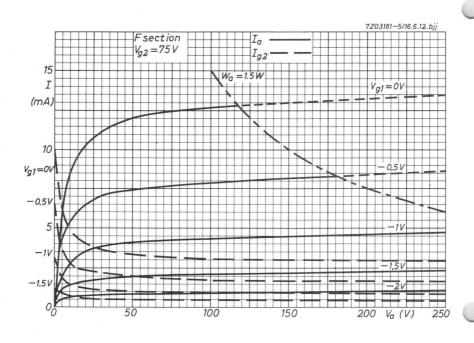








9



LINE OUTPUT PENTODE

Pentode intended for use as line output tube in television receivers.

QUICK REFER	RENCE DATA			
Anode peak voltage	Vap	max.	7	kV
Cathode current	$I_{\mathbf{k}}$	max.	200	mA
Drive at $V_{a_p} = 7 \text{ kV}$		min.	120	V

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

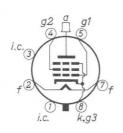
Heater voltage

$I_{\mathbf{f}}$	300	mA		
$\overline{v_f}$	25	V		

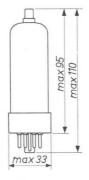
DIMENSIONS AND CONNECTIONS

Base: Octal

Top cap: Type 1



Dimensions in mm



CAPACITANCES

Anode to all except grid No.1 Grid No.1 to all except anode

Anode to grid No.1

$$C_{a(g_1)}$$
 8 pF
 $C_{g_1(a)}$ 17.5 pF
 C_{ag_1} max. 1.1 pF

TYPICAL CHARACTERISTICS

Anode voltage		v_a	100	V	
Grid No.2 voltage		v_{g_2}	100	V	
Grid No.1 voltage		v_{g_1}	-8.2	V	
Anode current		Ia	100	mA	
Grid No.2 current		I_{g_2}	7	mA	
Transconductance		S	14	mA/V	
Amplification factor		$\mu_{g_2g_1}$	5.6		(
Internal resistance		R_{i}	5	$k\Omega$,

REMARKS

On pages D to M curves are given for nominal new tubes. On designing a line output circuit it has to be taken into account that due to tube spread and deterioration during life the current may be reduced by 25%.

When the tube is operated below the knee of its $I_a\text{-}V_a$ characteristic the screen grid series resistor must have a minimum value of 2.2 k Ω to avoid the occurrence of Barkhausen oscillations.

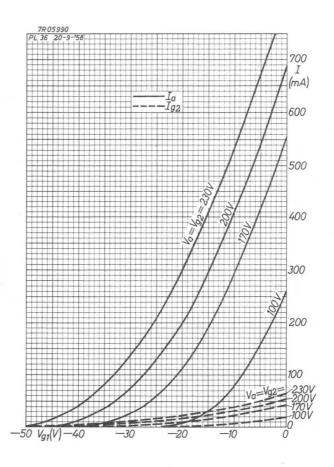
The min. drive at
$$\rm V_{ap}$$
 = 5 kV is 100 V and at $\rm V_{ap}$ = 7 kV $\,$ 120 V

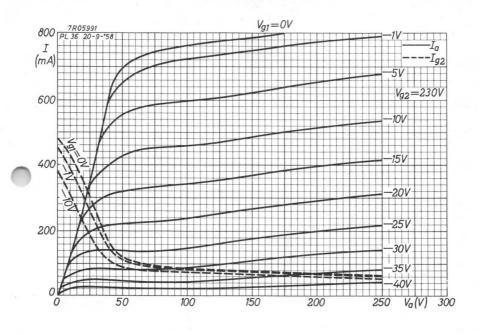
LIMITING	VALUES	(Design	centre	rating	system)	
THAIL LILY	VALUES	(Degign	CCIICLE	Tarring	By BLCIII)	

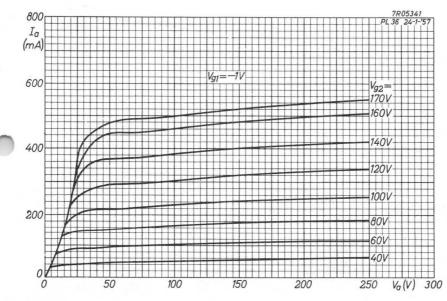
	, 0				
	Anode voltage	v_{ao}	max.	550	V
		v_a	max.	250	V
	Anode peak voltage				
	positive	V_{ap}	max.	7	kV^{1})
	negative	-V _{ap}	max.	1.5	kV^{1})
	Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
		v_{g_2}	max.	250	V
7	Grid No.1 peak voltage	$v_{g_{1p}}$	max.	1	kV ¹)
	Anode dissipation	w_a			
	Grid No.2 dissipation	W_{g_2}	See pa	age 7	
	Anode + grid No. 2 dissipation	Wa+Wg2			
	Cathode current	$I_{\mathbf{k}}$	max.	200	mA
	Grid No.1 resistor	R_{g_1}	max.	0.5	$M\Omega^2$)
	Cathode to heater voltage				
	A.C. value	V_{kf}	max.	250	V _{RMS}
	D.C. value, k pos.	v_{kf}	max.	250	V
	D.C. value, k neg.	v_{kf}	max.	200	V

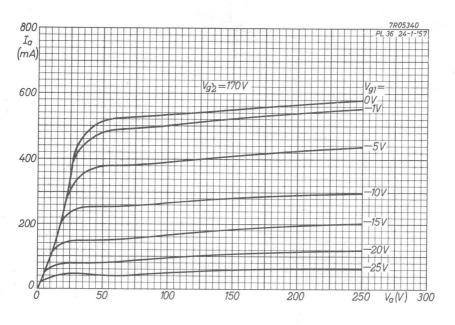
 $^{^1)}$ Valid for application in line output circuits where the max. pulse duration is 22% of a cycle with a max. of 18 $\mu s.$

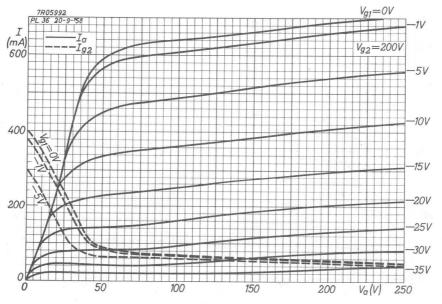
 $^{^2)\;\}mathrm{Rg}_1$ = max. 2.2 $\mathrm{M}\Omega$ for line output application only.

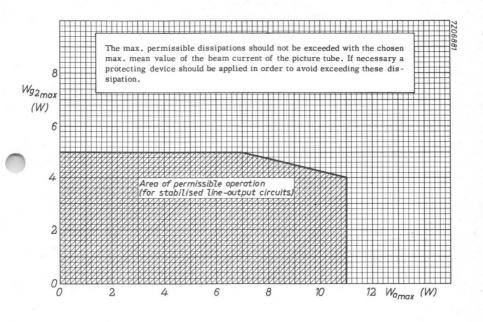


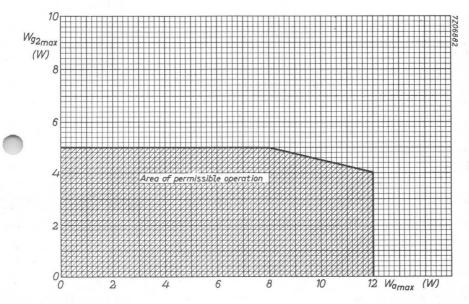


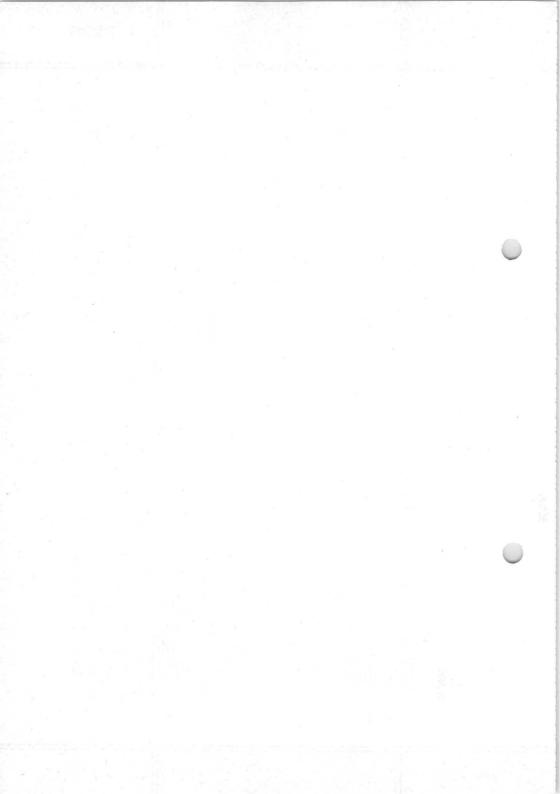












OUTPUT PENTODE FOR LINE DEFLECTION

Output pentode intended for use as horizontal deflection amplifier in small screen television receivers.

	QUICK REFERE	NCE DATA		5.7 5	p a a oct
Anode peak voltage		$V_{a_{D}}$	max.	7	kV
Cathode current		I_k	max.	180	mA

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

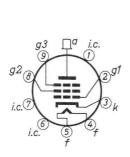
Heater voltage

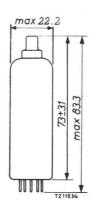
$I_{\mathbf{f}}$	300	mA	
V_{f}	21.5	V	

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No. 1	$C_{a(g_1)}$		6	pF
Grid No. 1 to all except anode	$C_{g_1(a)}$		14	pF
Anode to grid No. 1	C_{ag1}	max.	0.8	pF
Anode to cathode	c_{ak}	max.	0.1	pF
Grid No. 1 to heater	C_{g1f}	max.	0.2	pF

TYPICAL CHARACTERISTICS

Anode voltage	v_a	170	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 voltage	v_{g_2}	170	V
Grid No. 1 voltage	v_{g_1}	-24	V
Anode current	I_a	45	mA
Grid No. 2 current	I_{g_2}	2.4	mA
Transconductance	S	6.3	mA/V
Internal resistance	R_{i}	11	$k\Omega$
Amplification factor	μg2g1	5.0	

TYPICAL CHARACTERISTICS (continued)

B) (Measured under pulse conditions)

D) (,				
Anode voltage		Va	40	V	
Grid No. 3 voltage		v_{g_3}	0	V	
Grid No. 2 supply voltage		V_{bg2}	190	V	
Grid No. 2 series resistor		R_{g_2}	4.7	$\mathbf{k}\Omega$	
Grid No. 1 voltage		v_{g_1}	0	V	
Anode current		Ia	180	mA	
Grid No. 2 current		I_{g_2}	18	mA	

OPERATING CONDITIONS

Stabilized circuits (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage (-V $_{g_1}$) during flyback is 120 V at V $_a$ = 6000 V, V $_{g2}$ = 190 V and Z $_{g1}$ = 1 k Ω at line frequency.

Supply voltage: See page 5

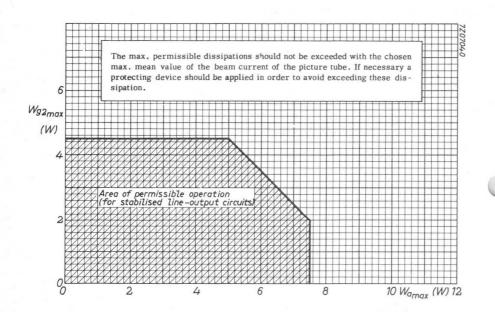
Minimum required values of the screengrid voltage and of the anode voltage, when the tube is used in a line output stage.

The graphs refer to nominal mains voltage provided the specified values of I_a at $V_{a\ min},$ will be available throughout life of the tube at supply voltage values 10% below nominal.

In order to prevent Barkhausen interferences and less of stabilisation, care should be taken that the anode voltage never drops below the specified $V_{a\ min}$ during the scanning period.

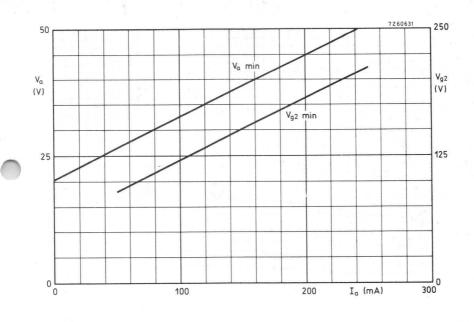
LIMITING VALUES (Design centre rating system)

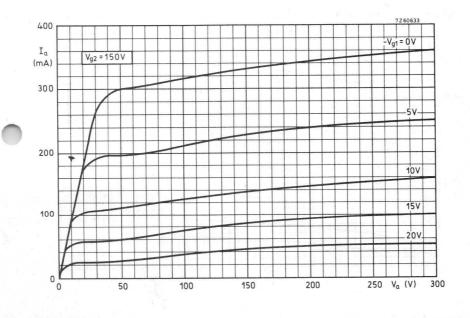
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	250	V
Anode voltage, peak	v_{ap}	max.	7	kV 1)
negative peak	$-v_{a_p}$	max.	7	kV^{1})
Anode dissipation	Wa	1		
Grid No. 2 dissipation	W_{g2}^{2}	see fi below		
Anode + grid No. 2 dissipation	$W_a + W_{g2}$	Berow		
Grid No. 2 voltage	v_{g2_0}	max.	550	V
	v_{g_2}	max.	250	V
Cathode current	$I_{\mathbf{k}}$	max.	180	mA
Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	200	V
Grid No. 1 resistor	R_{g_1}	max.	0.5	$M\Omega$

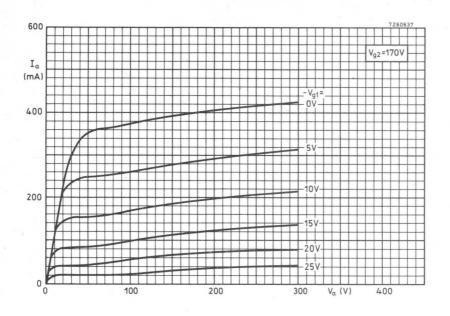


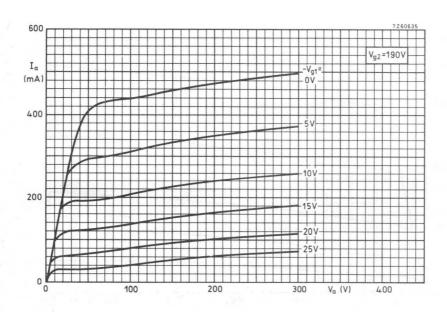
 $^{^{1})}$ Maximum pulse duration $22\,\%$ of a cycle but maximum 18 $\mu s.$

²) During the heating-up of the cathode W_{g2} = max. 6 W.









VIDEO OUTPUT PENTODE

Pentode intended for use as video output tube.

QUICK REF	TERENCE DATA		
Anode current	Ia	36	mA
Transconductance	S	10.5	mA/V
Amplification factor	$^{\mu}$ g $_2$ g $_1$	24	-

HEATING: Indirect by A.C. or D.C.; series supply

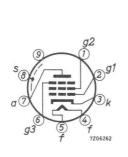
Heater current Heater voltage

300 mA 15

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		6.6	pF	
Grid No.1 to all except anode	Cg ₁ (a)		10.8	pF	
Anode to grid No.1	C_{ag_1}	max.	0.1	pF	
Grid No.1 to grid No.2	$C_{g_1g_2}$		3.2	pF	
Grid No.1 to heater	$C_{g_{1f}}$	max.	0.15	pF	

TYPICAL CHARACTERISTICS					
Anode voltage	Va	170	200	V	
Grid No.3 voltage	v_{g_3}	0	0	V	
Grid No.2 voltage	v_{g_2}	170	200	V	
Grid No.1 voltage	V_{g_1}	-2.3	-3.5	V	
Anode current	Ia	36	36	mA	
Grid No.2 current	I_{g_2}	5.0	5.0	mA	
Transconductance	S	10.5	10.5	mA/V	
Amplification factor	$\mu_{g_2g_1}$	24	24	-	
Internal resistance	Ri	0.1	0.1	$\mathrm{M}\Omega$	
LIMITING VALUES (Design centre rating system)	em)				
Anode voltage	v_{a_0}	max.	550	V	
	Va	max.	250	V	
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V	
	v_{g_2}	max.	250	V	
Anode dissipation	w_a	max.	9	W	
Grid No.2 dissipation	w_{g_2}	max.	2	W	
Cathode current	I_k	max.	70	mA	
Grid No.1 resistor					
for fixed bias	R_{g_1}	max.	0.5	$M\Omega$	

for automatic bias

Cathode to heater voltage

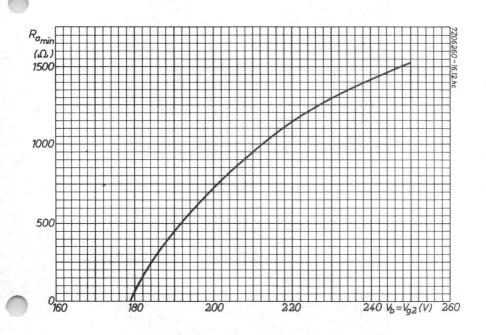
max. 1 $M\Omega$

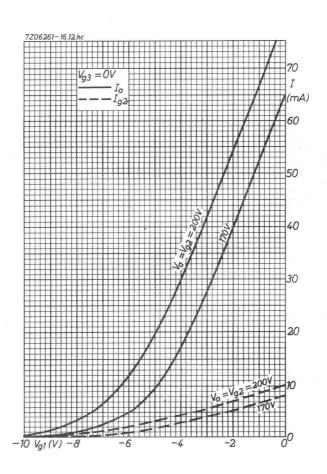
max. 200 V 1)

R_{g1}

 V_{kf}

¹⁾ D.C. component max. 150 V





FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as $A.F.\ power\ amplifier.$

QUICK REFER	ENCE DATA	ä		
Anode peak voltage	Vap	max.	2	kV
Cathode current	$I_{\mathbf{k}}$	max.	100	mA
Output power	Wo		53	W

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

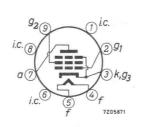
Heater voltage

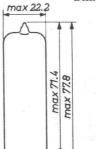
$I_{\mathbf{f}}$	300	mA
$\overline{v_{\mathrm{f}}}$	15	V

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





CAPACITANCES

Anode to all except grid No.1 Grid No.1 to all except anode Anode to grid No.1

Grid No.1 to heater

$C_{a(g_1)}$		6.8	pF
$C_{g_1(a)}$		13	pF
C_{ag_1}	max.	0.6	pF
C_{g_1f}	max.	0.25	pF

OPTIMUM PEAK ANODE CURRENT IN FRAME OUTPUT APPLICATION

The circuit should be designed so that the peak anode current does not exceed:

The minimum available value of the peak anode current at end of life and $\rm I_f$ = 285 mA is:

125 mA at
$$V_a$$
 = 60 V, V_{g2} = 170 V
160 mA at V_a = 70 V, V_{g2} = 200 V
185 mA at V_a = 80 V, V_{g2} = 220 V

OPERATING CHARACTERISTICS

A.F. power amplifier, class A	(mea	sured with V _k con	nstant)	
Supply voltage	V_{b}	170	200	V
Grid No.2 series resistor (non decoupled)	R_{g_2}	0	470	Ω
Cathode resistor	$R_{\mathbf{k}}$	130	215	Ω
Load resistance	$^{R}a_{ \sim}$	2	2.5	$\mathbf{k}\Omega$
Grid No.1 driving voltage	$V_{\mathbf{i}}$	0 0.47 6.1	0 0.52	7.0 V _{RMS}
Anode current	I_a	75 – 76	65 -	64 mA
Grid No.2 current	I_{g_2}	4.0 - 16.5	3.2 - 1	1.4 mA
Output power	W_{o}	0 0.05 5.1	0 0.05	5.3 W
Distortion	d_{tot}	10		10 %
Anode supply voltage	V _{ba}	,	230	V
Grid No.2 supply voltage	v_{bg2}		200	V
Grid No.2 series resistor (non decoupled)	R_{g_2}		220	Ω
Cathode resistor	$R_{\mathbf{k}}$		270	Ω
Load resistance	$R_{a_{\sim}}$		3.25	$\mathbf{k}\Omega$
Grid No.1 driving voltage	$V_{\mathbf{i}}$		0 0.42	5.7 V _{RMS}
Anode current	I_a		56 -	54 mA
Grid No.2 current	I_{g_2}		2.2 -	9.7 mA
Output power	Wo		0 0.05	5.4 W
Distortion	d_{tot}		_ '	10 %

OPERATING CHARACTERISTICS

	A.F. power amplifier, cla	ss AB,	two tub	es in	push-	pull			
	Anode supply voltage	V_{ba}		200			230		V
	Grid No.2 voltage	v_{bg_2}		200			200		V
	Common cathode resistor	$R_{\mathbf{k}}$		120			130		Ω
	Load resistance	R_{aa}		3			4		kΩ
	Grid No.1 driving voltage	v_i	0	0.47	14.	3 0	0.4	14.6	V _{RMS}
	Anode current	I_a	2x60	-	2x64.	5 2x56	-	2x61	mA
	Grid No.2 current	I_{g_2}	2x3.0	-	2x18.	5 2x2.3	- 2x	17.5	mA
	Output power	W_{o}	0	0.05	14.	3 0	0.05	17.5	W
	Distortion	d_{tot}	-	- ,	3.	8 -	-	5.4	%
	LIMITING VALUES (Desig	n centr	e rating	g sys	tem)				
	Anode voltage					v_{a_0}	max.	550	V
						v_a	max.	250	V
	Anode peak voltage					v_{a_p}	max.	2	kV ¹)
	Grid No.2 voltage					$v_{g_{2o}}$	max.	550	V
						v_{g_2}	max.	250	V
	Anode dissipation					Wa	max.	12	W^2)
	Grid No.2 dissipation								
	average					w_{g_2}	max.	1.75	W
	peak					$W_{g_{2p}}$	max.	6	W
	Cathode current					I_k	max.	100	mA
3	Grid No.1 resistor								
	for automatic bias					R_{g_1}	max.	1	$M\Omega$

for frame output with automatic bias

Cathode to heater voltage

max. $2 M\Omega$

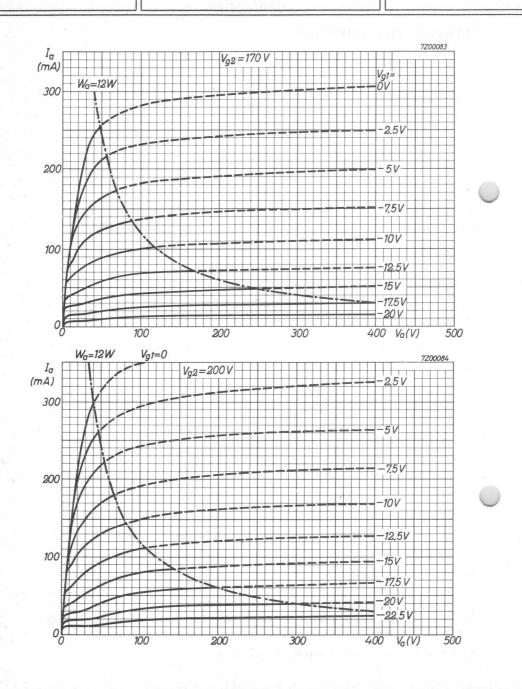
max. 200 V

Rg1

 $V_{\mathbf{k}\mathbf{f}}$

 $^{^{1})\,\}mathrm{In}$ frame output circuits where the max. pulse duration is 4% of a cycle with a max. of 0.8 ms.

 $^{^{2}}$) For frame output application W_{a} = max. 10 W.



A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFERI	ENCE DATA	
Anode current	I _a 24	mA
Transconductance	s 5.4	mA/V
Amplification factor	$\mu_{\rm g2g1}$ 17	
Output power	W_0 3	W

HEATING: Indirect by A.C. or D.C.; series supply

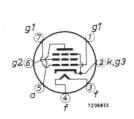
Heater current Heater voltage

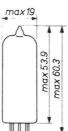
If 300 mA Vf 4.5 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: miniature 7-pin





CAPACITANCES

Anode to all except grid No.1
Grid No.1 to all except anode
Anode to grid No.1
Grid No.1 to heater

6:	
max 53	max 60.3
Ē	ma
 ,	
	1

$Ca(g_1)$		3.5	рF
$C_{g1}(a)$		5.3	рF
Cag1	max.	0.4	рF
Cglf	max.	0.2	рF

1

TYPICAL CHARACTERISTICS			
Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g2}	250	V
Grid No.1 voltage	v_{g_1}	-9.0	V
Anode current	Ia	24	mA
Grid No.2 current	I_{g2}	4.5	mA
Transconductance	S	5.4	mA/V
Amplification factor	$\mu_{ m g2g1}$	17	
Internal resistance	R _i	70	kΩ
OPERATING CHARACTERISTICS			
Class A			
Anode voltage	Va	200 250	V
Grid No.2 voltage	v_{g_2}	200 250	V
Cathode resistor	Rk	230 320	Ω
Anode current (V _i = 0)	I_a	23 24	mA
Grid No.2 current (V _i = 0)	I_{g2}	4.2 4.5	mA
Load resistance	Ra ~	8 10	$k\Omega$
Grid No.1 driving voltage	$V_{\mathbf{i}}$	4.5 5	V _{RMS}
Output power	Wo	2.3 3.0	W
Distortion	d_{tot}	10 10	%

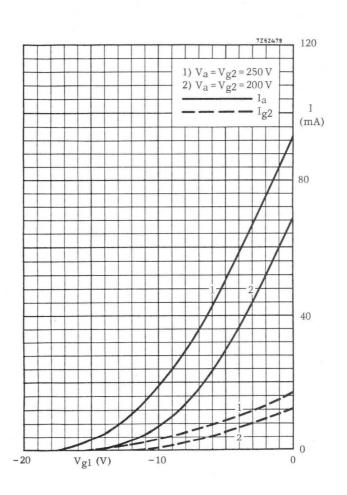
0.50 0.50 V_{RMS}

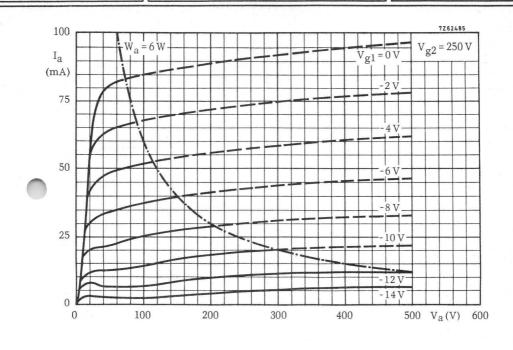
 $V_{\mathbf{i}}$

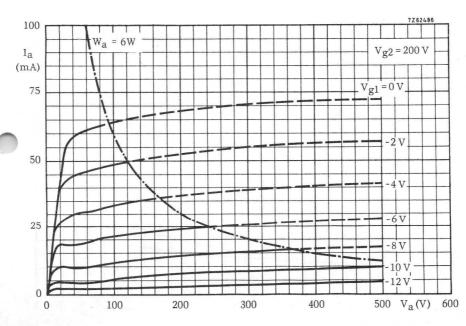
Grid No.1 driving voltage for $W_0 = 50 \text{ mW}$

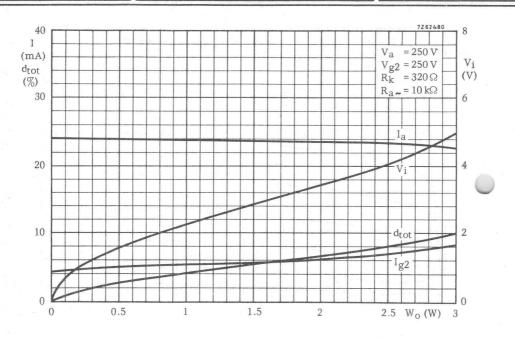
LIMITING V	ALUES	(Design	centre	rating	system)	
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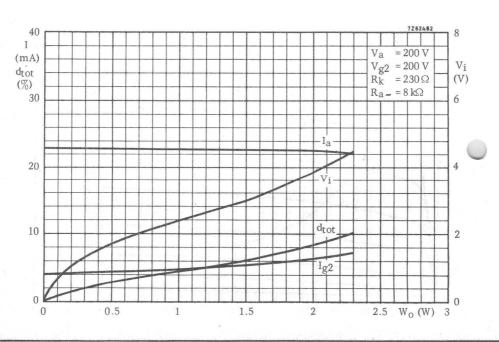
	Anode voltage	v_{ao}	max.	550	V	
		Va	max.	300	V	
	Grid No.2 voltage	V_{g2_0}	max.	550	V	
		Vg_2	max.	300	V	
	Anode dissipation	Wa	max.	6	W	
	Grid No.2 dissipation					
	average at $V_i = 0$	W_{g_2}	max.	1.25	W	
)	peak	W_{g2_p}	max.	2.5	W	
	Cathode current	Ik	max.	35	mA	
	Grid No.1 resistor, automatic bias	Rg1	max.	2.2	$\mathrm{M}\Omega$	
	Cathode to heater voltage	VILE	max	200	V	







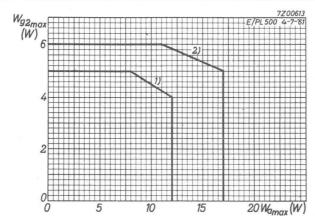




LINE OUTPUT PENTODE

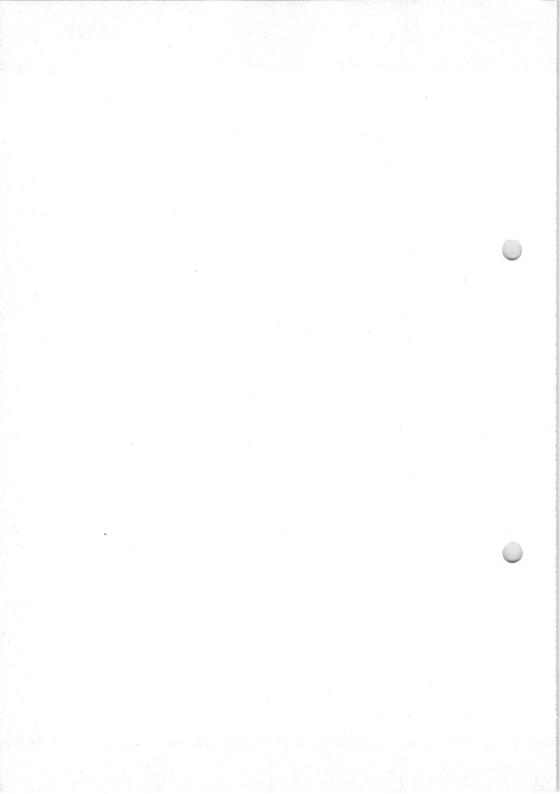
Beam pentode intended for use as line output tube in television receivers.

QUICK REF	FERENCE DATA			
Anode peak voltage	V_{a_p}	max.	7	kV
Cathode current	I_k	max.	250	mA
Anode dissipation	W_a	max.	12	W



- $^{\rm l})\,{\rm Design}$ centre limits for ${\rm W}_a$ and ${\rm W}_{\rm g2}.$
- These limits for W_a and W_{g_2} should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.

For further data and curves of this type please refer to PL504



LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

	QUICK REFERENCE DATA				
7	Anode peak voltage	Vap	max.	7	kV
	Cathode current	I _k	max.	250	mA
	Anode dissipation	Wa	max.	16	w

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

 $\frac{I_{\mathbf{f}}}{V_{\mathbf{f}}} = \frac{300 \text{ mA}}{27 \text{ V}}$

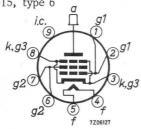
DIMENSIONS AND CONNECTIONS

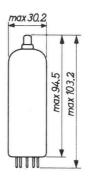
Dimensions in mm

Base: Magnoval; IEC 67-I-36a

Cap: Type 1

Outline: IEC67-II-15, type 6





CAPACITANCES

Anode to grid No. 1

Grid No. 1 to heater

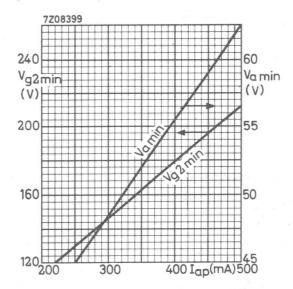
$$C_{ag_1}$$
 1.75 pF C_{g_1f} max. 0.2 pF

TYPICAL DYNAMIC CHARACTERISTICS (measured under pulse conditions)

Anode voltage	V_a	50	7000	V
Grid No.2 voltage	V_{g2}	200	200	V
Grid No.1 voltage	v_{g1}	-10	-120	V
Anode current	Ia	420	0.05	mA
Grid No.2 current	I_{g2}	37		mA

OPERATING CHARACTERISTICS

Stabilized circuits (D.C. feedback)



Minimum required values of the screen grid voltage and of the anode voltage when the tube is used in line output stages. The graphs refer to nominal mains voltage provided the specified values of $\rm V_a$ are increased by 10% of the anode supply voltage. The specified values of $\rm I_{ap}$ will be available throughout life of the tube at supply voltage values 10% below nominal.

In order to prevent Barkhausen interferences, care should be taken that the anode voltage never drops below the specified $V_{\rm a}$ min. during the scanning period.

Non stabilized circuits

Supply voltage	V_b	190	230	V
Grid No.2 series resistor	Rg2	2.2	2.2	$\mathbf{k}\Omega$
Grid No.1 voltage	v_{g_1}	+1	+1	V
Anode peak current	I_{a_p}	230	320	mA^1)

¹⁾ See page 3

HUM

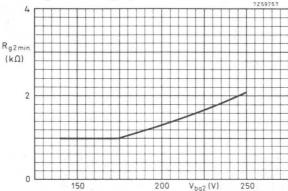
At $\rm Z_{g1}$ = 200 k Ω (f = 50 Hz), $\rm V_{kf}$ = 220 $\rm V_{RMS}$ and without wiring and socket capacitances, the equivalent grid hum voltage is < 5 mV.

LIMITING VALUES (Design centre rating system unless otherwise stated)

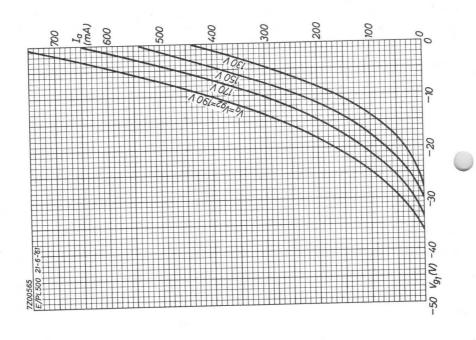
	Anode voltage	V_{a_0}	max.	550	V	
	Anode voltage	Va	max.	250	V	
	Anode voltage, peak	v_{a_p}	max.	7000	V 3)4)	
1	-Grid No.2 voltage	V_{g2o}	max.	550	V	
	Grid No.2 voltage	V_{g2}	max.	250	V	
	Anode dissipation	Wa	see pag			
	Grid No.2 dissipation	W_{g2}	see page 4		2)	
	Cathode current	$I_{\mathbf{k}}$	max.	250	mA	
	Grid No.1 resistor	R _{g1}	max.	0.5	$M\Omega$ 5)	
	Cathode to heater voltage	Vkf	max.	250	V	
	Bulb temperature	tbulb	max.	280	°C 6)	

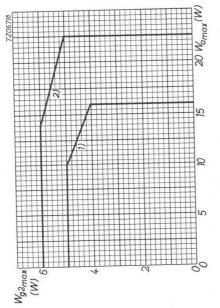
NOTES

- 1. To allow for tube spread, deterioration during life and a mains voltage 10 $\%\,below$ nominal, the specified values for I_{ap} should not be exceeded at nominal mains voltage and at the specified conditions.
- 2. To prevent an excessive value of W_{g2} during the heating-up period, the minimum R_{g2} values are given in the graph below.



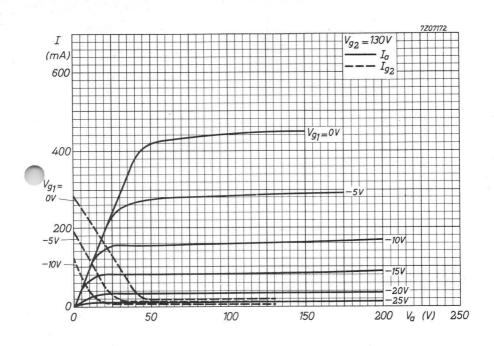
- 3. Maximum pulse duration is 22 % of a cycle and max. 18 μ s.
- 4. Vap design max. 8 kV
- 5. $R_{g1} = max$. 2.2 M Ω for line output application.
- Absolute max. value.

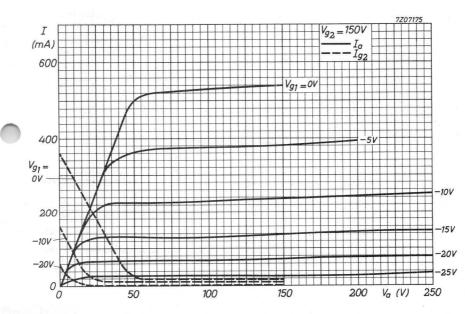


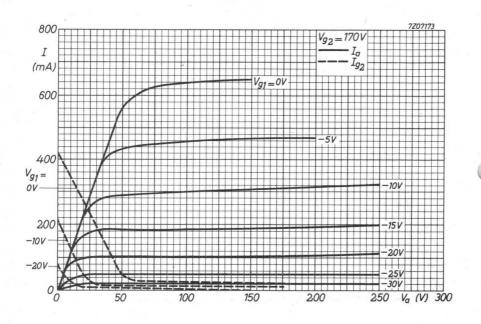


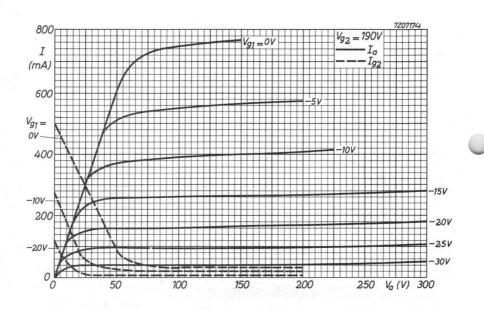
1) Disign centre limits for W_a and $W_{\rm S2}$.

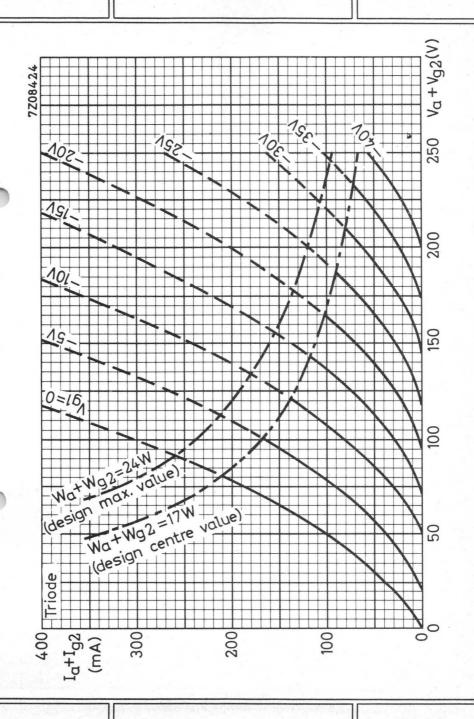
2) These limits for W_a and $W_{\rm E2}$ should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.

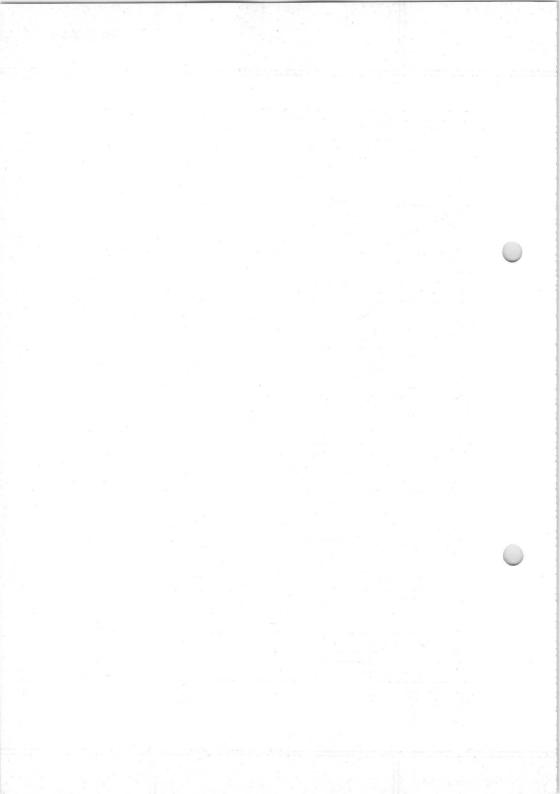












LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

	~					
Π	Anode peak voltage	Vap		7000	V	
	Cathode current	I_k	max.	500	mA	
	Anode dissipation	Wa	max.	25	W	
	LIMITING VALUES (Design centre rating system)					
	Anode dissipation	w_a		max.	25	W

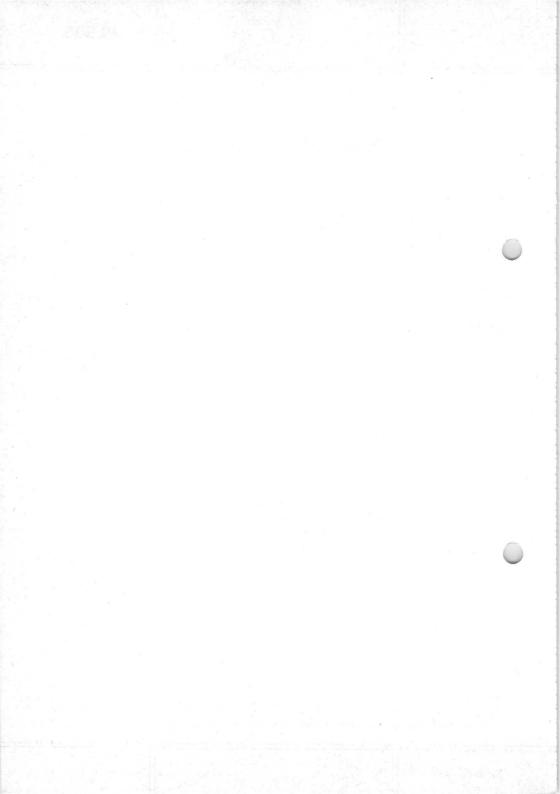
OUICK REFERENCE DATA

Anode dissipation	Wa	max.	25	W
Anode + grid No. 2 dissipation (triode connected)	$w_a+w_{g_2}$	max.	26	W
(Design max. rating system) 1)				
Anode dissipation	W_a	max.	34	W
Anode + grid No.2 dissipation (triode connected)	$w_a + w_{g_2}$	max.	35	W

For further data and curves of this type please refer to type PL 509

January 1969

 $^{^{\}rm l}$) The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width.



FRAME OUTPUT PENTODE

Pentode intended for use as frame output amplifier in colour television receivers.

I	QUICK REFERENCE DATA				
7	Cathode current, average	I _k	max.	100	mA
	Anode dissipation	w_a	max.	12	W

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

300 mA

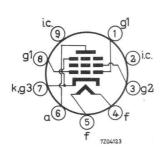
Heater voltage

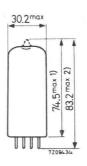
17 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Magnoval





CAPACITANCES

Anode to grid No. 1

Grid No. 1 to heater

 C_{agl} max. 1.6 pF C_{g_1f} max. 0.2 pF

¹⁾ Max. 71.4

for execution with pumping stem on base side. 2) Max. 80.1

TYPICAL CHARACTERISTICS

(Measured under pulse conditions)

Anode voltage	Va		50	Va	190	V
Grid No.2 voltage	v_{g_2}		190	v_{g2}	190	V
Grid No.1 voltage	v_{g_1}		-1	v_{g_1}	-17	V
Anode current	I_{a_p}		320	Ia	60	m A
Grid No.2 current	I_{g_2}	approx.	60	I_{g_2}	5	m A
Transconductance				S	9	mA/V
Amplification factor				$\mu_{\rm g2gl}$	8	

Remarks.

The minimum $\rm I_a$ to be expected as a result of spread of the tube characteristics tube deterioration during life and decrease of the mains voltage to 10 % below the nominal value can be derived from the curves on page B by decreasing by 40 % the $\rm I_a$ values situated on the curve A-B at $\rm V_{g_2}$ occurring at the decreased mains voltage.

In order not to exceed the maximum permissible value of W_{g_2} , the circuit should be designed in such a way that the anode voltage should never be lower than the value determined by curve A-B at the relevant V_{g_2} value.

OPERATING CHARACTERISTICS (end of scan values)

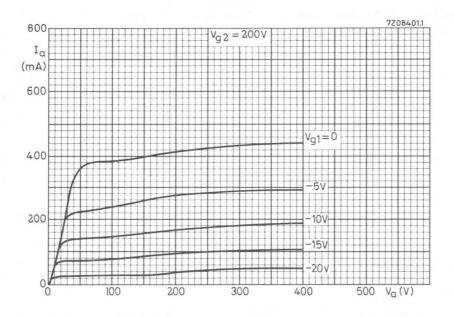
Anode voltage	Va	70	V
Grid No.2 voltage	v_{g_2}	200	V
Grid No.1 voltage	v_{g_1}	-5	V
Anode peak current	I_{a_p}	230	mA

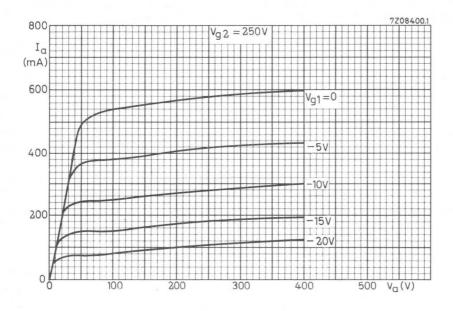
Anode voltage	v_{a_0}	max.	700	V
	v_a	max.	400	V
Anode peak voltage	V_{a_D}	max.	2.5	kV 1)
Grid No.2 voltage	v_{g20}	max.	700	V
	v_{g2}	max.	275	V
Anode dissipation	w_a	max.	12	W
Grid No.2 dissipation	W_{g2}	max.	3	W
design max.	W_{g2}	max.	4	W
Cathode current	Ik	max.	100	m A
Grid No.1 resistor, fixed bias	R_{g_1}	max.	1	$M\Omega$
automatic bias	R_{g_1}	max.	2.2	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	220	V

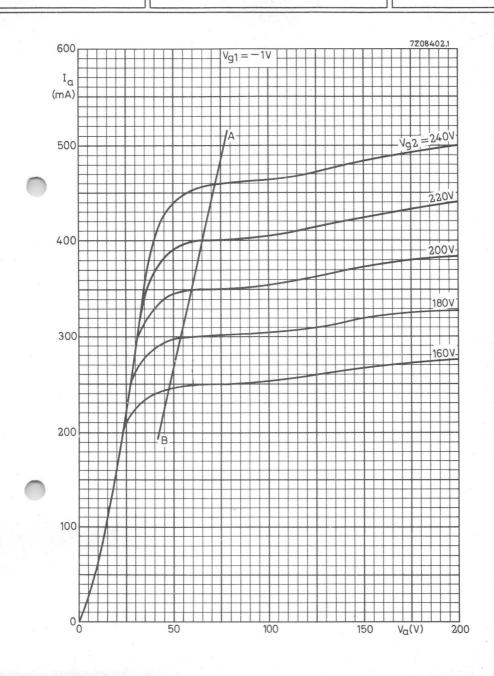
MICROPHONY

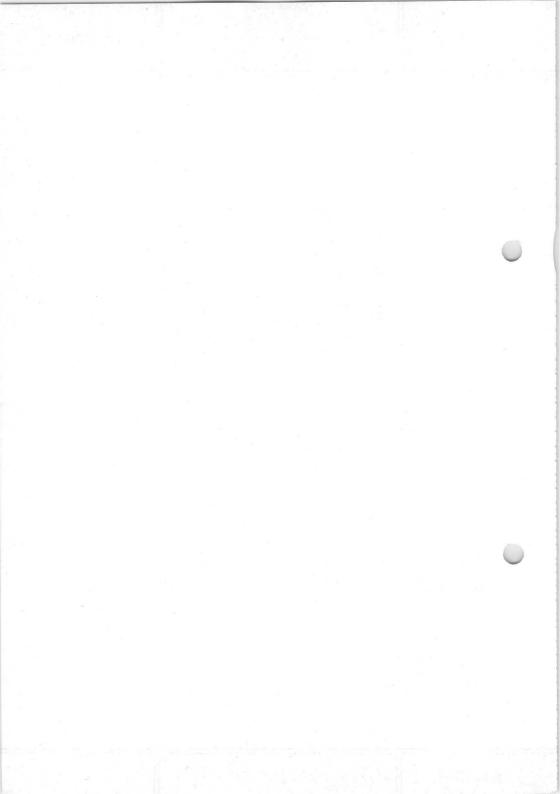
The maximum peak accelaration to which the tube may be subjected under the most unfavourable conditions is 1.5 g at frequencies $< 600 \; Hz$. and 0.2 g at frequencies $> 600 \; Hz$. The equivalent interferance voltage at grid No.1 will than be $< 25 \; mV$.

¹⁾ Max. pulse duration 5% of a cycle and max. 1 ms.









LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

QUICK RE	FERENCE DATA		
Anode peak voltage	v_{a_p}	7000	V
Cathode current	I_k max.	500	mA
Anode dissipation	W_a max.	30	W

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

$I_{\mathbf{f}}$	300	mA
V_{f}	40	V

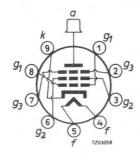
Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Magnoval Top cap: Type 1

Mounting: Additional supporting of the

tube at the top is required.



109.5 – 116 max 39.7 – 116 max 124.7

CAPACITANCES

Grid No.1 to filament

Anode to grid No.1

	720		
$C_{g_{1f}}$	max.	0.2	pF
C_{ag_1}	max.	3.0	pF
Cag1		2.5	pF

TYPICAL CHARACTERISTICS (measured under pulse conditions)

Anode voltage		v_a	160	50	V
Grid No.3 voltage		v_{g_3}	0	0	V
Grid No.2 voltage		v_{g_2}	160	175	V
Grid No.1 voltage		v_{g_1}	0	-10	V
Anode current		Ia	1400	800	mA
Grid No.2 current		I_{g_2}	45	70	mA

OPERATING CONDITIONS (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage (-Vg $_1$) during flyback at V $_a$ = 7000 V and at line frequency is at:

$$\begin{array}{l} v_{g_2} = 150 \ V : \ v_{g_1} = -175 \ V \\ v_{g_2} = 200 \ V : \ v_{g_1} = -195 \ V \\ v_{g_2} = 250 \ V : \ v_{g_1} = -215 \ V \end{array}$$

Supply voltages: See pages 4-5-6

Minimum required anode voltage: Va min

In order to prevent Barkhausen interference and loss of stabilization, care should be taken that the anode voltage never drops below the specified $V_{\mbox{a}\mbox{ min}}$ during the scanning period.

If low values of $V_{a\ min}$ are required, the $V_{a\ min}$ 1-line can be shifted over 10 V to $V_{a\ min}$ 2, provided a D.C. voltage of at least +20 V is applied to the beamplate (g3). To compensate for the influence of mains voltage variations, the specified values of $V_{a\ min}$ have to be increased with 10% of the anode supply voltage.

Minimum required values of the screen grid voltage: $V_{\rm g2\ min}$

The graph refers to nominal mains voltage. The specified values of ${\rm Ia_p}$ will be available throughout life of the tube at supply voltages 10% below nominal.

Maximum permissible screen grid series resistance: Rg2 max. See pages 4-5-6

Decoupling-capacitors in the grid no 2 and/or grid no 3 circuit

In circuits where decoupling capacitors in the grid no 2 or the grid no 3 circuits are applied, incidental flashover in the tube may give rise to excessive discharge currents and component or tube failure.

Therefore it is recommended to limit the discharge currents to these capacitors by means of an 100 Ohm resistance between g2 and the g2-bvpass capacitance.

The 1000 Ohms resistance should be protected by a spark-gap connected between $\ensuremath{\mathrm{g}}^3$ and earth.

Hum

At $\rm Z_{g1}$ = 200 k (f = 50 Hz), $\rm V_k/f$ = 220 $\rm V_{RMS}$ and without wiring and socket capacitance, the equivalent grid hum voltage is less than 5 mV.

LIMITING VALUES

Bulb temperature

	Anode voltage in cold condition
	Anode peak voltage
	Anode dissipation
	Anode + grid No. 2 dissipation (triode-connected)
	Grid No. 3 voltage
	Grid No. 2 voltage in cold condition
	Grid No. 2 voltage
	Grid No. 2 dissipation
	Cathode current
à	Cathode peak current
	athode-to-heater voltage
	Grid No. 1 resistor: fixed bias
	. stabilized circuits
	Grid No. 3 circuit resistance

Design	centre	rating	system

Vao	max.	700	V
Vap	max.	7000	V^{-1}
W_a	max.	30	W
$W_a + W_{g_2}$	max.	31	W
Vg3	max.	50	V
$V_{\alpha\beta}^{\alpha\beta}$	max.	700	V
Vg _{2o}	max.	275	V
$\mathbf{w}_{g_2}^{g_2}$	max.	7	W^{2}
I_k	max.	500	mA
I_{k_p}	max.	1200	mA
Vkf	max.	250	V
R _{g1}	max.	0.5	$M\Omega^3$)
Rg ₁	max.	2.2	$M\Omega^{3}$)
R _{g3}	max.	10	$k\Omega^{4}$)
tbulb	max.	300	°C 5)

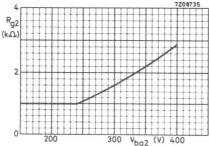
Design max. rating system 6)

1)

1)

Anode dissipation	Wa	max.	40	W
Anode + grid No.2 dissipation (triode connected)	$W_a + W_{g_2}$	max.	42	W
Grid No. 2 dissipation	W_{g_2}	max.	9	W
Anode peak voltage	Vap	max.	8000	V
Neg. grid No.1 peak voltage	-Vg ₁ p	max.	.550	V

- 1. Max. pulse duration is 22% of a cycle and max. 18 $\mu s.$
- 2. To prevent an excessive value of W_{g_2} the minimum R_{g_2} values are given in the graph below.



- 3. The circuit design has to be such that negative control grid currents up to 5 micro-amperes do not have any detrimental effect upon tube adjustment or circuit performance.
 - Care should be taken that with 5 micro-amperes grid current the limiting values for ${\rm I}_k,\ W_a$ and ${\rm W}_{g_2}$ are not exceeded.
- 4. With $R_{g_3} \le 10 \text{ k}\Omega$ capacitive decoupling of g_3 is not required.
- 5. Absolute max. value.
- The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width.

November 1969

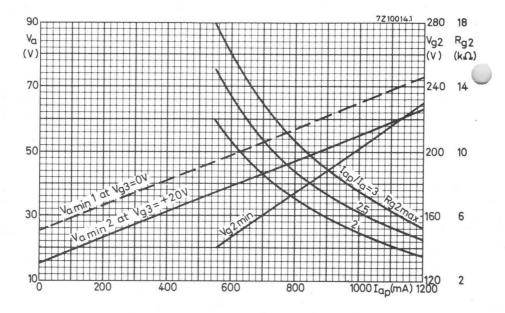
PL509

Min. required anode voltage.

 $R_{\mbox{\scriptsize g}_{2}\mbox{\scriptsize max}}$: max, permissible screen grid series resistance for 400 V screen grid supply.

The specified values of ${\rm I}_{ap}$ are available at supply voltages 10% below nominal and throughout the tube life.

Remark: $R_{g_2~min}$ for 400~V screen grid supply is 2.9 k $\!\Omega_{\star}$ (See page 3)

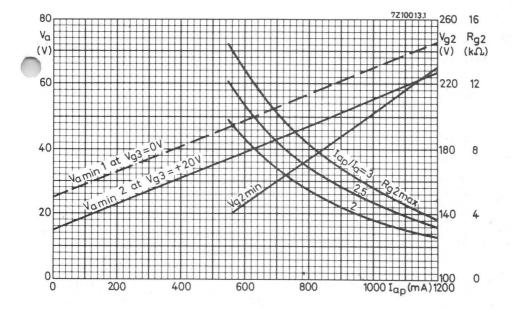


Min. required anode voltage.

 ${\rm Rg}_{2\,\,{\rm max}}$: max, permissible screen grid series resistance for 350 V screen grid supply.

The specified values of ${\rm I}_{a\,p}$ are available at supply voltages 10% below nominal and throughout the tube life.

Remark: $R_{g_2\ min}$ for 350 V screen grid supply is 2.2 k $\Omega.$ (See page 3)



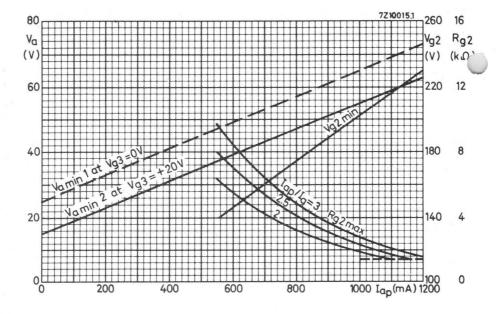
PL509

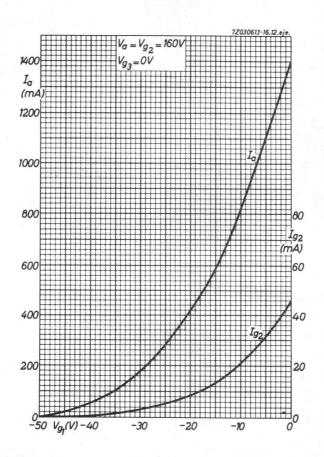
Min. required anode voltage.

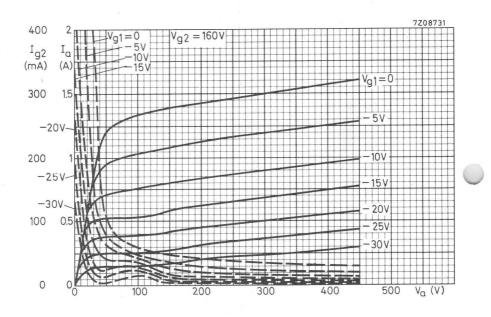
 $R_{\mbox{\scriptsize g2\ max}}$.: max. permissible screen grid series resistance for $280\ V$ screen grid supply.

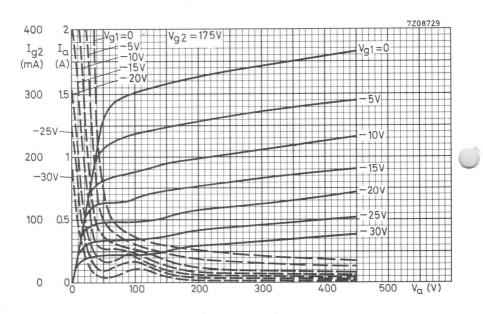
The specified values of ${\rm I}_{a_p}$ are available at supply voltages 10% below nominal and throughout the tube life.

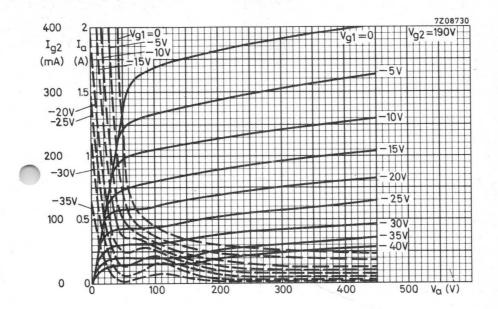
Remark: $R_{\rm g_2~min}$ for 280 V screen grid supply is 1.4 kΩ. (See page 3)











LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

$I_{\mathbf{f}}$	300	mA
V_{f}	40	V

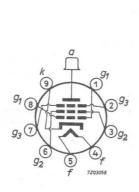
DIMENSIONS AND CONNECTIONS

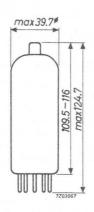
Base: Magnoval Top cap: Type 1

Mounting: Additional supporting of the

tube at the top is required.

Dimensions in mm





CAPACITANCES

Grid No. 1 to filament

Anode to grid No. 1

C_{g_1f}	max.	0.2	pН
C_{ag_1}	max.	3.0	pI
Cagi		2.5	рI

TYPICAL CHARACTERISTICS (measured under pulse conditions)

Anode voltage		v_a	160	50	70	V
Grid No. 3 voltage		v_{g_3}	0	0	0	V
Grid No. 2 voltage		v_{g_2}	160	175	205	V
Grid No. 1 voltage		v_{g_1}	0	-10	-11	V
Anode current		I_a	1400	800	1100	mA
Grid No.2 current		I_{g_2}	45	70	85	mA

OPERATING CONDITIONS (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage (-V $_{g1}\!)$ during flyback at V $_a$ = 7000 V and at line frequency is at:

$$V_{g_2} = 150 \text{ V}: V_{g_1} = -175 \text{ V}$$

 $V_{g_2} = 200 \text{ V}: V_{g_1} = -195 \text{ V}$
 $V_{g_2} = 250 \text{ V}: V_{g_1} = -215 \text{ V}$

Minimum required anode voltage during the scanning period: $V_a \ \text{min.See} \ \text{page} \ 6$

Minimum required screen grid voltage: Vg2 min.

See page 4, 5

Recommended screen grid series resistor: R_{g2} rec

See page 4, 5

Decoupling capacitors in the grid no.2 and/or grid no.3 circuit

In circuits where decoupling capacitors in the grid no.2 or the grid no.3 circuits are applied, incidental flashover in the tube may give rise to excessive discharge currents and component or tube failure.

Therefore it is recommended to limit the discharge currents from these capacitors by means of a $100\,\Omega$ resistor between g_2 and the g_2 -bypass capacitor and a $1000\,\Omega$ resistor between g_3 and the g_3 -bypass capacitor. The $1000\,\Omega$ resistor should be protected by a spark-gap connected between g_3 and earth.

Hum

At Z_{g_1} = 200 k Ω (f = 50 Hz), $V_{kf\,RMS}$ = 220 V and without wiring and socket capacitance, the equivalent grid hum voltage is less than 5 mV.

Design centre rating system

max. 9 max. 8000

max.

Vap

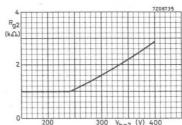
 $-V_{g_{1}p}$

V

550

Design	cilite 1a	ting sy	Stem	
Vao	max.	700	V	
Vap	max.	7000	V	
Wa	max.	35	W	
V_{g_3}	max.	30	V	
Vg2	max.	700	V	
V_{g_2}	max.	275	V	
Wgg	max.	7	W	2)
I_k	max.	500	mA	
	max.	1500	mA	
	max.	250	V	
	max.	0.5	$M\Omega$	3)
R _{g1}	max.	2.2	$M\Omega$	3)
Rg3	max.	10	$k\Omega$	4)
tbulb	max.	300	oC	5)
Design	max. rat	ing sys	stem	6)
Wa	max.	45	W	
	Vao Vap Wa Vg3 Vg2o Vg2 Wg2 Ik Ikp Vkf Rg1 Rg1 Rg3 tbulb Design	$\begin{array}{cccc} V_{a0} & \text{max.} \\ V_{ap} & \text{max.} \\ W_{a} & \text{max.} \\ V_{g3} & \text{max.} \\ V_{g20} & \text{max.} \\ V_{g2} & \text{max.} \\ V_{g2} & \text{max.} \\ I_{k} & \text{max.} \\ I_{kp} & \text{max.} \\ V_{kf} & \text{max.} \\ R_{g1} & \text{max.} \\ R_{g1} & \text{max.} \\ R_{g3} & \text{max.} \\ R_{g3} & \text{max.} \\ t_{bulb} & \text{max.} \end{array}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

- 1. Max. pulse duration is 22% of a cycle and max. $18~\mu s$.
- 2. To prevent an excessive value of W_{g2} the minimum R_{g2} values are given in the graph below.



- The circuit design has to be such that negative control grid currents up to 5 micro-amperes do not have any detrimental effect upon tube adjustment or circuit performance.
 - Care should be taken that with 5 micro-amperes grid current the limiting values for $\rm I_k,\ W_a$ and $\rm W_{g_2}$ are not exceeded.
- 4. With $R_{g_3} \le 10 \text{ K}\Omega$ capacitive decoupling of g_3 is not required.
- 5. Absolute max. value.

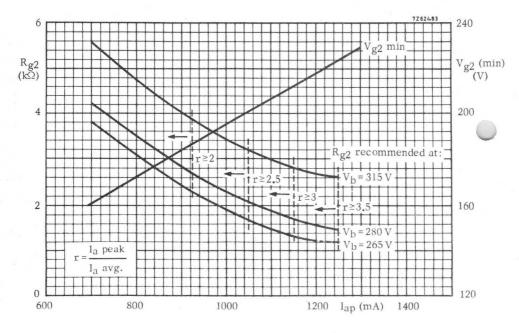
LIMITING VALUES

Grid No. 2 dissipation

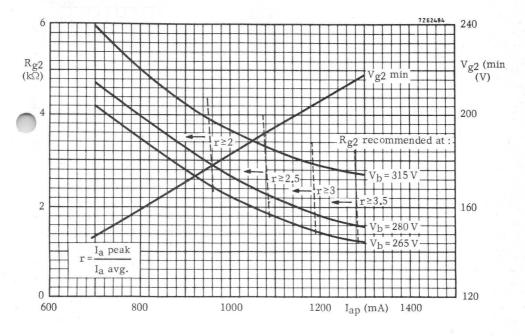
Neg. grid No. 1 peak voltage

Anode peak voltage

The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width. Min. required \mathbf{V}_{g_2} and recommended \mathbf{R}_{g_2} Non-stabilized supply voltages.

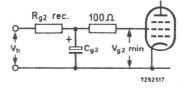


Min. required V_{g_2} and recommended R_{g_2} Stabilized supply voltage.



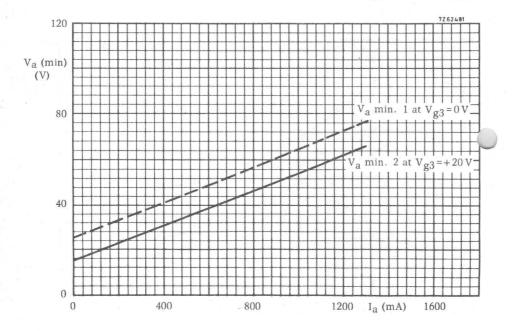
The above graphs concern the design of a line-output circuit adjusted at a beam current of 1000 μA and a nominal mains voltage.

If the recommended R_{g_2} is used, V_{g_2} will be equal to higher or than the specified V_{g_2} min. and there will be adequate reserve in anode peak current throughout the life of the tube. (Tolerances of deflection-components and 10 % mains voltage fluctuations taken into account).

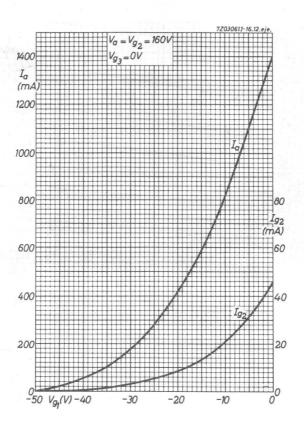


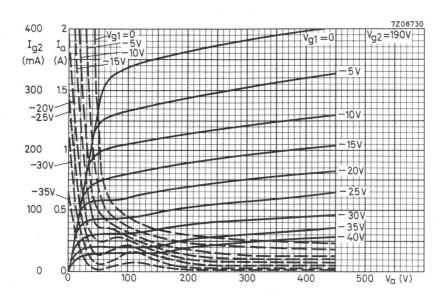
5

Min. required anode voltage, during the scanning period.



To suppress Barkhausen interference and to ensure stability, the anode load line should not be allowed to drop below the $\rm V_a$ line shown in the diagram. If $\rm V_a$ min. must be low, the $\rm V_a$ min. 1-line can be shifted over 10 V to $\rm V_a$ min. 2, provided a D.C. voltage of at least +20 V is applied to the beam plate (g₃). To compensate for the influence of mains voltage fluctuations, the specified values of $\rm V_a$ min. must be increased with 10 % of the anode supply voltage when not stabilized.





VIDEO OUTPUT PENTODE

Luminance output tube in colour TV receivers.

QUICK R	EFERENCE DATA		
Anode current	Ia	30	mA
Transconductance	S	40	mA/V
Anode dissipation	W_a max.	6	W

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

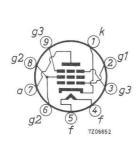
Heater voltage

I_f	300	mA
$\overline{V_f}$	16	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Anode to grid No.1

TYPICAL CHARACTERISTICS

Anode voltage	v_a	170	V	
Grid No.2 voltage	v_{g_2}	170	V	
Grid No.3 voltage	v_{g_3}	0	V	
Grid No.1 supply voltage	V_{bg_1}	0	V	
Cathode resistor (decoupled)	R _k	36	Ω	
Anode current	Ia	30	mA	
Grid No.2 current	I_{g_2}	6.5	mA	
Transconductance	S	40	mA/V	
Amplification factor	$\mu_{g_2g_1}$	70	-	

LIMITING VALUES (Design centre rating system to	unless oth	erwise	state	d)	
Anode supply voltage	v_{ba}	max.	400	V	
Anode voltage,	v_{a_0}	max.	550	V	
long term average	Va	max.	300	V	
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V	
	v_{g_2}	max.	300	V	
Anode dissipation	Wa	max.	6	W	
Grid No.2 dissipation	W_{g_2}	max.	2.5	W	
	w_{g_2}	max.	3.0	W 1)	
Cathode current	I_k	max.	100	mA	
Grid No.1 resistor	R_{g_1}	max.	0.1	$M\Omega$	
at $R_k \ge 39 \Omega$	R_{g_1}	max.	0.5	$M\Omega$	
Cathode to heater voltage	v_{kf}	max.	200	V	

¹⁾ Design maximum rating system including no signal condition.

OPERATING CONDITIONS (negative modulation)

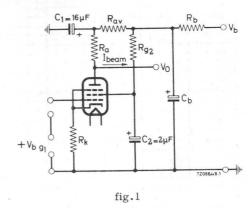
$$V_b$$
 = 250 V
 R_b = 330 Ω

$$R_{av} = 560 \Omega$$

$$R_a = 2.7 k\Omega$$

$$R_{g_2} = 5.6 \text{ k}\Omega$$

$$R_k^{1}$$
) = 39 Ω
+ V_{bg_1} = 4 V



$$V_{o1}$$
 = 100 V
 V_{opp} \geq 140 V
Video-
linearity \geq 0.8 -
 V_{ipp} ca. 5 V
Iboam max. 7 mA

Ibeam

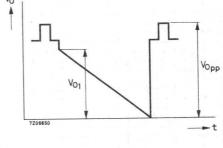
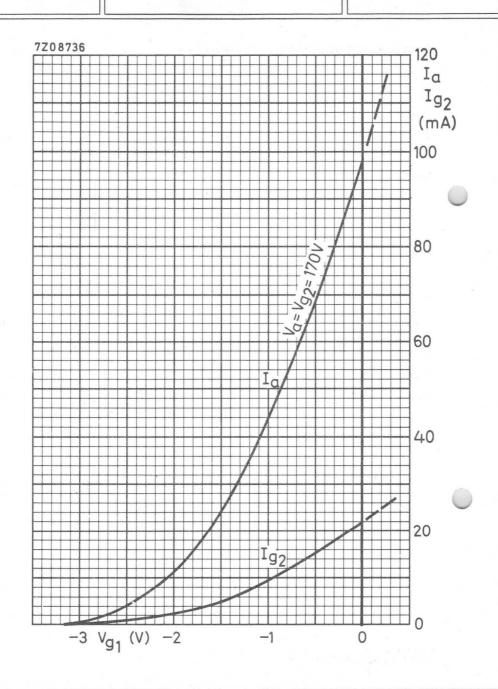
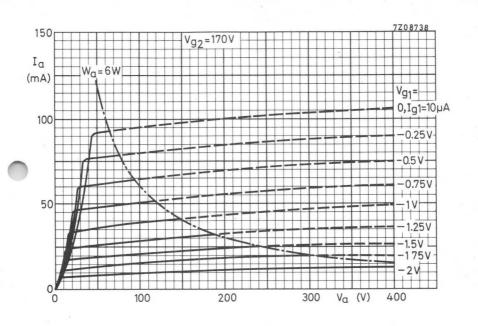
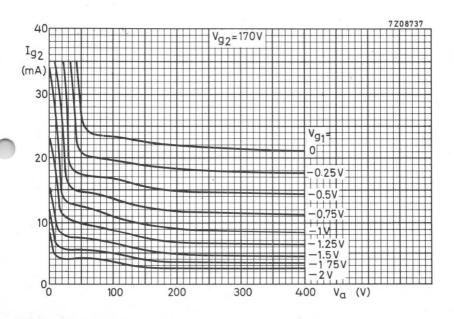


fig.2

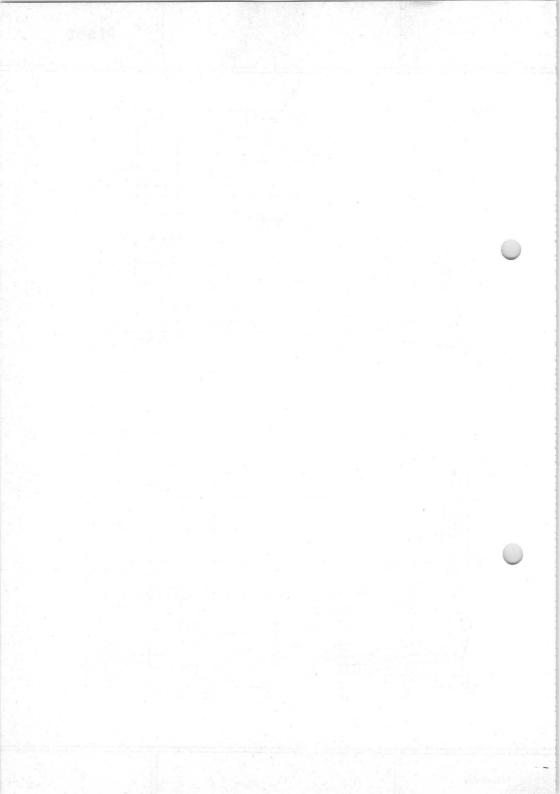
¹⁾ Without by-pass capacitor.







5



BOOSTER DIODE

Booster diode intended for use in line time-base circuits of transformerless television receivers.

QUICK REFEREN	NCE DATA			
Anode current, peak	Iap	max.	450	mA
Anode voltage, peak	v_{a_p}	max.	5000	V
Cathode to heater voltage, peak	V_{kf_p}	max.	5000	V

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

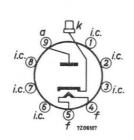
I_f	300	mA
$\overline{v_f}$	17	V

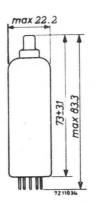
Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval

Top cap: Type 1





CAPACITANCES

Anode to all

Cathode to heater

 C_a 6.4 pF C_{kf} 2.8 pF

LIMITING VALUES (Design centre rating system, unless otherwise specified)

Supply voltage	V_{b_0}	max.	550	V	
2, 4, 6, 79, 3	V_{b}	max.	250	V	
Anode dissipation	Wa	max.	3.5	W	
Anode current, average	Ia	max	150	mA	
peak	I_{a_p}	max.	450	mA	
Anode voltage, peak	V_{a_p}	max	5000	$V^{1})^{2})$	
Absolute max.	V_{a_p}	max.	5600	$V^{1})^{2}$)	
Cathode to heater voltage, peak	$V_{\mathrm{kf}_{\mathrm{p}}}$	max.	5000	V^{1})	
Series resistance heater chain	R _s	min.	80	Ω^3)	
Heater to earth voltage	V _{f/earth}	max.	220	V_{RMS}	

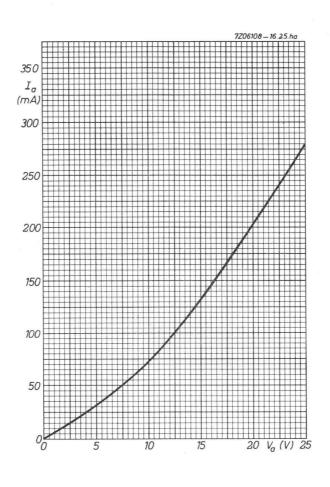
REMARK

In general it will be necessary to take measures in order to prevent the maximum permissible screen grid dissipation of the tube that derive their anode voltage from this booster diode, from being exceeded during the heating-uptime of the booster diode.

 $^{^{1})\,\}mathrm{Max.}$ pulse duration 22% of a cycle with a maximum of 18 $\mu\mathrm{sec.}$

 $^{^{2}}$) Cathode positive with respect to the anode.

³⁾ R_S = minimum resistance of the heater chain between any heater pin and any mains terminal under working conditions (the heater of another tube can be used for this resistance).



SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

	QUICK REFERENCE DATA			
Transformer voltage		v_{tr}	250	VRMS
D.C. current		I_{o}	180	mA

HEATING: Indirect by A.C. or D.C.; series supply

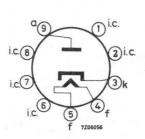
Heater current

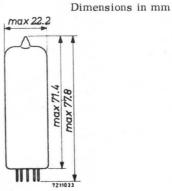
Heater voltage

I_f	300	mA		
$\overline{v_f}$	19	V		

DIMENSIONS AND CONNECTIONS

Base: Noval



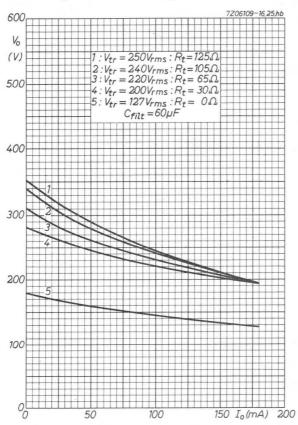


OPERATING CHARACTERISTICS as single-phase half-wave rectifier

Transformer voltage	v_{tr}	250	240	220	200	127	VRMS
D.C. output voltage	V_{o}	195	195	195	195	127	V
D.C. current	I_{o}	180	180	180	180	180	mA
Protecting resistance	R_t	125	105	65	30	0	Ω
Input capacitance of smoothing filter	$C_{ ext{filt}}$	60	60	60	60	60	μF

LIMITING VALUES (Design centre rating system)

Transformer voltage	v_{tr}	max.	250	v_{RMS}	
Anode voltage, peak inverse	Vainvp	max.	700	V	
D.C. current	Io	max.	180	mA	
Cathode to heater voltage, peak	v_{kf_p}	max.	550	V 1)	
Input capacitance of smoothing filter	C _{filt}	max.	60	μF^2)	
Protecting resistance at transformer voltage	R _t min. 100 V _{tr} 250		40 220	30 0 200 127	${\Omega}\\V$



¹⁾ Max. 220 VRMS A.C. voltage + max. 250 VD.C. voltage. Cathode positive with respect to the heater.

²⁾ When two tubes are placed in parallel, C_{filt} = max. 100 μF . The resistor R_t must be inserted in the anode lead of each tube.

BOOSTER DIODE

Booster diode intended for use in line time-base circuits of transformerless television receivers.

QUICK REFERI	ENCE DATA		
Anode current, peak	I _{ap}	max. 550	mA
Anode voltage, negative peak	$-V_{a_{D}}$	max. 6000	V
Cathode to heater voltage, peak	v_{kfp}	max. 6600	V

HEATING: Indirect by A.C. or D.C.; series supply

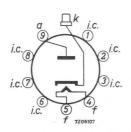
Heater current

Heater voltage

$I_{\mathbf{f}}$	300	mA		
$V_{\mathbf{f}}$	30	V		

DIMENSIONS AND CONNECTIONS

Base: Noval
Top cap: Type 1



Dimensions in.mm



CAPACITANCES

Anode to all
Cathode to heater

 C_a 8.6 pF C_{kf} 2.7 pF

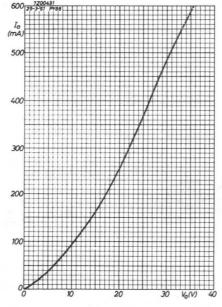
LIMITING VALUES (Design centre rating system unless otherwise specified)

Supply voltage	v_{b_0}	max.	550	V	
	v_b	max.	250	V	
Anode dissipation	Wa	max.	5	W	
Anode current, average	I_a	max.	220	mA	
peak	I_{ap}	max.	550	mA	
Anode voltage, negative peak	-V _{ap}	max.	6000	V 1)	1
negative peak (absolute max.)	-Vap	max.	7500	V 1)	. (
Cathode to heater voltage, peak	v_{kf_p}	max.	6600	V 1)	
Heater to earth voltage	V _{f/earth}	max.	220	v_{RMS}	

Series resistance heater chain

During operation, the external resistance between either heater pin of the PY88 and either mains terminal should be at least 80 Ω when Vf/earth = 220 V_{RMS} 40 Ω when Vf/earth = 110 V_{RMS}

The hot heater resistances of other tubes in the heater chain can serve for this purpose.



¹⁾ Max. pulse duration 22% of a cycle but maximum 18 μs .

BOOSTER DIODE

Booster diode for timebase circuits of colour TV receivers.

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

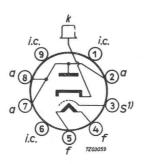
I_f	300	mA
$\overline{v_f}$	42	V

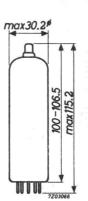
Dimensions in mm

MECHANICAL DATA

Base: Magnoval

Cap: Type 1





CAPACITANCES

Anode to cathode

Cathode to heater

C_{ak} 13 pF C_{kf} 3.7 pF

¹⁾ Insertion of a resistor of 300 Ω between pins 3 and 5 is recommended to improve the high-tension properties of the tube. If no resistor is used, pins 3 and 4 should be interconnected.

TYPICAL CHARACTERISTICS

Internal	resistance	(Ia	=	440	mA)	
----------	------------	-----	---	-----	-----	--

 R_i

 45.5Ω

LIMITING VALUES (Design centre rating system)

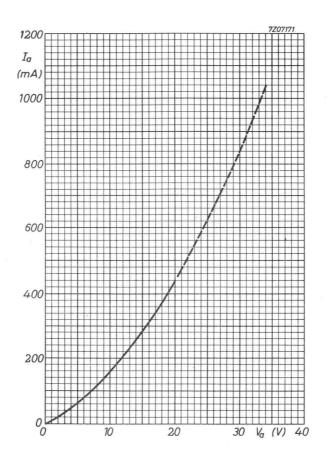
Anode dissipati	on	Wa	max.	11	W
Anode current,	average	Ia	max. 4	140	mA
	peak	I_{a_p}	max. 8	300	mA
Anode voltage,	negative peak	-Vap	max. 56	600	V 1)
	negative peak, (absolute max.)	-V _{ap}	max. 70	000	V 1
Cathode to heat	er voltage, peak	V_{kfp}	max. 63	300	V 1)

Series resistance heater chain

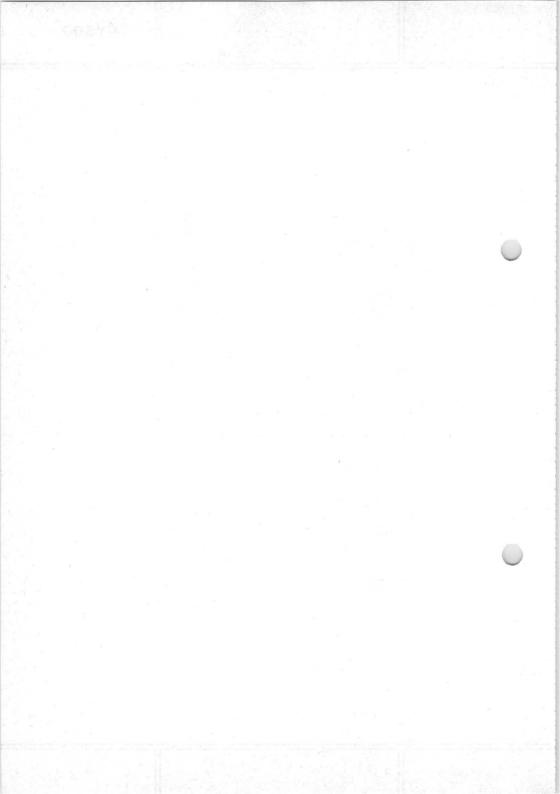
During operation, the external resistance between either heater pin of the PY500 and either mains terminal should be at least 100 Ω when Vf/earth = 220 V_{RMS} 50 Ω when Vf/earth = 110 V_{RMS}

The hot heater resistances of other tubes in the heater chain can serve for this purpose.

 $^{^{1})}$ Max. pulse duration 22% of a cycle, but max. 18 μs .



August 1970



BOOSTER DIODE

Booster diode for timebase circuits of colour television receivers. The PY500A is unilaterally interchangeable with the PY500 in existing circuits. In new equipment designs the 300 Ω protection resistance between pins 3 and 5 can be deleted for the PY500A.

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

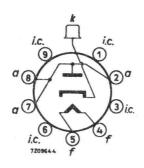
I_f	300	mA
V_f	42	V

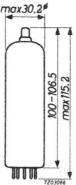
Dimensions in mm

MECHANICAL DATA

Base: Magnoval

Cap: Type 1





CAPACITANCES

Anode to cathode

Cathode to heater

4	1	
	100-106.5	max 115.2
		,

 C_{ak} 12.5 pF

 C_{kf} 3.1 pF

PY500A

TYPICAL CHARACTERISTICS

Internal resistance (I _a = 440 mA)	R_i	45.5 Ω
---	-------	---------------

LIMITING VALUES (Design centre rating system)

Anode dissipation	Wa	max.	11	W
Anode current, average	I_a	max.	440	mA
peak	I_{a_p}	max.	1000	mA
Anode voltage, negative peak	-Vap	max.	5600	V 1)
negative peak (absolute max.)	-V _{ap}	max.	7000	V 1)
Cathode to heater voltage, peak	V _{kfp}	max.	6300	V 1)

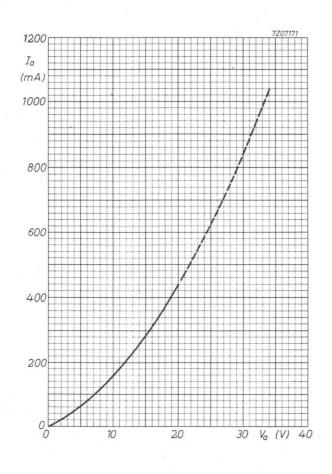
Series resistance heater chain

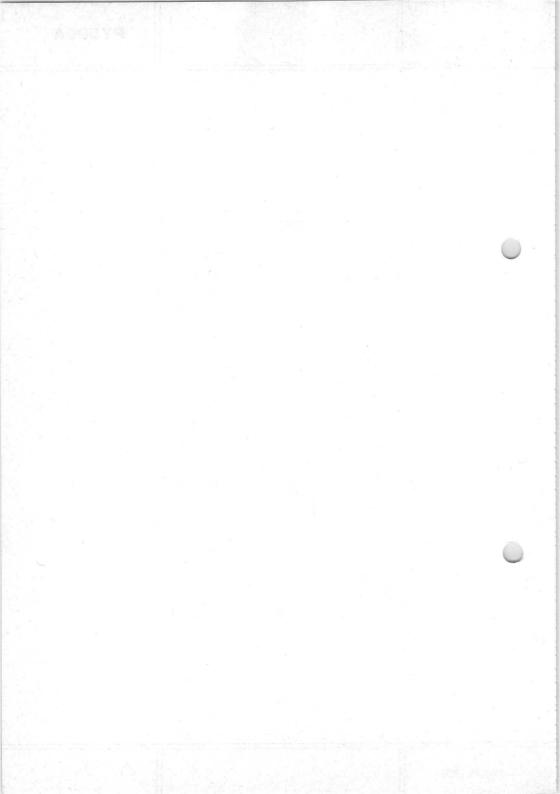
During operation, the external resistance between either heater pin of the PY500A and either mains terminal should be at least 100 Ω when Vf/earth = 220 V_{RMS} 50 Ω when Vf/earth = 110 V_{RMS}

The hot heater resistances of other tubes in the heater chain can serve for this purpose.

 $^{^{1})}$ Max. pulse duration 22% of a cycle, but max. 18 $\mu \mathrm{s}.$

PY500A





TRIPLE DIODE-TRIODE

Triple diode-triode intended for F.M. and A.M. signal detection and A.F. signal amplification.

fg ax ii	QUICK REFERENCE DATA			
Triode section			- Harts	reff refr n
Anode current	L.	I_a	1.0	mA
Transconductance		S	1.45	mA/V
Amplification factor		μ	70	. a n esta

HEATING: Indirect by A.C. or D.C.; series supply

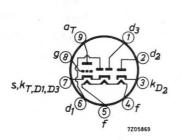
Heater current

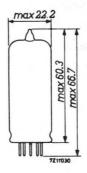
100 $\overline{V_f}$ Heater voltage 28

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





It is recommended to connect pin 5 to earth.

UABC80

CAP	ACIT	AN	CES

CAPACITANCES				
Triode section				
Grid to all except anode	$C_{g(a)}$		1.9	pF
Anode to all except grid	Ca(g)		1.4	pF
Anode to grid	C_{ag}		2.0	pF
Grid to heater	C_{gf}	max.	0.04	pF
Diode sections				
Diode No.1 to all	C_{d_1}		0.8	pF
Diode No.2 to all	C_{d_2}		4.8	pF
Diode No.3 to all	C_{d_3}		4.8	pF
Cathode (D ₂) to all	C_{kD_2}		5.0	pF
Diode No.1 to heater	C_{d_1f}	max.	0.25	pF
Diode No.3 to heater	C_{d_3f}	max.	0.2	pF
Cathode (D ₂) to heater	${^{C_{kD}}}_{2}\mathbf{f}$		2.5	pF
Between triode and diode sections				
Anode to diode No.1	C_{ad_1}	max.	0.12	pF
Anode to diode No.3	C_{ad_3}	max.	0.1	pF
Anode to cathode (D ₂)	C_{akD_2}	max.	0.01	pF
Grid to diode No.1	$^{\mathrm{C}_{\mathrm{gd}_{1}}}$	max.	0.07	pF
Grid to diode No.3	C_{gd_3}	max.	0.02	pF

 C_{gkD_2}

max. 0.005 pF

Grid to cathode (D_2)

TYPICAL C	HARAC	TERISTICS
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Triode	section
--------	---------

Anode voltage	Va	100	170	200	V
Grid voltage	v_g	-1	-1.85	-2.3	V
Anode current	I_a	0.8	1.0	1.0	mA
Transconductance	S	1.45	1.45	1.40	mA/V
Amplification factor	μ	70	70	70	-
Internal resistance	Ri	48	48	50	kΩ

OPERATING CHARACTERISTICS

Triode section as R.C. coupled A.F. amplifier

Grid resistor $R_g = 10 \text{ M}\Omega$

$V_{\mathbf{b}}$	200	200	200	170	170	170	V
R_a	220	100	47	220	100	47	kΩ
Rg*	0.68	0.33	0.15	0.68	0.33	0.15	$M\Omega$
I_a	0.56	1.00	1.60	0.46	0.82	1.25	mA
V_0/V_1	53	44	34	51	42	32	-
d_{tot}	0.3	0.4	0.5	0.4	0.5	0.6	%
d_{tot}	0.4	0.6	0.9	0.5	0.8	1.1	%
d_{tot}	0.9	1.0	1.5	1.1	1.3	2.0	%
V _b	V		100	100	0 1	00	V
V _b			100 220	100		00 47	V kΩ
					0	47	
R_a			220	100	0 3 0.	47 15	kΩ
R _a R _g '	i		220 0.68	0.3	0 3 0. 5 0.	47 15	kΩ MΩ
R _a Rg' I _a	i		220 0.68 0.21	0.3 0.3	0 3 0. 5 0.	47 15 52	kΩ MΩ
R _a Rg' I _a	i		220 0.68 0.21	0.3 0.3	0 3 0. 5 0.	47 15 52	kΩ MΩ
	Rg' Ia Vo/Vi dtot dtot	Rg' 0.68 I _a 0.56 V ₀ /V _i 53 d _{tot} 0.3 d _{tot} 0.4	Rg* 0.68 0.33 Ia 0.56 1.00 Vo/Vi 53 44 dtot 0.3 0.4 dtot 0.4 0.6	Rg* 0.68 0.33 0.15 Ia 0.56 1.00 1.60 Vo/Vi 53 44 34 dtot 0.3 0.4 0.5 dtot 0.4 0.6 0.9	Rg' 0.68 0.33 0.15 0.68 I _a 0.56 1.00 1.60 0.46 V _o /V _i 53 44 34 51 d _{tot} 0.3 0.4 0.5 0.4 d _{tot} 0.4 0.6 0.9 0.5	Rg* 0.68 0.33 0.15 0.68 0.33 I _a 0.56 1.00 1.60 0.46 0.82 V _o /V _i 53 44 34 51 42 d _{tot} 0.3 0.4 0.5 0.4 0.5 d _{tot} 0.4 0.6 0.9 0.5 0.8	Rg' 0.68 0.33 0.15 0.68 0.33 0.15 I _a 0.56 1.00 1.60 0.46 0.82 1.25 V _o /V _i 53 44 34 51 42 32 d _{tot} 0.3 0.4 0.5 0.4 0.5 0.6 d _{tot} 0.4 0.6 0.9 0.5 0.8 1.1

TYPICAL CHARACTERISTICS

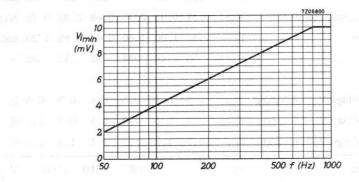
Diode section

Internal resistance diode No.1	
at diode voltage $V_{d_1} = +10 \text{ V}$	$R_i D_1$ 5 $k\Omega$
Internal resistance diode No.2 at diode voltage V _{d2} = +5 V	$R_i D_2 = 200 \Omega$
Internal resistance diode No.3 at diode voltage V _{d3} = +5 V	R _i D ₃ 200 Ω
Ratio between R _i (D ₂) and R _i (D ₃)	min. 0.67 max. 1.5

Microphony Triode section

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube at frequencies higher than 800 Hz.

At lower frequencies the sensitivity may be increased according to the figure below.



LIMITING VALUES (Design centre rating system)

Triode section			
Anode voltage	v_{a_0}	max. 550	V
	v_a	max. 250	V
Anode dissipation	w_a	max. 1	W
Cathode current	$I_{\mathbf{k}}$	max. 5	mA
Grid resistor	Rg	max. 3	$M\Omega$
Grid resistor at grid current bias	$R_{\mathbf{g}}$	max. 22	$M\Omega$
Cathode to heater voltage	v_{kf}	max. 150	V^1)
Diode sections			
Diode No.1 voltage, negative peak	$-v_{d_{1p}}$	max. 350	V
Diode No.2 voltage, negative peak	-Vd _{2p}	max. 350	V
Diode No.3 voltage, negative peak	-V _d _{3p}	max. 350	V
Diode No.1 current;	op		
D.C. component	I_{d_1}	max. 1	mA
peak	$I_{d_{1p}}$	max. 6	mA
Diode No.2 current:	•		
D.C. component	I_{d_2}	max. 10	mA
peak	$I_{d_{2p}}$	max. 75	mA
Diode No.3 current:	-1		
D.C. component	I_{d_3}	max. 10	mA
peak	$I_{d_{3p}}$	max. 75	mA
	- L'		

 $^{^{\}mathrm{1}}$) With regard to hum a max. AC heater to cathode voltage of 30 V_{RMS} is recommended.

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DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

QUICK REFERENCE DATA						
Triode section						
Anode current		I_a	1.5	mA		
Transconductance		S	1.65	mA/V		
Amplification factor		μ	70	-da		

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

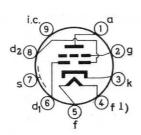
Heater voltage

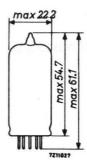
I_f	100	mA
$\overline{\mathrm{v_f}}$	14	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





¹⁾ Earthed side of the heater circuit.

CAPACITANCES

Diode No.2 to anode

CHI HOI PHICES					
Triode section					
Grid to all except anode	Cg(a)		2.3	pF	
Anode to all except grid	$C_{a}(g)$		2.3	pF	
Anode to grid	C_{ag}		1.2	pF	
Grid to heater	C_{gf}	max.	0.05	pF	
Diode sections					
Diode No.1 to all	C_{d_1}		0.9	pF	
Diode No.2 to all	C_{d_2}		0.9	pF	
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.2	pF	
Diode No.1 to heater	C_{d_1f}	max.	0.25	pF	
Diode No.2 to heater	C_{d_2f}	max.	0.05	pF	
Between triode and diode sections					
Diode No.1 to grid	C_{d_1g}	max.	0.007	pF	
Diode No.2 to grid	C_{d_2g}	max.	0.007	pF	
Diode No.1 to anode	C_{d_1a}	max.	0.005	pF	
	-				

TYPICAL CHARACTERISTICS OF THE TRIODE SECTION

Anode voltage	V_a 170 100	V
Grid voltage	v _g -1.55 -1.0	V
Anode current	I _a 1.5 0.8	mA
Transconductance	S 1.65 1.4	mA/V
Amplification factor	μ 70 70	-
Internal resistance	R _i 42 50	$\mathbf{k}\Omega$

C_{d2}a max. 0.01 pF

ODED ATTRIC	CITAD A COURD TOTTO	C
UPPERALING	CHARACTERISTICS	•

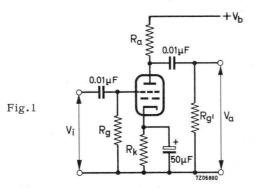
Triode section as A.F. amplifier,	circuit Fig	1				
Supply voltage	V _b	170	100	170	100	V
Anode resistor	Ra	0.22	0.22	0.1	0.1	
Cathode resistor	Rk	5.6	5.6	3.9	3.9	kΩ
Grid resistor	Rg	1.0	1.0	1.0	1.0	МΩ
Grid resistor next stage	Rg	0.68	0.68	0.33	0.33	МΩ
Anode current	Ia	0.28	0.18	0.45	0.28	mA
Voltage gain	V_{o}/V_{i}	44	41	37	34	
Distortion at:	to agreed of					
output voltage Vo = 3 VRMS	d _t	1.1	1.4	1.1	. 2.0	%
output voltage Vo = 5 VRMS	d _t	1.3	1.9	1.7	3.5	%
output voltage V_0 = 8 V_{RMS}	d _t	1.85	-	2.6	-	%
Supply voltage	$V_{\rm b}$	170	100	170	100	V
Anode resistor	Ra	0.22	0.22	0.1	0.1	$M\Omega$
Cathode resistor	$R_{\mathbf{k}}$	0	0	0	0	Ω
Grid resistor	R_g	22	22	22	22	$M\Omega$
Grid resistor next stage	Rg"	0.68	0.68	0.33	0.33	$M\Omega$
Anode current	I_a	0.46	0.21	0.82	0.35	mΐA
Voltage gain	V_{o}/V_{i}	48	41	42	35	
Distortion at						
output voltage $V_0 = 3 V_{RMS}$	d_t	0.95	1.45	0.75	1.6	%
output voltage $V_0 = 5 V_{RMS}$	d _t	1.1	2.0	1.0	2.8	%
output voltage Vo = 8 VRMS	dt	1.3	-	1.2	-	%

January 1970

OPERATING CHARACTERISTICS (continued)

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.



LIMITING VALUES (Design centre rating system)

Triode section				
Anode voltage	v_{a_0}	max.	550	V
	Va	max.	250	V
Anode dissipation	w_a	max.	0.5	W
Cathode current	$I_{\mathbf{k}}$	max.	5	mA
Grid resistor	R_g	max.	3	$M\Omega$
Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	100	V
Diode sections (each diode)				
Diode voltage, negative peak	-V _{dp}	max.	3 50	V
Diode current:				
average	I_d	max.	0.8	mA
peak	I_{d_p}	max.	5	mA
Cathode to heater voltage	v_{kf}	max.	100	V

DOUBLE DIODE-PENTODE

Double diode-pentode. Pentode intended for use as R.F. or I.F. amplifier.

QUICK REFER	ENCE DATA		
Pentode section			
Variable ransconductance			
Anode current	I_a	11	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	20	- -

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

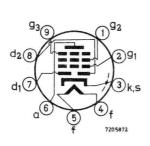
Heater voltage

 $\frac{I_f}{V_f} = \frac{100 \text{ mA}}{19 \text{ V}}$

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





UBF89

CAPACITANCES

Pentode	section
---------	---------

Diode No.2 to anode

Anode to all except grid No.1	$C_{a(g_1)}$	5.2	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$	5.0	pF	
Anode to grid No.1	Cag ₁	max. 0.0025	pF	
Grid No.1 to heater	$C_{g_{1f}}$	max. 0.05	pF	
Diode sections				
Diode No.1 to all	C_{d_1}	2.5	pF	(
Diode No.2 to all	C_{d_2}	2.5	pF	
Diode No.1 to diode No.2	$C_{d_1d_2}$	max. 0.25	pF	
Diode No.1 to heater	C_{d_1f}	max. 0.015	pF	
Diode No.2 to heater	C_{d_2f}	max. 0.003	pF	
Between pentode and diode sections				
Diode No.1 to grid No.1	$C_{d_1g_1}$	max. 0.0008	pF	
Diode No.2 to grid No.1	$C_{d_2g_1}$	max. 0.001	pF	
Diode No.1 to anode	C_{d_1a}	max. 0.15	pF	

 C_{d_2a}

max. 0.025 pF

TYPICAL CHARACTERISTICS

Pentode	section
---------	---------

Anode voltage	v_a	200	170	100	V
Grid No.2 voltage	v_{g_2}	100	100	100	V
Grid No.3 voltage	v_{g_3}	0	0	0	V
Grid No.1 voltage	v_{g_1}	-1.5	-1 ¹)	-2	V
Anode current	Ia	11	12	8.5	mA
Grid No.2 current	I_{g_2}	3.3	4	2.8	mA
Transconductance	S	4.5	5	3.5	mA/V
Amplification factor	$\mu_{\mathrm{g}_{2}\mathrm{g}_{1}}$	20	20	20	-
Internal resistance	R;	0.6	0.4	0.3	MΩ

OPERATING CHARACTERISTICS

Pentode section as R.F. or I.F. amplifier

Supply voltage	V_{b}	200		10	00	V
Anode resistor	R_a	0	E .		0	Ω
Grid No.3 voltage	v_{g_3}	0			0	V
Grid No.2 resistor	R_{g_2}	30		0.90	0	$k\Omega$
Grid No.1 voltage	v_{g_1}	-1.5	-20	-2	-10	V
Anode current	Ia	11	-	8.5	-	mA
Grid No.2 current	I_{g_2}	3.3	-	2.8	-	mA
Transconductance	S	4.5	0.12	3.5	0.11	mA/V
Internal resistance	R_{i}	0.6	_	0.3	_	$M\Omega$

 $[\]overline{\mbox{1}}$) To avoid grid No.1 current the negative grid No.1 voltage should be min. 1.5 V

UBF89

LIMITING VALUES (Design centre rating system)

Pentode section					
Anode voltage	v_{a_0}	max.	550	V	
	v_a	max.	250	V	
Anode dissipation	w_a	max.	2.25	W	
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V.	
Grid No.2 voltage					
at anode current I_a max. 4 mA	v_{g_2}	max.	250	V	
at anode current I_a min. 8 mA	v_{g_2}	max.	125	V	-
Grid No.2 dissipation	w_{g_2}	max.	0.45	W	
Cathode current	I_k	max.	16.5	mA	
Grid No.1 resistor	R_{g_1}	max.	3	$M\Omega$	
Grid No.3 resistor	R_{g_3}	max.	10	$k\Omega$	
Cathode to heater voltage	v_{kf}	max.	100	V	
Diode sections (each diode)					
Diode voltage, negative peak	-V _{dp}	max.	200	V	
Diode current; average	I_d	max.	0.8	mA	
peak	I_{d_p}	max.	5	mA	
Cathode to heater voltage	v_{kf}	max.	100	V	

R.F. DOUBLE TRIODE

Double triode intended for use as $\ensuremath{\text{R.F.}}$ amplifier and self oscillating mixer.

QU	CK REFERENCE DATA	
Anode current	I _a 10	mA
Transconductance	S 6.7	mA/V
Amplification factor	μ 48	_

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

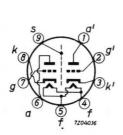
Heater voltage

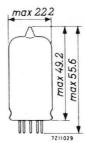
I_f	100	mA		
$\overline{v_f}$	26	V		

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES (each unit unless otherwise specified)

Anode to grid	C_{ag}	1.5	pF
Anode to cathode	c_{ak}	0.18	pF
Anode to cathode + heater + screen	Ca/kfs	1.2	pF
Grid to cathode + heater + screen	$C_{g/kfs}$	3.1	pF
Anode to cathode + heater + screen (measured with external screen of 22.5 mm dia	C _{a/kfs}	1.8	pF
Anode to anode other unit	Caa'	max. 0.04	pF
Anode to anode other unit (measured with external screen of 22.5 mm dia	C _{aa} '	max. 0.008	pF
Grid to grid other unit	Cgg'	max. 0.003	pF
Anode to grid other unit	Cag'	max. 0.008	pF
Anode to grid other unit	Ca'g	max. 0.008	pF
Anode to cathode other unit	cak'	max. 0.008	pF
Grid to cathode other unit	Cgk'	max. 0.003	pF
Anode to cathode other unit	Ca'k	max. 0.008	pF
Grid to cathode other unit	Cg'k	max. 0.003	pF

TYPICAL CHARACTERISTICS (each unit)

Anode voltage	v_a	100	170	200	V
Grid voltage	v_g	-1.2^{1})	-1.75	-2.4	V
Anode current	Ia	4.5	10	10	mA
Transconductance	S	4.8	6.7	6	mA/V
Amplification factor	μ	46	48	46	-

 $^{^{1}}$) In this case grid current may occur. If this is not permissible, a condition with a bias of -1.5 V should be chosen.

OPERATING CHARACTERISTICS						
As R.F. amplifier (unit a, g, k)						
Supply voltage	v_b	170	170	100	V	
Anode resistor	Ra	1.3	1.5	1.5	$k\Omega$	
Anode voltage	v_a	161	155	91	V	
Cathode resistor	$R_{\mathbf{k}}$	330	150	138	Ω	
Grid voltage	V_g	-2.2	-1.5	-0.8	V	
Anode current	I_a	6.6	9.8	5.7	mA	
Transconductance	S	5.1	6.7	5.9	mA/V	
Internal resistance	R_i	8.5	7	8	$k\Omega$	
Grid input resistance (f = 100 MHz)	rg	5.2	3.8	2.8	$k\Omega$	
Equivalent noise resistance	Req	0.82	0.55	0.61	$k\Omega$	
As self oscillating additive mixer (each	unit)					
Anode supply voltage	v_b	100	170	200	V	
Anode resistor	R_a	4.7	4.7	8.2	$k\Omega$	
Grid resistor	Rg	1	1	1	$M\Omega$	
Oscillator voltage	Vosc.	1.8	2.8	2.8	v_{RMS}	
Anode current	I_a	2.7	5.5	6	mA	
Conversion conductance	$S_{\mathbf{c}}$	2.2	2.8	2.9	mA/V	
Internal resistance	R_{i}	19	15	14	$k\Omega$	
Grid input resistance (f = 100 MHz)	r_g		15		$k\Omega$	
LIMITING VALUES (each unit) (Design	centre ra	ting syst	tem)			
Anode voltage	, ,	V_{a_0}	max	c. 550	V	
		V_a	max	c. 250	V	
Anode dissipation	7	W _a	max	c. 2.5	W	
Anode dissipation, total		Wa+Wa*	max	k. 4.5	W	
Cathode current]	k	max	k. 15	mA	
Cathode to heater voltage		V _{kf}	max	k. 90	V	
Grid voltage (negative)	_`	Vg	max	k. 100	V	
Grid resistor		R_{g}	max	k. 1	$M\Omega$	

For curves please refer to type PCC85

2

OPERATING CHARACTERS TICS

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TRIODE-HEPTODE

Triode-heptode. Heptode section intended for use as mixer R.F. - or I.F. amplifier. Triode section intended for use as oscillator in A.M./F.M. receivers.

N. A. C.	QUICK REFEREN	NCE DATA		
Triode section	3778	Just flam		
Anode current		I_a	13.5	mA
Transconductance	1.27	S	3.7	mA/V
Amplification factor		μ	22	r Take be
Heptode section				
Anode current		I_a	9.8	mA
Transconductance		S	4.3	mA/V
Amplification factor		$^{\mu}\mathrm{g}_{2}\mathrm{g}_{1}$	25	egad selo

HEATING: Indirect by A.C. or D.C.; series supply

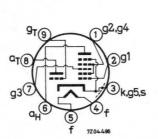
Heater current

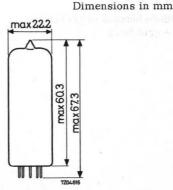
Heater voltage

$I_{\mathbf{f}}$	100	mA		
$V_{\mathbf{f}}$	19	V		

DIMENSIONS AND CONNECTIONS

Base: Noval





UCH81

CAPACITANCES

Triode	section

Grid to all except anode	$C_{g(a)}$	2.6	pF	
Anode to all except grid	$C_{a(g)}$	2.1	pF	
Anode to grid	C_{ag}	1.0	pF	
Grid to heater	$\mathrm{c_{gf}}$	max. 0.02	pF	
Heptode section				
Grid No.1 to all except anode	$C_{g_1(a)}$	4.8	pF	
Anode to all except grid No.1	$c_{a(g_1)}$	7.9	pF	
Anode to grid No.1	c_{ag_1}	max.0.006	pF	
Grid No.1 to heater	C_{g_1f}	max. 0.17	pF	
Grid No.3 to all	c_{g_3}	6	pF	
Grid No.1 to grid No.3	$c_{g_1g_3}$	max. 0.3	pF	
Grid No.3 to heater	c_{g_3f}	max. 0.06	pF	
Between heptode and triode section	us_			
Anode heptode to anode triode	$c_{a_H a_T}$	0.20	pF	
Anode heptode to grid triode	$C_{a_{\hbox{\scriptsize H}g_{\hbox{\scriptsize T}}}}$	max. 0.09	pF	
Grid No.1 heptode to anode triode	$c_{g_{1}H^{a}T}$	max. 0.06	pF	
Grid No.1 heptode to grid triode	$c_{g_1Hg_T}$	max. 0.17	pF	
Grid No.1 heptode to grid triode + grid No.3	Cg _{1H} /gTg ₃	max. 0.45	pF	

max. 0.35 pF

 C_{a_H/g_Tg_3}

Anode heptode to grid triode + grid No.3

Transconductance Amplification factor

	TYPICAL CHARACTERIST	TCS			
	Triode section				
	Anode voltage		v_a	100	V
	Grid voltage		v_g	0	V
	Anode current		Ia	13.5	mA
	Transconductance		S	3.7	mA/V
	Amplification factor		μ	22	
0	Heptode section				
	Anode voltage		 v_a	160	v
	Grid No.3 voltage		v_{g_3}	0	V
	Grids No.2 and 4 voltage		$v_{g_{2+4}}$	90	\mathbf{v}
	Grid No.1 current		I_{g_1}	0.5	μΑ
	Grid No.1 voltage		v_{g_1}	-0.5	\mathbf{v}
	Anode current		Ia	9.8	mA
	Grids No.2 and 4 current		Ig ₂₊₄	6.1	mA

 $\mu_{g_2g_1}$

OPERATING CHARACTERISTICS

Heptode section as m	ixer								
Supply voltage	v_b	10	00	17	70	20	00	V	
Anode resistor	R_a		0		0		0	Ω	
Grids No.2 and 4 resistor	Rg ₂₊₄]	10	1	10	1	10	kΩ	
Grid triode + grid No.3 resistor	R _{gT+g3}	4	17	4	17	4	17	kΩ	
Grid triode + grid No.3 current	$I_{g_T+g_3}$	11	15	20	00	23	30	μΑ	
Grid No.1 current	I_{g_1}	0.5	-	0.5	-	0.5	/ / -	μA 1)	
Grid No.1 voltage	v_{g_1}	-0.5	-12	-0.5	-19	-0.5	-22	V	
Anode voltage	Va	100	-	170	-	200	-	\mathbf{v}	
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	56	_	88	-	100	-	v	
Anode current	Ia	2.0	-	3.3	-	4.1	-	mA	
Grids No.2 and 4 current	Ig ₂₊₄	4.4	-	8.2	-	10	- 1 millongs	mA	
Conversion conductance	s_c	850	8.5	1100	11	1200	12	μA/V	
Internal resistance	R_i	0.75	min.3	0.8	min.3	0.85	min.3	$M\Omega$	
Equivalent noise resistance	Req	33	-	30	-	32	-	kΩ	

 $^{^1)}$ Grid current bias obtained with Rg1 = 1 $M\Omega$ and with zero volts a.g.c. voltage; resulting grid No.1 voltage: -0.5 V.

OPERATING	CHARACTERISTICS	(continued)
OLLIVATING	CHARACTERISTICS	(Continued)

Supply voltage	V_{b}	10	00	17	70	200		V
Anode resistor	Ra		0		0	3.9		kΩ
Grids No.2 and 4 resistor Grid No.3 voltage	$R_{g_{2+4}}$ V_{g_3}	1	.8	1	0	18		kΩ V
		~ -			~			
Grid No.1 current	I_{g_1}	0.5		0.5		0.5		μΑ
Grid No.1 voltage	v_{g_1}	-0.5	-15.7	-0.5	-26	-0.5	-30	V
Anode voltage	v_a	100	-	170	_	162	0.0	V
Grids No.2 and 4 voltage	$v_{g_{2+4}}$	52	_	80	_	90	-	v
Anode current	I_a	4.1	10.0	8.0	-	9.8	-	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	2.7	_	5.0	- III	6.1	al for	mA
Transconductance	S	2900	29	3900	39	4300	43	μΑ
Internal resistance	R_i	0.45	min.10	0.4	min.10	0.35 n	nin.10	МΩ
Amplification factor	$\mu_{g_2g_1}$	24	-	25	_	25		v sta
Equivalent noise resistance	Req	4.0	-	4.0	_	4.3	416 j 3	kΩ
Triode section as os	cillator							
Supply voltage			V	b	100	170	200	v
Anode resistor			R		15	15	15	kΩ
Grid triode + grid N resistor	0.3			g _T +g ₃	47	47	47	kΩ
Grid triode + grid N current	0.3			g _T +g ₃	115	200	230	μΑ
Anode current			I		2.5	4.5	5.4	mA
Effective transcondu	ctance			eff	0.58	0.65	0.65	mA

 $^{^1)}$ Grid current bias obtained with Rg $_1$ = 1 $M\Omega$ and with zero volts a.g.c. voltage; resulting grid No.1 voltage: -0.5 V.

UCH81

LIMITING VALUES (Design centre rating system)

, 0	,			
Heptode section				
Anode voltage		v_{a_0}	max. 550	V
		Va	max. 250	V
Anode dissipation		W_a	max. 1.8	W
Grids No.2 and 4 voltage		$v_{g_{2+4_0}}$	max. 550	V
		$v_{g_{2+4}}$	max. 125	V
Grids No.2 and 4 voltage (I_a max. 1 mA)		$v_{g_{2+4}}$	max. 250	V
Grids No.2 and 4 dissipation		$W_{g_{2+4}}$	max. 1	w
Cathode current		I _k	max. 18	mA
Grid No.1 resistor		R_{g_1}	max. 3	$M\Omega$
Grid No.3 resistor		R_{g_3}	max. 20	$\mathbf{k}\Omega$
Grid No.3 resistor grid No.3 directly connected		00		
to grid triode		R_{g_3}	max. 3	$M\Omega$
Cathode to heater voltage		v_{kf}	max. 100	V
Triode section				
Anode voltage		v_{a_0}	max. 550	V
		Va	max. 250	V
Anode dissipation		w_a	max. 0.8	W
Cathode current		I_k	max. 6.5	mA
Grid resistor		R_g	max. 3	$M\Omega$
Cathode to heater voltage		v_{kf}	max. 100	v

TRIODE-OUTPUT PENTODE

The triode section is intended for use as A.F. amplifier. The pentode section is intended for use as A.F. power amplifier.

QUICK REFERENCE DATA						
Triode section						
Anode current	I _a . 3.5	mA				
Transconductance	S 2.2	mA/V				
Amplification factor	μ 70					
Pentode section						
Anode current	I_a 41	mA				
Transconductance	S 7.5	mA/V				
Amplification factor	$\mu_{g_2g_1}$ 9.5	- 300.5				
Output power	W _o 3.3	W				

HEATING: Indirect by A.C. or D.C.; series supply

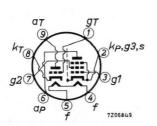
Heater current

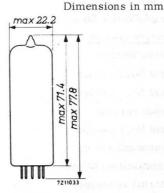
Heater voltage

$I_{\mathbf{f}}$	100	mA		
$\overline{v_{\mathrm{f}}}$	50	V		

DIMENSIONS AND CONNECTIONS

Base: Noval





UCL82

CAPACITANCES

CAPACITANCES					
Triode section					
Anode to all except grid	Ca(g)		4.3	pF	
Grid to all except anode	Cg(a)		2.7	pF	
Anode to grid	Cag		4.4	pF	
Grid to heater	C_{gf}	max.	0.02	pF	
Pentode section	3				
Anode to all except grid No.1	$C_{a(g_1)}$		8.0	pF	
Grid No.1 to all except anode	$C_{g_1(a)}$		9.3	pF	
Anode to grid No.1	C _{ag1}	max.	0.3	pF	
Grid No.1 to heater	C_{g_1f}	max.	0.3	pF	
Between triode and pentode sections	81,			3127	
Anode triode to grid No.1 pentode	$C_{a_Tg_{1P}}$	max.	0.02	pF	
Grid triode to anode pentode	$C_{g_{T}a_{p}}$	max.	0.02	pF	
Grid triode to grid No.1 pentode	C _{gTg1P}	max.	0.025	pF	
Anode triode to anode pentode	C _{a_Ta_p}		0.25	pF	
TYPICAL CHARACTERISTICS	a-Ta-b				
Triode section					
Anode voltage	v_a		100	V	
Grid voltage	V_g		0	V	
Anode current	Ia		3.5	mA	
Transconductance	S		2.2	mA/V	
Amplification factor	μ		70	-	8 1
Pentode section					
Anode voltage	Va		170	V	
Grid No.2 voltage	v_{g_2}		170	V	
Grid No.1 voltage	v_{g_1}		-11. 5	V	
Anode current	Ia		41	mA	
Grid No.2 current	I_{g_2}		9	mA	
Transconductance	S		7.5	mA/V	
Amplification factor	$\mu_{g_2g_1}$		9.5	-	

Internal resistance

16 kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier

11.	tode section as A.I. ampini	CI					
A)	Signal source resistance	R_S			0	. 22	МΩ
	Grid resistor	Rg				3	МΩ
	Grid resistor of next stage	Rg'			0	. 68	МΩ
	Supply voltage	V_b			170	100	V
	Cathode resistor	$R_{\mathbf{k}}$			2.7	2.7	kΩ
	Anode resistor	R_a			220	220	kΩ
	Anode current	I_a			0.43	0.23	mA
	Voltage gain	V_0/V_i^{-1}			51	47	(- 1944)
	Max. output voltage	v_{omax}			25	15	v_{RMS}
	Distortion	d_{tot}^{2})			2.3	4.0	%
B)	Signal source resistance	R_S		0.	22		МΩ
	Grid resistor	$R_{\mathbf{g}}$			22		ΜΩ
	Grid resistor of next stage	R_g		0.	68	JUB - 11 1	МΩ
	Supply voltage	V_{b}	170	170	100	100	v
	Cathode resistor	$R_{\mathbf{k}}$	0	0	0	0	Ω
	Anode resistor	R_a	100	220	100	220	kΩ
	Anode current	I_a	.86	0.50	0.37	0.22	mA
	Voltage gain	V_0/V_i^{-1}	49	53	42	46	Diare
	Max. output voltage	Vo max	19	20	8	9	v_{RMS}
	Distortion	d_{tot}	1.43)	1.43)	1.3^{2}	1.5 ²)	%

Microphony and hum

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage of minimum $10\,\text{mV}_{RMS}$ is required for an output of $50\,\text{mW}$ of the output stage, Z_g (f = $50\,\text{Hz}$)= 0.25 $M\Omega$ and without A.C. voltage between pin 4 and cathode.

¹⁾ Measured at small input voltage.

²⁾ At lower output voltages the distortion is proportionally lower.

³⁾ At lower output voltages down to 5 V_{RMS} the distortion is approximately constant. At values below 5 V_{RMS} the distortion is approximately proportional to V_0 .

OPERATING CHARACTERISTICS

Pentode	section

Class A	(Measured	with Vr	constant)
Clubb 11	(IVICUDUI CU	AATCTT AV	COLL Decerte

Class A (Measured	with VK cons	laiit)								
Supply voltage		v _{ba} =	V_{bg_2}	100			170		V	
Cathode resistor		$R_{\mathbf{k}}$	2	170			200		Ω	
Load resistance		$R_{a\sim}$		3.0			3.25		$\mathbf{k}\Omega$	
Grid No.1 driving vo	oltage	$V_{\mathbf{i}}$	0	0.7	3.75	0	0.61	5.9	v_{RMS}	
Anode current		I_a	26	-	27	42	-	44	mA	-
Grid No.2 current		I_{g_2}	5.8	-	8.6	9.2	-	15.5	mA	
Output power		Wo	0	0.05	1.0	0	0.05	3.2	W	
Distortion		d_{tot}	-	-	10	-	-	10	%	
Supply voltage	* _ X			V _{ba}	= V _{bg2}		200		V	
Grid No.2 series re	sistor (non-c	lecoupl	ed)	R_{g_2}			470		Ω	
Cathode resistor				$R_{\mathbf{k}}$			33 0		Ω	
Load resistance				R _a ∼			4.5		$\mathbf{k}\Omega$	
Grid No.1 driving vo	oltage			$v_{\mathbf{i}}$		0	0.66	6.7	v_{RMS}	
Anode current				I_a		35	-	37	mA	
Grid No.2 current				I_{g_2}		7.8	- ,	13.3	mA	
Output power				W_{o}		0	0.05	3.3	W	
Distortion				d_{tot}		-	-	10	%	

(2008)				
Triode section				
Anode voltage	V_{a_0}	max.	550	V
	v_a	max.	250	V
Anode dissipation	W_a	max.	1	W
Cathode current	$I_{\mathbf{k}}$	max.	15	mA
Grid resistor				
for fixed bias	$R_{\mathbf{g}}$	max.	1	$M\Omega$
for automatic bias	$R_{\mathbf{g}}$	max.	3	$M\Omega$
Grid impedance at 50 Hz	z_{g}	max.	0.5	$M\Omega$
Cathode to heater voltage	$V_{\mathbf{k}\mathbf{f}}$	max.	200	V
Pentode section				
Anode voltage	v_{a_0}	max.	550	V
	v_a	max.	250	V
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V
	v_{g_2}	max.	250	V
Anode dissipation	W_a	max.	7	W
Grid No.2 dissipation				
average	W_{g_2}	max.	2	W
peak	$w_{g_{2p}}$	max.	3.2	W
Cathode current	$I_{\mathbf{k}}$	max.	50	mA
Grid No.1 resistor				
for fixed bias	R_{g_1}	max.	1	$M\Omega$
for automatic bias	R_{g_1}	max.	2	$M\Omega$
Cathode to heater voltage	v_{kf}	max.	200	V

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R.F. PENTODE

Pentode with variable transconductance intended for use as $R.F.\ \text{or}\ I.F.\ \text{amplifier.}$

QUICK REFE	RENCE DATA	286	died Probe
Anode current	Ia	12	mA
Transconductance	S	4.4	mA/V
Amplification factor	$\mu_{\mathrm{g_2g_1}}$	21	
Internal resistance	$R_{\mathbf{i}}$	400	kΩ

HEATING: Indirect by A.C. or D.C.; series supply

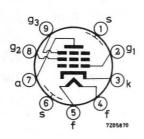
Heater current

Heater voltage

If	100	mA		
$V_{\mathbf{f}}$	12.6	v		

DIMENSIONS AND CONNECTIONS

Base: Noval



Dimensions in mm max 22.2

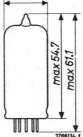
CAPACITANCES

Anode to all except grid No.1

Grid No.1 to all except anode

Anode to grid No.1

Grid No.1 to heater



$$C_{a(g_1)}$$
 5.1 pF $C_{g_1(a)}$ 5.5 pF

$$C_{g_1}(a)$$
 5.5 pF C_{ag_1} max. 0.002 pF

$$C_{g_1f}$$
 0.05 pF

TYPICAL CHARACTERISTICS

Anode voltage	Va 170	V
Grid No.2 voltage	Vg ₂ 100	V
Grid No.3 voltage	v_{g_3} 0	V
Anode current	I _a 12	mA
Grid No.1 voltage	V _{g1} -1.2	V 1)
Grid No.2 current	I_{g_2} 4.4	mA
Transconductance	S 4.4	mA/V
Internal resistance	R _i 0.4	$M\Omega$
Amplification factor	$\mu_{g_2g_1}$ 21	

OPERATING CHARACTERISTICS

Anode voltage, supply voltage	$v_a = v_b$	2	00	17	70	V
Grid No.3 voltage	v_{g_3}		0		0	V
Grid No.2 resistor	R_{g_2}		24		15	$k\Omega$
Cathode resistor	R_k	13	130		30	Ω
Grid No.1 voltage	v_{g_1}	-1.95	-20	-1.95	-20	$\overline{\mathbf{v}}$
Anode current	I_a	11.1	15-77	11.0	_	mA
Grid No.2 current	I_{g_2}	3.8	-	3.9	-	mA
Transconductance	S	3.85	0.16	3.8	0.11	mA/V
Internal resistance	R_i	550	-	450	-	$k\Omega$
Equivalent noise resistance	Req	4.2	Constant	4.5	-	$k\Omega$
Input conductance f = 50 MHz	g	102	7.2	102	-	$\mu A/V$

 $^{^{}m l}$) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.

TYPICAL CHARACTERISTIC	S AND OPERATING	CHARACTERISTICS
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(continued)

Anode voltage, supply voltage	$v_a = v_b$	10	00	10	00	V	
Grid No.3 voltage	v_{g_3}		0		0	V	
Grid No.2 resistor	R_{g_2}		15		0	$k\Omega$	
Cathode resistor	R_k	13	30	10	60	Ω	
Grid No.1 voltage	v_{g_1}	-1.05	-10	-1.9	-10	V	
Anode current	Ia	6.0		8.6	-	mA	
Grid No.2 current	I_{g_2}	2.1	-	3.1	-	mA	
Transconductance	S	3.2	0.15	3.3	0.16	mA/V	
Internal resistance	R_{i}	475	-	300	-	$k\Omega$	
Equivalent noise resistance	Req	3.5	-	4.7	-	$k\Omega$	
Input conductance f = 50 MHz	g	120	-	102	-	$\mu A/V$	

Ano	de voltage	v_{a_0}	max.	550	V	
		Va	max.	250	V	
Ano	de dissipation	w_a	max.	2.25	W	
Grid	l No.2 voltage	$v_{g_{2o}}$	max.	550	V	
		v_{g_2}	max.	250	V	
Grid	l No.2 dissipation	W_{g_2}	max.	0.45	W	
Cath	node current	I_k	max.	16.5	mA	
Grid	l No.1 resistor	R_{g_1}	max.	3	$M\Omega$	
Grid	l No.3 resistor	R_{g_3}	max.	10	$k\Omega$	
Cath	node to heater voltage	v_{kf}	max.	150	\mathbf{v}	

			*				

A DELEGRACIO DE LES COMENÇÃO (1) RELIGIOS ENTREMENTO

1127			

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFER	RENCE DATA		
Anode current	Ia	70	mA
Transconductance	S	11	mA/V
Amplification factor	$^{\mu}$ g $_{2}$ g $_{1}$	8	
Output power	W_{o}	5.3	W

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

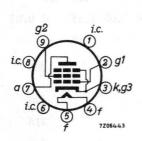
Heater voltage

I_f	100	mA	
$\overline{v_{f}}$	45	V	

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a}(g_1)$	6.8	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	13	pF
Anode to grid No.1	c_{ag_1}	max. 0.6	pF
Grid No.1 to heater	C_{g_1f}	max. 0.25	pF

TYPICAL CHARACTERISTICS

Anode voltage	Va	170	V	
Grid No.2 voltage	v_{g_2}	170	V	
Grid No.1 voltage	v_{g_1}	-12.5	V	
Anode current	Ia	70	mA	
Grid No.2 current	I_{g_2}	3.5	mA	
Transconductance	S	11	mA/V	
Amplification factor	$\mu_{g_2g_1}$	8		
Internal resistance	R _i	26	$k\Omega$	

OPERATING CHARACTERISTICS

Class A 1) Supply voltage								
Supply voltage								
	$V_{\mathbf{b}}$		100			170		V
Cathode resistor	$R_{\mathbf{k}}$		130			130		Ω
Load resistance	R_{a}		2.1			2.0		kΩ
Grid No.1 driving voltage	v_i	0	0.55	3.8	0	0.47	6.1	v_{RMS}
Anode current	Ia	41	-	42	75	-	76	mA
Grid No.2 current	I_{g_2}	2.6	-	8.6	4.0	-	16.5	mA
Output power	W_{o}	0	0.05	1.55	0	0.05	5.1	W
Distortion	d_{tot}	-	-	10	-	-	10	%
Supply voltage	V_{b}				20	00		V
Grid No.2 series resistor (non decoupled)	Rg2				4	70		Ω
Cathode resistor	$R_{\mathbf{k}}$				2	15		Ω
Load resistance	R_{a}				2	. 5		$k\Omega$
Grid No.1 driving voltage	v_i			0	0	. 52	7.0	v_{RMS}
Anode current	I_a			65		- 6	64	mA
Grid No.2 current	I_{g_2}			3.2		ā julies	11.4	mA
Output power	W_{o}			0	0	.05	5.3	W
Distortion	d_{tot}			-		_ 1.01	10	%
	Grid No.1 driving voltage Anode current Grid No.2 current Output power Distortion Supply voltage Grid No.2 series resistor (non decoupled) Cathode resistor Load resistance Grid No.1 driving voltage Anode current Grid No.2 current Output power Distortion	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

 $^{^{1}}$) Measured with V_{k} kept constant.

OPERATING	CHARACTERISTICS	(continued)

Class	AB.	two	tubes	in	push-pull
Class	Tru,	CAAO	tuncs	777	basii bari

Supply voltage	$V_{\mathbf{b}}$		200		V
Common cathode resistor	$R_{\mathbf{k}}$		120		Ω
Load resistance	Raa~		3		$k\Omega$
Grid No.1 driving voltage	Vi	0	0.47	14.3	v_{RMS}
Anode current	I_a	2x60	-	2x64.5	mA
Grid No.2 current	I_{g_2}	2x3.0	-	2 x 18.5	mA
Output power	W_{o}	0	0.05	14.3	W
Distortion	d_{tot}	-	-	3.8	%

Anode voltage	v_{a_0}	max.	550	V	
	Va	max.	250	V	
Grid No.2 voltage	$v_{g_{2o}}$	max.	550	V	
	v_{g_2}	max.	200	V	
Anode dissipation	w_a	max.	12	W	
Grid No.2 dissipation, average	W_{g_2}	max.	1.75	W	
peak	$w_{g_{2p}}$	max.	6	W	
Cathode resistor	I _k	max.	100	mA	
Grid No.1 resistor, automatic bias	R_{g_1}	max.	1	$M\Omega$	
Cathode to heater voltage	v_{kf}	max.	200	V	

(Seining) The BEST SARAM STOLENS

	agree to a	

SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

	QUICK REFERENCE DATA			That
Transformer voltage	HARACTE AND THE	V _{tr}	250	V _{RMS}
D.C. current		I_{o}	110	mA

HEATING: Indirect by A.C. or D.C.; series supply

Heater current

Heater voltage

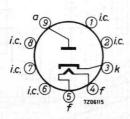
If	100	mA	
$V_{\mathbf{f}}$	38	V	

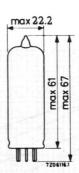
Dimensions in mm

1

DIMENSIONS AND CONNECTIONS

Base: Noval



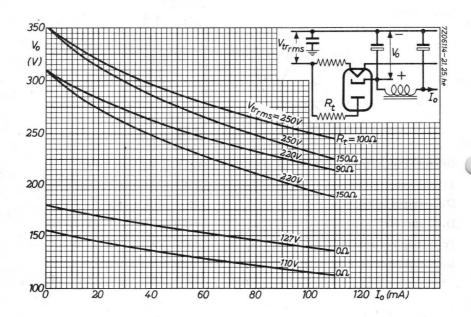


OPERATING CHARACTERISTICS as single-phase half-wave rectifier

Transformer voltage	V _{tr}	250	220	127	110	v_{RMS}
D.C. output voltage	V _o	245	215	135	112	V
D.C. current	I_{O}	110	110	110	110	mA
Protecting resistance	R _t	100	90	0	0	Ω
Input capacitor of smoothing filter	C _{filt}	100	100	100	100	μF

January 1970

Anode voltage, peak inverse	V_{ainv_p}	max.	700	V
D.C. current	Io	max.	110	mA
Anode peak current	I_{a_p}	max.	660	mA
Cathode to heater voltage, peak, k pos.	v_{kfp}	max.	550	V
Input capacitor of smoothing filter	$C_{ m filt}$	max.	100	μF
Protecting resistance at transformer voltage	R _t min.100 9 V _{tr} 250 22	0 0 0 0 127	0 110	Ω V_{RMS}



SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

QUICK REFE	RENCE DATA		rve
Transformer voltage	v_{tr}	250	V
D.C. current	I_{O}	100	mA

HEATING: Indirect by A.C. or D.C.; series supply

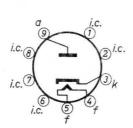
Heater current

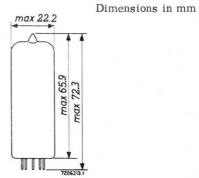
Heater voltage

I_f	100	mA	
$V_{\mathbf{f}}$	31	V	

DIMENSIONS AND CONNECTIONS

Base: Noval





OPERATING CHARACTERISTICS as single-phase half-wave rectifier.

Transformer voltage	v_{tr}	250	220	127	110	v_{RMS}
D.C. output voltage	V_{o}	205	188	135	113	V
D.C. current	I_{o}	100	100	100	100	mA
Protecting resistance	Rt	210	160	0	0	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μ F

Anode voltage, peak inverse	$v_{a_{inv_p}}$	max.	700		V
D.C. current	Io	max.	100		mA
Anode current, peak	I_{a_p}	max.	600		mA
Heater to cathode voltage, peak, k pos.	v_{kf_p}	max.	550		V
Protecting resistance at transformer voltage	R _t V _{tr}	min. 210 250	160 0 220 127	0 110	$_{V_{RMS}}^{\Omega}$

INDEX OF TYPE NUMBERS

Type No.	Type No.	Type No.	Type No.
DY51	ECL82	EY500	PL36
DY86	ECL84	EY500A	PL81
DY87	ECL85	EZ80	PL83
DY802	ECL86	EZ81	PL84
EAA91	ECL805	GY501	PL95
EABC80	ED500	GZ34	PL500
EB91	EF80	PABC80	PL504
EBC81	EF85	PC86	PL505
EBF80	EF86	PC88	PL508
EBF89	EF89	PC92	PL509
EC86	EF183	. PC900	PL519
EC88	EF184	PCC85	PL802
EC92	EFL200	PCC88	PY81
EC900	EL34	PCC189	PY82
ECC81	EL36	PCF80	PY88
ECC82	EL81	PCF86	PY500
ECC83	EL84	PCF200	PY500A
ECC85	EL86	PCF201	UABC80
ECC88	EL95	PCF801	UBC81
ECC189	EL500	PCF802	UBF89
ECF80	EL503	PCH200	UCC85
ECF86	EL504	PCL82	UCH81
ECF200	EL508	PCL84	UCL82
ECF201	EL509	PCL85	UF89
ECF801	EL519	PCL86	UL84
ECF802	EL802	PCL805	UY85
ECH81	EM84	PD500	UY89
ECH83	EM87	PD510	
ECH84	EY81	PF86	
ECH200	EY88	PFL200	

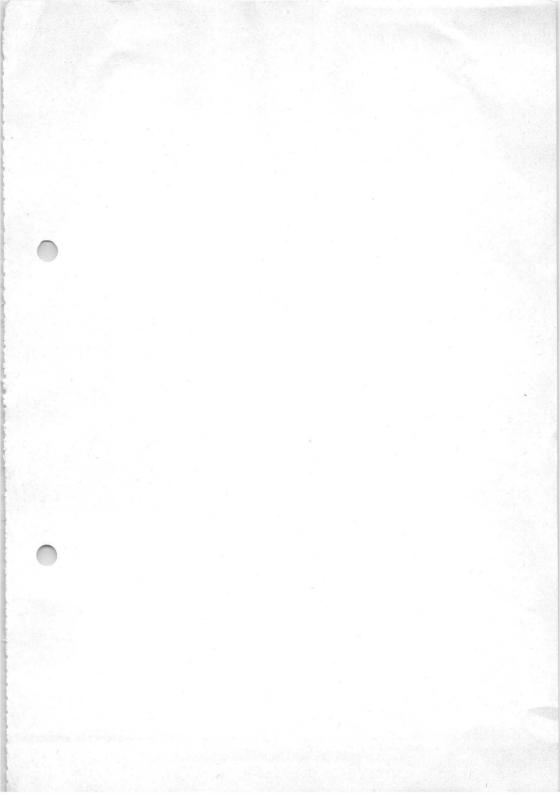
PHILIPS

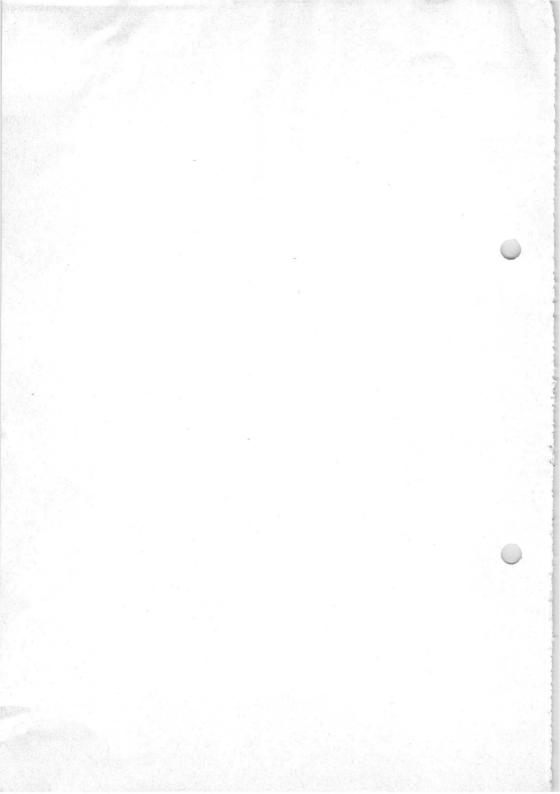
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March 1972

ASSEMBLY SET TO RECE

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Jena al section Receiving tubes General section

Receiving tubes